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博士論文"ELECTRONIC STRUCTURES OF Si-SiO₂ SYSTEM"「Si-SiO₂系の電子状態」

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電子工学専門課程

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ABSTRACT

Various energy levels caused by micro-structural defects such as dangling bonds of silicon or oxygen atoms, oxygen vacancies and impurity atoms (H, OH, Cl and F) at the interface between amorphous SiO_2 and the crystalline Si substrate, and in the SiO_2 film are calculated based on Green's function formulation and the parameterized tight-binding Hamiltonians for Si and O. The extended Hückel theory in which overlap integrals are not included is used to calculate Hamiltonians for H, Cl and F.

The major results are as follows. (1) The perfect interface and the interface with oxygen dangling bonds do not have a energy level in the Si bandgap, whereas $\text{Si}_2=\text{Si}$ -dangling bond and oxygen vacancy at the interface have. (2) This dangling bond level moves out from the Si bandgap with bonding any of H, OH, Cl and F. This corresponds to the annealing behavior of the interface trap states. (3) Si-Si weak bond, Si-Si weak interaction, Si-O weak bond, Si-O weak interaction at the interface give rise to localized states in the Si bandgap whose energy vary by changing the geometrical configuration of the chemical bonding such as the bond length and the bond angles. These are thought to be possible origins of interface states continuously distributed in energy. (4) Amorphous SiO_2 without Si dangling bonds or oxygen vacancies

has no localized level in the SiO_2 bandgap, even if the Si-O-Si bond angle is varied in a wide range. (5) The Si dangling bond and Si-Si bond in SiO_2 cause gap states. These states can be origins of neutral traps in the SiO_2 .

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CHAPTER 1. INTRODUCTION

Silicon is widely used for electronic devices and its oxide, especially SiO_2 , also takes an important role in the recent semiconductor electronics as protecting layers of silicon ICs and insulators of MOSFETs. So that great amount of activities have been carried out on the Si- SiO_2 system but there still remains some problems about the Si- SiO_2 interface trap states and SiO_2 bulk traps.^{1 ~ 45}

The trap states at the Si- SiO_2 interface are important in controlling the threshold voltage V_{th} , transconductance and flicker noise of MOS transistors. Although MOS technology has made possible to reduce the density of the Si- SiO_2 interface states, there typically remains a residual density of the interface states between 10^{11} and 10^{12} [cm^{-2}].⁵⁴

On the other hand, the SiO_2 bulk traps have much to do with a "hot electron injection problem". Recently, the size of MOS devices in ICs becomes very minute, and as a result, the doping density becomes higher due to the "scaling theory".

Consequently, the electric field near the Si- SiO_2 interface increases to the point where the electrons are accelerated by the field and injected into the SiO_2 layer. The injected electrons are then trapped by the SiO_2 bulk traps and shift the threshold voltage. This gives rise to the instability of MOS devices and is considered to be a technological problem. Since the SiO_2 bulk traps are much generated by the electron beam

lithography, the "hot electron injection problem" severely limits the design of VLSI.

However, the microscopic origins of the Si-SiO₂ interface states and SiO₂ neutral traps are not yet understood clearly.

The purpose of this research is to obtain the theoretical background of the microscopic origins of these traps. In this thesis the following items are discussed. (1) The calculation method to treat the electronic structure of crystalline Si-amorphous SiO₂ interfaces and bulk amorphous SiO₂ with or without microscopic structural disorders such as defects and impurities, has been developed based on tight-binding Hamiltonians and Green's function formulation. (2) This method has been applied to the real system with varying physical parameters such as bonding lengths and bonding angles in a wide range.

(3) According to the results of the calculation, the possible origins of the Si-SiO₂ interface trap states continuously distributed in energy and the SiO₂ bulk traps are proposed.

Theoretical explanation of the annealing behaviors of these traps are also discussed.

Chapter 1 of this thesis is dedicated for the determination of the tight-binding parameters for silicon. Chapter 2 describes the Extended Hückel Theory which is used for the impurity problems in this work. Chapter 3 is dealing with the Green's function formulation as a general tool for calculating the electronic structures of solids and some applications of this method are described in this chapter. In chapter 5, the

calculation method for the interface problem and the calculated results are given together with the possible models of the interface trap states and their annealing behavior. The bonding defects in amorphous SiO_2 are discussed in chapter 6.

Chapter 7 is dedicated for general conclusions. Appendix A, B, and C treat the computer programs used in this work, the measurements of SiO_2 bulk traps, and the useful tables and figures, respectively.

CHAPTER 2. SINGLE CRYSTALLINE SILICON SUBSTRATE

SECTION 2-1. INTRODUCTORY REMARK

In this chapter the determination of a new set of tight-binding interaction parameters for silicon is described.

In order to calculate the electronic structures of solids, the first thing to do is to set up Hamiltonians. The basis of the Hamiltonian can be plane waves, orthogonalized plane waves, muffin-tin orbitals, or atomic orbitals. Since the interface problems which this work deals with is itself complex, one electron Hamiltonian together with atomic orbitals as a basis set (Linear Combination of Atomic Orbitals or tight-binding method) has been adopted because the tight-binding method is the most simple and flexible, but nevertheless it is known that this method can describe the various electronic properties of solids satisfactorily if the parameters in the tight-binding method are properly chosen. The interaction parameters in the simple tight-binding method, which can be regarded as resonance integrals or hopping integrals, are usually determined so as to fit the calculated band structure to the experimental results and the band structure calculated by the pseudopotential method. As for the interaction parameters for Si several authors have published the parameters, but the agreement of the band structure calculated by using previously published parameters^{55~57} with the band structure which was experimentally known

and calculated by the pseudopotential method is not necessarily satisfactory, so that the parameters up to 2nd nearest neighbor interactions have been determined to improve the results.

In this chapter, firstly, the tight-binding method is described briefly and then the fitting procedure is mentioned which is followed by the results and discussions.

SECTION 2-2. TIGHT-BINDING METHOD

The Schrödinger equation for one electron is expressed as

$$\mathcal{H} \psi_n = \epsilon_n \psi_n \quad \text{Eq. 2-2-1}$$

,where \mathcal{H} is a Hamiltonian, ψ_n is the eigen function belonging to an eigen value ϵ_n . In the tight-binding method, ψ_n is expanded by atomic orbitals φ_j 's as

$$\psi_n = \sum_j c_j^n \varphi_j \quad \text{Eq. 2-2-2}$$

Then, substituting eq. 2-2-2 into eq. 2-2-1, multiplying φ_i^* from the left and integrating over the space coordinate (including spin coordinate if spins are taken into consideration), we have

$$H |\epsilon_n\rangle = \epsilon_n S |\epsilon_n\rangle \quad \text{Eq. 2-2-3}$$

,where

$$H_{ij} \triangleq \int \varphi_i^* \mathcal{H} \varphi_j d\mathbf{x}, \quad \text{Eq. 2-2-4}$$

$$S_{ij} \triangleq \int \varphi_i^* \varphi_j d\mathbf{x}, \quad \text{Eq. 2-2-5}$$

and

$$|\epsilon_n\rangle \triangleq (c_1^n, c_2^n, \dots, c_N^n)^T \quad \text{Eq. 2-2-6}$$

In the simple tight-binding method, S_{ij} is set equal to δ_{ij} . This means that S_{ij} ($i \neq j$) is neglected or that the atomic orbitals are orthogonalized by the Löwdin method.⁷² The distinction between these two interpretations is not made clear, but the assumption of $S_{ij} = \delta_{ij}$ is generally used quite flexibly. The resulting equation is

$$H|\epsilon_n\rangle = \epsilon_n|\epsilon_n\rangle \quad \text{Eq. 2-2-7}$$

In the simple tight-binding method, the resonance integral, H_{ij} , is considered as a parameter which is to be determined so as to reproduce the experimentally known band structure of a crystal solid. Since H_{ij} is usually a rapidly decreasing function on the distance of the orbitals i and j , H_{ij} between two distant orbitals are set equal to zero. Here, it should be noted that this approximation does not mean the exclusion of the functions which spread over a large area of the space. For example, the Bloch orbitals can be constructed within this approximation. If only the H_{ij} 's between the orbitals belonging to the nearest neighbor atoms (up to the 2nd nearest neighbor atoms) are taken into account, the approximation is called the "1st nearest neighbor approximation (2nd nearest neighbor approximation)".

SECTION 2-3. FITTING PROCEDURE

The 2nd nearest neighbor approximation is adopted here due to the reason given in section 2-4, and consequently 10 free interaction parameters exist. These parameters are the self-energy of Si s orbital (E_s), that of Si p orbital (E_p), and the 8 resonance integrals which are given in table 2-3-1.

Let the vectors $P^\circ = (P_1^\circ, \dots, P_{10}^\circ)^T$, $E^\circ = (E_1^\circ, \dots, E_N^\circ)^T = E(P^\circ)$, and $E^\dagger = (E_1^\dagger, \dots, E_N^\dagger)^T$ be the initial values of the interaction parameters, the initial energy eigen values, and the true energy eigen values which are derived from the experiments and the pseudopotential calculation. New set of parameters $P^\circ + \Delta P^\circ$ are determined so as to reproduce the true energy eigen values E^\dagger . Using Taylor expansion the problem can be linearized in the form as

$$E(P^\circ + \Delta P^\circ) \sim E^\circ + \frac{dE^\circ}{dP^\circ} \Delta P^\circ = E^\dagger \quad \text{Eq. 2-3-1}$$

ΔP° is calculated from this equation. The algorithm is shown in fig. 2-3-1 as a flowchart. Generally speaking, however, eq. 2-3-1 can not be solved uniquely because it takes the form as

$$N \begin{pmatrix} \overbrace{\frac{dE^\circ}{dP^\circ}}^{10} \\ \underbrace{\Delta P^\circ}_1 \end{pmatrix} = \begin{pmatrix} E^\dagger \\ -E^\circ \end{pmatrix} \quad N > 10 \quad \text{Eq. 2-3-2}$$

But it can be solved by using the method of least squares.

This method is already enrolled in the program library of Tokyo university computer center as LESW1.

The fitted eigen values are seven valence band eigen values derived from the experiments, six conduction band eigen values given by the pseudopotential calculation, and three

eigen values of the Si (111) free surface with no relaxation and no reconstruction calculated by the pseudopotential method which is in good agreement with the experimental results. The eigen value problem of the Si free surface is solved by the method presented in Section 4-4. The fitting procedure is carried out with the special care to fit the bandgap of 1.12 [eV]. The computer programs used for this fitting (SBFIT and SBFIT3) are shown in Appendix A.

SECTION 2-4. RESULTS AND DISCUSSIONS

Figure 2-4-1 is the calculated energy band structure of Si with the new interaction parameters determined in this work together with the energy band structures calculated with the previously published parameters. The values of the parameters are listed in Table 2-4-1. The free surface states calculated with various sets of interaction parameters are compared with one another in Fig. 2-4-2.

Chadi's parameters⁵⁷ are obtained on the basis of the 1st nearest neighbor approximation. These parameters can reproduce the valence band but completely fail to reproduce the conduction band and the calculated bandgap is 3.41 [eV] as seen in Table 2-4-2. Dresselhaus and Dresselhaus's (D&D) parameters⁵⁶ show good agreement about the bandgap with the experimental

results but the calculated eigen value of the bottom of the valence band is very different from the true value. With Pandey and Phillips's (P&P) parameters⁵⁵ which include 8 non-zero parameters, the energy band structure can be calculated correctly except the bandgap whereas the calculated surface states are not in good agreement with the self-consistent pseudopotential calculation⁵⁸ as seen from Fig. 2-4-2.

On the other hand, the agreement of the calculated results by the parameters determined in this work which include 10 non-zero parameters, with the experimental results and the pseudopotential calculation results⁵⁵ is satisfactory. Of course the more number of parameters are included, the better fit with the true values can be achieved. However, the calculation with many parameters is tedious and sometimes impossible. So that the 2nd nearest neighbor approximation can be said the best approximation in dealing with the complex problems such as interface problems with microstructural disorders.

SECTION 2-5. SUMMARY

The interaction parameters for Si are determined within the 2nd nearest neighbor approximation with a special care to fit the calculated electronic structures near the bandgap to the experimental results and the pseudopotential results. The calculation with the parameters reproduces the true electronic

band structures of bulk Si and the energy eigen values of the Si (111) free surfaces satisfactorily, so that the present parameters can be used in the calculation of the electronic structures of the Si-SiO₂ system.

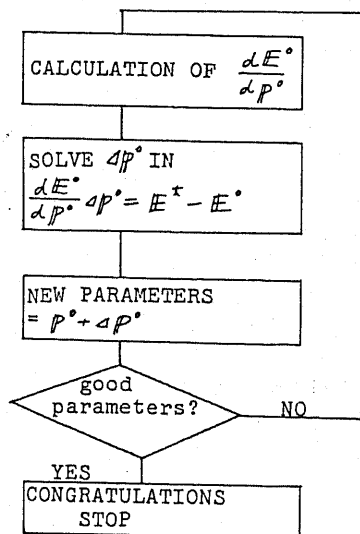


Fig. 2-3-1.
Fitting algorithm

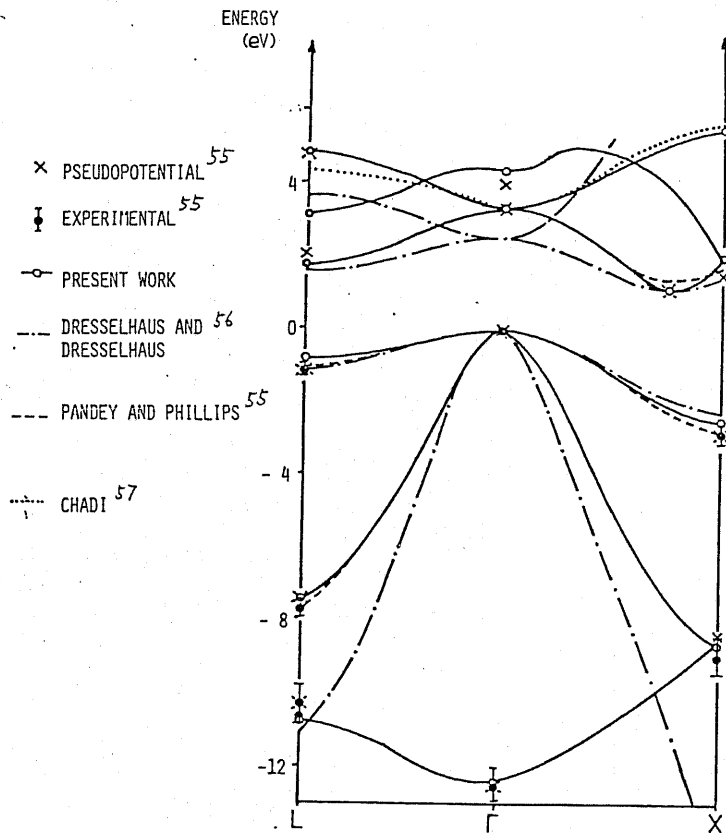


Fig. 2-4-1

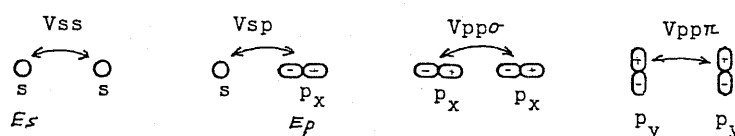
CALCULATED ENERGY BAND STRUCTURE OF BULK SILICON USING TIGHT-BINDING HAMILTONIAN

In the present work Si bandgap is calculated to be 1.1 eV which agrees with the experimental result. The top of the valence band is chosen energy zero.

Table 2-4-1

Tight-binding parameters for silicon. Unit is eV. Notation is standard and schematically illustrated below the table.

	E_s	E_p	V_{ss}^1	V_{sp}^1	$V_{pp\sigma}^1$	$V_{pp\pi}^1$	V_{ss}^2	V_{sp}^2	$V_{pp\sigma}^2$	$V_{pp\pi}^2$
present	-5.22	0.83	-2.05	2.09	2.33	-0.54	0.084	-0.29	0.47	-0.13
P & P ⁵⁵	-4.20	0.19	-2.08	2.12	2.32	-0.52	0.	0.	0.58	-0.1
Chadi ⁵⁷	-4.2	1.7	-2.08	2.76	3.13	-0.92	0.	0.	0.	0



Superscript 1 and 2 denote 1st and 2nd nearest neighbor interaction respectively.

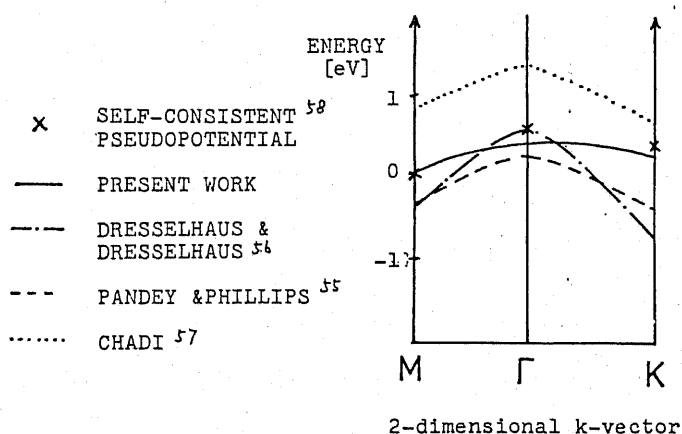


Fig. 2-4-2

Si (111) free surface state with no relaxation and no reconstruction. Calculated results with the other author's parameters are also shown.

Table 2-4-2. Calculated bandgap

	transition	bandgap [eV]
experimental ⁵⁹	indirect	1.12
present work	indirect	1.11
Dresselhaus et al ⁵⁶	indirect	1.1
Pandey et al ⁵⁵	indirect	1.40
Chadi ⁵⁷	direct	3.41

CHAPTER 3. EXTENDED HUCKEL THEORY

SECTION 3-1. INTRODUCTORY REMARK

In setting up the Hamiltonians for the Si-SiO₂ system which includes impurities such as H, Cl, and F, the simple tight-binding method described in Chap. 2 can not be directly applied because the electronic band structures of these materials are not sufficiently known. Therefore, some other method to calculate the tight-binding Hamiltonian must be investigated. The Extended Hückel Theory (EHT),⁶⁰ the Complete Neglect of Differential Overlap method (CNDO),⁶¹ the Indirect Neglect of Differential Overlap method (INDO),⁶¹ and the Modified Complete Neglect of Differential Overlap (MINDO) are the possible candidates for this. The INDO and MINDO can only treat the elements up to Ne, that is, they can not treat Si properly.

So that they are omitted. Shimizu et al⁶⁸ reported that the band structure of Si can not be reproduced by the CNDO method whereas it can be reproduced by the EHT. Taking this result into consideration, the EHT has been adopted here in calculating the Hamiltonians of the system including H, Cl, and F.

In Sec. 3-2, the EHT method is explained. Sections 3-3 and 3-4 are dedicated for the applications of this method to crystalline SiO₂ and to impurities (H, Cl, and F) in the

Si-SiO₂ system, respectively. Summary comes lastly.

SECTION 3-2. EXPLANATION OF THE METHOD

In the EHT, the *ij* element of the Hamiltonian is calculated as

$$H_{ij} = -K_{\alpha(i), \alpha(j)} S_{ij} \cdot (VOIP_i + VOIP_j) / 2, \quad \text{Eq. 3-2-1}$$

$$H_{ii} = -VOIP_i \quad \text{Eq. 3-2-2}$$

, where VOIP_{*i*} represents the valence orbital ionization potential of the *i*-th orbital whose value is listed in Table C-2, $\alpha(i)$ denotes the kind of the *i*-th orbital, say Si3s or H1s, $K_{\alpha(i), \alpha(j)}$ is a proportional constant, and S_{ij} is an overlap integral ($\int \psi_i^* \cdot \psi_j dx$). In calculating S_{ij} , the Slater type orbital as

$$\psi_{nlm}(r, \theta, \phi) = N r^{n-1} e^{-\zeta_{nl} \cdot r} Y_{lm}(\theta, \phi) \quad \text{Eq. 3-2-3}$$

is chosen as a basis. In Eq. 3-2-3, *n*, *l*, and *m* are principal, azimuthal, and magnetic quantum number, respectively, *N* denotes normalization factor, ζ_{nl} is a parameter which is given in Table C-1, and $Y_{lm}(\theta, \phi)$ represents a spherical harmonic function. The calculation method of the overlap integrals

between two Slater type orbitals is given in Ref. 61,62.

The EHT was first successfully used for the organic materials including C, H, and O by Hoffmann in 1963⁶⁰ and afterwards great many applications are reported in the field of chemistry. The basis of the EHT approximation was given by Blyholder and Coulson⁶³ as follows. The LCAO molecular Hartree-Fock equations for a closed-shell configuration can be reduced to a form identical with that of the EHT if (1) we accept the Mulliken approximation⁶⁴ for overlap charge distributions, and (2) we assume a uniform charge distribution in calculating two-electron integrals over molecular orbitals. Numerical comparisons indicate that this approximation leads to results which, while unsuitable for high accuracy calculations, should be reasonably satisfactory for molecules that can not at present be handled with facility by standard LCAO molecular Hartree-Fock methods.

Although the EHT is widely used for organic molecules, the application to the amorphous Se,⁶⁵ transition metals in GaAs as impurities,⁶⁶ and Nitrogen in crystalline Si⁶⁷ have been reported with success. Good introduction for the EHT in Japanese is in the book titled "Rhoshi kagaku nyumon" by Yonezawa et al published from Kagaku- dojin K.K.

SECTION 3-3. APPLICATION TO CRYSTALLINE SiO₂

In order to see how the EHT works for the problems of

solids it is applied to the calculation of the electronic energy band structure of alpha-quartz and it is examined whether the EHT with K constants as parameters can reproduce the band structure calculated by the pseudopotential method and estimated by the experimental results. In this connection, if all $K_{\alpha(i), \alpha(j)}$ parameters are set equal to 1.75 which was used by Hoffmann⁶⁰ and believed to be valid in C-H system, the method is sometimes called the normal EHT, and on the other hand, if K's are varied as parameters, the method is sometimes called the modified EHT.

When all $K_{\alpha(i), \alpha(j)}$ are set equal to 1.75, the calculated bandgap of alpha-quartz was 16 eV and the top valence band width was 1 eV, which disagree with the experimental observation.⁴⁶⁻⁵³ Therefore, the modified EHT is used and furthermore VOIPs are considered as parameters because these can be changed with the charge distribution. The parameters are chosen to fit the calculated energy levels of Γ and M points of alpha-quartz which have been shown⁵⁰ to reflect the peaks of density of states (DOS) to those estimated by the experiments. The structure and the 1st Brillouin zone of alpha-quartz are illustrated in Figs. 3-3-1 and 3-3-2, respectively. The 2nd nearest neighbor approximation is adopted in the calculation.

The fitting was possible. The calculated band structure are given in Fig. 3-3-3. The calculated DOS are shown in Fig. 3-3-4 and the peaks of DOS are in good agreement with the experiments⁶⁹ and other calculation results.^{49, 50} Calculated

ionicity of 50% is consistent with the value estimated from Pauling's electronegativity consideration (see Table C-3 and Fig C-4 in Appendix C). Although the valence band widths are in good agreement with the results of the pseudopotential calculation,⁴⁹ the top of the highest valence band is located at point in the present calculation, which is different from the results of the pseudopotential method where the top exists at A or K. This discrepancy, though small, can not be overcome as far as the approximation that K parameter between P_x and P_x is equal to that between P_z and P_z is employed. The bottom of the lowest conduction band shows the symmetry of Γ_1 and consists of Si3s and O2s, which agrees well with the Fowler et al's results.⁵⁰

The chosen parameters are listed in Table 3-3-1. Using these parameters, the band structure of beta-cristobalite is calculated. Figures 3-3-5 and 3-3-6 illustrate the structure and the 1st Brillouin zone of beta-cristobalite, respectively. The calculated band structure is shown in Fig. 3-3-7. The overall band positions are similar to those of alpha-quartz. This result indicates that the electronic structures of various forms of SiO₂ are determined by the short range order of atomic configurations.

The application of the EHT to the problems of crystals using Bloch orbitals as a basis is briefly described in Ref. 70. The actual calculation is carried out using the programs BAND, ALPHA, and BETA in Appendix A.

STRUCTURE OF
 α -QUARTZ

- SILICON
- OXIGEN

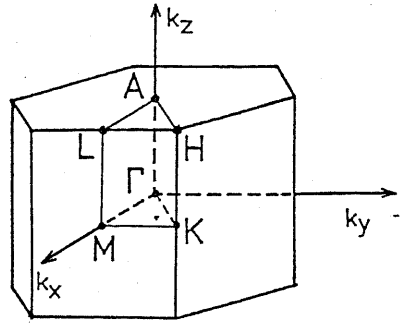
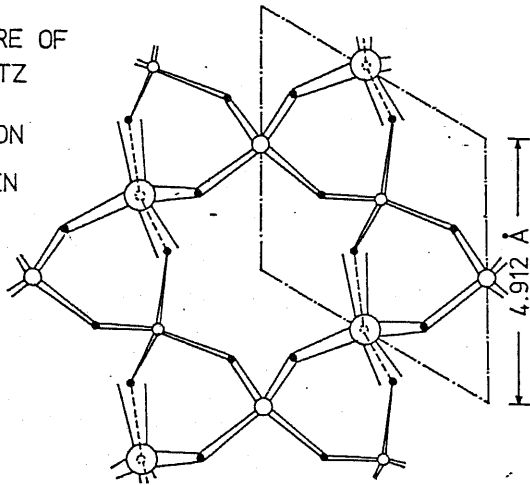


Fig. 3-3-1. Structure of α -quartz.

Fig. 3-3-2. 1st Brillouin zone of α -quartz.

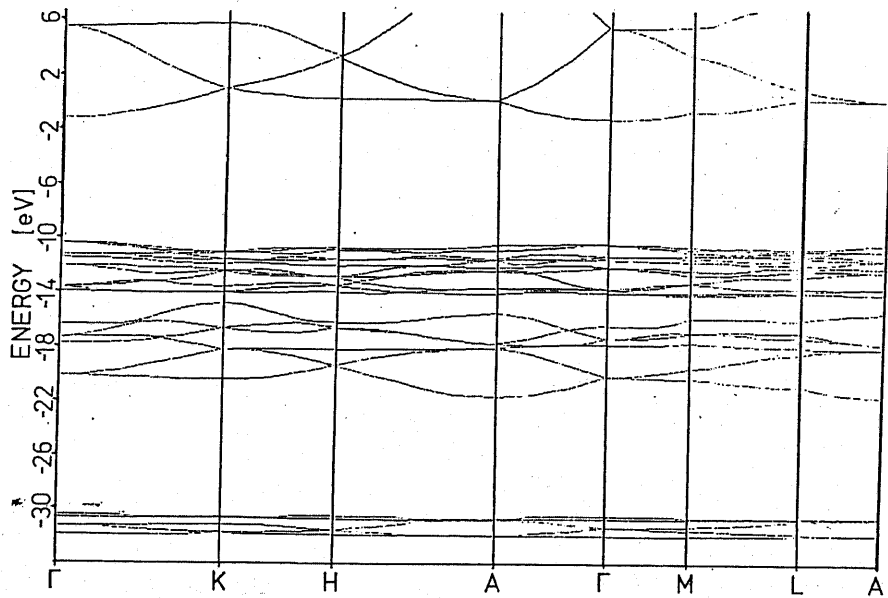


Fig. 3-3-3 Calculated band structure of α -quartz by the EHT.

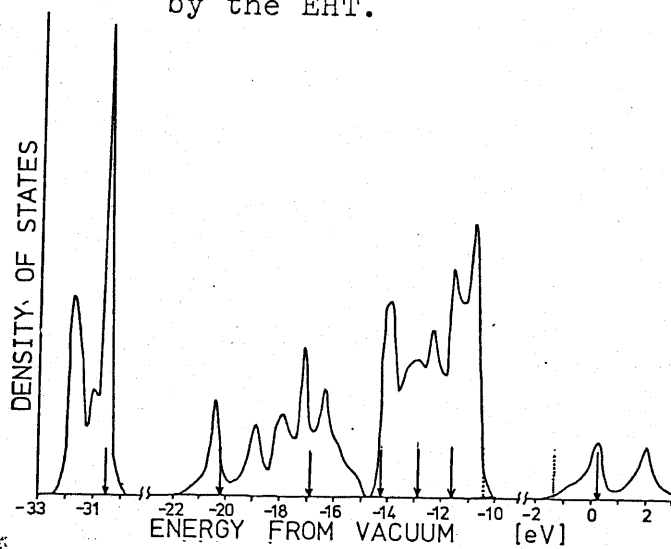


Fig. 3-3-4. Density of states of α -quartz. The arrows indicate the estimated peaks of DOS and dotted line indicate band edges.⁶⁹

Table 3-3-1. Determined parameters.

	Si3s, Si3s	= -14.95	eV
	Si3p, Si3p	= -7.78	eV
	O2s, O2s	= -29.6	eV
	O2p, O2p	= -12.7	eV
\	Si3s, Si3s	= 0.87	
\	Si3p, Si3p	= 2.5	
\	O2s, O2s	= 2.5	
\	O2p, O2p	= 6.0	
\	Si3s, O2s	= 1.34	
\	Si3p, O2p	= 2.9	

K parameters between s and p orbitals are chosen to be an arithmetic average of those between s-s and p-p orbitals.

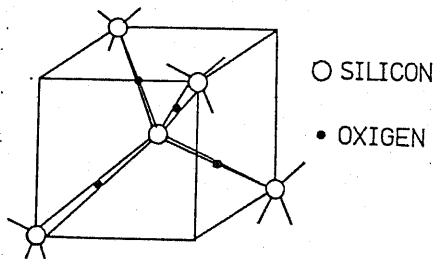


Fig. 3-3-5. STRUCTURE OF β -CRISTOBALITE.

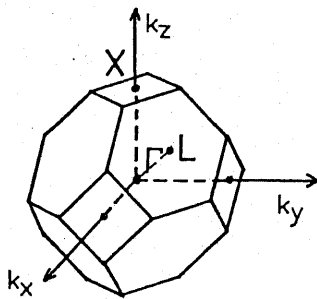


Fig. 3-3-6. 1st Brillouin zone of β -cristobalite.

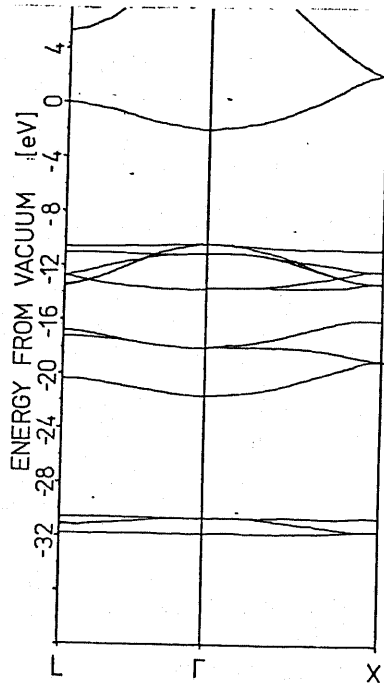


Fig. 3-3-7. Calculated band structure of β -cristobalite.

SECTION 3-4. APPLICATION TO THE Si-SiO₂ SYSTEM INCLUDING
IMPURITIES

The orbital exponents and the VOIPs used in the calculation of the energy levels of impurities in the Si-SiO₂ are listed in Tables 3-4-1 and 3-4-2, respectively. The nearest neighbor interaction is adopted for the impurity problem. The approximation of $S_{ij} = \delta_{ij}$ is also used according to Ref. 66. The normal bond lengths between O and H, Si and O, Si and H, Si and Cl, and Si and F are chosen to be 0.97, 1.61, 1.50, 1.50, and 1.50 [A], respectively. The bond lengths between O and H, and Si and H are cited from Ref. 71, and that between Si and O is a normal bond length in the SiO₂. The bond lengths between Si and Cl, and Si and F are not ascertained. But these ambiguities can be compensated by varying the K parameters in a wide range. In fact K parameters are varied between 1.0 and 4.0 in the calculation described in Chaps. 5 and 6, although the value between 1.0 and 2.0 is empirically believed to be probable for K parameters.^{66,68} This variation of K parameters do not affect the results of Chaps. 5 and 6.

The EHT is also used in varying the bond lengths between Si and O, and Si and Si. That is, we assume that each simple tight-binding parameter is altered according to

$$V_{ij}(R_{kl}) = V_{ij}(R_{kl}^0) \cdot S_{ij}(R_{kl}) / S_{ij}(R_{kl}^0) \quad \text{Eq. 3-4-1}$$

,where the interaction parameter and the overlap integral at the bond length of R_{kl} are denoted as $V_{ij}(R_{kl})$ and $S_{ij}(R_{kl})$, respectively and R_{kl} represents the bulk bond length.

The interactions between valence orbitals are taken into account

Table 3-4-1.

Employed exponents for Slater type orbitals. ^{Fig. C-1}

	ζ_{1s}	ζ_{2s}	ζ_{2p}	ζ_{3s}	ζ_{3p}
H	1.0				
O		2.2458	2.2266		
F		2.5638	2.5500		
Si				1.6344	1.4284
Cl				2.3561	2.0387

Table 3-4-2.

Employed values of VOIP. ^{Fig. C-2}

	VOIP _{1s}	VOIP _{2s}	VOIP _{2p}	VOIP _{3s}	VOIP _{3p}
H	13.6				
O		32.33	15.80		
F		40.12	18.65		
Si				14.83	7.75
Cl				25.27	13.70

SECTION 3-5. SUMMARY

In conclusion, the modified EHT can be applied to crystal SiO_2 satisfactorily. This result encourages to use the EHT in the problems of solids and the determined parameters can be used in the further research. The calculated results indicate that the electronic structures of various form of SiO_2 is derived from the short range order such as the valencies and the tetrahedral SiO_4 structure.

In Sec 3-4, the values of the VOIPs and the orbital exponents are listed. The method for varying the simple tight-binding parameters is also described.

CHAPTER 4. GREEN'S FUNCTION FORMULATION

SECTION 4-1. INTRODUCTORY REMARK

Once the Hamiltonian is established, various energy levels can be calculated by solving the eigen value problem of Eq. 2-2-7. However, it is impossible to solve this eigen value problem because the size of the Hamiltonian is enormously large. But if the short range interactions are assumed, like in Chaps. 2 and 3, the calculation effort can be greatly reduced with the help of a Green's function formulation and the energy levels of the system can be obtained. In Secs. 4-2, the general Green's function theory is reviewed. Section 4-3 deals with the Green's function formulation with short range interactions which is developed in this work. This formulation is applied to the case of surface problems and the Bethe-lattices in Secs. 4-4 and 4-5, respectively.

SECTION 4-2. GENERAL GREEN'S FUNCTION THEORY

The Green's function G is defined as

$$G(E) = (EI - H)^{-1} = \sum_n \frac{|E_n \rangle \langle E_n|}{E - E_n} \quad \text{Eq. 4-2-1}$$

, where E denotes energy, I a unit matrix, H a Hamiltonian, and E_n and $|E_n\rangle$ the n -th eigenvalue and eigenvector, respectively. The local density of the j -th orbital (LDOS _{j}) is expressed as

$$\text{LDOS}_j = \sum_n |\langle j|E_n\rangle|^2 \delta(E - E_n) \quad \text{Eq. 4-2-2}$$

$$= -\frac{1}{\pi} \lim_{\delta \rightarrow +0} \text{I}_m [G(E + i\delta)_{jj}] \quad \text{Eq. 4-2-3}$$

, where $\text{I}_m [G(E + i\delta)_{jj}]$ is an imaginary part of the jj element of the matrix $G(E + i\delta)$.

If the LDOS _{j} is summed over j , then it is easily shown that the resulting quantity is a total density of states. The weighting term $|\langle j|E_n\rangle|^2$ is the j -th orbital component of the n -th eigen function. Therefore, the LDOS _{j} is considered as the j -th orbital contribution to the total density of states or it of interpreted as the density of states belonging to the j -th orbital. For example, if an eigen function is localized on the j -th orbital, then LDOS _{j} shows a large peak at the corresponding energy eigen value. Since the Green's function has poles at the energy eigen values, it can be suited for the problem of defects and impurities.

When the $i\delta$ in Eq. 4-2-3 is approximated by a finite value due to the practical limitation, the δ -function in Eq. 4-2-2 has the Lorentzian broadness. That is, a sharp line spectrum at E_n is broadened by a factor of $\delta / \{(E - E_n)^2 + \delta^2\}$. However,

if the values y_1 and y_2 at two points E_1 and E_2 near the peak are given, then the peak value y_p and the peak energy E_p can be calculated by the following formulae,

$$E_p = \frac{(y_1 E_1 - y_2 E_2) + \sqrt{y_1 y_2 (E_1 - E_2)^2 - \delta^2 (y_1 - y_2)^2}}{y_2 - y_1}$$

$$y_p = y_1 \left\{ 1 + \frac{(E_1 - E_p)^2}{\delta^2} \right\} \quad \text{Eq. 4-2-4}$$

The explanation of y_1 , y_2 , y_p , E_1 , E_2 , and E_p is given in Fig. 4-2-1. Therefore, though $\delta=0.04$ eV and energy step of 0.1 eV are adopted here, the error of calculation by this approximation is less than 0.01 eV with help of Eq. 4-2-4

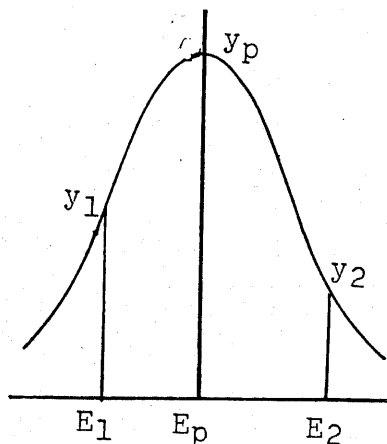


Fig. 4-2-1.

Lorentzian curve. If E_1 , y_1 , E_2 , and y_2 are known, E_p and y_p can be calculated.

SECTION 4-3. GREEN'S FUNCTION WITH SHORT RANGE

INTERACTIONS

The matrix size to be manipulated is greatly reduced if the interactions among atoms are short-ranged. When a system A and B interact each other through short-range interaction as shown in Fig. 4-3-1, the Hamiltonian and Green's function G are written in the forms

$$(EI-H)^{-1} = EI - \begin{bmatrix} \begin{array}{|c|c|c|c|} \hline h_{AA}^{22} & h_{AA}^{21} & 0 & 0 \\ \hline h_{AA}^{12} & h_{AA}^{11} & V_{AB}^{11} & 0 \\ \hline 0 & V_{BA}^{11} & h_{BB}^{11} & h_{BB}^{12} \\ \hline 0 & 0 & h_{BB}^{21} & h_{BB}^{22} \\ \hline \end{array} \end{bmatrix}^{-1} \quad \text{Eq. 4-3-1}$$

$$=G(E) = \begin{bmatrix} \begin{array}{|c|c|c|c|} \hline G_{AA}^{22} & G_{AA}^{21} & G_{AB}^{21} & G_{AB}^{22} \\ \hline G_{AA}^{12} & G_{AA}^{11} & G_{AB}^{11} & G_{AB}^{12} \\ \hline G_{BA}^{12} & G_{BA}^{11} & G_{BB}^{11} & G_{BB}^{12} \\ \hline G_{BA}^{22} & G_{BA}^{21} & G_{BB}^{21} & G_{BB}^{22} \\ \hline \end{array} \end{bmatrix} \quad \text{Eq. 4-3-2}$$

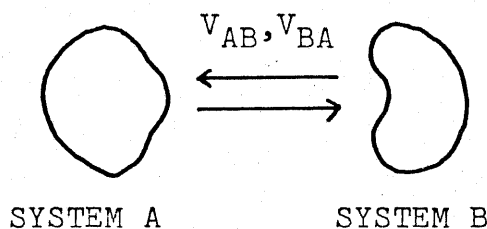


Fig. 4-3-1.

Schematic illustration that system A and B interact with each other.

On the other hand, when the system A and B are independent, as illustrated in Fig. 4-3-2, the Green's function for each system, g_{AA} and g_{BB} are written as

$$g_{AA} = \left[EI - \begin{array}{c|c} h_{AA}^{11} & h_{AA}^{12} \\ \hline h_{AA}^{21} & h_{AA}^{22} \end{array} \right]^{-1} = \begin{array}{c|c} g_{AA}^{11} & g_{AA}^{12} \\ \hline g_{AA}^{21} & g_{AA}^{22} \end{array} \quad \text{Eq. 4-3-3}$$

and

$$g_{BB} = \left[EI - \begin{array}{c|c} h_{BB}^{22} & h_{BB}^{21} \\ \hline h_{BB}^{12} & h_{BB}^{11} \end{array} \right]^{-1} = \begin{array}{c|c} g_{BB}^{22} & g_{BB}^{21} \\ \hline g_{BB}^{12} & g_{BB}^{11} \end{array} \quad \text{Eq. 4-3-4}$$

, respectively.

Then the following equations are obtained,

$$g_{AA}^{11} = ((g_{AA}^{11})^{-1} - v_{AB}^{11} g_{BB}^{11} v_{BA}^{11})^{-1} \quad \text{Eq. 4-3-5}$$

(equation for connection)

$$g_{AA}^{11} = ((g_{AA}^{11})^{-1} + v_{AB}^{11} g_{BB}^{11} v_{BA}^{11})^{-1} \quad \text{Eq. 4-3-6}$$

(equation for separation)

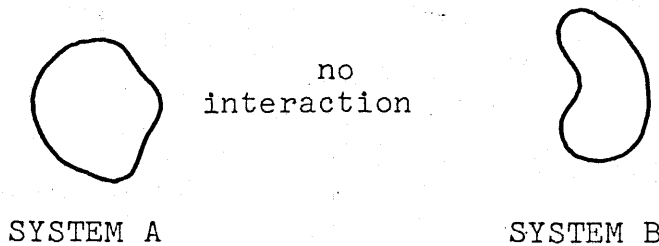


Fig. 4-3-2.

Schematic illustration that system A and B are independent.

The derivation of these equations are given afterwards.

These two equations show that the size of the matrix is small if the local density of states within a small part of the system is to be calculated. Moreover, connection and separation of atomic groups as illustrated in Fig. 4-3-3 can be done quite easily using these two equations. For example, if the system A is the crystalline Si and the system B is the amorphous SiO_2 then using Eq. 4-3-5, the Green's functions near the interface are calculated, and if G_{AA} is a Green's function of the crystalline Si at the perfect interface and g_{BB} is a Green's function of a Bethe-lattice and an extra oxygen atom, then using Eq. 4-3-6, the Green's function of the interface including a dangling bond (g_{AA}) can be obtained.

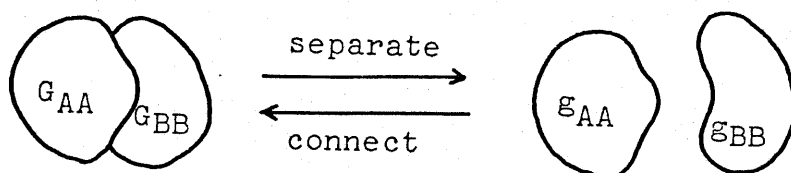


Fig. 4-3-3.

Schematic illustration of connecting and separating two systems.

The derivation of Eqs. 4-3-5 and 4-3-6 is carried out as follows. Calculation of $(EI-H)G=I$ using

$$\left(\begin{array}{c|c} G_{AA} & G_{AB} \\ \hline G_{BA} & G_{BB} \end{array} \right) = \left(\begin{array}{c|c} g_{AA}^{-1} & -V_{AB} \\ \hline -V_{BA} & g_{BB}^{-1} \end{array} \right) \quad \text{Eq. 4-3-7}$$

leads

$$\left[\begin{array}{c|c} G_{AA}^{22} & G_{AA}^{21} \\ \hline G_{AA}^{12} & G_{AA}^{11} \end{array} \right] = \left[\begin{array}{c|c} g_{AA}^{22} + g_{AA}^{21} v_{AB}^{11} G_{BA}^{12} & g_{AA}^{21} + g_{AA}^{21} v_{AB}^{11} G_{AB}^{11} \\ \hline g_{AA}^{12} + g_{AA}^{11} v_{AB}^{11} G_{BA}^{12} & g_{AA}^{11} + g_{AA}^{11} v_{AB}^{11} G_{BA}^{11} \end{array} \right] \quad \text{Eq. 4-3-8}$$

and

$$\left[\begin{array}{c|c} G_{BA}^{12} & G_{BA}^{11} \\ \hline G_{BA}^{22} & G_{BA}^{21} \end{array} \right] = \left[\begin{array}{c|c} g_{BB}^{11} v_{BA}^{11} G_{AA}^{12} & g_{BB}^{11} v_{BA}^{11} G_{AA}^{11} \\ \hline g_{BB}^{21} v_{BA}^{11} G_{AA}^{12} & g_{BB}^{21} v_{BA}^{11} G_{AA}^{11} \end{array} \right] \quad \text{Eq. 4-3-9}$$

Particularly, the following equations are useful,

$$G_{AA}^{11} = g_{AA}^{11} + g_{AA}^{11} v_{AB}^{11} G_{BA}^{11} \quad \text{Eq. 4-3-10}$$

$$G_{BA}^{11} = g_{BB}^{11} v_{BA}^{11} G_{AA}^{11} \quad \text{Eq. 4-3-11}$$

Substituting Eq. 4-3-11 into Eq. 4-3-10 and solving the resultant equation as to G , we have Eq. 4-3-5. Equation 4-3-6 is easily derived from Eq. 4-3-5. Other than Eq. 4-3-5 and Eq. 4-3-6,

$$G_{AA}^{11} = g_{AA}^{11} v_{AB}^{11} G_{BB}^{11} v_{BA}^{11} g_{AA}^{11} + g_{AA}^{11} \quad \text{Eq. 4-3-12}$$

also holds.

When the approximation that S_{ij} is set equal to δ_{ij} is not valid, the Green's function G is defined as $(ES-H)^{-1}$ instead of $(EI-H)^{-1}$. Nevertheless, the discussions of this section are all valid if g and V are substituted by $(ES-h)^{-1}$ and $V-ES$, respectively. However, it should be notified that the quantity $-\frac{1}{\pi} \lim_{\delta \rightarrow 0} \text{Im}(\text{Trace}[G(E+i\delta)])$ does not give a DOS in this case. This fact is sometimes overlooked. The true formula which gives a DOS is

$$-\frac{1}{\pi} \lim_{\delta \rightarrow 0} \text{Im}(\text{Trace}[SG(E+i\delta)]), \quad \text{Eq. 4-3-13}$$

$$-\frac{1}{\pi} \lim_{\delta \rightarrow 0} \text{Im}(\text{Trace}[G(E+i\delta)S]), \text{ or} \quad \text{Eq. 4-3-14}$$

$$-\frac{1}{\pi} \lim_{\delta \rightarrow 0} \text{Im}(\text{Trace}[S^{\frac{1}{2}}G(E+i\delta)S^{\frac{1}{2}}]). \quad \text{Eq. 4-3-15}$$

In this case of non-zero overlap, there is an overlap part contribution to DOS in addition to an orbital contribution which is considered in Eq. 4-2-2. The discussion of the non-zero overlap is also given in Sec. 4-5.

SECTION 4-4. APPLICATION TO SURFACE PROBLEMS

The problem of the electronic structures of solid surfaces has attracted much attention. Various methods have been developed and used to study surfaces of metals and semiconductors. However, all of the theoretical investigations based on realistic models of semiconductor surfaces belong to either of

the following major categories. One is a slab method⁷³ where the semi-infinite solid is simulated by a finite number of atomic layers having two-dimensional periodicity. The other is a perturbation method⁷⁴ where the semi-infinite solid is treated as a perturbed perfect solid.

Here, as an application of the method described in the previous section, we report a new method which does not belong to either of the two categories and which treats the semi-infinite solids as infinitely stacked atomic layers. It has advantages over the above-mentioned slab method in that it deals with the exactly semi-infinite solid, instead of a finite number of atomic layers. Consequently, the band continua are expressed in terms of continuous functions.

From the computational point of view, the sizes of the matrices to be manipulated in the present method are about a tenth of those in the slab method. Compared with the perturbation method, the present method is economical because there is no need for solving the perfect solid problem.

Furthermore, different from the perturbation method, this method can treat the relaxed surfaces quite easily.

Since the present method is fit especially for examining the numerical validity of the widely used slab-type calculation, this course of study is carried out by using the Si (111) surface.

Although the description of the method is done by using the Si (111) surface, the method is quite general.

Let k be a two-dimensional reciprocal vector of the Si (111) surface. Then, taking Bloch orbitals as a basis set, the Hamiltonian H^k and the Green's function G^k for a certain k vector are expressed in the form

$$G^k(E) = (EI - H^k)^{-1}$$

$$= \left[EI - \begin{pmatrix} h_{11}^k & v_{1s}^k & & & \\ v_{s1}^k & h_{11}^k & v_{1s}^k & & \\ & v_{s1}^k & h_{11}^k & v_{1s}^k & \\ 0 & & v_{s1}^k & h_{11}^k & \ddots \\ & & & v_{s1}^k & h_{11}^k & \ddots \end{pmatrix} \right]^{-1}$$

Eq. 4-4-1

$$= \begin{pmatrix} G_{11}^k \\ * \\ * \\ * \\ * \\ * \\ * \\ * \end{pmatrix}$$

Eq. 4-4-2

where h_{11}^k , v_{s1}^k , v_{1s}^k , and G_{11}^k are 8×8 matrices.

The exact forms of these matrices are given in Ref. 75.

Taking into account the fact that the semi-infinite solid should not be influenced by the addition of one atomic layer on the surface (Hereafter we will call this techniques as the layer stacking method. See Fig. 4-4-1), the self-consistent equation for G_{11}^k

$$G_{11}^k = ((E + i\delta)I - h_{11}^k - v_{1s}^k G_{11}^k v_{s1}^k)^{-1}$$

Eq. 4-4-3

holds, which is derived by the use of Eq. 4-3-5. G_{11}^k can be de-

terminated by this equation. To solve Eq.4-4-3 in terms of G_{11}^k numerically, the relaxation method is effective. Since this relaxation process is rather oscillatory, the damping type procedure must be efficient to accelerate the convergence. In fact averaging operation over each oscillation period has shortened the computation time by a factor of 2-10. Once the G_{11}^k 's for various k-vectors are obtained, the Green's function G_{11} which takes normal atomic orbitals as a basis set is calculated by

$$G_{11} = \frac{1}{N} \sum_k G_{11}^k \quad \text{Eq. 4-4-4}$$

,where N is the number of the unit cells. The derivation of this equation is demonstrated in Appendix D. Any G_{11}^k in the course of the numerical relaxation is a Green's function for a finite slab, whereas the converged value is that for the semi-infinite solid. So that the comparison of surface LDOS between the slabs and the semi-infinite solid is easily carried out.

The two-dimensional Brillouin zone of the Si (111) surface is given in Fig. 4-4-2. Figure 4-4-3 shows how the surface LDOS changes as the number of atomic layers of the slab increases from 8 through infinity at the point of the Si (111) surface. The interaction parameters given in Ref. is used in the calculation. These results show that the gap state for the finite slab monotonously approaches that of the infinite solid and that the widely used slab approximation is excellent for the gap state level when the slab includes more than 30 atomic layers, but not so good for the band continua.

The calculation in this chapter is carried out by using SURF and SURF12 in Appendix A.

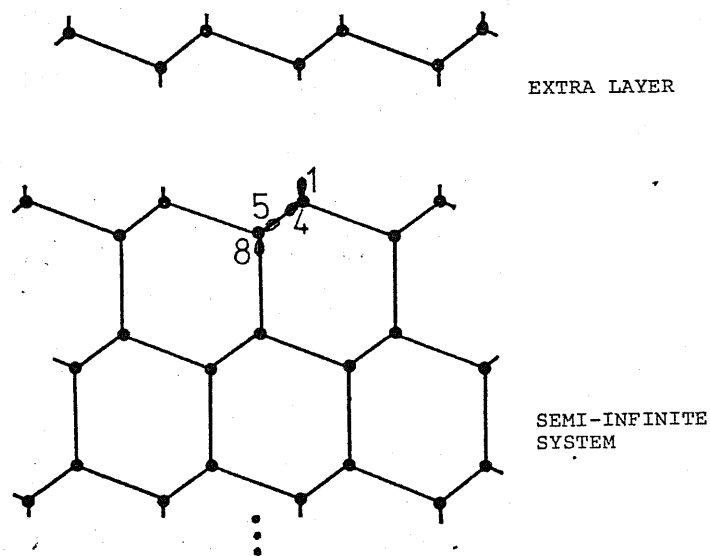


Fig. 4-4-1 Layer stacking method. When the system is semi-infinite, it should not be influenced by the addition of the extra atomic layers. The number denotes orbital number.

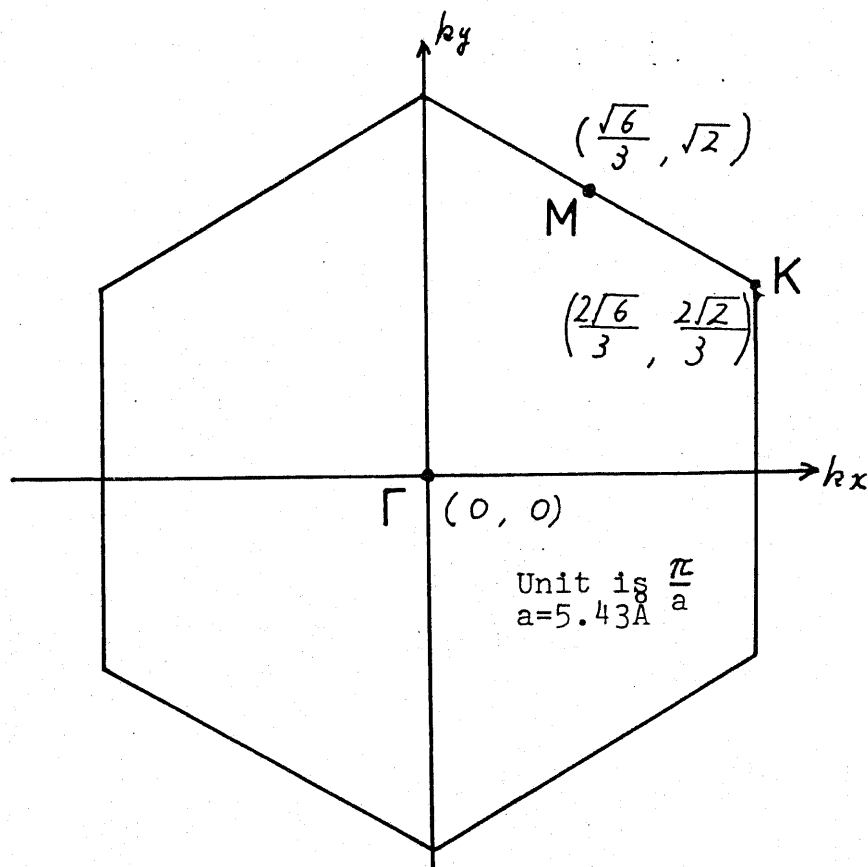


Fig. 4-4-2. Two-dimensional 1st Brillouin zone of Si (111) surface.

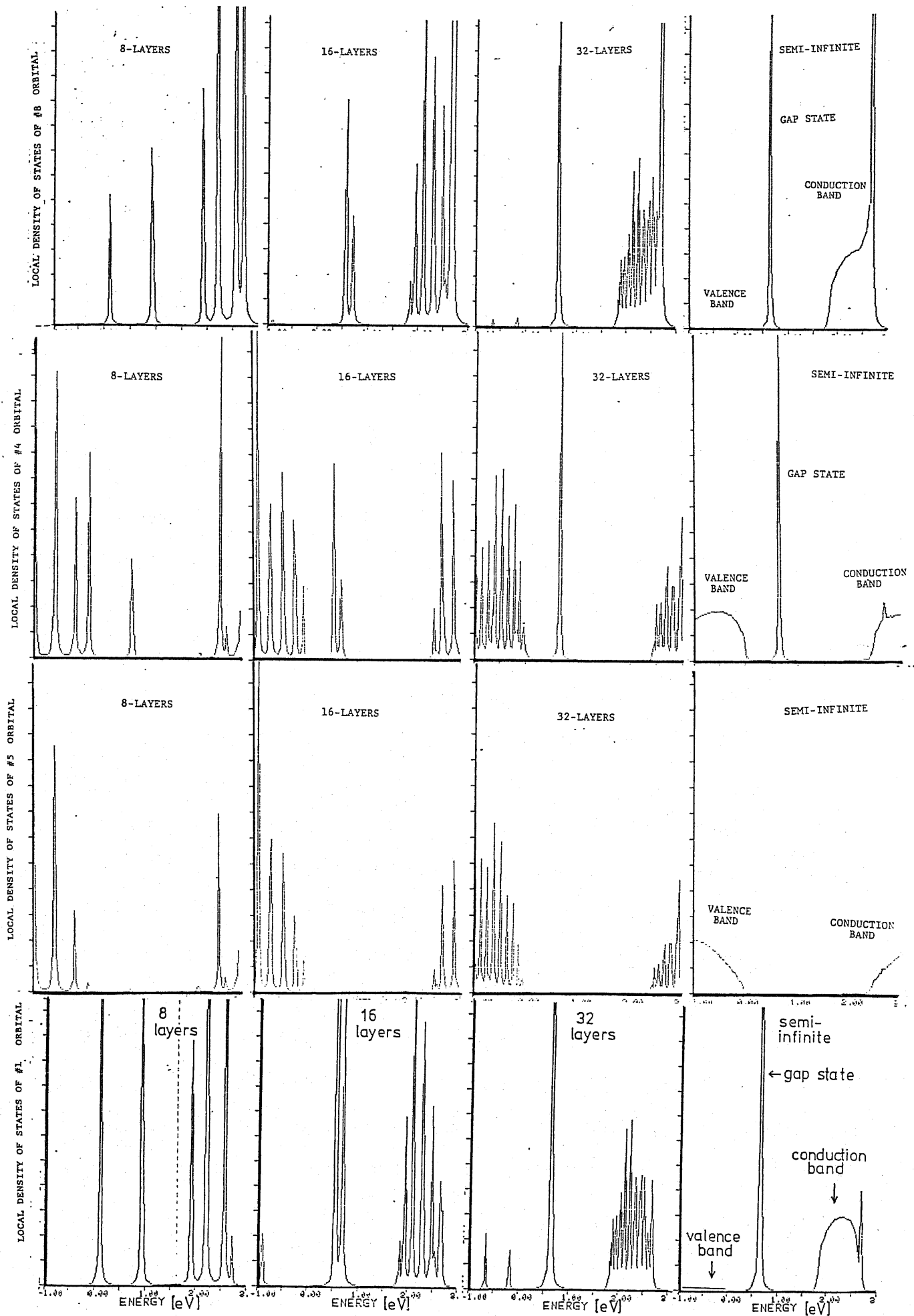


Fig. 4-4-3.

LDOS of free Si surface (at Γ). From left to right the number of layers increases. From top to bottom the orbital number is 8, 4, 5, and 1.

SECTION 4-5. APPLICATION TO BETHE-LATTICES

4-5-1.

The Green's function for the SiO_2 is also calculated by use of an equation of self-consistency. Since the SiO_2 Bethe-lattice employed here has been constructed by infinitely connecting SiO_3 units, one SiO_3 unit whose three oxygen dangling-bonds are terminated by the SiO_2 Bethe-lattices is equal to the SiO_2 Bethe-lattice itself. This fact leads to the equation of self-consistency similar to Eq. 4-4-3. The Green's function of SiO_2 Bethe-lattice is determined through this equation, where the manipulation of matrices sized 16×16 are required. The solution of the SiO_2 Bethe-lattice is first obtained by Laughlin and Joannopoulos⁷⁶ using a transfer matrix technique. In the present method, however, the Green's functions are computed directly without transfer matrices.

4-5-2. Since the case of SiO_2 is difficult as an introductory explanation, the simple case of tetrahedrally bonded solids with Weaire-Thorpe Hamiltonian is described as an example.

The Weaire-Thorpe Hamiltonian⁷⁷ takes sp^3 orbitals as a basis set and includes two interaction parameters as illustrated in Fig. 4-5-1. The energy zero is taken at the self energy of the sp^3 orbital. Let g_0 denote the Green's function of the orbital 0 in Fig. 4-5-1. Then, the self-consistency mentioned above requires that the 1,1 element of

$$\left[\begin{array}{cccc} E & -V1 & -V1 & -V1 \\ -V1 & E & -V1 & -V1 \\ -V1 & -V1 & E & -V1 \\ -V1 & -V1 & -V1 & E \end{array} \right] - \left[\begin{array}{cccc} 0 & 0 & 0 & 0 \\ 0 & V2 & 0 & 0 \\ 0 & 0 & V2 & 0 \\ 0 & 0 & 0 & V2 \end{array} \right] \left[\begin{array}{cccc} 0 & * & * & * \\ * & g_0 & * & * \\ * & * & g_0 & * \\ * & * & * & g_0 \end{array} \right] \left[\begin{array}{cccc} 0 & 0 & 0 & 0 \\ 0 & V2 & 0 & 0 \\ 0 & 0 & V2 & 0 \\ 0 & 0 & 0 & V2 \end{array} \right]^{-1}$$

Eq. 4-5-1

is equal to g_0 using Eq. 4-3-5. If the energy is measured in terms of V_1 and V_2/V_1 is substituted by V , then we have

$$g_0 = \frac{E - V^2 g_0 + 2}{E(E - V^2 g_0 + 2) - 3} \quad \text{Eq. 4-5-2}$$

This quadratic equation of g_0 have two roots. Solving Eq. 4-5-2 by the numerical relaxation method with the substitution of $E + i\delta$ into E corresponds in the physical sense to connecting more and more atoms to the system. So that this relaxation method gives the physically meaningful results. On the other hand, this relaxation method if applied to the problem of the type as

$$T^{(n)} = \frac{a + bT^{(n-1)}}{c + dT^{(n-1)}} \quad \text{Eq. 4-5-3}$$

turns out to converge on the absolutely smaller root of the equation

$$x = \frac{a + bx}{c + dx} \quad \text{Eq. 4-5-4}$$

This is easily seen from the equation

$$\begin{aligned} \frac{T^{(n)} - \alpha}{T^{(n)} - \beta} &= \frac{\frac{a + bT^{(n-1)}}{c + dT^{(n-1)}} - \frac{a + b\alpha}{c + d\alpha}}{\frac{a + bT^{(n-1)}}{c + dT^{(n-1)}} - \frac{a + b\beta}{c + d\beta}} \\ &= \frac{\alpha}{\beta} \cdot \frac{T^{(n-1)} - \alpha}{T^{(n-1)} - \beta} \end{aligned} \quad \text{Eq. 4-5-5}$$

,where α and β are two roots of Eq. 4-5-4. Therefore, the physically meaningful root of Eq.4-5-2 is that which has the smaller absolute value.

The Green's function of perfectly bonded Bethe-lattice, G , as illustrated in Fig. 4-5-2 is calculated as

$$G=(g_0 -g_0V^2)^{-1} \quad \text{Eq. 4-5-6}$$

which is derived by using Eq. 4-3-5. The LDOS calculated by Eq.4-5-6 with $V=\sqrt{3}$ is shown in Fig. 4-5-3. This figure suggests that the bandgap and the band continuum arise from the fact that the large number of atoms are bonded in the solids but not from the fact that the system has a translational symmetry.⁹⁰

The band continuum is the region where the imaginary part of g_0 or G is non-zero, that is,

$$[(E+1)^2-(V+\sqrt{3})^2-1][(E+1)^2-(V-\sqrt{3})^2-1]\leq 0, \quad \text{Eq. 4-5-7}$$

This region is given in Fig. 4-5-4. When the energy is measured in terms of V^2 and V_1/V^2 is denoted as V_1 , then the corresponding equation to Eq.4-5-7 is

$$\begin{aligned} & [(E+\frac{\sqrt{3}}{4})^2+2(E+\frac{\sqrt{3}}{4})(V_1-\frac{\sqrt{3}}{4})-3(V_1-\frac{\sqrt{3}}{4})^2-\frac{1}{4}] \times \\ & [(E-\frac{\sqrt{3}}{4})^2+2(E-\frac{\sqrt{3}}{4})(V_1+\frac{\sqrt{3}}{4})-3(V_1+\frac{\sqrt{3}}{4})^2-\frac{1}{4}] \leq 0 \quad \text{Eq. 4-5-7} \end{aligned}$$

,whose graph is shown in Fig. 4-5-5. This graph agrees with

the band diagram calculated by the "cluster method"^{78,79}. The results of the cluster method are obtained through a numerical calculation, whereas the analytical expression is attained in the present method.

The Green's function of the i -th orbital (in Fig. 4-5-1) is expressed as

$$g_i = g^2 V^2 (y - G) (zV)^{2i-2} + G \quad \text{Eq. 4-5-9}$$

, where

$$y = \frac{E(b+1) - 2}{(b-1)(E(b+2) - 3)}, \quad \text{Eq. 4-5-10}$$

$$z = \frac{-1}{E(b+2) - 3}, \quad \text{Eq. 4-5-11}$$

and $b = E - g_0 V^2. \quad \text{Eq. 4-5-12}$

These equations are derived by the use of Eq. 4-3-12. Since g_i should not be diverged, this formula shows that the LDOS of the system including a dangling bond approaches that of the perfectly bonded Bethe-lattice, as the orbital gets far away from a dangling bond.

4-5-3. Here, the effect of the non-zero overlap is investigated using the even simpler Hamiltonian. The Hamiltonian is based on tetrahedrally bonded s orbitals and consists of only one parameter as illustrated in Fig. 4-5-6.

If the non-zero overlap S is taken into account, the LDOS is formulated as

$$\text{LDOS} = \frac{2}{\pi} \cdot \frac{\sqrt{12V^2 - E^2}}{16V^2 - E^2} + \frac{2SE}{\pi V} \cdot \frac{\sqrt{12V^2 - E^2}}{16V^2 - E^2}. \quad \text{Eq. 4-5-13}$$

the first term and the second term can be considered as an orbital contribution and an overlap part contribution, respectively. The second term can be 30% of the LDOS if $S=0.1$ and $V=1$ are adopted. So that Eqs. 4-3-13 ~ 4-3-15 must be used instead of Eq. 4-2-3 when the non-zero overlap is taken into consideration. Usually, however, the proper set of interaction parameters with the neglect of the overlap integrals are employed to get rid of the complications.

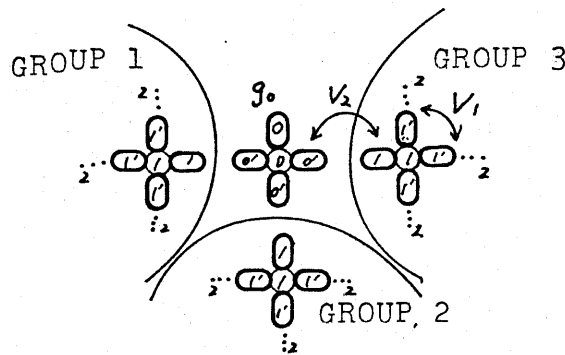


Fig. 4-5-1. Bethe-lattice with Weaire-Thorpe Hamiltonian. GROUP 1, 2, 3, and the whole system are the same one another.

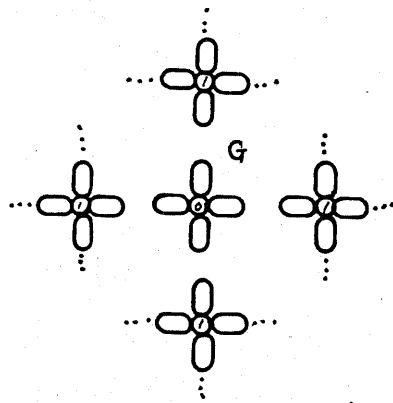


Fig. 4-5-2. Perfectly bonded Bethe-lattice.

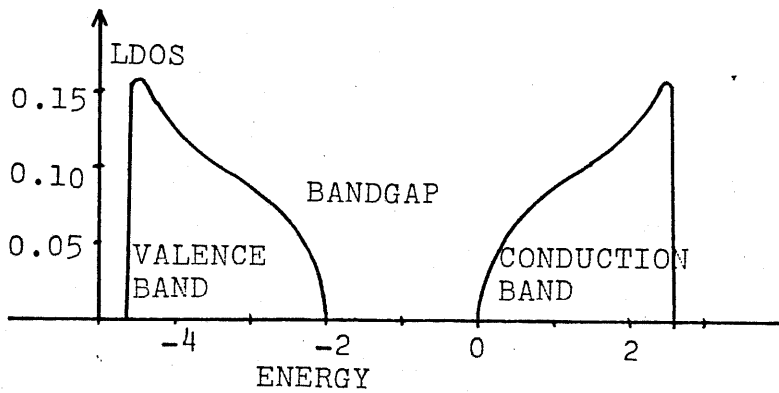


Fig. 4-5-3. LDOS of Bethe-lattice calculated by Eq. 4-5-6. This suggests that the bandgap and the band continuum arise not from the fact that the system has a translational symmetry but from the fact that the large number of atoms are bonded.

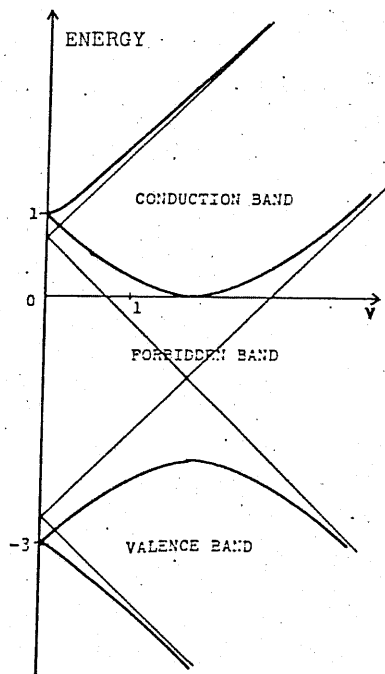


Fig. 4-5-4. Band diagram of Bethe-lattice. Parameter is V .

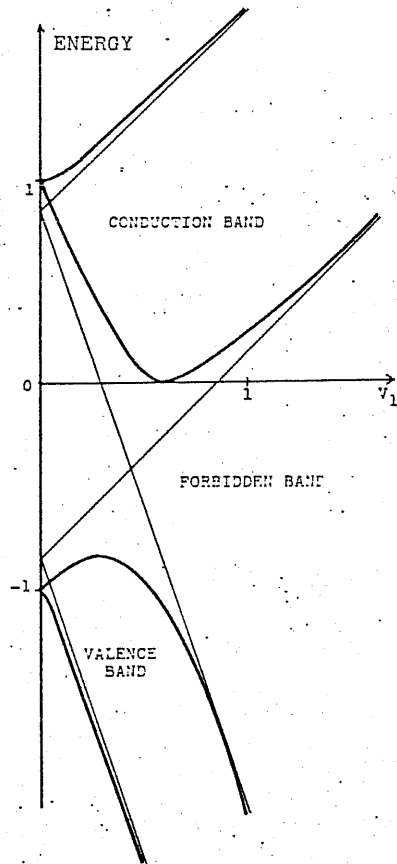


Fig. 4-5-5. Band diagram of Bethe-lattice. Parameter is V_1 . This agrees with the calculated results by the "cluster method".

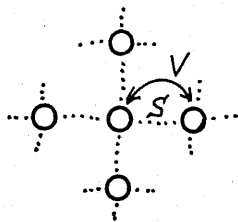


Fig. 4-5-6. Tetrahedrally bonded s orbitals.

SECTION 4-6. SUMMARY

The Green's function formulation can make use of the sparsity of the non-zero elements of the Hamiltonian and make the eigen value problem solvable. The local density of states which includes the information of the wave functions and energy levels is calculated from the Green's function.

The developed method itself is simple and flexible and can be applied to crystalline free surfaces with or without relaxation and/or reconstruction, impurity chemisorped surfaces, Bethe-lattices, bulk impurity problems, defects, and other complex problems such as superlattices and multilayer problems, if the proper tight-binding parameters are given. If a dynamic matrix is used for Hamiltonian, phonon spectra and Raman spectra can also be calculated.⁸⁰ It should be noted that the calculation method used in Chaps. 5 and 6 is mathematically exact except for the limitation caused by the practical numerical calculation such as the finite number of the sampling points in k space.

CHAPTER 5. INTERFACE STATES

SECTION 5-1. INTRODUCTORY REMARK

The trap states between Si-SiO₂ interface have been attracting much attention because these states take an important role in controlling the threshold voltage V_{th} , transconductance and flicker noise of MOS transistors. However, the chemical and physical origins of these states have not been fully understood, although some attempts were made to shed light on these problems by Chadi, Joannopoulos, and Laughlin.^{80, 81, 82} In particular, little is known about the theoretical background of the fact that these interface trap states are continuously distributed in energy. Our work is an extension of Chadi et al's approach with a special emphasis on this continuous distribution of the trap states at Si-SiO₂ interfaces.

Our basic model has been constructed with a crystalline Si with (111) orientation and amorphous SiO₂ represented by a Bethe-lattice as shown in Fig.5-1-1. This can be considered as a Cluster-Bethe-Lattice model (CBLM) first introduced by Joannopoulos and Yndurain,⁸³ but in our case the cluster is the crystalline silicon, whose dangling bonds are terminated by the SiO₂ Bethe-lattices. The experimental evidences for very thin Si-SiO₂ transition layer^{84, 85} and the theoretical conclusion that the elastic energy of the Si-SiO₂ system is lowered as the width of the SiO_x layer goes zero,⁸⁶ encourage us to use this idealized abrupt-junction

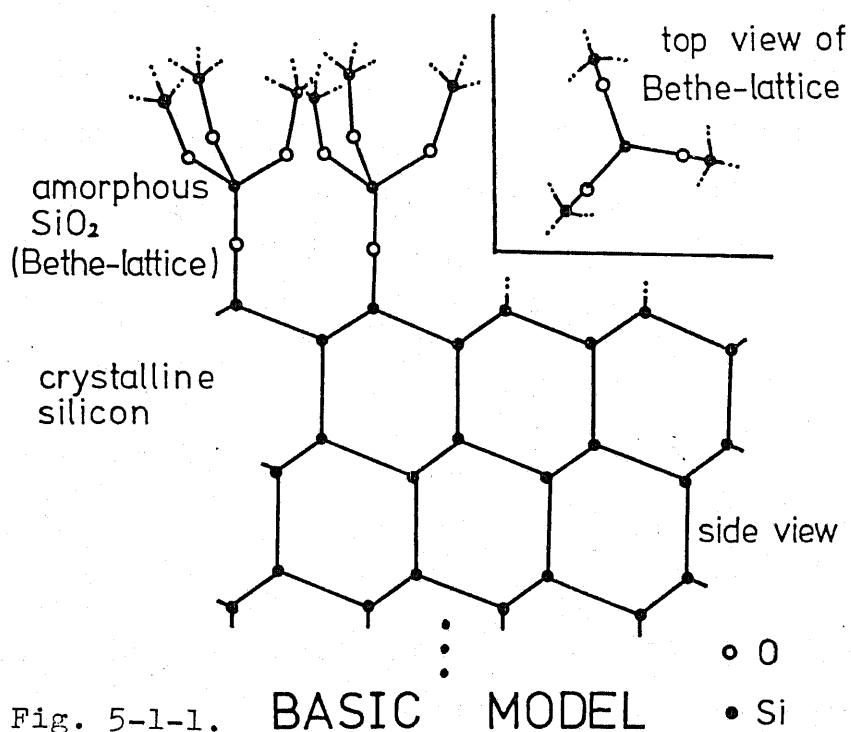


Fig. 5-1-1. BASIC MODEL

Basic model constructed with amorphous SiO_2 represented by Bethe-lattice and Si substrate with (111) orientation. Open and closed circles denote O and Si atoms, respectively.

model to simulate a thermally grown SiO_2 -Si interface. Since oxygen chemisorption of 1/3 monolayer on a Si free surface is enough to cancel the surface reconstruction,⁸⁷ it is not needed to include the reconstruction of crystalline Si surface at the interface.

A Bethe-lattice used here to represent amorphous SiO_2 is a hypothetical, tree-like lattice containing no closed rings, where the valencies of O and Si are maintained 2 and 4 respectively. It is constructed by connecting SiO_4 tetrahedrals and has three-fold symmetry. Normal Si-O-Si angle is chosen to be 144° which is believed to be the peak value of Si-O-Si angle in amorphous SiO_2 system⁸⁸ and this angle is varied in the range between 120° and 180° in case that an amorphous effect is taken into consideration. The electronic structures of crystalline SiO_2 and amorphous SiO_2 are shown to be similar by optical absorption measurements⁸⁹, though the long-range atomic configurations are quite different. This suggests that the short-range orders such as valencies and SiO_4 tetrahedrals play an important role to determine the electronic structures, so that the Bethe-lattice model is thought to be a good approximation to represent amorphous SiO_2 . (also cf. Sec. 3-5)

Based on this basic model we have calculated the energy levels of microscopic defects at Si- SiO_2 interfaces with changing various bonding parameters such as bond lengths, bond bending angles and bond rotation angles and investigated the possible origins of the interface traps continuously dis-

tributed in the forbidden gap of Si. Furthermore we have obtained the energy levels of impurities such as H, OH, Cl, and F bonded to Si dangling bond at the interface and discussed the annealing behavior of the interface traps.

In section 5-2, the various theories which deal with the calculation of the electronic structures of amorphous materials are discussed. Section 5-3 is dedicated for the models and procedures of the calculation of the Si-SiO₂ interface. Section 5-4 describes the calculated results of the interface states and impurities at the interface together with the proposed model for the interface states continuously distributed in energy and their annealing behavior. Section 5-5 is a summary.

SECTION 5-2. CALCULATION THEORIES OF THE ELECTRONIC
STRUCTURES OF AMORPHOUS MATERIAL

The density of states is a basic physical quantity which has much to do with the photo characteristics and the electronic conduction of amorphous materials. In the following, various theories calculating the DOS are reviewed. From this review, it is shown that the 'Bethe-lattice model' is the only theory which can reproduce the electronic structure of amorphous materials and whose calculation is carried out in a practical length of time. For every theory, the following sequence is used: a) authors, b) reference number, c) year, d) materials which are actually treated by the theory, e) characteristics, and f) conclusions.

5-2-1. COHERENT POTENTIAL APPROXIMATION

a) Yonezawa et al, b) 91, c) 1975, d) actually no material is treated.

e) The extension of the theory which was successful in the theory of alloys.

f) It has not reached the stage of the application to the real material. The calculation effort is felt too heavy.

5-2-2. CLUSTER MODEL

a) McGill & Klima, Keller & Ziman, Okazaki et al, b) 92, 93, 94

c) 1972-1975, d) a-C, a-Si, vacancy in Si

e) The electron multiple scattering by many spherical muffin-tin atomic potentials (atomic cluster) which are floating in an effective potential is correctly calculated. Okazaki et al⁹⁴ introduced self-consistency in determining the effective potential.

f) The region where the DOS is small (pseudogap) certainly exists without assuming long range order of the atomic configuration (Fig. 5-2-1). If there is a vacancy of Si, then a peak in the DOS arises in the pseudogap. This corresponds to the generation of a dangling-bond state (Fig. 5-2-2). But even a large cluster which contains more than 30 atoms does not have a real bandgap where the DOS is completely zero (Fig. 5-2-3).

This is due to the imperfect treatment of the surface of the

"atomic cluster".

5-2-3. BAND CALCULATION WITH POLYMORPH

- a) Joannopoulos et al, Chin et al, b) 95,96 , c) 1973-1975,
- d) Si, Ge
- e) Band calculation by a pseudopotential method is carried out for complex structured crystals which have atoms of 2-12 in a unit cell. Chin et al calculated the band structure of a Si crystal which has 61 atoms in a unit cell by the LCAO method.
- f) The differences between the DOS of a-Si and that of crystal are that the top of the valence band gets steeper in a-Si and that the fine structures in DOS disappear in a-Si,⁹⁷ as shown in Fig. 5-2-4. These effects are reproduced in Fig. 5-2-5. But the physical reasons of these effects are not clear. The calculation is tedious.

5-2-4. PERTURBED CRYSTAL MODEL

- a) Kramer, b) 98 , c) 1970, d) a-Ge, a-Si, a-Se
- e) If the crystal undergoes a certain kind of perturbation, the Hamiltonian becomes non-Hermite and the energy eigen values have imaginary part, that is, the band structure is blurred.
- f) It is interesting in the sense that the transition from the crystal to the amorphous state can be analyzed. However, the existing amorphous material can not be considered as a

perturbed crystal, so that the theory loses its basis. The calculated results (Fig. 5-2-6) of amorphous material shows no change from a crystal in the valence band, which does not agree with the experimental results.

5-2-5. SIMPLE TIGHT-BINDING MODEL

a) Weaire & Thorpe, b) 77, c) 1971, d) tetrahedrally bonded material

e) The theoretical discussions are made by using a very simple Hamiltonian given in Sec. 4-5 (Fig. 4-5-1).

f) They proved the mathematical fact that the bandgap larger than $\text{abs}(2xV2-4xV1)$ is produced, only assuming that the atoms are bonded with four surrounding atoms, and without assuming the definite atomic configuration. If $V1$ and $V2$ fluctuate in the range of $V1 \pm |d1|$ and $V2 \pm |d2|$, respectively, then the minimal bandgap decreases to

$$2(|V2| - |d2|) - 4(|V1| + |d2|).$$

5-2-6. MOLECULAR ORBITAL METHOD

a) Chen, Shimizu et al, b) 99, 100, c) 1973-, d) Se, AsSe, SiO_2 , defects, etc.

e) Energy levels are calculated for imaginary molecules or large molecules.

f) The method itself has been established in the field of

chemistry and is considered to be quite general. A calculated example is shown in Fig. 5-2-7. Treatments of molecular surfaces and the wave functions extended all over a material are problems.

5-2-7. CLUSTER BETHE-LATTICE MODEL

- a) Joannopoulos et al, b) 1974, c) 1974-, d) Si, Ge, SiO₂
- e) Bethe-lattices are connected to the surface of a certain cluster of atoms (Fig. 5-2-8). The Bethe-lattice is an imaginary, tree-like, and infinite connected network of atoms with the same coordination number as found in the real material but without rings of bonds. It provides a "neutral" background upon which the individual properties of the cluster are studied. The reasons for using the Bethe-lattices as a boundary condition are that the electronic structure of the system can be solved exactly, that DOS of the Bethe-lattice is featureless and smooth, and that the short range order of the atomic configuration found in a real material is maintained in the Bethe-lattice.
- f) In Fig. 5-2-9, they concluded that the steepness of DOS near the top of the valence band is due to the short range disorder such as the distorted tetrahedral structure, whereas the smoothness of DOS at the lower half of the valence band is due to the middle range disorder.

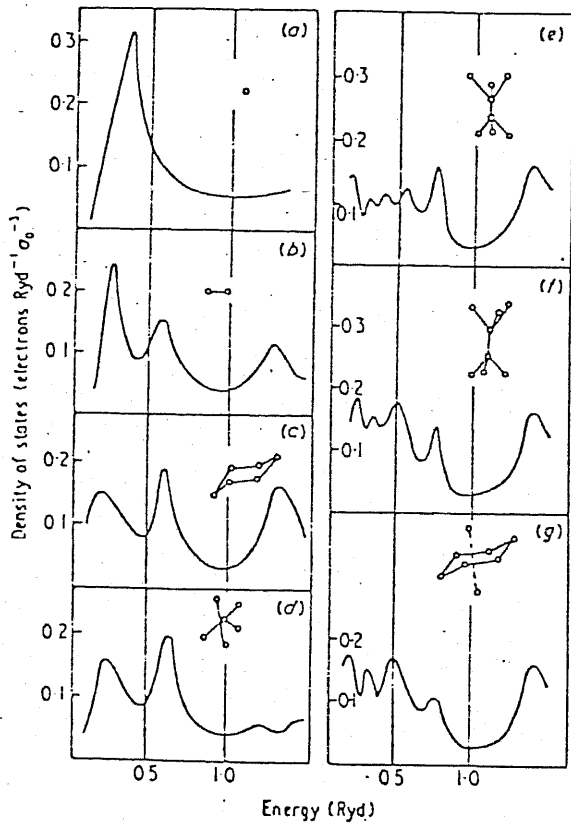


Fig. 5-2-1.⁹² DOS for various carbon clusters by cluster method.

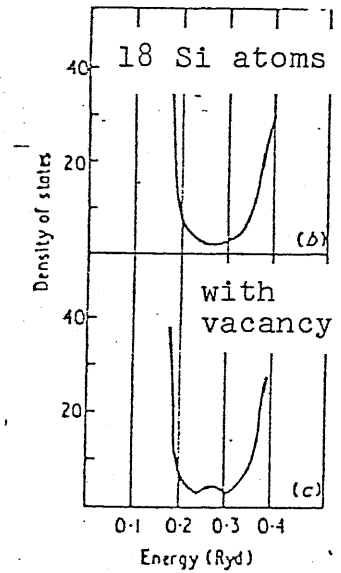


Fig. 5-2-2.⁹⁴ DOS peak is generated by Si vacancy.

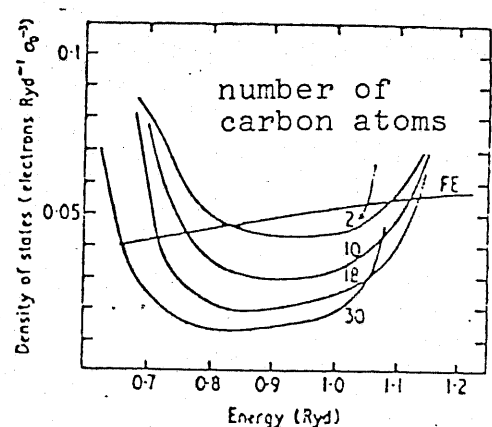


Fig. 5-2-3.⁹³ Complete bandgap can not be reproduced even if the cluster contains as many as 30 atoms.

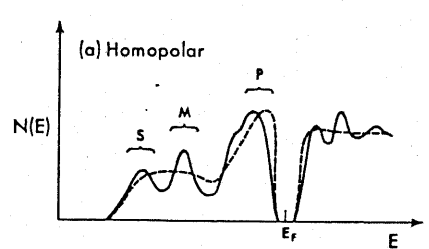


Fig. 5-2-4.¹⁰¹ Sketch of DOS. Solid line is for amorphous, and dotted line is for crystal. DOS near valence band top gets steeper and fine structure disappears when in amorphous.

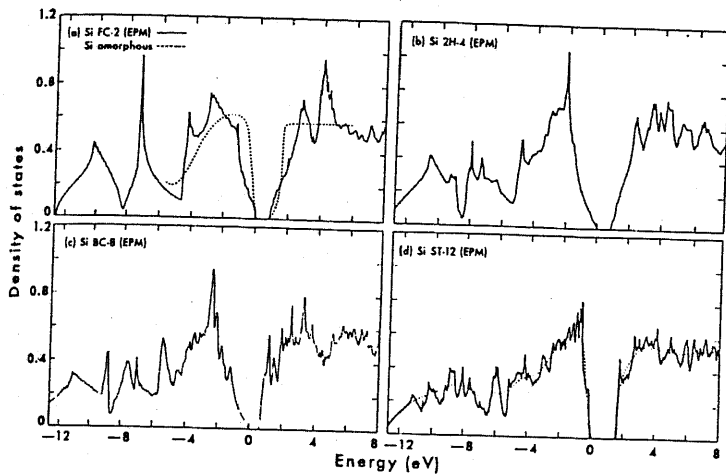


Fig. 5-2-5.⁹⁵ Band calculation for polymorph. Structure gets more complex from (a) to (d).

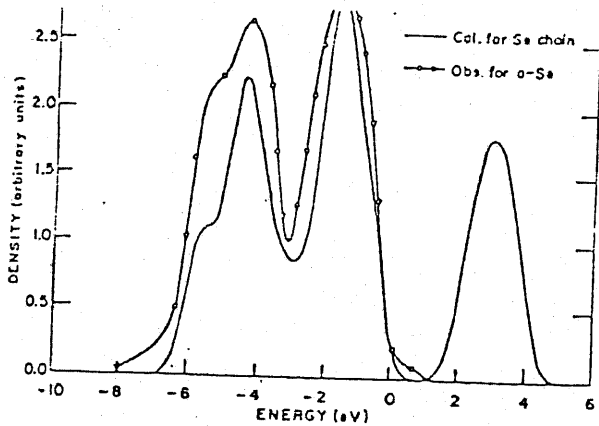


Fig. 5-2-7.¹⁰⁰ DOS for Se by EHT. Energy levels are Gaussian-broadened.

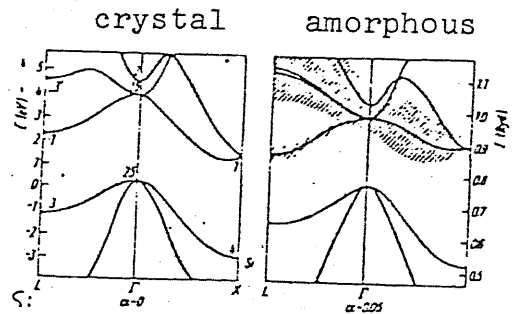


Fig. 5-2-6.⁹⁸ Band structure is blurred in amorphous phase.

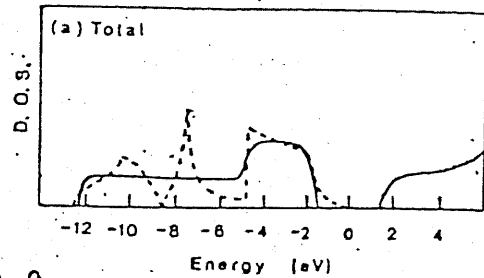


Fig. 5-2-9 Densities of states for the Bethe lattice. The filled valence bands lie at negative energies. (a) Total density of states with superimposed (dashed line) crystalline density of states.

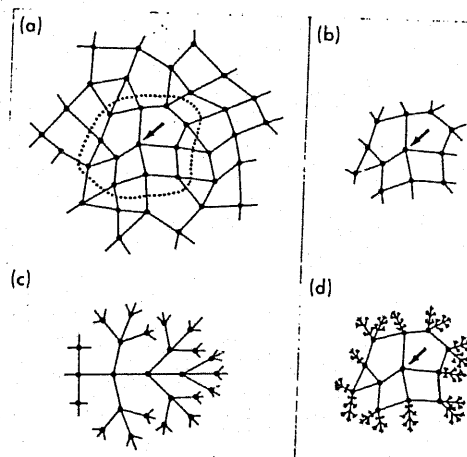


Fig. 5-2-8.¹⁰¹

The "cluster-Bethe lattice" method involves (a) taking an infinite system of atoms and choosing one atom as a reference point; (b) removing a small cluster surrounding and including this atom from the system; (c) using a Bethe lattice, which is an infinite system of atoms with fixed coordination and no rings of bonds to (d) satisfy the dangling bonds of the cluster. This new structure is called a "cluster-Bethe lattice" system.

PROCEDURE

Models of the atomic configurations used in the calculation are shown schematically in Fig. 5-3-1. The following is the procedure of the calculation.

- (1) Fix one certain k-vector.
- (2) Calculate the Green's function for Si (111) free surface (Fig. 5-3-1(a)).
- (3) Connect a Bethe-lattice and one oxygen to this surface (Fig. 5-3-1(b)).
- (4) Sum up the Green's functions over various k-vectors.
- (5) Separate the Bethe-lattice and one oxygen to form a $\text{Si}_3 \equiv \text{Si}$ -dangling bond (Fig. 5-3-1(c)).
- (6) Bring the Bethe-lattice closer to the Si dangling bond to simulate Si-Si bonding and O-Vacancy (Fig. 5-3-1(d)).
- (7) Bring the Bethe-lattice and one oxygen closer to the Si dangling bond to form Si-O weak bond at the interface (Fig. 5-3-1(e)).
- (8) Bond any of H, O, OH, Cl and F to the Si dangling bond to represent the bonding of impurity atom (Fig. 5-3-1(f)).

These are the rough sketches of the calculation procedure and other atomic configurations used in the calculation will be shown schematically in each time in the results.

The tight-binding parameters for SiO_2 employed in the present calculation have been determined by Chadi et al. The values are given in Table 5-3-1. The orbitals used in the calculation of the SiO_2 Bethe-lattice are illustrated in Fig. 5-3-2.

The computer programs used in this chapter are shown in Appendix A. The calculation has been carried out at the computer center of the Univ. of Tokyo with some library subroutines provided by the center.

The Hamiltonian and the basical calculation method are explained in the previous chapters.

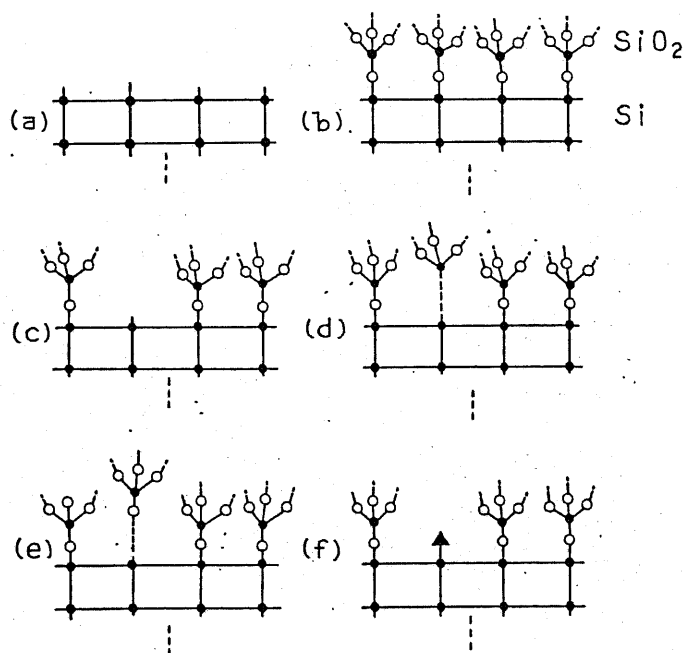


Fig. 5-3-1.

Models of various configurations used in the calculation.

a) Si free surface, b) perfect interface, c) $\text{Si}_3 = \text{Si}$ -dangling bond, d) Si-Si weak bond and O-vacancy at interface, e) Si-O weak bond at interface, f) impurity at interface. Closed circle, open circle and closed triangle denote Si, O, and impurity atoms (H, OH, Cl, and F), respectively.

Table 5-3-1.

Tight-binding interaction parameters (in eV) for SiO_2 . The unprimed (primed) subscripts refer to $\text{Si}(0)$ orbitals. Notation is standard and similar to that used in Table

$E_s=4.42$	$E_p=10.67$	$E_{s'}=-14.63$	$E_{p'}=-1.83$
$V_{ss'\sigma}=-2.85$	$V_{s's'\sigma}=-0.15$	$V_{sp'\sigma}=-5.4$	$V_{s'p'\sigma}=-9.5$
$V_{pp'\sigma}=-5.4$	$V_{pp'\pi}=-1.4$	$V_{p'p'\sigma}=-0.45$	$V_{p'p'\pi}=-0.45$

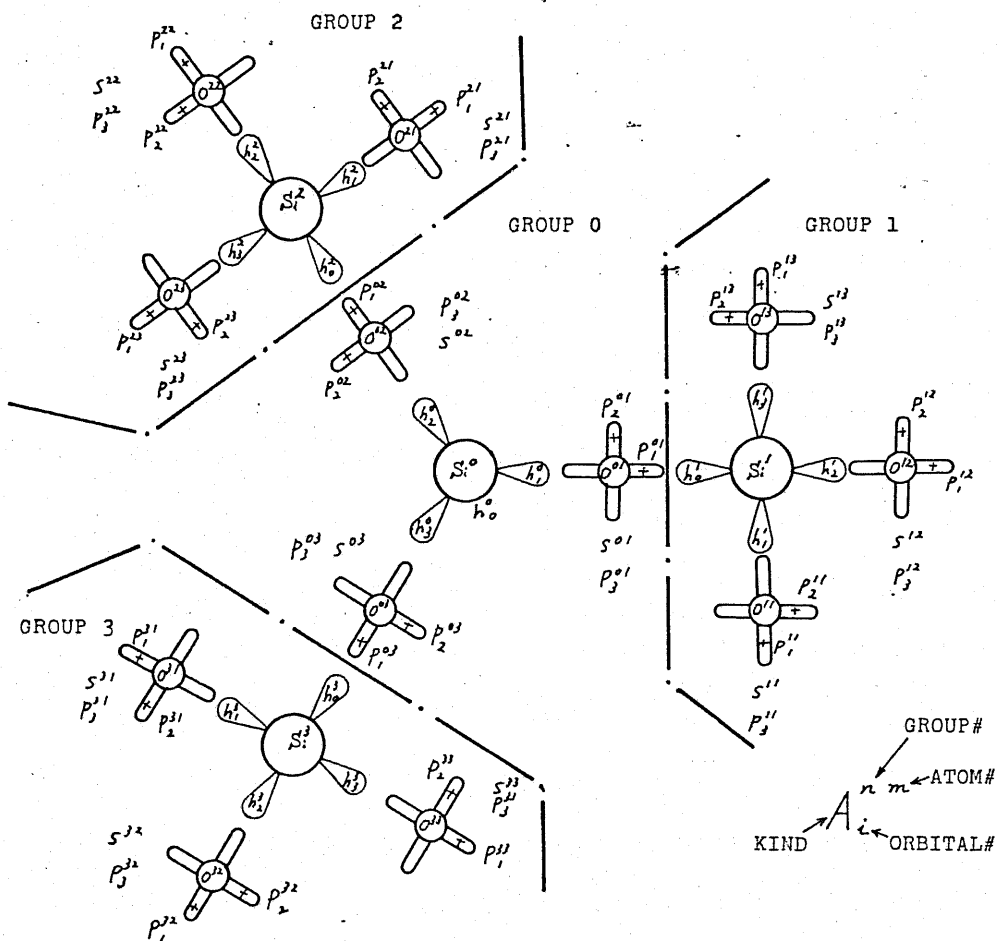


Fig. 5-3-2. Orbitals used in the calculation of the SiO_2 Bethe-lattice.

SECTION 5-4. RESULTS AND DISCUSSIONS

Both the perfect interface with the Si-O-Si bond angle ranged from 120° to 180° and the interface with oxygen dangling bond do not have a gap state as illustrated in Fig. 5-4-0. However, $\text{Si}_3\equiv\text{Si}$ -dangling bond at the interface gives rise to a gap state at about the middle of the Si bandgap as shown in fig.10, as Laughlin et al have indicated. But it should be noted that Si bandgap in their calculation was about 2.5 eV due to the nearest neighbor approximation and a Bethe-lattice approximation for the Si substrate, whereas in our model Si bandgap is calculated to be exactly 1.1 eV

The O-vacancy and Si-Si weak bond at the interface produce trap states in the Si bandgap, whose energy levels vary in the energy range lower than the midgap of Si by changing various bonding parameters. Figure 5-4-1 demonstrates the dependence of Si-Si weak bond level (including O-vacancy level) on the Si-Si bond length. Figures 5-4-2 and 5-4-3 show how O-vacancy level varies in energy depending on the bond bending angle, and the rotation angle, respectively. In these bonding parameters, bond length variation gives the strongest effect on the energy level.

When the Si dangling bond interact weakly with Si atom which is already bonded to four oxygen atoms in the SiO_2 network, the level also appears in the Si bandgap. This level moves in the lower half of the Si bandgap when the distance between these two Si atoms are varied from 2.3 \AA to infinity as is shown in Fig. 5-4-4.

On the contrary, Si-O weak bond and Si-O weak interaction produce trap levels in the upper half of the Si bandgap. Si-O weak bond state changes its energy level depending on the bond length and the bond bending angle as demonstrated in Figs. 5-4-5 and 5-4-6, respectively. Si-O weak interaction indicates the situation where the Si dangling bond interacts weakly with O atom which is already bonded to two Si atoms in the SiO₂ network. Figure 5-4-7 shows the dependence of the Si-O weak interaction level on the distance between Si atom and O atom which is already bonded to two Si atoms in the SiO₂ network. In calculating the energy levels of Si-Si weak interaction shown in Fig. 5-4-4 and those of Si-O weak interaction shown in Fig. 5-4-7, the interaction parameters among atoms having normal valency have been used. To weaken these interaction parameters is almost equivalent to increase the distance between the atoms at the interface. (cf. Fig. 5-4-8)

The bonding parameters at the actual Si-SiO₂ interface can be supposed to vary because of the amorphous structure and the large internal stress included in this system. Therefore, Si-Si weak bond, Si-Si weak interaction, Si-O weak bond, and Si-O weak interaction are thought to be the possible origins of the interface trap states continuously distributed in energy. Commonly observed U-shaped distribution of the interface trap densities (Fig. 5-4-9) is explained if bond length distributions in Fig. 5-4-10 and energy level dependences on the bond length as Fig. 5-4-1 and Fig. 5-4-5 are assumed. The rapid decrease of the distribution (Fig. 5-4-10) as the bond length

increases is reasonable because the normal bond lengths are shorter than 2.5 Å and the longer bond lengths are less likely.

The gap states move out of the energy range between 0.5 eV below the top of Si valence band and 0.5 eV above the bottom of Si conduction band when any of H, OH, Cl and F is bonded to the Si atom at the interface. This situation is illustrated in Fig. 5-4-11. Since an energy level outside the Si bandgap can not work as a trap state at the interface under normal operating conditions, this result explains the reduction of the interface trap density by H₂ annealing, trichloro-ethylene annealing, and HCl oxidation and further suggests the possibility of F annealing.

The level moves up in the conduction band of Si in bonding with either of H, OH, Cl, and F. (cf. Fig. 5-4-12 and 5-4-13)

AT THE Si - SiO₂ INTERFACE

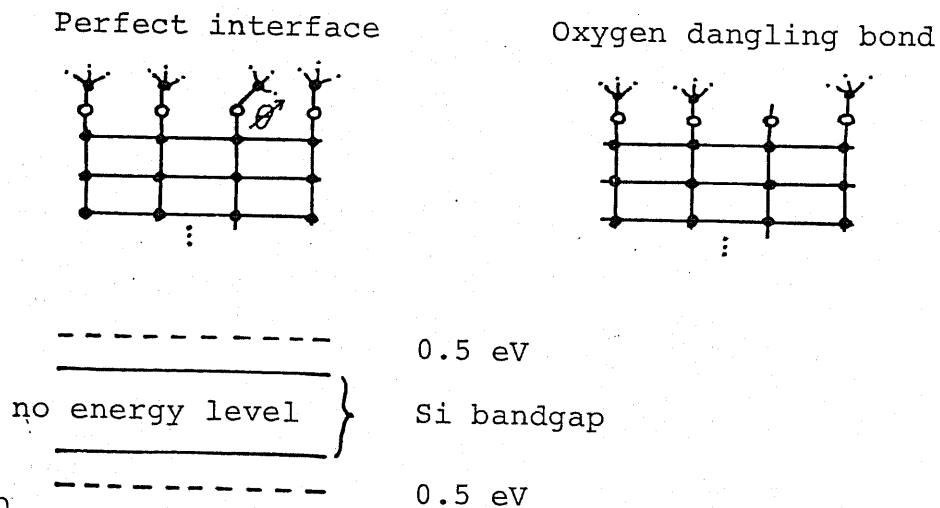


Fig. 5-4-0.

Perfect interface and oxygen dangling bond at the Si-SiO₂ interface have no energy level in the range between 0.5 eV below the top of the valence band and 0.5 eV above the bottom of the conduction band of Si. Open and closed circles denote O and Si atoms, respectively.

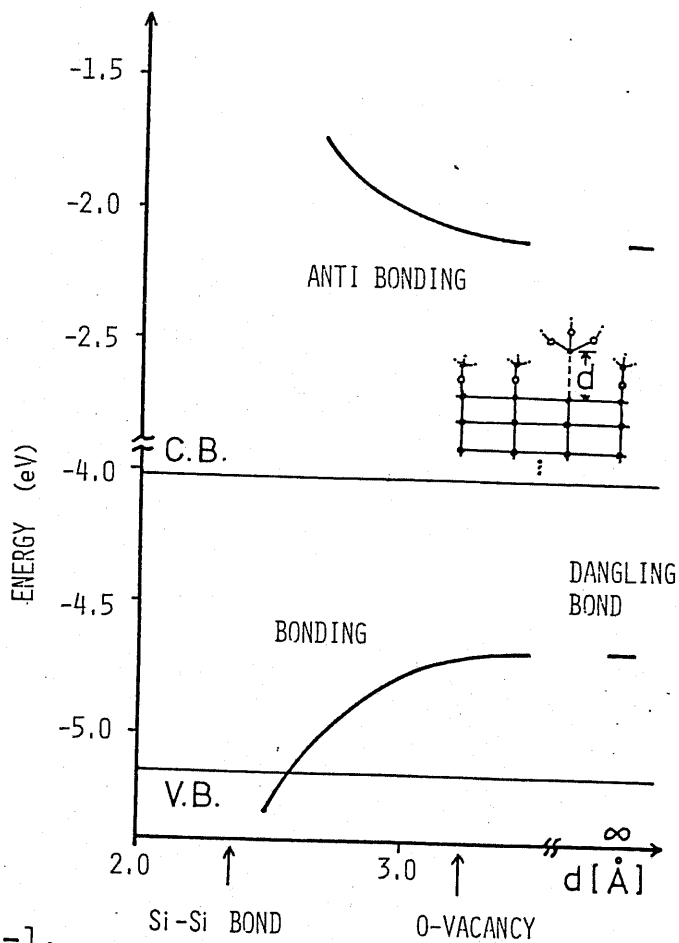


Fig. 5-4-1. Si dangling bond, Si-Si bond, and O-vacancy level at the interface. These energy levels move in the lower half of the Si bandgap with changing the bond length d . Open and closed circles denote O and Si atoms, respectively.

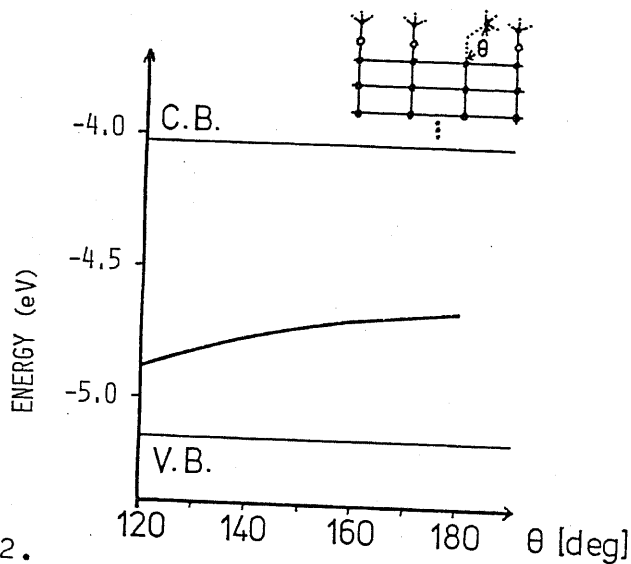


Fig. 5-4-2.

O-vacancy level and its dependence on the bond bending angle. Open and closed circles denote O and Si atoms, respectively.

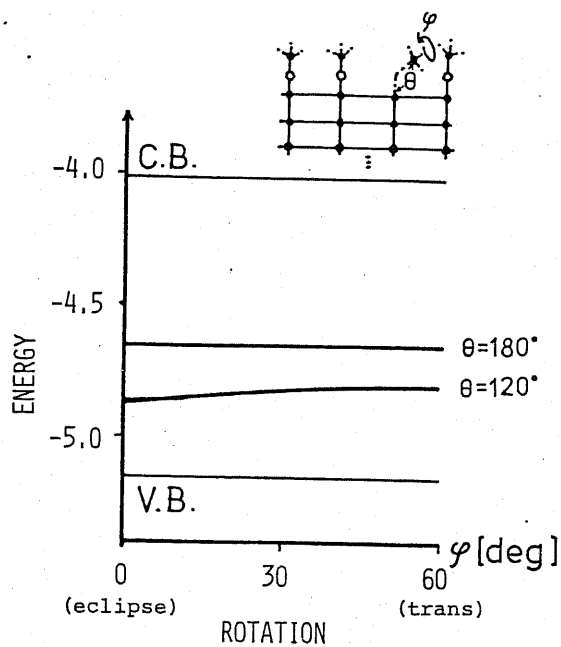


Fig. 5-4-3.

Dependence of O-vacancy level on the bond rotation angle. This dependence is very weak. Open and closed circles denote O and Si atoms, respectively.

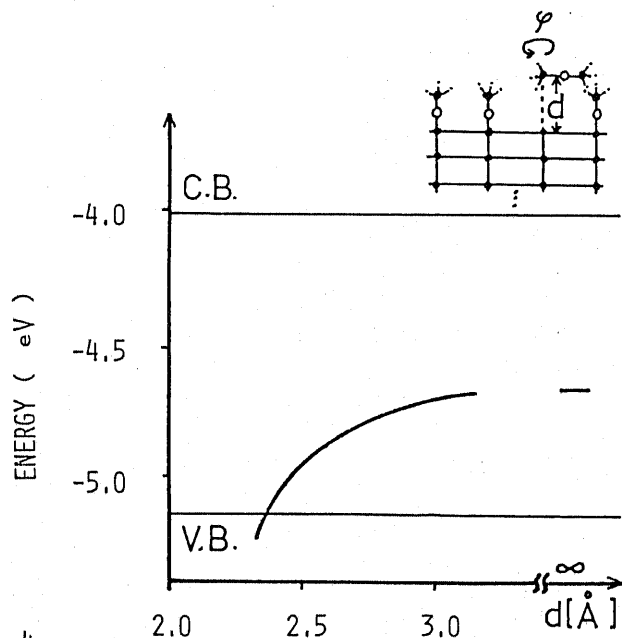


Fig. 5-4-4.

Energy level of Si dangling bond weakly interacting with Si atom which is already bonded to four oxygen atoms in SiO_2 network. The energy level varies with changing the distance d . φ -rotation gives no significant effect on the energy level. Open and closed circles denote O and Si atoms, respectively.

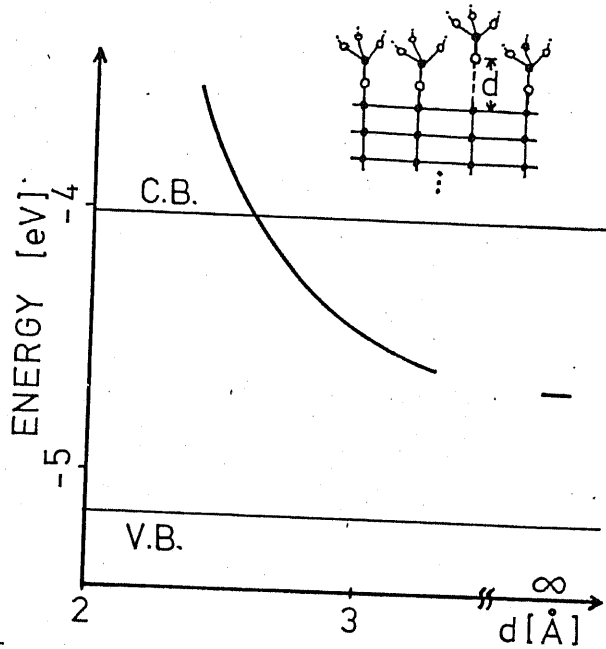


Fig. 5-4-5.

Energy level of Si-O weak bond at the interface. This energy level moves in the energy range higher than the midgap with changing the bond length d . Open and closed circles denote O and Si atoms, respectively.

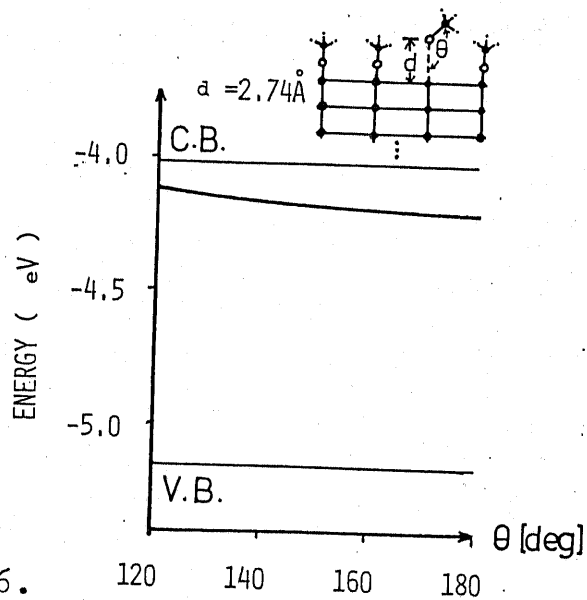


Fig. 5-4-6.

The dependence of the energy level of Si-O weak bond on bond bending angle. The dependence is minor. Open and closed circles denote O and Si atoms, respectively.

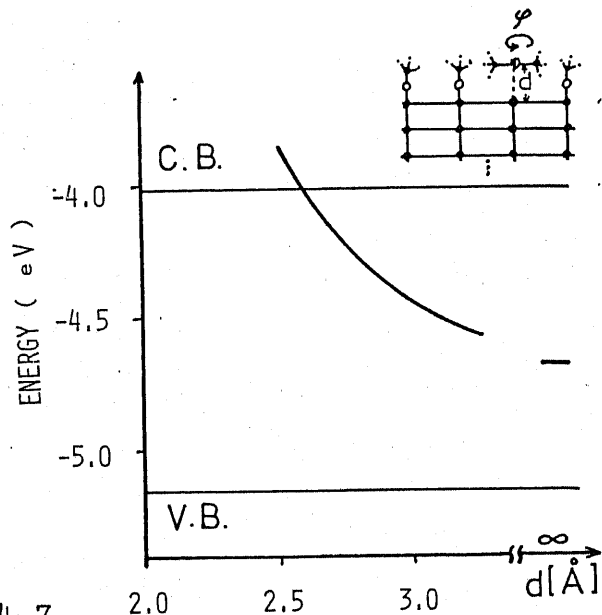


Fig. 5-4-7.

Energy level of Si dangling bond weakly interacting with oxygen atom which is already bonded to two Si atoms in SiO₂ network. The energy level varies with changing the distance d . ψ -rotation gives no significant effect on the energy level. Open and closed circles denote O and Si atoms, respectively.

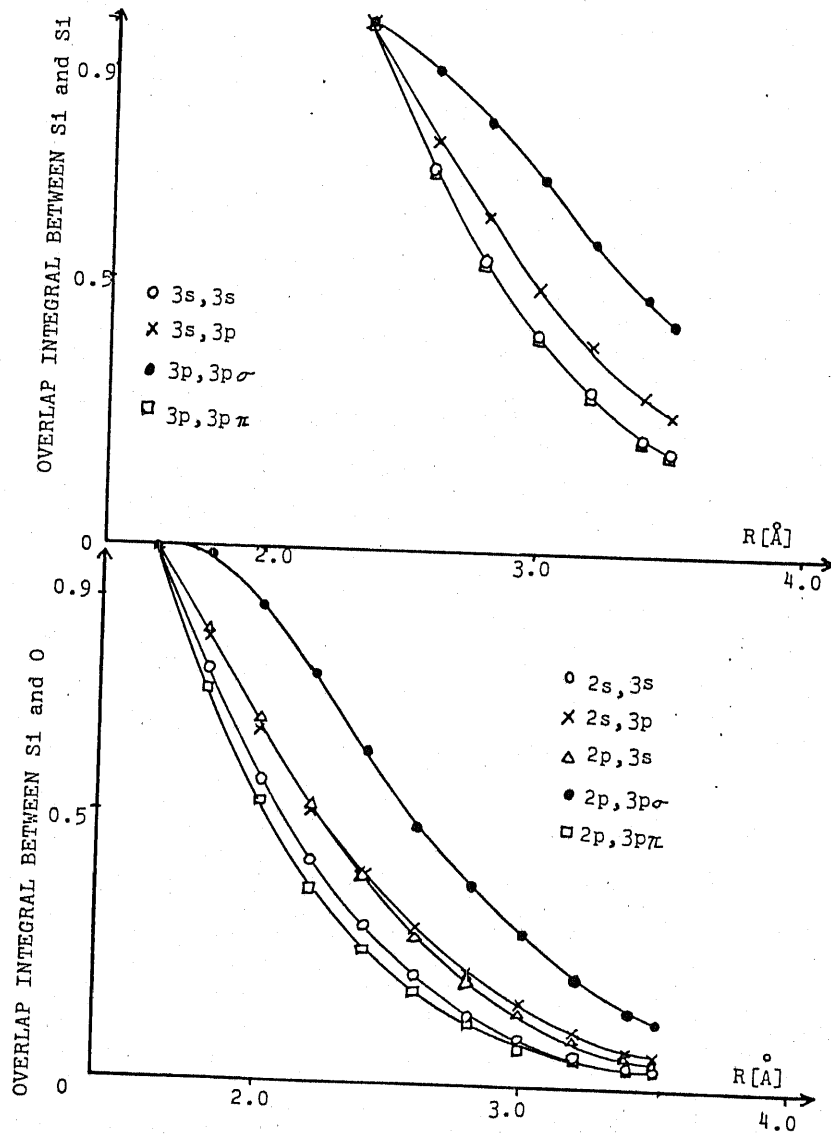


Fig. 5-4-8.

Values of overlap integrals dependent on distances of orbitals, R .

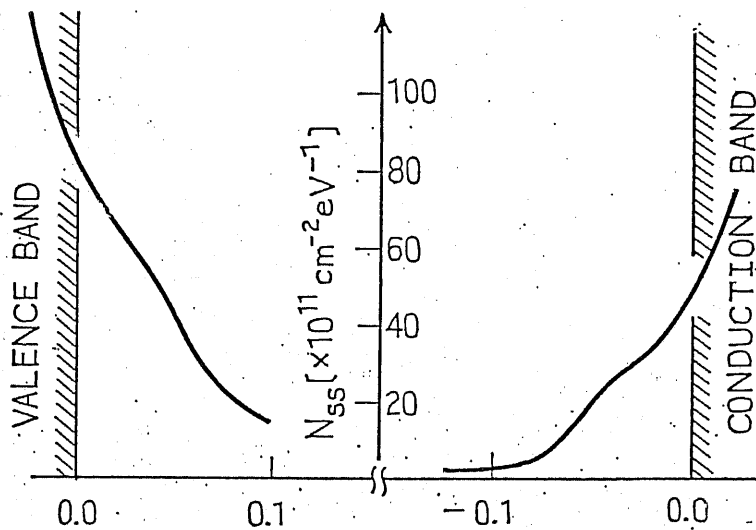


Fig. 5-4-9. SURFACE POTENTIAL [eV]

Commonly observed U-shaped distribution of interface trap-state density in the forbidden gap of Si. (Cited from Ref. (02))

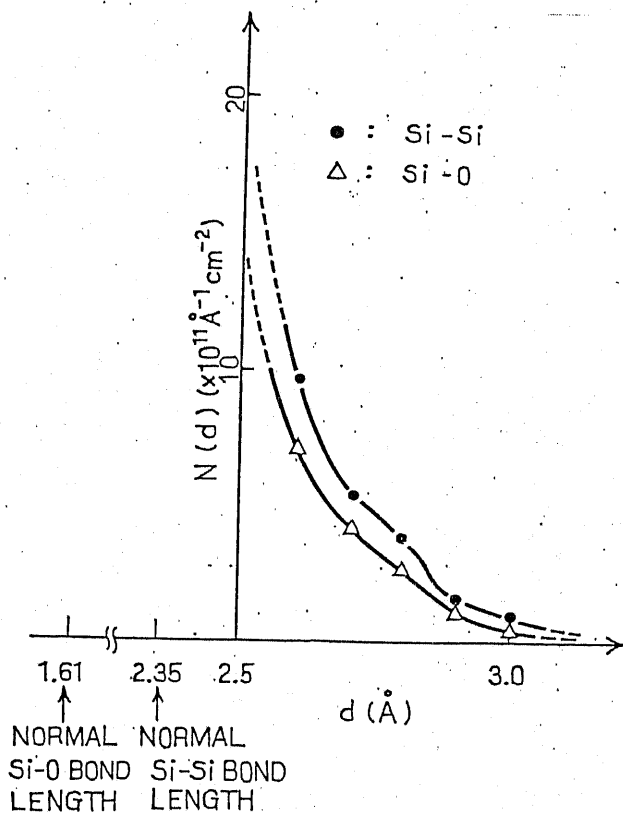
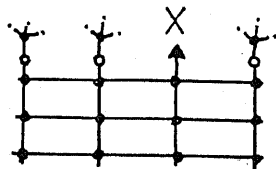


Fig. 5-4-10.

Assumed bond length density $N(d) (\text{Å}^{-1} \text{cm}^{-2})$ vs. bond length $d (\text{Å})$. Using this distribution together with the energy level dependence on bond length of Fig. 5-4-1 and 5-4-5, U-shaped distribution as shown in Fig. 5-4-9 can be explained.

(1) At the Si-SiO₂ interface



No level exists in and near the Si bandgap.

Fig. 5-4-11. X=any of H, OH, Cl, and F

Impurity at the Si-SiO₂ interface. If any of H, OH, Cl, and F is bonded to the Si dangling bond, no energy level exists in the energy range between 0.5eV below the top of the valence band and 0.5eV above the bottom of the conduction band of Si. Open and closed circles denote O and Si atoms, respectively.

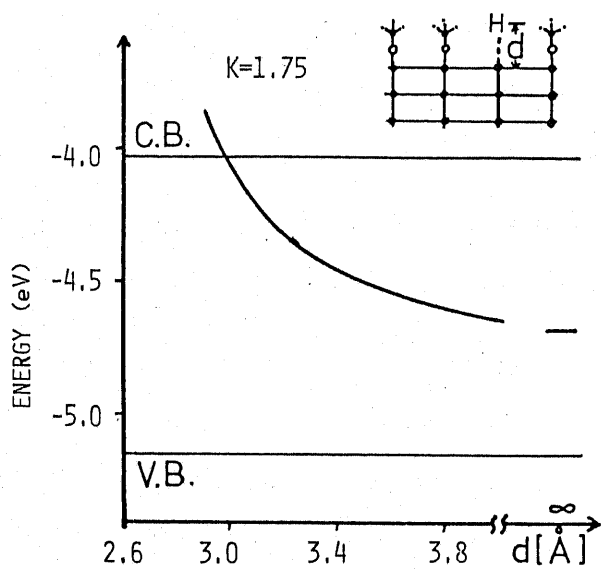


Fig. 5-4-12. STRETCHED Si-H BOND AT INTERFACE

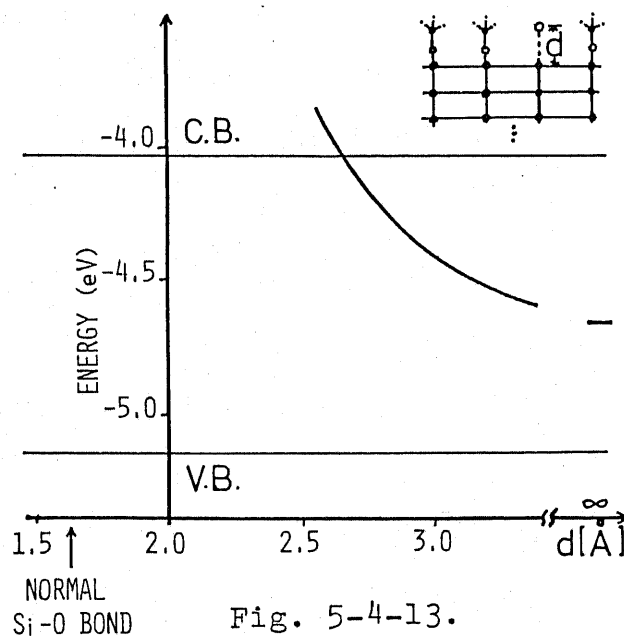


Fig. 5-4-13. STRETCHED Si-O ATOM BOND AT INTERFACE

SECTION 5-5. SUMMARY

A calculation procedure dealing with the electronic structures of crystalline Si-amorphous SiO₂ interface including microstructural defects based on semiempirical tight-binding Hamiltonians and Green's function formulation is applied to the calculation of interface trap states between amorphous SiO₂ and the Si substrate with (111) orientation.

The following results are obtained. Perfect interface and the interface including oxygen dangling bond have no energy level in the Si bandgap, whereas Si₃= Si- dangling bond has a energy level at about the middle of the Si bandgap. Si-Si weak bond and weak interaction at the interface give rise to gap states whose energy move in the energy range lower than the midgap with varying the distances between two Si atoms, while the energy levels of Si-O weak bond and weak interaction at the interface appear at the upper half of the forbidden gap of Si depending on the distances between the Si atom and the O atom.

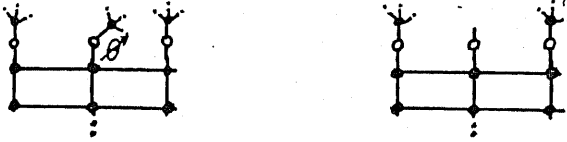
Possible origins of interface trap states which are distributed continuously in Si energy gap are suggested to be these Si-Si weak bond, Si-Si weak interaction, Si-O weak bond, and Si-O weak interaction at the interface.

The reduction of the gap state density by H₂-annealing, trichloro-ethylene annealing, or HCl oxidation is understood by bonding H or Cl to the Si₃= Si- dangling bond at the interface.

These situations are illustrated in Fig. 5-5-1.

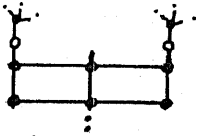
Fig. 5-5-1. Calculated results on Si-SiO₂ interfaces.

- (1) (a) Perfect interface (b) oxygen dangling bond



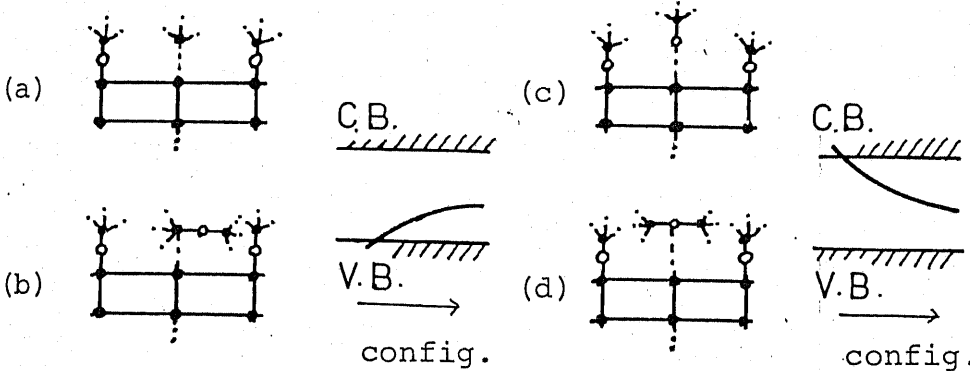
No energy level exists in the Si bandgap.

- (2) Si dangling bond



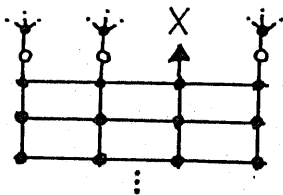
A energy level appears about the Si midgap.

- (3) (a) Si-Si bond (O-vacancy) (c) Si-O weak bond
(b) Si-Si weak interaction (d) Si-O weak interaction

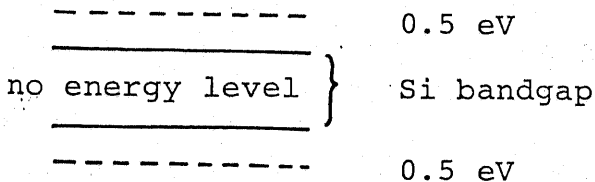


The energy level in the Si bandgap varies with the change of the configuration.

- (4) Impurity at the Si-SiO₂ interface



X=any of H, OH, Cl, and F



No energy level exists in the energy range between 0.5 eV below the top of the valence band and 0.5 eV above the bottom of the conduction band of Si.

CHAPTER 6. BONDING DEFECTS IN SiO₂

SECTION 6-1. INTRODUCTORY REMARK

1~45

Recently, as the sizes of MOS integrated circuits become very small to the order of sub-microns and accordingly the high doping density is employed, the electric field near the channel becomes very high. This high electric field accelerates the electrons and injects them into the SiO₂ layer. The injected electrons are then trapped in the SiO₂ bulk traps and change the V_{th}. This instability of MOS devices becomes a technological problem in making short channel MOS transistors. It is called the "hot electron injection problem", hot, because the injected electrons have enough energy to overcome the Si-SiO₂ electronic barrier higher than 3 eV and electrons having the energy of 3 eV are considered hot in a thermal equilibrium.

The bulk traps of SiO₂ is thought neutral before they are negatively charged up by the injected electrons, because they do not affect the initial flat band voltage shift and in addition the capture cross sections of these traps are between 1.7×10^{-15} and 1.0×10^{-18} [cm²],³⁸ which are considered to be those of neutral traps.¹⁰³

In addition to the problem concerning to MOS transistors, the electron capture in the oxide gives a grave effect on the operation of FAMOS. In FAMOS devices, the avalanche voltage

increases as the write-erase cycle is repeated (so called "walk-out effect"). However, the microscopic origins of the neutral traps are not yet clear. This chapter is dedicated for obtaining the theoretical background of the neutral traps and shedding light on the electron injection problem. The calculation has been carried out assuming various atomic configurations of amorphous SiO_2 with or without bonding defects and impurities in Sec. 6-2. According to the results, some of the origins of the neutral traps are proposed in Sec. 6-3. Section 6-4 is devoted for the summary.

SECTION 6-2. MODELS FOR CALCULATION

The structure of amorphous SiO_2 is considered as a randomly connected SiO_2 network as shown in Photo 6-2-1. There is another kind of model called "micro-crystalline model", but in anyway the radial distribution function calculated by the "random network model" agrees excellently with experimental results. The Si-O-Si bond angle is thought to be varied between 120° and 180° , so that the calculations of this chapter is executed with varying the bond angle in this range. The Bethe-lattices mentioned in the previous chapter are used to represent the amorphous SiO_2 . Two Bethe-lattices and an oxygen atom are connected all together with varying Si-O-Si bond angles to make a perfectly bonded amorphous SiO_2 . In

order to simulate a Si-Si bond in SiO₂, two Bethe-lattices are interacted each other. Furthermore, impurities such as H, Cl, and F are bonded to a SiO₂ Bethe-lattice to calculate the effect of impurities in SiO₂. These models are illustrated in each figure of calculated results in the next section. The employed Hamiltonians are the same as those explained in Chap. 5.

SECTION 6-3. RESULTS AND DISCUSSIONS

Amorphous SiO₂ without Si dangling bonds and oxygen vacancies has no localized level in the SiO₂ bandgap, even if the Si-O-Si bond angle is varied in the range from 120° to 180°. In this perfectly bonded SiO₂ without bonding defects, the top of the valence band fluctuates about 0.4 eV by varying the Si-O-Si bond angle as shown in Fig. 6-3-1. This fluctuation may cause some effects on the hole injection from Si to SiO₂. Si dangling bonds, oxygen vacancies, and Si-Si bonds in SiO₂ produce levels in the SiO₂ bandgap, whose energy levels are given in Fig. 6-3-2. This dangling bond level changes its energy level about 1 eV¹⁰⁴ as shown in Fig. 6-3-3 according to the Si-O-Si bond angle variation, that is, by amorphous effect. The O-vacancy level also varies by this amorphous effect slightly, as shown in Fig. 6-3-4.

The Si dangling bond level and antibonding level of Si-Si bond

in SiO_2 can be the origins of the neutral traps. If the Si dangling bond or Si-Si bond exist in SiO_2 near the Si-SiO₂ interface, the electrons in these levels can go into the Si conduction band by tunneling and leaves positive charges, which can be one of the physical origins of the positive fixed charges commonly observed in the Si-SiO₂ system.¹⁰⁵

The effects of the bonding of H, Cl, and F can not be predicted clearly because the results are dependent on the choice of K parameter of the EHT. If the value less than 1.0 is used for the K parameter, then the impurity level appears in the SiO_2 bandgap, whereas with the greater value the level disappears. So that the situation is critical. But in anyway, the level moves upward to the conduction band of SiO_2 . Since we thought that this effect can be detected by an avalanche injection and a photo-depopulation measurements, these experiments are carried out in Appendix B only to find that the sensitivity of the measurements is too low to say some definite conclusions.

SECTION 6-4. SUMMARY

Calculated results are summarized in Fig. 6-4-1. According to these results, some chemical origins of neutral traps in the thermally grown oxide might be a Si dangling bond level and an anti-bonding level of a Si-Si bond including an oxygen vacancy in the oxide.

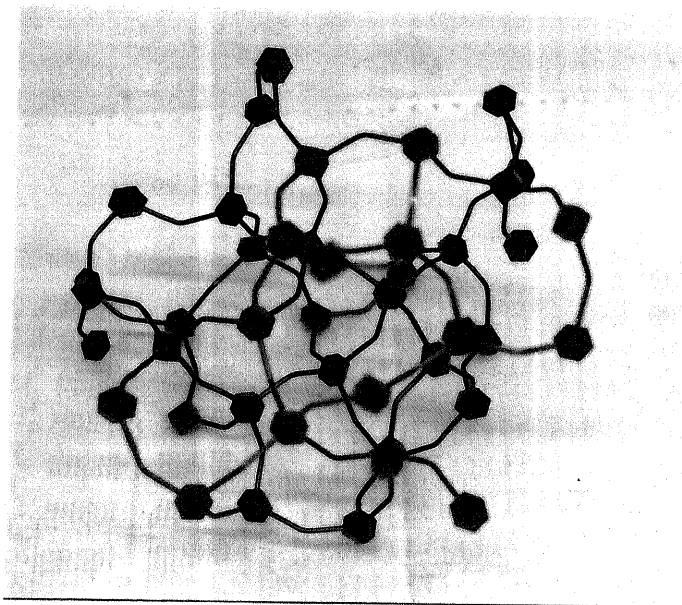


Photo. 6-2-1. Random network model of amorphous SiO_2 . Black plastic balls are Si atoms and bended point of lines is oxygen atom. Si-O-Si angle is chosen to be 144° which is believed to be the peak value of the Si-O-Si angle distribution in the real a-SiO_2 . It is easy to construct this kind of model without heavy stress.

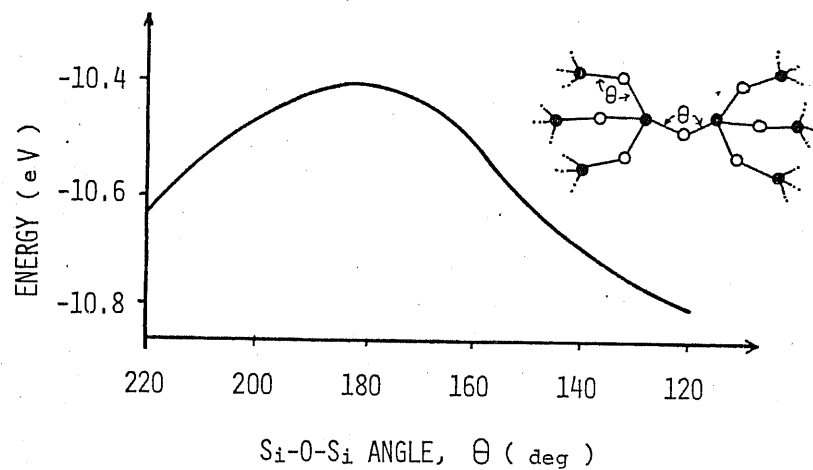


Fig. 6-3-1. Si-O-Si bond angle dependency of the top of the SiO₂ valence band. In the illustration open circles and closed circles denote O and Si atoms, respectively.

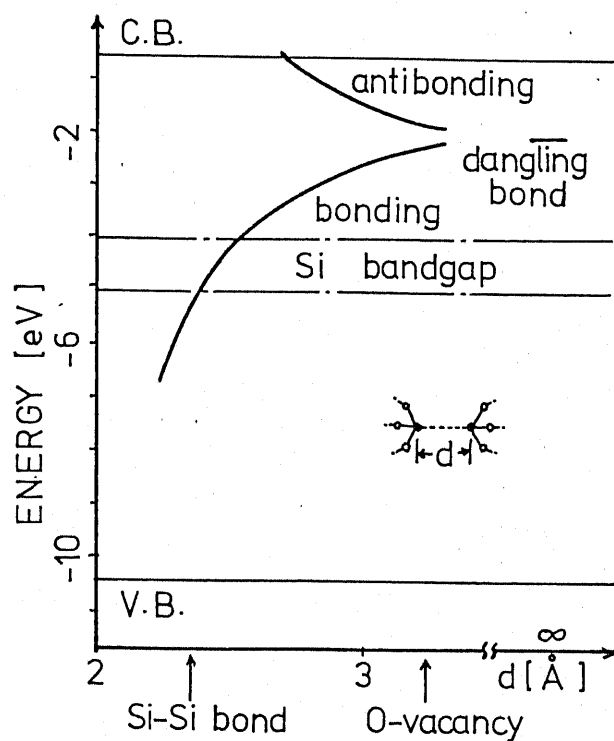


Fig. 6-3-2. Energy level of Si-Si bond in SiO₂ and its dependence on Si-Si bond length

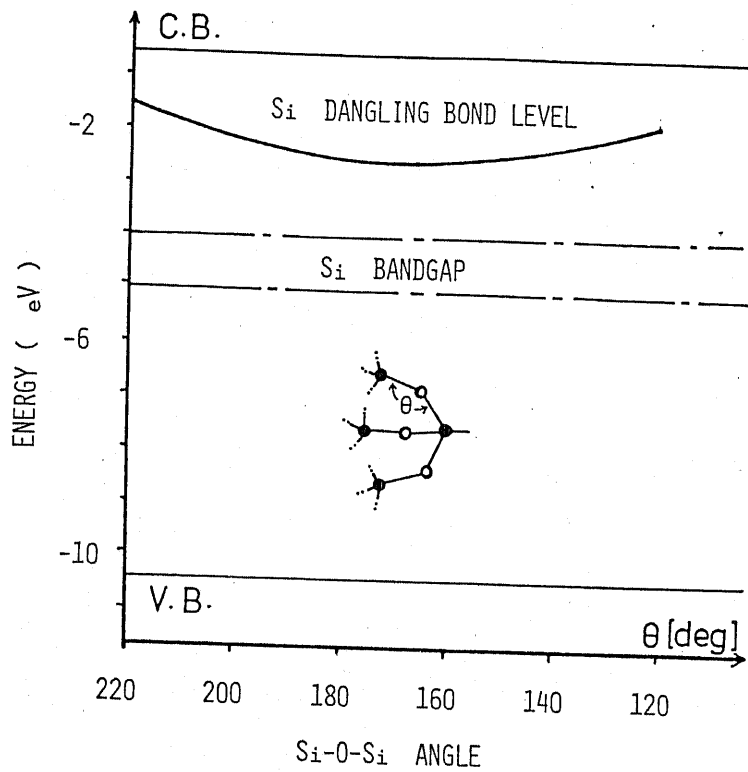


Fig. 6-3-3. Si-O-Si ANGLE DEPENDENCY OF Si DANGLING BOND LEVEL IN AMORPHOUS SiO_2

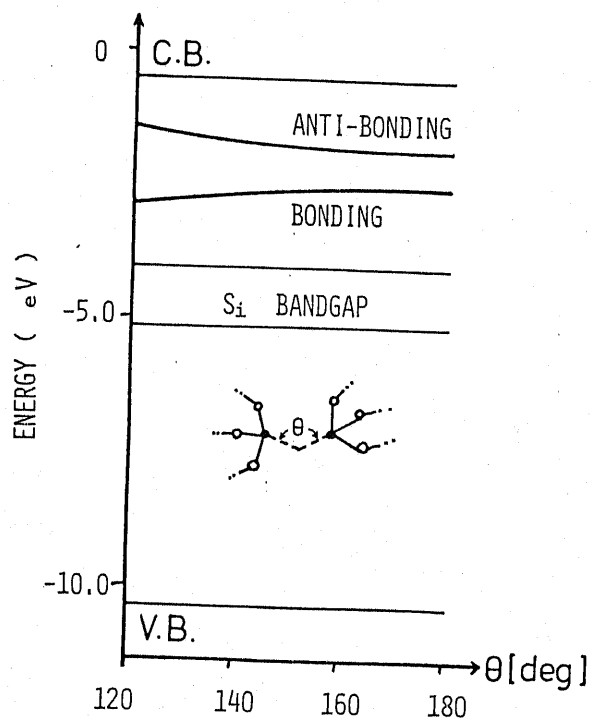
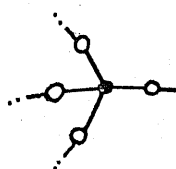
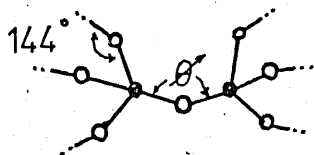


Fig. 6-3-4. O-VACANCY LEVEL IN SiO_2 AND ITS DEPENDENCE ON BOND BENDING

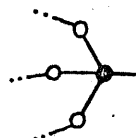
IN SiO_2

(1) (a) SiO_2 with no defects : (b) oxygen dangling bond



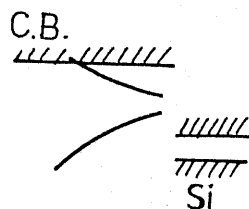
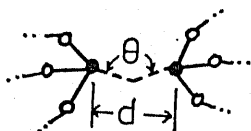
No energy level exists in the SiO_2 bandgap.

(2) Si dangling bond



A energy level exists in the SiO_2 bandgap.

(3) Si-Si bond (O-vacancy)



Two energy levels exist in the SiO_2 bandgap. These levels vary with changing d and θ .

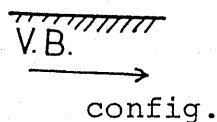


Fig. 6-4-1. Summary of the calculated results on the amorphous SiO_2 .

CHAPTER 7. CONCLUSIONS

A calculation procedure dealing with the electronic structure of crystalline Si-amorphous SiO_2 interface including microstructural defects is presented based on semiempirical tight-binding Hamiltonians and Green' function formulation and applied to the calculation of trap states at the interface between amorphous SiO_2 and the Si substrate with (111) orientation. This calculation method can be applied to the interfaces of materials other than Si- SiO_2 if the proper tight-binding parameters are given. The electronic structures of the amorphous SiO_2 with or without bonding defects are also calculated.

The following results are obtained. A perfect interface and the interface including oxygen dangling bond have no energy level in the Si bandgap, whereas $\text{Si}_3\equiv\text{Si}$ -dangling bond has a energy level at about the middle of the Si bandgap. Si-Si weak bond and Si-Si weak interaction at the interface give rise to gap states whose energy move in the energy range lower than the midgap with varying the distances between these two Si atoms.

On the other hand, the energy levels of Si-O weak bond and Si-O weak interaction at the interface appear at the upper half of the forbidden gap of Si, depending on the distances between the Si atom and the O atom.

Possible origins of interface trap states whose energy levels are distributed continuously in the Si bandgap are

suggested to be these Si-Si stretched bond, Si-Si weak interaction, Si-O stretched bond, and Si-O weak interaction at the interface.

The reduction of the interface trap state density by H₂ annealing, trichloro-ethylene annealing, or HCl oxidation is understood by bonding H or Cl to the Si₃=Si- dangling bonds at the interface. According to the calculated results, the possibility of F annealing is also suspected.

As for the SiO₂ bulk traps, some of the origins of the neutral traps in the SiO₂ film are suggested to be the Si dangling bonds and Si-Si bonds in SiO₂.

These situations are illustrated in Fig. 7-1.

The developed method itself is simple and flexible and can be applied to crystalline free surfaces with or without relaxation and/or reconstruction, impurity chemisorped surfaces, Bethe-lattices, bulk impurity problems, defects, and other complex problems such as superlattices and multilayer problems, if the proper tight-binding parameters are given. If a dynamic matrix is used for Hamiltonian, phonon spectra and Raman spectra can also be calculated. It should be noted that the calculation method used in Chaps. 5 and 6 is mathematically exact except for the limitation caused by the practical numerical calculation such as the finite number of the sampling points in k space.

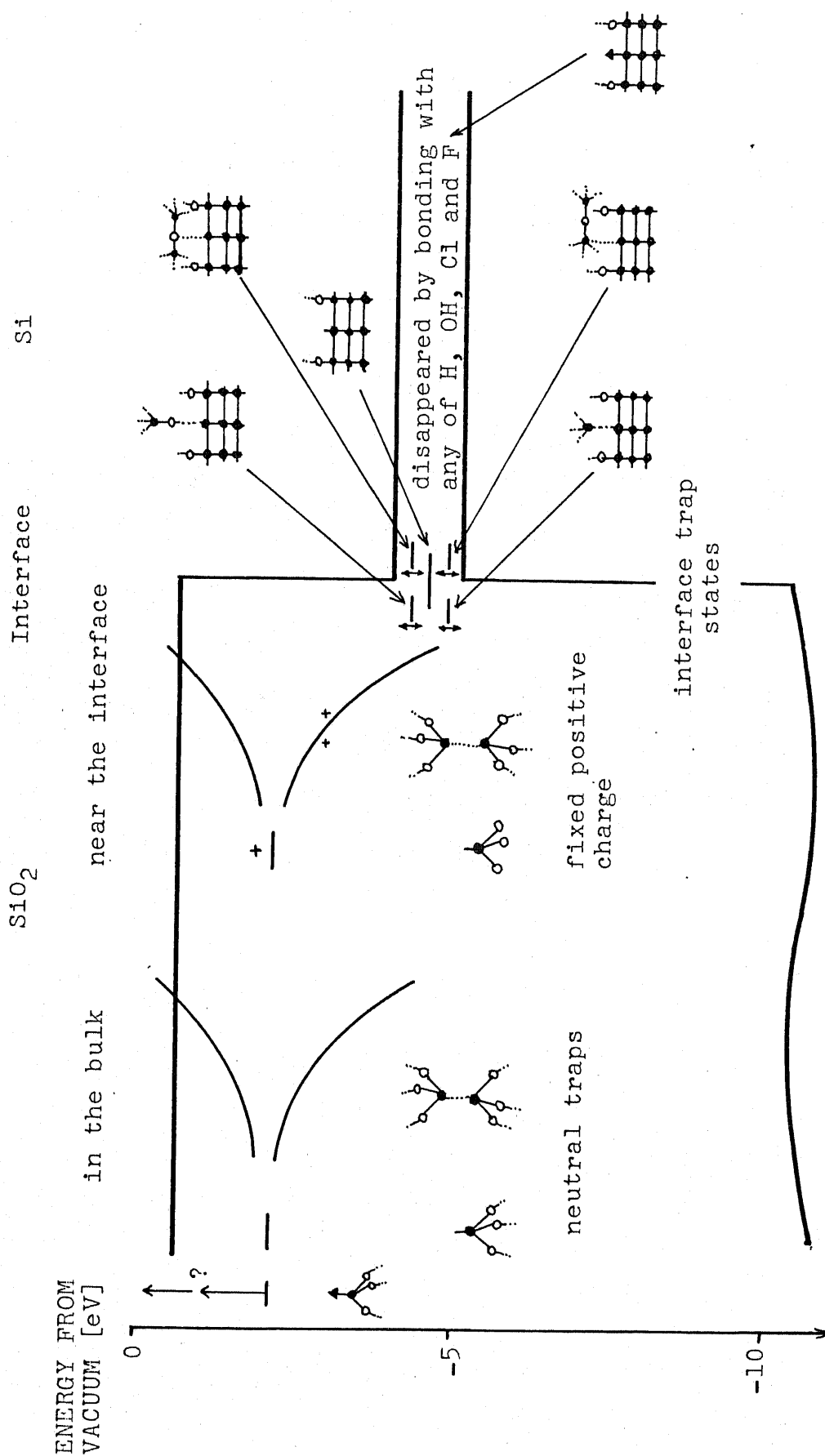


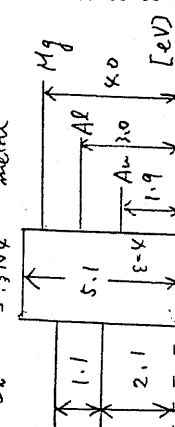
Fig. 7-1. Some of the possible origins of various gapstates of Si-SiO₂ system proposed in this work. Open and closed circles represent O and Si atoms, respectively. Solid triangles denote impurity atoms.

ACKNOWLEDGMENT

The author would like to express his profound appreciation to Prof. T. Sugano for his constant advices and encouragement in carrying out this work and to Prof. Y. Okabe for many useful suggestions and fruitful discussions. The author also wishes to give thanks to Dr. S. Sakai for giving him the theoretical background of the electronic structures of disordered materials and for introducing him the Green's function approach. The author is indebted to all staffs of Sugano and Okabe laboratories, especially to Dr. Asada for supporting him to make the electronic circuits, to Dr. F. Koshiga and Mr. M. Kitagawa for giving him the comfortable atmosphere for the research, to Mr. C.F. Yeh and Mr. Ho Quoc Vu for their aid in the experiments, and to Mr. H. Matsumoto and Mr. T. Akiyama for stimulating the author with the intellectual problems.

REFERENCES

AUTHOR	JOURNAL	SAMPLE	OBJECT	INJECTION/DETRAP	SIGNAL	CONTENTS/CONCLUSIONS
1: Goodman	Phys. Rev. <u>144</u> : 588 (1966)	n (111) 0.002 Ωcm barrier height: $2 \sim 5 \mu\text{SiO}_2$ 1100°C of Al-SiO ₂ 1 μ gold 0.2 cm ²	barrier height of metal - SiO ₂	photo current	Photo current	mean free pass $w = \mu E$ $\mu\tau \sim 10^{-13} \text{ m}^2/\text{V}$
2: Deal Snow Mead	JPCS <u>27</u> : 1873 (1966)	P, n, (111), (100) 750 $\mu\phi$	barrier height of metal - SiO ₂	"	"	barrier work ϕ_b [eV] Mg 3.70 Al 4.20 Ni 4.74 Cu 4.52 Au 4.70 Ag 4.31
3: Nicollian Berglund	JAP <u>41</u> : 3052 (1970)	P, $10^{16} \sim 10^{17} \text{ cm}^{-3}$ 500 ~ 2000 Å	theory of AC-avalanche	avalanche inj.	IDC	ω , F dependence of I_{DC} (theoretical, experimental) details of setup
4: Powell Berglund	JAP <u>42</u> : 4390 (1971)	P, 1 Ωcm , 2230 Å 1100°C dry, ~3000 Å	photo inj.	photo inj.	photo I-V ($I \sim 10^{-8} \text{ A}$) $t_{1/2} < 5.4 \text{ eV}$ bias = +90 V	minute theory of photo I-V eg (7) is important photo I-V changes in time (Fig 5)
5: Nicollian Berglund Schmidt Andrews	JAP <u>42</u> : 5654 (1971)	P, 0.2 Ωcm , 1500 ~ 2500 Å 250 $\mu\phi$, Cu-Au dot 80°C ~ 200°C anneal	water-related: center	avalanche inj.		$\sigma \sim 1.5 \times 10^{-17} \text{ cm}^{-2}$ E _A ~ 0.35 eV (annealed in H ₂ O) emits H when captures electron electro-chemical reaction
6: Thomas Feigl	J. Phys. Chem. <u>76</u> : 2197 (1972)	n, Si: (111) 0.01 Ωcm , 1 μgum wet, 2 x 10 mm	2.1 eV \pm 0.5 trap (by Na ⁺)	photo inj. photo detrap. 60 W deuterium lamp 80° K ~ 300° K, < 10 ⁻⁵ Torr in inert gas	photo Q-V ($\sim 10^{-12} \text{ A}$) sweep λ (6.3 mm/sec) photo I(t),	photo Q-V measurement was difficult $\frac{dI}{I} = 0.6 \times 10^{-14}$; $2.6 \times 10^{15} \text{ cm}^{-2}$ $\frac{X}{L} = 0.62, 0.7$ $dE = 0.5 \text{ eV}$
7: Yun	APL <u>23</u> : 152 (1973); APL <u>25</u> : 340 (1974)	n-Si, 2 Ωcm MNOS	\bar{x} location technique	dV_{FB} & $\int I dt$		$Q = \int I dt$ if the capacitance is constant if there is no conduction current, \bar{x} and η_T are separable
8: Pimarina Feigl	Phys. Rev. <u>B9</u> : 1874 (1974)	photo detrap.	photo detrap.	photo Q-V		minute theory of photo Q-V

AUTHOR	JOURNAL	SAMPLE	OBJECT	INJECTION/DETRAP	SIGNAL	CONTENTS/CONCLUSIONS
9 Dimaria	JAP 45 5454 (1974)	p-Si: 0.001Ωcm (100), ~500Å Al ₂ O ₃ of metal and Al ₂ O ₃	Barrier height:	photo current (~10 ⁻¹² A)	photo current	full setup for photo I-V neglect light interference Y = I _{hw} /ST (photoelectrons/photons)
10 Ning Yu	JAP 45 5373 (1974)	n-dk IGFEF 0.15~2Ωcm 350~1500 Å 2x40mm	electron trap	photo inj. (non-avalanche inj.) 10 ⁻⁴ ~10 ⁻⁹ A/cm ² visible light	$V_T(t)$ $\eta_{eff} = \frac{d(Cox \phi V_T)}{dt} \frac{1}{q}$ $= \sum_i (N_{T_i}) \phi \sigma_i e^{-\sigma_i N_{T_i} x}$	Al, Au, Ni, Mg 4.1 3.7 3.2 2.5 [eV] $\sigma = 3.3 \times 10^{-13} \text{ cm}^2$ $2.4 \times 10^{-19} \text{ cm}^2$
11 Dimaria Kerr	APL 21 505 (1975)	poly-Si	why SiO ₂ on poly-Si; leaky?	dark current photo current (I-V)	dark current photo current (I-V)	barrier height of poly-Si-SiO ₂ = cy-Si-SiO ₂ leakage is due to the roughness of the interface and enhancement of the field
12 Dimaria Annett	APL 26 711 (1975)	MNS, P, n, CVD Si ₃ N ₄ 815°C SiO ₂ ~ 15 Å	barrier height	photo current 2.0~5.5eV 14-eV gate bias by hole injection	photo current 2.0~5.5eV 14-eV gate bias by hole injection	Si Si ₃ N ₄ metal 
13 Annett Dimaria	APL 27 34 (1975)	MNS	dark current	dark current	dark current	dark current dependence on contact metal and insulator thickness
14 Dimaria Feigl Butler	Phys. Rev. B11 5023 (1975)	1~4μm 0.001~5Ωcm [Au, Ni, Al]	2.4eV trap in SiO ₂	photo inj. photo detrap field detrap deuterium lamp	photo I-V (5eV) (< 1A/mm ² ·cm ²) photo Q-V $\frac{I}{T} = nV_T \sigma_z + \sigma_p + nV_T \alpha$	$\sigma_T \sim 10^{-18} \text{ cm}^2$ $\sigma_z \sim 10^{-14} \text{ cm}^2$ table of light intensity X = 0.5 · theory 1% of traps are photo-accessible neglect of detrap $\sigma_{eff} = \sigma_{FB}$
15 Dimaria	JAP 47 4073 (1976)	MOWOS	electron trap	5eV photo emission 115V gate bias at 300°K, air	photo I-V (5eV)	1% of traps are photo-accessible neglect of detrap $\sigma_{eff} = \sigma_{FB}$

AUTHOR	JOURNAL	SAMPLE	OBJECT	INJECTION/DETRAP	SIGNAL	CONTENTS/CONCLUSIONS
16 Ma Yum Dimaria Scoggan	JAP 47 1599 (1976)	MNOS	EB- irradiation		C-V (interface trap) dark current charge-centroid method (μm)	thick films N_{ss} thin films N_{ss} constant
17 Dimaria Aitken Young	JAP 42 2740 (1976)	P-Si, 0.15cm 1500Å dry forming gas 400°C, 20min	Na^+ trap ($\approx 2.4\text{eV}$ trap)	avalanche inj. 500kHz square wave. 77°K $J_{oc} = 10^{-3} \sim 10^{-9} [\text{A}/\text{cm}^2]$	ΔV_{FB} $(= \frac{q\bar{x}}{e\epsilon} Q \exp(-\frac{x}{L}))$ $\tau = \frac{L}{v}$	no field detrapp at 77°K $\sigma = 2 \times 10^{-15}, 2 \times 10^{-19}, 5 \times 10^{-20} [\text{cm}^2]$
18 Aitken Dimaria Young	IE ³ NS-23 1526 (1976)	500 ~ 1000Å dry at 1000°C photo. P. m 2.2cm ava. P 0.1 ~ 0.22cm Al gate 125Å poly Si: gate	EP, Xray induced trap	avalanche inj. photo inj.	photo I-V ΔV_{FB}	Induced positive charge is localized in } 10Å from Si-SiO ₂ interface } 50Å from Al-SiO ₂ interface
19 Feigl Butler Dimaria Kapoor	Thermal & Photostimulated Currents in Insulators (1976)		Review on photo Q-V		photo Q-V	absorption & photolumi. are complex. $W(E, E_i) \propto \int \vec{r}_{if} ^2 g(E_i + E)$
20 Butler Feigl Ota Dimaria	" "	n. P doped-Si (100), ~5.0cm 1μm + Na	Na related trap (wet)	photo inj. photo detrapp (400Å)	ΔV_{FB}	There is a difference of the several orders between doped Na density and electrically active density
21 Aitken Young	JAP 47 1196 (1976)	P, 0.15cm 100Å SiO ₂ dry 400°C, 20min in forming gas	X-ray induced trap	avalanche inj 100 ~ 500 KHz 77°K & 300°K	ΔV_{FB}	5 traps whose σ are ranging $10^{-13} \sim 10^{-19} [\text{cm}^2]$
22 Ning	JAP 42 1079 (1976)	P-ch IGFET (100), 0.15cm 1000Å	hole trap	"	$V_T(t)$ $N_{inj}(t) = C_{ox} \cdot \Delta V_T(t) / q$ $+ \int_0^t J_g(t') / q dt'$	$\eta_{eff} \sim 99\%$ $\sigma = 3.1 \times 10^{-13} [\text{cm}^2]$ $n_T = 1.4 \times 10^{15} [\text{cm}^{-3}]$ neglect of detrapp

AUTHOR	JOURNAL	SAMPLE	OBJECT	INJECTION/DETRAP	SIGNAL	CONTENTS/CONCLUSIONS
23 Jones Embree	JAP 41 5365 (1976)	quartz α-SiO ₂	O-vacancy		photo luminescence	quartz 6.77 (2600Å) 6.2 (2000Å) α-SiO ₂ 4.28 (2900Å) 5.9 (2100Å) signal is due to O-vacancy. because decrease with O ₂ anneal
24 Dimaria Young Ormond	APL 31 680 (1977)	MOWOS	effect of W layer		photo I-V (→x̄)	leakage current } are improved breakdown voltage } by W. Due to uniformization of trap density.
25 Young Dimaria Bojarczuk	JAP 48 3425 (1977)	W implanted (50keV) & evaporated	W in SiO ₂	avalanche inj. Thermal detrapping 275 ~ 310 °C	ΔV _{FB} photo I-V (→x̄)	σ = 4.56 × 10 ⁻¹⁴ ~ 1 × 10 ⁻¹⁴ cm ⁻² (clustering?) -E _T = 0.6 [eV] thermal photo inaccessible
26 Dimaria Weinberg Aitken Young	J. Elec. Mat. 6, 207 (1977)	MOS MOWOS	hole & electron trap	photo inj.	photo I-V (<10 ⁻¹⁰ AT) ΔV _{FB} ~ 10 [V]	Review of photo I-V trap center is equal to W location
27 Dimaria Weinberg Aitken	JAP 48 898 (1977)	P, n Si, 2.8cm (100) ~1000 Å dry Al ~ 100 Å 0.5 × 0.5 mm 400°C, 20 min firing	hole traps in SiO ₂	Ne-discharge (VUV) 20keV Xray by W high field	photo I-V (5eV) C-V	no bulk hole trap in SiO ₂ hole traps are localized near interface (500 Å) theory of photo I-V
28 Young Dimaria Hunter	J. Elec. Mat. 6 569 (1977)	P-Si, 0.1 × 0.25cm 700 Å at 1000°C dry	Al trap in SiO ₂	avalanche inj. 500kHz. square wave	ΔV _{FB}	setup of avalanche inj. anneal ↑ trap comparison between X & LSS theory
29 Ning Osburn Yu	(1977)	n-ch EG-FET SiO ₂ , Si ₃ N ₄	hot electron trapping	avalanche inj.	V _T Transconductance	Si ₃ N ₄ V _{FB} SiO ₂ V _{FB} & Transconductance
30 Ning Osburn Yu	JAP 48 289 (1977)	poly-Si gate EG-FET	Theory of injection	non-avalanche inj.	gate current	Energy electron model Prob. = 2.9 e ^{-λ} λ = .108 Tcmk (0.63/kT) V(d) = 3.1 - pE _{ox} ^{1/2} - αE _{ox}

AUTHOR	JOURNAL	SAMPLE	OBJECT	INJECTION/DETRAP	SIGNAL	CONTENTS/CONCLUSIONS
31 Dimaria	JAP 48 5149 (1978)	P-S 0.1 Ω cm (100) Al \sim 130 \AA N _a dope by NaCl	location of N _a ⁺ ion		photo I-V	• N _a ⁺ is localized near Si-SiO ₂ interface (50 \AA)
32 Dimaria Dekeersmaecker Young	IBM. Res. Rep. #29814 1/24/78 (1978)	Light Activated Storage Device (As or P implanted MOS)				• Write and Erase by light • no damage by avalanche • volume type memory
33 Dimaria	IBM. Res. Rep. #31120 7/21/78 (1978)	Al, P, As, B implanted MOS		avalanche inj. thermal detrapp photo detrapp 77°K \sim 300°K	"	• σ_{ph} is const. on T • no trap by B • no field detrapp (\sim 3 MV/cm) EA P 0.25 eV AS 0.15 eV AL 0.9 eV • thermal detrapp in N ₂ 100-350°C
34 Dekeersmaecker Dimaria Pantelides	IBM. Res. Rep. #30337 4/21/78 (1978)	P-Si (100) 0.1 \sim 0.2 Ω cm 1000°C dry 560 \sim 1430 \AA Al \sim 100 \AA 0.52 mm ²	As, P implanted	avalanche - inj. 50 kHz ramp. photo detrapp λ -scan step by step.	ΔV_{FB} (1 MHz) $\frac{\Delta V_{FB}(0) - \Delta V_{FB}(t)}{\Delta V_{FB}(0)} = \lambda \chi(h\nu)$ $\cdot \Sigma (h\nu)$	• $\sigma_p \sim 3 \times 10^{-17}$, $\sigma_{As} \sim 10^{-15}$ cm ² ET \sim 4 eV
35 Dimaria Young Dekeersmaecker Hunter Serano	JAP 49 5441 (1978)	P-Si (100) 1300 \sim 1400 \AA 0.1 \sim 0.2 Ω cm	B, Al, P, As implanted (5-100 keV)	avalanche inj	photo I-V	• comparison with LSS
36 Dimaria Young Hunter Serano	IBM J. Res. Dev. 22 285 (1978)	"	Al implanted	avalanche inj 500 kHz sig. 4 hours	ΔV_{FB}	• 400 \sim 600 points by computer • $\bar{X} = 0.59$ σ cm ² 1.6 $\times 10^{-15}$ Nt cm ⁻² 1.26 $\times 10^{-16}$ 4.6 $\times 10^{-11}$ 1.40 $\times 10^{-17}$ 1.14 $\times 10^{12}$ 1.26 $\times 10^{18}$ 5 $\times 10^{11}$
37 "	ibid. 289 (1978)	"	"	"	photo I-V	• without Al \rightarrow no trapping • good agreement with \bar{X} and SIMS • certain portion is active trap.

AUTHOR	JOURNAL	SAMPLE	OBJECT	INJECTION/DETRAP	SIGNAL	CONTENTS/CONCLUSIONS
38 Aitken Young Pan	JAP 49 3386 (1978)	P 0.2 Ω cm (100) 440 \AA dry 1000°C	EB 25keV induced trap	avalanche -inj $4 \times 10^{-8} \text{ A}$ at 10^4 sec 77°K, 295°K	ΔV_{FB}	neutral trap can not be annealed by low temp. anneal. trap density decrease at 500°C $\sigma \sim 10^{-15} \sim 10^{-12} \text{ cm}^{-2}$ formula for emission probability hot carrier injection phenomenology
39 Ning	Sol. St. Elec. 21 273 (1978)					
40 Ning	JAP 49 4077 (1978)	n-ch poly-Si gate IGFET (100) 0.5 Ω cm 500 \AA 1000°C HCl or wet oxidation	traps induced by EB deposited Al	non-avalanche inj.		X ray induced by EB produces traps $\sigma \sim 10^{-13} \text{ cm}^{-2}$ positive trap $\sigma \sim 10^{-15} \text{ cm}^{-2}$ neutral trap annealed in forming gas $\sigma_{pos} \propto E_{Dr}^{-1} T^0$ $\sigma_{neu} \propto e^{-kE_{Dr}}$
41 Ning	JAP 49 5997 (1978)	"	forward bias pulsed injection in dark atm.	TSR 77°K \sim 300°K	ΔV_{FB}	peaks 300mV \sim 50mV 90% is shallow level X ray induced trap is deep.
42 Dimaria Young	JAP 50 5826 (1979)	proposal of GI-MIS, SI-MIS				low voltage, high reliability no degradation of Si-SiO ₂ int. electrically "erase" & "write"
43 Dimaria Ephraath Young	JAP 50 4015 (1979)	RIE CF ₄ , O ₂ , Ar	Reactive Ion etching		C-V photo I-V	Traps can be annealed out changing is done by plasma induced photon
44 Weinberg Young Dimaria Rubloff	JAP 50 5757 (1979)	P, n-Si (100) 0.1 \sim 0.2 Ω cm (0.50 \AA , 1.25 mm ϕ) Al \sim 150 \AA	water effect on MOS	avalanche inj. photo inj. (10eV)	ΔV_{FB} $\Delta V_{FB}(t)$, $\Delta V_{FB}(\lambda)$ photo I-V	avalanche electron hole VUV
45 Ning	IE ³ ED-26 546 (1979)		Voltage Limitation in VLSI			$V_{DS} - V_{GS} \leq 4.75 \text{ V}$ (25°C) $\leq 3.5 \text{ V}$ (77°K)

AUTHOR	JOURNAL	METHOD	MATERIAL	RESULTS	FIT WITH EXP.
46 Schneider Fowler	Phys. Rev. Let 25, 425 (1976)	mixed - basis method	β - cristobalite valence, conduction band	Band structure	○
47 Pantelides Harrison	Phys. Rev. B13 2667 (1976)	linear combination of bond orbitals	β - cristobalite, GeO ₂ valence band	Band structure DOS	○ UV, UPS XPS, XES
48 Ciraci Batra	Phys. Rev. B15, 4923 (1977) The Phys. of SiO ₂ & its interface 65	extended tight- binding method basis = GTO, STO, sp ³	β - cristobalite α - quartz valence, conduction band	Band structure DOS E _g = 9.8 eV	○ UPS XPS XES
49 Chelikowsky Schlüiter	Phys. Rev. B15 4020 (1977)	self-consistent pseudopotential	α - quartz valence, conduction band	Band structure DOS charge distribution E _g = 9.2 eV indirect	○ excellent agreement
50 Calabrese Fowler	Phys. Rev. B18 2888 (1978)	mixed - basis method	α - quartz valence, conduction band	Band structure DOS similar to β - cristobalite	○
51 Calabrese Fowler Schneider	The Phys. of SiO ₂ & its interface 70 (1978)	tight - binding fit	α - quartz β - cristobalite α - trinitride valence, conduction band	Band structure DOS	
52 Nucho Madhukar	ibid. 60 (1978)	simple tight- binding	α - quartz valence, conduction band	Band structure DOS	○
53 Chadi Laughlin Joannopoulos	ibid. 55 (1978)	"	α - quartz β - cristobalite Bethe - lattice	Band structure (α - quartz) DOS	

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APPENDIX A
INDEX FOR PROGRAMS

PROGRAM NAME	PAGE	CONTENTS
SBFIT	Al-1	Calculate silicon energy eigen values and their sensitivities to tight-binding parameters, and store them in file 20.
DSBFIT	Al-7	Data for SBFIT.
SBFIT3	Al-8	Calculate better tight-binding parameters for Si, using eigenvalues and sensitivity matrix given by SBFIT.
DFIT	Al-9	Data for SBFIT3. Offering fitting points.
BAND	Al-10	Subprograms for calculating band structure of SiO ₂ , and electronic structures of SiO ₂ Bethe-lattice, which must be compiled before following all programs.
BETA	Al-25	Calculate energy band structure of bete-crist- obalite.
ALPHA	Al-35	Calculate energy band structure of alpha-quartz.
DOS	Al-44	Calculate density of states for alpha-quartz.
SURF	Al-45	Calculate Green's functions for semi-infinite Si free surface for a certain k-vector Output χ_{ss}^s to file 21.
SURF12	Al-53	Calculate Green's functions for Si slabs of finite thickness.
CBLM3	Al-55	Calculate local density of states for amorphous Si.
GEE	Al-60	Calculate Green's functions for SiO ₂ Bethe-la-

PROGRAM NAME	PAGE	CONTENTS
		tttice. Output \dot{q}_{BB}^B to file 22.
DATAO	A1-74	Data for GEE.
GEEO	A1-75	Connect oxygen atom to SiO ₂ Bethe-lattice. Input \dot{q}_{BB}^B from file 22. Output \dot{q}_{YY}^Y to file 23. And calculate Si-Si bond level and impurity levels in amorphous SiO ₂ . In addition, calculate DOS of bulk a-SiO ₂ . Output \dot{q}_{OO}^O and \dot{q}_{SS}^O to file 28 and 29.
DGEEO	A1-84	Data for GEEO.
PERFIN	A1-85	Solve perfect interface problem. Input \tilde{q}_{SS}^S and \dot{q}_{YY}^Y from file 21 and 23. Output \dot{q}_{PP}^P to file 24.
DPERF	A1-89	Data for PERFIN.
DANGLE	A1-90	Calculate dangling-bond level. Input \dot{q}_{PP}^P and \dot{q}_{YY}^Y from file 24 and 23. Output \dot{q}_{SS}^P to file 26.
DDANG	A1-92	Data for DANGLE.
OVAC	A1-93	Calculate Si-Si bond level at the Si-SiO interface. Input \dot{q}_{SS}^P and \dot{q}_{BB}^B from file 26 and 22. Output \dot{q}_{VV}^V to file 27.
DOVAC	A1-96	Data for OVAC.
OHCL	A1-97	Calculate impurity problem at the Si-SiO ₂ interface. Input \dot{q}_{BB}^B and \dot{q}_{SS}^P from file 22 and 26. Output \dot{q}^W .
DOHCL3	A1-104	Data for OHCL.
SIGEEO	A1-105	Calculate energy level of stretched Si-O bond

PROGRAM NAME	PAGE	CONTENTS
		at the Si-SiO ₂ interface. Input \dot{q}_{Yr}^Y and \dot{q}_{SS}^D from file 23 and 26. Output \dot{q}_{SS}^{STR} .
DSIG	A1-107	Data for SIGEEO.
WEAK	A1-108	Calculate energy levels for weak Si-O interaction at the Si-SiO ₂ interface. Input \dot{q}_{SS}^D and \dot{q}_{OO}^O from file 26 and 28.
DWEAK	A1-111	Data for WEAK.
WEAKS	A1-112	Calculate energy levels for weak Si-Si interaction at the Si-SiO ₂ interface. Input \dot{q}_{SS}^D and \dot{q}_{SS}^O from file 26 and 29.
DWEAKS	A1-114	Data for WEAKS.

SER SBFIT

JF A1402.S.FORT

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00000100      FUNCTION HH(ANK,LCI,MCI,ANL,LCJ,R,NANK,NANL)
00000200      INTEGER ANK,ANL
00000300      EQUIVALENCE (P(1),SESS),(P(2),SESP),
00000400      *                (P(3),SVSS),(P(4),SVSP),(P(5),SVPPS),(P(6),SVPPP),
00000500      *                (P(7),SUSS),(P(8),SUSP),(P(9),SUPPS),(P(10),SUPPP)
00000600      COMMON /COMP/P(10)
00000700      ANK=ANK;ANL=ANL;NANK=NANK;NANL=NANL
00000800      SVPS=SVSP ;SUPS=SUSP
00000900 C-----SILICON-----
00001000      200 CONTINUE
00001100      IF(ABS(R).LT.0.01) GO TO 220
00001200      IF(ABS(R).GT.5.) GO TO 210
00001300 C-----1ST NEAREAT-----
00001400      400 CONTINUE
00001500      EXPBR=1.
00001600      IF(LCI.EQ.0.AND.LCJ.EQ.0) GO TO 201
00001700      IF(LCI.EQ.0.AND.LCJ.EQ.1) GO TO 202
00001800      IF(LCI.EQ.1.AND.LCJ.EQ.0) GO TO 203
00001900      IF(MCI.EQ.0) GO TO 204
00002000      IF(MCI.EQ.1) GO TO 205
00002100      STOP 0008
00002200      201 HH=EXPBR*SVSS ;GO TO 1
00002300      202 HH=EXPBR*SVSP ;GO TO 1
00002400      203 HH=EXPBR*(-SVPS) ;GO TO 1
00002500      204 HH=EXPBR*SVPPS ;GO TO 1
00002600      205 HH=EXPBR*SVPPP ;GO TO 1
00002700 C-----2ND NEAREST-----
00002800      210 CONTINUE
00002900      IF(LCI.EQ.0.AND.LCJ.EQ.0) GO TO 211
00003000      IF(LCI.EQ.0.AND.LCJ.EQ.1) GO TO 212
00003100      IF(LCI.EQ.1.AND.LCJ.EQ.0) GO TO 213
00003200      IF(MCI.EQ.0) GO TO 214
00003300      IF(MCI.EQ.1) GO TO 215
00003400      STOP 0009
00003500      211 HH=SUSS ;GO TO 1
00003600      212 HH=SUSP ;GO TO 1
00003700      213 HH=-SUPS ;GO TO 1
00003800      214 HH=SUPPS ;GO TO 1
00003900      215 HH=SUPPP ;GO TO 1
00004000      220 IF(LCI.EQ.0) GO TO 221
00004100      IF(LCI.EQ.1) GO TO 222
00004200      STOP 0013
00004300      221 HH=SESS ;GO TO 1
00004400      222 HH=SESP ;GO TO 1
00004500      1 CONTINUE
00004600 C      WRITE(6,101) HH
00004700 C 101 FORMAT(' HH=',F10.3)
00004800      RETURN ;END
00004900      PROGRAM SBFIT
00005000      COMMON/COM03/ V(40),W(20,40)
00005100      COMMON/VECK/VECK(3)
00005200      COMMON/ARRAYS/S(40,40),Y(9,5,203),Z(17,45)
00005300      COMMON/NATOMS/ NATOMS,N,NK
00005400      COMMON/INFO/ AN(40),NOUT
00005500      COMMON/INFO1/CZ(40),U(80),ULIM(40),LLIM(40),ULK,ULL,ANL,ANK
00005600      COMMON /CON/CSSSS,CSSSX,CSSXX,COSS,COOSX,COOXX,CSS,CSX,CXS,CX)
00005700      COMMON/VOIP/ VOIP(4,10),AZETA(4,10),CONST,OM1,OM2,VP(4,10),
00005800      *                AZP(4,10)

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00005900 COMMON /POS/POS(3,10),BL,AU,TH,PAI,ROOT2,ROOT3
00006000 COMMON /H/H(40,40)
00006100 COMMON /NC/NC(13),LC(10),MC(10)
00006200 COMMON /COM01/ ZS(40,40),ZH(40,40)
00006300 COMMON /COM02/ PM(40,40),RM(40,40)
00006400 COMMON /NAN/NAN(40)
00006500 COMMON /COMSF/FAC(12,40),OLDEP(6),IP1
00006600 INTEGER AN,ULIM,ULK,ULL,CZ,U,ANL,ANK
00006700 REAL*8 V
00006800 COMPLEX*16 ZS,ZH,PM,RM
00006900 COMPLEX*8 ZTHETA,ZEXP
00007000 C DIMENSION SD(2,2,12),ST(13),DELV(8),SROT(12,12)
00007100 DIMENSION F(3,12),HD(16,16,12)
00007200 DIMENSION AKM(3,7),ROT(12,12),ROTD(4,4),ROTD1(4,4)
00007300 *, HRJT(12,12),RT(13)
00007400 DATA ROT/144*0./
00007500 DATA AKM/5*0.,0.6122,3*0.3061,0.,0.,0.4592,
00007510 * 2*0.459,0.,2*0.,0.48,2*0.,0.5/
00007600 DATA AU/.529167/,PAI/3.141592/,BL/2.35/,A/5.43/
00007700 DATA AN/14,14,14,14/,NATOMS/4/
00007800 DATA F/0.,1.,1.,1.,0.,1.,1.,1.,0.,
00007900 * 0.,-1.,-1.,-1.,0.,-1.,-1.,-1.,0.,
00008000 * 0.,1.,-1.,-1.,0.,1.,1.,-1.,0.,
00008100 * 0.,-1.,1.,1.,0.,-1.,-1.,1.,0./
00008200 DATA ROTD/1.,1.,1.,1.,1.,1.,-1.,-1.,
00008300 * 1.,-1.,1.,-1.,1.,-1.,-1.,1./
00008400 DATA TH/109.5/
00008500 DATA ROTD1/1.,-1.,-1.,-1.,1.,-1.,1.,1.,
00008600 * 1.,1.,-1.,1.,1.,1.,1.,-1./
00008700 DATA NAN/5,5,5,5/
00008800 REAL*8 WW(40,7)
00008900 DIMENSION DP(10),LW(40),OLDV(8,7)
00009000 COMMON /COMP/P(10)
00009100 C-----CJ NEW PARAM NNN----
00009200 C DATA P/-4.2,1.7,-2.075,2.7583,3.129,-0.9212,4*0./
00009300 C-----PP PARAM----
00009400 C DATA P/-4.203,0.187,-2.08,2.12,2.32,-0.52,2*0.,0.58,-0.1/
00009500 C-----CJ 2 PARAM-----
00009600 C DATA P/-4.4,1.8,-2.03,2.546,4.188,-1.452,3*0.,-0.365/
00009610 C-----PRESENT-----
00009620 C DATA P/-5.22,0.83,-2.05,2.09,2.33,-0.54,0.084,-0.29,.47,-.13/
00009630 C-----TEST1-----
00009640 C DATA P/-5.658,1.178,-2.053,2.087,2.426,-.647,.106,-.539,.379,-
00009650 C DIMENSION TESTD(11)
00009660 C DATA TESTD/.509,.043,-.016,.056,-.156,.082,-.021,.18,.064,.0/
00009700 DATA DP/6*0.1,4*0.01/
00009800 EQUIVALENCE (R1,RT(1))
00009900 COMMON /R/R1,R2,R3,R4,R5,R6,R7,R8,R9,R10,R11,R12,R13
00010000 * ,AK1,AK2
00010010 C-----PARAM FROM FILE 30-----
00010020 C READ(30) (P(I),I=1,10)
00010030 READ(5,301) (P(I),I=1,10)
00010040 301 FORMAT(F10.0)
00010100 DO 21 J=1,12
00010200 DO 21 I=1,3
00010300 21 F(I,J)=F(I,J)*A/2./AU
00010400 C-----MAKE POS-----
00010500 DO 30 I=1,3
00010600 POS(J,1)=0. ; POS(I,2)=A/4./AU
00010700 30 CONTINUE
00010800 DO 1000 IPARAM=1,11
00010900 IP1=IPARAM-1 ; IP2=IPARAM-2
00011000 IF(IP1.EQ.0) GO TO 1001
00011100 IF(IP1.EQ.1) GO TO 1002
00011200 P(IP1)=P(IP1)+DP(IP1)
00011300 P(IP2)=P(IP2)-DP(IP2)

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00011400      GO TO 1001
00011500 1002  P(1)=P(1)+DP(1)
00011600      GO TO 1001
00011700 1001  CONTINUE
00011800      CALL RWRIT(P,'PARAM ',10,10)
00011900 C-----BULK PROBLEM-----
00012000 C-----MAKE SD AND HS-----
00012100      DO 40 IF=1,12
00012200      DO 41 I=1,3
00012300      POS(I,3)=F(I,IF)
00012400      POS(I,4)=F(I,IF)+A/4./AU
00012500      41 CONTINUE
00012600      DO 46 J=1,16
00012700      DO 46 I=1,16
00012800      46 S(I,J)=0.
00012900      CALL INTGRL
00013000 C      CALL RWRITE(POS,'POS ',3,10,10)
00013100 C      CALL RWRITE(S,'S ',40,16,8)
00013200      DO 408 I=1,16
00013300      DO 408 J=1,16
00013400      408 HD(I,J,IF)=S(I,J)
00013500      40 CONTINUE
00013600      DO 43 I=1,16
00013700      DO 43 J=1,16
00013800      HD(J,I,3)=HD(I,J,3)
00013900      43 S(J,I)=S(I,J)
00014000      DO 44 J=1,16
00014100      DO 44 I=1,16
00014200      44 H(I,J)=HD(I,J,3)
00014300 C      CALL RWRITE(H,'H ',40,16,8)
00014400 C-----SCANNING OF K VECTOR-----
00014500      DO 2 MODE=1,7
00014510      IF(IP1.NE.0.AND.MODE.GE.5) GO TO 2
00014600      DO 181 I=1,3
00014700      181 VECK(I)=AKM(I,MODE)
00014800      DO 50 J=1,8
00014900      DO 50 I=1,8
00015000      ZH(I,J)=HD(I,J,3)
00015100      DO 50 IF=1,12
00015200      ZTHETA=0.
00015300      DO 51 K=1,3
00015400      51 ZTHETA=ZTHETA+VECK(K)*F(K,IF)*(0.,1.)
00015500      ZEXP=EXP(ZTHETA)
00015600      ZH(I,J)=ZH(I,J)+HD(I,J+8,IF)*ZEXP
00015700      50 CONTINUE
00015800      CALL DEIGCH(ZH,8,40,-8,8,1.E-15,WW,LW,V,ZS)
00015900      WRITE(6,12) (VECK(I),I=1,3),(V(I),I=1,8)
00016000      12 FORMAT(' EIGENVALUES AT NK=',3F10.3,' ARE',8F9.4)
00016100      IF(IP1.EQ.0) GO TO 1003
00016200      DO 1004 I=1,8
00016300      1004 FAC(IP1,8*(MODE-1)+I)=V(I)-OLDV(I,MODE)
00016400      GO TO 2
00016500      1003 DO 1005 I=1,8
00016600      1005 OLDV(I,MODE)=V(I)
00016700      2 CONTINUE
00016800 C-----MAKE ROT-----
00016900      DO 60 J=1,4
00017000      DO 60 I=1,4
00017100      ROT(I,J)=.5*ROTD(I,J)
00017200      ROT(I+4,J+4)=.5*ROTD1(I,J)
00017300      60 ROT(I+8,J+8)=.5*ROTD(I,J)
00017400      DO 63 J=1,12
00017500      DO 63 I=1,12
00017600      HROT(I,J)=0.
00017700      DO 63 K=1,12
00017800      DO 63 L=1,12

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00017900      HROT(I,J)=HROT(I,J)+ROT(L,I)*H(L,K)*ROT(K,J)
00018000      63 CONTINUE
00018100      RT(1)=HROT(1,1)
00018200      RT(2)=HROT(1,2)
00018300      RT(3)=HROT(1,5)
00018400      RT(4)=HROT(1,8)
00018500      RT(5)=HROT(2,8)
00018600      RT(6)=HROT(2,6)
00018700      RT(7)=HROT(1,9)
00018800      RT(8)=HROT(2,10)
00018900      RT(9)=HROT(1,12)
00019000      RT(10)=HROT(1,10)
00019100      RT(11)=HROT(4,10)
00019200      RT(12)=HROT(2,11)
00019300      RT(13)=HROT(4,9)
00019400      CALL RWRIT(RT,'RT      ',13,13)
00019500      C      CALL RWRITE(HROT,'HROT ',12,12,8)
00019600      CALL SBSURF
00019700      1000 CONTINUE
00019800      C-----OUT FILE 20-----
00019810      P(10)=P(10)-DP(10)
00019900      DO 1006 MODE=1,4
00020000      DO 1006 I=1,8
00020100      1006 FAC(11,8*(MODE-1)+I)=OLDV(I,MODE)
00020200      DO 1007 MODE=1,3
00020300      1007 FAC(11,MODE+32)=OLDEP(MODE)
00020400      DO 1008 IP=1,10
00020500      DO 1008 I=1,40
00020600      1008 FAC(IP,I)=FAC(IP,I)/DP(IP)
00020700      DO 1010 I=1,10
00020800      1010 FAC(I,40)=P(I)
00020900      WRITE(20)((FAC(I,J),J=1,40),I=1,12)
00021000      CALL RMAT(FAC,'FAC      ',12,40,12,8)
00021100      STOP ;END
00021200      SUBROUTINE SBSURF
00021300      IMPLICIT COMPLEX*8 (G,V,Z)
00021400      COMPLEX*8 H(8,16),V(8,8)
00021500      COMPLEX*8 G(8,8),CDET,CW(8)
00021600      COMPLEX*8 ZP(8,8)
00021700      COMPLEX*8 GST(8,8,30),ZQ(8,8)
00021800      COMMON /R/R1,R2,R3,R4,R5,R6,R7,R8,R9,R10,R11,R12,R13
00021900      *      ,AK1,AK2
00022000      COMMON /COMH/H
00022100      COMMON /H0HDF/ H0,HD,F
00022200      DIMENSION IP(8)
00022300      EQUIVALENCE (H(1,9),V(1,1))
00022400      DIMENSION HD(8,16,6),F(3,6),H0(8,16)
00022500      COMMON /COMSF/FAC(12,40),OLDEP(6),IP1
00022600      DIMENSION AKM(2,3),RGST(30),EST(30)
00022700      DATA AKM/2*0.,2*-3.1416,2.094,4.189/
00022800      DATA V/64*0./
00022900      DATA F/-0.6124,0.3536,0.,-0.6124,-0.3536,0.,
00023000      *      0.,0.7071,0.,0.,-0.7071,0.,
00023100      *      0.6124,-0.3536,0.,0.6124,0.3536,0./
00023200      DATA H0/123*0./,HD/768*0./
00023300      AG1=1. ;EPSG=0.05
00023400      EI=-0.9 ;EF=1.6;DE=0.1 ;DELTA=0.04 ;EPSG=0.05
00023500      VN=(EF-EI+0.01)/DE ;NN=NN+1
00023600      ICONT=0 ;BNDCT=0.33 ;BNDCT=BNDCT/0.529
00023700      ISC=0
00023800      C-----SCANNING OF K VECTOR-----
00023900      DO 1 MODE=1,3
00024000      AK1=AKM(1,MODE) ;AK2=AKM(2,MODE)
00024100      C-----SETTING UP OF HAMILTONIAN-----
00024200      CALL SETH11
00024300      C      CALL CWRITE(H,'H      ',8,16,8)

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00024400 C-----RESETTING OF G-----
00024500     JO 30 I=1,8
00024600     JO 30 J=1,8
00024700     30 G(J,I)=0.
00024800 C-----SCANNING OF ENERGY-----
00024900     E=EI-DE ;NUME=0
00025000 C-----CHANGE ENERGY-----
00025100     40 NUME=NUME+1
00025200     E=E+DE
00025300     IF(E.GT.EF+0.1*DE) GO TO 2
00025400     ZE=E+(0.,1.)*DELTA
00025500     I=0 ;IN=0 ;ISW=0
00025600     50 I=N+1
00025700 C-----CALCULATION OF NEW G-----
00025800     JO 51 I=1,8
00025900     JO 51 J=1,8
00026000     ZP(I,J)=0.
00026100     JO 51 L=1,8
00026200     51 ZP(I,J)=ZP(I,J)+V(I,L)*G(L,J)
00026300     JO 52 I=1,8
00026400     JO 52 J=1,8
00026500     ZQ(I,J)=-H(I,J)
00026600     JO 52 L=1,8
00026700     52 ZQ(I,J)=ZQ(I,J)-ZP(I,L)*CONJG(V(J,L))
00026800     JO 53 I=1,8
00026900     53 ZQ(I,I)=ZQ(I,I)+ZE
00027000     CALL CINV(ZQ,8,0,8,8,1.D-14,CDET,CW,IP,NSTOP)
00027100 C     WRITE(6,205) N,EPSC,G(1,1),G(4,4),G(5,5),G(8,8),IN,ISW
00027200 C 205 FORMAT(1H ,I4,9F8.3,2I2)
00027300 C-----CONVERGENCE CHECK-----
00027400     C1=ABS(G(1,1)-ZQ(1,1))/(ABS(ZQ(1,1))+0.001)
00027500     C2=ABS(G(4,4)-ZQ(4,4))/(ABS(ZQ(4,4))+0.001)
00027600     C3=ABS(G(5,5)-ZQ(5,5))/(ABS(ZQ(5,5))+0.001)
00027700     C4=ABS(G(8,8)-ZQ(8,8))/(ABS(ZQ(8,8))+0.001)
00027800     EPSC=C1+C2+C3+C4
00027900     JO 230 J=1,8
00028000     JO 230 I=1,8
00028100     230 G(I,J)=ZQ(I,J)
00028200     IF(ICONT.EQ.1.AND.ISC.EQ.1) GO TO 303
00028300     IF(EPSC.GT.EPSG) GO TO 203
00028400     GO TO 204
00028500 C-----NOT YET CONVERGED-----
00028600     203 AG2=ABS(G(1,1))+ABS(G(2,2))
00028700     IF(N.LT.3) GO TO 240
00028800     IF((AG2-AG1)*(AG1-AG0).GT.0.) GO TO 241
00028900 C-----MAX OR MIN-----
00029000     IF(IN.GE.29) GO TO 244
00029100     GO TO (243,244) ,ISW
00029200     243 ISW=ISW+1
00029300 C-----BEFORE AVERAGING-----
00029400     241 IF(ISW.EQ.0) GO TO 240
00029500 C-----IN AVERAGING-----
00029600     IN=IN+1
00029700 C-----STORAGE-----
00029800     JO 245 I=1,8
00029900     JO 245 J=1,8
00030000     245 GST(J,I,IN)=G(J,I)
00030100     GO TO 240
00030200 C-----AVERAGE AND CHANGE-----
00030300     244 JO 247 I=1,8
00030400     JO 247 J=1,8
00030500     G(J,I)=0.
00030600     JO 248 K=1,IN
00030700     248 G(J,I)=G(J,I)+GST(J,I,K)
00030800     247 G(J,I)=G(J,I)/IN
00030900     ISW=0 ;IN=0

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00031000 240 150=AG1 ;AG1=AG2
00031100      GO TO 50
00031200 C-----CONVERGED-----
00031300 204 CONTINUE
00031400 C      CALL CWRITE(G,'G      ',8,8,8)
00031500      IF(ICONT.EQ.0) GO TO 302
00031600 C      DO 301 J=1,4
00031700 C      DO 301 I=1,4
00031800 C      H(I,J+8)=H(I,J+8)*EXP2
00031900 C      H(I+4,J+12)=H(I+4,J+12)*EXP2
00032000 C 301 H(I+4,J+8)=H(I+4,J+8)*EXP1
00032100 C      ISC=1 ;GO TO 50
00032200 C 303 CONTINUE
00032300 C      ISC=0
00032400 C      DO 306 J=1,4
00032500 C      DO 306 I=1,4
00032600 C      H(I,J+8)=H(I,J+8)/EXP2
00032700 C      H(I+4,J+12)=H(I+4,J+12)/EXP2
00032800 C 306 H(I+4,J+8)=H(I+4,J+8)/EXP1
00032900 C 302 CONTINUE
00033000 C      WRITE(6,202) N,NUME,E,EPSC,G(1,1),G(4,4),G(5,5),G(8,8)
00033100 C      CALL CWRITE(G,'G      ',8,8,8)
00033200 C 202 FORMAT(1H ,2I3,F7.2,F8.3,8F7.3)
00033300      RGST(NUME)=-AIMAG(G(1,1))
00033400      EST(NUME)=E
00033500      GO TO 40
00033600      2 CONTINUE
00033700      PEAK=0.
00033800      DO 63 NUME=1,NN
00033900      IF(RGST(NUME).LE.PEAK) GO TO 63
00034000      PEAK=RGST(NUME)
00034100      IE=NUME
00034200      63 CONTINUE
00034300      IF(RGST(IE-1)-RGST(IE+1)) 64,65,65
00034400      64 Y1=RGST(IE) ;Y2=RGST(IE+1)
00034500      E1=EST(IE) ;E2=EST(IE+1)
00034600      GO TO 66
00034700      65 Y1=RGST(IE-1) ;Y2=RGST(IE)
00034800      E1=EST(IE-1) ;E2=EST(IE)
00034900      66 EPEAK=((Y1*E1-Y2*E2)
00035000      *      +SQRT(Y1*Y2*(E1-E2)**2-DELTA**2*(Y1-Y2)**2))/(Y1-Y2)
00035100      IF(IP1.EQ.0) GO TO 67
00035200      FAC(IP1,MODE+32)=EPEAK-OLDEP(MODE)
00035300      GO TO 68
00035400      67 OLDEP(MODE)=EPEAK
00035410      68 CONTINUE
00035500      WRITE(6,69) AK1,AK2,EPEAK,MODE
00035600      69 FORMAT(1H ,AK1,AK2,EPEAK,MODE=',3F8.4,I5)
00035800      1 CONTINUE
00035900      RETURN ;END

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BER SBFIT JF A1402.S.FORT LIST END

BER DSBFIT JF A1402.S.FORT

00000100 -5.29
00000200 1.049
00000300 -2.144
00000400 2.09
00000500 2.346
00000600 -0.588
00000700 0.1233
00000800 -0.366
00000900 0.435
00001000 -0.1533

BER DSBFIT JF A1402.S.FORT LIST END

SER SBFIT3

JF A1402.S.FORT

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00000100 PROGRAM SBFIT3
00000200 IMPLICIT REAL*8(A-H,J-Y)
00000300 REAL*4 FAC(12,40),RP1(10)
00000400 DIMENSION ET(25),IET(25),W(25),AA(12,12),F(40,12),
00000500 * P0(10),P1(10),DELE0(25),DELE1(25),DPO(10),
00000600 * E1(25),NANS(12)
00000700 C-----LSUBPD (F4DLESW1,F4DLINS1)-----
00000800 C-----FETCH FAC FROM FILE 20-----
00000900 READ(20) ((FAC(I,J),J=1,40),I=1,12)
00001000 DO 10 I=1,12
00001100 DO 10 J=1,40
00001200 10 F(J,I)=FAC(I,J)
00001300 CALL RMAT(FAC,'FAC ',12,40,12,8)
00001400 DO 11 I=1,10
00001500 11 P0(I)=F(40,I)
00001600 C-----READ-IN IET,ET,W-----
00001700 READ(5,100) N
00001800 100 FORMAT(I2)
00001900 DO 20 I=1,N
00002000 READ(5,101) IET(I),ET(I),W(I)
00002100 101 FORMAT(I2,2E10.0)
00002200 20 CONTINUE
00002300 C-----CHANGING ORDER----
00002400 DO 30 I=1,N
00002500 DO 30 J=1,12
00002600 30 F(I,J)=F(IET(I),J)
00002700 C-----CALCULATE DELE0-----
00002800 DO 31 I=1,N
00002900 31 DELE0(I)=ET(I)-F(I,11)
00003000 C-----SOLVE-----
00003100 CALL DLESW1(F,N,10,40,12,DELE0,W,AA,NANS,DPO,NSTOP)
00003200 WRITE(6,220) NSTOP
00003300 220 FORMAT(' STOP=',I2)
00003400 C-----CALCULATE NEW PARAMETERS-----
00003500 DO 32 I=1,10
00003600 32 P1(I)=P0(I)+DPO(I)
00003700 CALL DWRT(P1,'NEWP ',10,10)
00003800 C-----EVALUATION OF NEW PARAMETERS-----
00003900 DO 33 I=1,N
00004000 E1(I)=F(I,11)
00004100 DO 34 J=1,10
00004200 34 E1(I)=E1(I)+F(I,J)*DPO(J)
00004300 33 DELE1(I)=ET(I)-E1(I)
00004400 C-----OUTPUT-----
00004500 WRITE(6,103)
00004600 103 FORMAT(1H0,' I IET ET W E0',
00004700 * ' DELE0 E1 DELE1')
00004800 DO 40 I=1,N
00004900 40 WRITE(6,102) I,IET(I),ET(I),W(I),F(I,11),DELE0(I),E1(I),DELE1(I)
00005000 102 FORMAT(1H ,2I3,3F10.4)
00005100 C-----OUT FILE ON 30-----
00005200 DO 41 I=1,10
00005300 41 RP1(I)=P1(I)
00005310 C RP1(1)=RP1(1)-E1(2) ; RP1(2)=RP1(2)-E1(2)
00005400 WRITE(30) (RP1(I),I=1,10)
00005500 STOP ;END

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SER SBFIT3 JF A1402.S.FORT LIST END

PER DFIT JF A1402.S.FORT

0000100	16		
0000200	1	-12.5	1.
0000300	2	0.	10.
0000400	5	3.5	1.
0000500	8	4.0	1.
0000600	9	-8.7	1.
0000700	11	-3.3	1.
0000800	13	1.3	1.
0000900	17	-10.5	1.
0001000	18	-7.7	1.
0001100	19	-1.2	1.
0001200	21	1.6	1.
0001300	23	4.0	1.
0001400	29	1.12	10.
0001500	33	0.7	10.
0001600	34	0.2	1.
0001700	35	0.7	10.

PER DFIT JF A1402.S.FORT LIST END

SER BAND

JF A1402.S.FORT

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0000100      SUBROUTINE COEFFT
0000200      IMPLICIT REAL*4(A-H,O-Z)
0000300      COMMON/ARRAYS/S(40,40),Y(9135),Z( 765)
0000400      DO 1 I=1,9135
0000500      1  Y(I)=0.0D0
0000600      DO 2 I=1,765
0000700      2  Z(I)=0.0D0
0000800      C-----LOAD NON-ZERO Y COEFFICIENTS
0000900      Y(7039)= 64.D0
0001000      Y(7040)= 64.D0
0001100      Y(7049)= -64.D0
0001200      Y(7032)= -128.D0
0001300      Y(7041)= -64.D0
0001400      Y(7033)= -128.D0
0001500      Y(7042)= 128.D0
0001600      Y(7025)= 64.D0
0001700      Y(7034)= 128.D0
0001800      Y(7026)= 64.D0
0001900      Y(7035)= -64.D0
0002000      Y(7027)= -64.D0
0002100      Y(6904)= -96.D0
0002200      Y(6913)= 32.D0
0002300      Y(6896)= -192.D0
0002400      Y(6905)= 192.D0
0002500      Y(6906)= 288.D0
0002600      Y(6915)= -96.D0
0002700      Y(6889)= 192.D0
0002800      Y(6907)= -192.D0
0002900      Y(6890)= 96.D0
0003000      Y(6899)= -288.D0
0003100      Y(6891)= -192.D0
0003200      Y(6900)= 192.D0
0003300      Y(6892)= -32.D0
0003400      Y(6901)= 96.D0
0003500      Y(2854)= -16.D0
0003600      Y(2863)= 16.D0
0003700      Y(2847)= 32.D0
0003800      Y(2856)= -16.D0
0003900      Y(2865)= -16.D0
0004000      Y(2840)= -16.D0
0004100      Y(2849)= -16.D0
0004200      Y(2858)= 32.D0
0004300      Y(2842)= 16.D0
0004400      Y(2851)= -16.D0
0004500      Y(2710)= 48.D0
0004600      Y(2719)= -48.D0
0004700      Y(2711)= 48.D0
0004800      Y(2720)= -96.D0
0004900      Y(2729)= 48.D0
0005000      Y(2703)= -48.D0
0005100      Y(2712)= -48.D0
0005200      Y(2721)= 96.D0
0005300      Y(2704)= -48.D0
0005400      Y(2713)= 48.D0
0005500      Y(2722)= 48.D0
0005600      Y(2731)= -48.D0
0005700      Y(2705)= 96.D0
0005800      Y(2714)= -48.D0

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00005900	Y(2723)=	-48.D0
00006000	Y(2706)=	48.D0
00006100	Y(2715)=	-96.D0
00006200	Y(2724)=	48.D0
00006300	Y(2707)=	-48.D0
00006400	Y(2716)=	48.D0
00006500	Y(5329)=	64.D0
00006600	Y(5322)=	-128.D0
00006700	Y(5340)=	-64.D0
00006800	Y(5315)=	64.D0
00006900	Y(5333)=	128.D0
00007000	Y(5326)=	-64.D0
00007100	Y(5185)=	-96.D0
00007200	Y(5194)=	32.D0
00007300	Y(5186)=	-96.D0
00007400	Y(5195)=	64.D0
00007500	Y(5204)=	32.D0
00007600	Y(5178)=	96.D0
00007700	Y(5187)=	32.D0
00007800	Y(5196)=	64.D0
00007900	Y(5179)=	96.D0
00008000	Y(5188)=	-32.D0
00008100	Y(5197)=	32.D0
00008200	Y(5206)=	-96.D0
00008300	Y(5180)=	-64.D0
00008400	Y(5189)=	-32.D0
00008500	Y(5198)=	-96.D0
00008600	Y(5181)=	-32.D0
00008700	Y(5190)=	-64.D0
00008800	Y(5199)=	96.D0
00008900	Y(5182)=	-32.D0
00009000	Y(5191)=	96.D0
00009100	Y(4375)=	-144.D0
00009200	Y(4384)=	96.D0
00009300	Y(4393)=	-16.D0
00009400	Y(4368)=	144.D0
00009500	Y(4386)=	-48.D0
00009600	Y(4395)=	96.D0
00009700	Y(4370)=	-96.D0
00009800	Y(4379)=	48.D0
00009900	Y(4397)=	-144.D0
00010000	Y(4372)=	16.D0
00010100	Y(4381)=	-96.D0
00010200	Y(4390)=	144.D0
00010300	Y(1900)=	144.D0
00010400	Y(1909)=	-144.D0
00010500	Y(1893)=	-144.D0
00010600	Y(1920)=	144.D0
00010700	Y(1895)=	144.D0
00010800	Y(1922)=	-144.D0
00010900	Y(1906)=	-144.D0
00011000	Y(1915)=	144.D0
00011100	Y(955)=	-16.D0
00011200	Y(964)=	32.D0
00011300	Y(973)=	-16.D0
00011400	Y(948)=	16.D0
00011500	Y(966)=	-48.D0
00011600	Y(975)=	32.D0
00011700	Y(950)=	-32.D0
00011800	Y(959)=	48.D0
00011900	Y(977)=	-16.D0
00012000	Y(952)=	16.D0
00012100	Y(961)=	-32.D0
00012200	Y(970)=	16.D0
00012300	Y(8155)=	64.D0
00012400	Y(8156)=	-64.D0

0012500	Y(8165)=	-64.D0
0012600	Y(8148)=	-64.D0
0012700	Y(8157)=	64.D0
0012800	Y(8149)=	64.D0
0012900	Y(8158)=	64.D0
0013000	Y(8150)=	-64.D0
0013100	Y(8020)=	-96.D0
0013200	Y(8029)=	32.D0
0013300	Y(8021)=	128.D0
0013400	Y(8013)=	96.D0
0013500	Y(8031)=	-96.D0
0013600	Y(8014)=	-128.D0
0013700	Y(8015)=	-32.D0
0013800	Y(8024)=	-96.D0
0013900	Y(7084)=	-64.D0
0014000	Y(7076)=	-128.D0
0014100	Y(7085)=	64.D0
0014200	Y(7086)=	128.D0
0014300	Y(7069)=	128.D0
0014400	Y(7070)=	64.D0
0014500	Y(7079)=	-128.D0
0014600	Y(7071)=	-64.D0
0014700	Y(3205)=	-16.D0
0014800	Y(3214)=	16.D0
0014900	Y(3206)=	16.D0
0015000	Y(3215)=	-16.D0
0015100	Y(3198)=	16.D0
0015200	Y(3216)=	-16.D0
0015300	Y(3199)=	-16.D0
0015400	Y(3217)=	16.D0
0015500	Y(3200)=	-16.D0
0015600	Y(3209)=	16.D0
0015700	Y(3201)=	16.D0
0015800	Y(3210)=	-16.D0
0015900	Y(7579)=	64.D0
0016000	Y(7580)=	-64.D0
0016100	Y(7572)=	-128.D0
0016200	Y(7573)=	128.D0
0016300	Y(7565)=	64.D0
0016400	Y(7566)=	-64.D0
0016500	Y(5680)=	64.D0
0016600	Y(5681)=	-64.D0
0016700	Y(5673)=	-64.D0
0016800	Y(5691)=	-64.D0
0016900	Y(5674)=	64.D0
0017000	Y(5692)=	64.D0
0017100	Y(5684)=	64.D0
0017200	Y(5685)=	-64.D0
0017300	Y(7435)=	-96.D0
0017400	Y(7444)=	32.D0
0017500	Y(7436)=	-96.D0
0017600	Y(7445)=	160.D0
0017700	Y(7428)=	96.D0
0017800	Y(7437)=	128.D0
0017900	Y(7446)=	-96.D0
0018000	Y(7429)=	96.D0
0018100	Y(7438)=	-128.D0
0018200	Y(7447)=	-96.D0
0018300	Y(7430)=	-160.D0
0018400	Y(7439)=	96.D0
0018500	Y(7431)=	-32.D0
0018600	Y(7440)=	96.D0
0018700	Y(5545)=	-96.D0
0018800	Y(5554)=	32.D0
0018900	Y(5546)=	32.D0
0019000	Y(5555)=	32.D0

00019100	Y(5538)=	96.D0
00019200	Y(5556)=	32.D0
00019300	Y(5539)=	-32.D0
00019400	Y(5557)=	-96.D0
00019500	Y(5540)=	-32.D0
00019600	Y(5549)=	-32.D0
00019700	Y(5541)=	-32.D0
00019800	Y(5550)=	96.D0
00019900	Y(3070)=	48.D0
00020000	Y(3079)=	-48.D0
00020100	Y(3071)=	-48.D0
00020200	Y(3080)=	48.D0
00020300	Y(3063)=	-48.D0
00020400	Y(3081)=	48.D0
00020500	Y(3064)=	48.D0
00020600	Y(3082)=	-48.D0
00020700	Y(3065)=	48.D0
00020800	Y(3074)=	-48.D0
00020900	Y(3066)=	-48.D0
00021000	Y(3075)=	48.D0
00021100	Y(8200)=	-64.D0
00021200	Y(8201)=	64.D0
00021300	Y(8193)=	64.D0
00021400	Y(8194)=	-64.D0
00021500	Y(7615)=	-64.D0
00021600	Y(7616)=	-64.D0
00021700	Y(7625)=	64.D0
00021800	Y(7608)=	64.D0
00021900	Y(7617)=	64.D0
00022000	Y(7609)=	64.D0
00022100	Y(7618)=	-64.D0
00022200	Y(7610)=	-64.D0
00022300	Y(3250)=	16.D0
00022400	Y(3259)=	-16.D0
00022500	Y(3243)=	-16.D0
00022600	Y(3261)=	16.D0
00022700	Y(3245)=	16.D0
00022800	Y(3254)=	-16.D0
00022900	Y(5725)=	-64.D0
00023000	Y(5718)=	64.D0
00023100	Y(5736)=	64.D0
00023200	Y(5729)=	-64.D0
00023300	C-----LOAD NON-ZERO Z COEFFICIENTS	
00023400	Z(341)=	-1.D0
00023500	Z(343)=	3.D0
00023600	Z(345)=	-3.D0
00023700	Z(347)=	1.D0
00023800	Z(664)=	-1.D0
00023900	Z(665)=	5.D0
00024000	Z(666)=	-10.D0
00024100	Z(667)=	10.D0
00024200	Z(668)=	-5.D0
00024300	Z(669)=	1.D0
00024400	Z(154)=	-1.D0
00024500	Z(156)=	5.D0
00024600	Z(158)=	-10.D0
00024700	Z(160)=	10.D0
00024800	Z(162)=	-5.D0
00024900	Z(164)=	1.D0
00025000	Z(222)=	-1.D0
00025100	Z(223)=	-1.D0
00025200	Z(224)=	4.D0
00025300	Z(225)=	-4.D0
00025400	Z(226)=	-6.D0
00025500	Z(227)=	6.D0
00025600	Z(228)=	4.D0

00025700	Z(229)=	-4.00
00025800	Z(230)=	-1.00
00025900	Z(231)=	1.00
00026000	Z(307)=	-1.00
00026100	Z(308)=	2.00
00026200	Z(309)=	2.00
00026300	Z(310)=	-6.00
00026400	Z(312)=	6.00
00026500	Z(313)=	-2.00
00026600	Z(314)=	-2.00
00026700	Z(315)=	1.00
00026800	Z(409)=	-1.00
00026900	Z(410)=	3.00
00027000	Z(411)=	-1.00
00027100	Z(412)=	-5.00
00027200	Z(413)=	5.00
00027300	Z(414)=	1.00
00027400	Z(415)=	-3.00
00027500	Z(416)=	1.00
00027600	Z(528)=	-1.00
00027700	Z(529)=	4.00
00027800	Z(530)=	-5.00
00027900	Z(532)=	5.00
00028000	Z(533)=	-4.00
00028100	Z(534)=	1.00
00028200	Z(562)=	-1.00
00028300	Z(563)=	2.00
00028400	Z(565)=	-2.00
00028500	Z(566)=	1.00
00028600	Z(732)=	-1.00
00028700	Z(733)=	1.00
00028800	Z(545)=	1.00
00028900	Z(546)=	-3.00
00029000	Z(547)=	2.00
00029100	Z(548)=	2.00
00029200		
00029300		
00029400	Z(549)=	-3.00
00029500	Z(550)=	1.00
00029600	Z(579)=	1.00
00029700	Z(580)=	-1.00
00029800	Z(581)=	-1.00
00029900	Z(582)=	1.00
00030000	Z(596)=	-1.00
00030100	Z(598)=	1.00
00030200	Z(443)=	-1.00
00030300	Z(444)=	1.00
00030400	Z(445)=	2.00
00030500	Z(446)=	-2.00
00030600	Z(447)=	-1.00
00030700	Z(448)=	1.00
00030800	Z(698)=	-1.00
00030900	Z(699)=	3.00
00031000	Z(700)=	-3.00
00031100	Z(701)=	1.00
00031200	Z(324)=	1.00
00031300	Z(325)=	-1.00
00031400	Z(326)=	-3.00
00031500	Z(327)=	3.00
00031600	Z(328)=	3.00
00031700	Z(329)=	-3.00
00031800	Z(330)=	-1.00
00031900	Z(331)=	1.00
00032000	Z(460)=	1.00
00032100	Z(462)=	-2.00
00032200	Z(464)=	1.00

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00032300 RETURN
00032400 END
00032500 FUNCTION SS(NN1,LL1,MM,NN2,LL2,ALPHA,BETA)
00032600 IMPLICIT REAL*4(A-H,I-Z)
00032700 C-----PROCEDURE FOR CALCULATING REDUCED OVERLAP INTEGRALS
00032800 COMMON/ARRAYS/S(40,40),Y(9,5,203),Z(17,45)
00032900 COMMON/AUXINT/A(17),B(17)
00033000 INTEGER ULIM
00033100 I1=NN1
00033200 L1=LL1
00033300 M=MM
00033400 J2=NN2
00033500 L2=LL2
00033600 P=(ALPHA + BETA)/2.00
00033700 PT=(ALPHA - BETA)/2.00
00033800 K = 0.00
00033900 M=IABS(M)
00034000 C-----REVERSE QUANTUM NUMBERS IF NECESSARY
00034100 IF((L2.LT.L1).OR.((L2.EQ.L1).AND.(N2.LT.N1))) GO TO 20
00034200 10 GO TO 30
00034300 20 K = N1
00034400 I1= N2
00034500 J2= K
00034600 K= L1
00034700 L1= L2
00034800 L2= K
00034900 PT=-PT
00035000 30 CONTINUE
00035100 K = MOD((N1+N2-L1-L2),2)
00035200 C-----FIND A AND B INTEGRALS
00035300 CALL AINTGS(P,N1+N2)
00035400 CALL BINTGS(PT,N1+N2)
00035500 IF((L1.GT.0).OR.(L2.GT.0)) GO TO 60
00035600 C-----BEGIN SECTION USED FOR OVERLAP INTEGRALS INVOLVING S FUNCTIONS
00035700 C-----FIND Z TABLE NUMBER L
00035800 40 L = (90-17*N1+N1**2-2*N2)/2
00035900 JLIM = N1+N2
00036000 LLIM = 0
00036100 DO 50 I=LLIM,ULIM
00036200 NNI1=N1+N2-I+1
00036300 50 X=X+Z(I+1,L)*A(I+1)*B(NNI1)/2.00
00036400 SS=X
00036500 GO TO 80
00036600 C-----BEGIN SECTION USED FOR OVERLAPS INVOLVING NON-S FUNCTIONS
00036700 C-----FIND Y TABLE NUMBER L
00036800 60 L=(5-M)*(24-10*M+M**2)*(83-30*M+3*M**2)/120+
00036900 1 (30-9*L1+L1**2-2*N1)*(28-9*L1+L1**2-2*N1)/8+
00037000 2 (30-9*L2+L2**2-2*N2)/2
00037100 LLIM = 0
00037200 DO 70 I=LLIM,8
00037300 JLIM=4 - MOD(K+I,2)
00037400 DO 70 J=LLIM,ULIM
00037500 IIII=2*J+MOD(K+I,2)+1
00037600 70 X=X+Y(I+1,J+1,L)*A(I+1)*B(IIII)
00037700 SS = X*(FACT(M+1)/8.00)**2* SQRT( FLOAT(2*L1+1)*FACT(L1-M)*
00037800 1 FLOAT(2*L2+1)*FACT(L2-M)/(4.00*FACT(L1+M)*FACT(L2+M)))
00037900 80 CONTINUE
00038000 RETURN
00038100 END
00038200 SUBROUTINE HARMTR(T,MAXL,E)
00038300 IMPLICIT REAL*4(A-H,I-Z)
00038400 DIMENSION T(9,9),E(3)
00038500 COST = E(3)
00038600 IF((1.00-COST**2).GT.0.0000000001) GO TO 20
00038700 10 SINT = 0.00
00038800 GO TO 30

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00038900 20 SINT= SQRT(1.D0-COST**2)
00039000 30 CONTINUE
00039100 IF(SINT.GT.0.000001D0) GO TO 50
00039200 40 COSP = 1.D0
00039300 SINTP = 0.D0
00039400 GO TO 70
00039500 50 COSP = E(1)/SINT
00039600 60 SINTP = E(2)/SINT
00039700 70 CONTINUE
00039800 DO 80 I=1,9
00039900 DO 80 J=1,9
00040000 80 T(I,J) = 0.D0
00040100 T(1,1) = 1.D0
00040200 IF (MAXL.GT.1) GO TO 100
00040300 90 IF (MAXL.GT.0) GO TO 110
00040400 GO TO 120
00040500 100 COS2T = COST**2-SINT**2
00040600 SIN2T = 2.D0*SINT*COST
00040700 COS2P = COSP**2-SINP**2
00040800 SIN2P = 2.D0*SINP*COSP
00040900 C-----TRANSFORMATION MATRIX ELEMENTS FOR D FUNCTIONS
00041000 SQR3= SQRT(3.D0)
00041100 T(5,5) = (3.D0*COST**2-1.D0)/2.D0
00041200 T(5,6) = -SQR3 *SIN2T/2.D0
00041300 T(5,8) = SQR3 *SINT**2/2.D0
00041400 T(6,5) = SQR3 *SIN2T*COSP/2.D0
00041500 T(6,6) = COS2T*COSP
00041600 T(6,7) = -COST*SINP
00041700 T(6,8) = -T(6,5)/SQR3
00041800 T(6,9) = SINT*SINP
00041900 T(7,5) = SQR3 *SIN2T*SINP/2.D0
00042000 T(7,6) = COS2T*SINP
00042100 T(7,7) = COST*COSP
00042200 T(7,8) = -T(7,5)/SQR3
00042300 T(7,9) = -SINT*COSP
00042400 T(8,5) = SQR3 *SINT**2*COS2P/2.D0
00042500 T(8,6) = SIN2T*COS2P/2.D0
00042600 T(8,7) = -SINT*SIN2P
00042700 T(8,8) = (1.D0+COST**2)*COS2P/2.D0
00042800 T(8,9) = -COST*SIN2P
00042900 T(9,5) = SQR3 *SINT**2*SIN2P/2.D0
00043000 T(9,6) = SIN2T*SIN2P/2.D0
00043100 T(9,7) = SINT*COS2P
00043200 T(9,8) = (1.D0+COST**2)*SIN2P/2.D0
00043300 T(9,9) = COST*COS2P
00043400 110 CONTINUE
00043500 C-----TRANSFORMATION MATRIX ELEMENTS FOR P FUNCTIONS
00043600 T(2,2) = COST*COSP
00043700 T(2,3) = -SINP
00043800 T(2,4) = SINT*COSP
00043900 T(3,2) = COST*SINP
00044000 T(3,3) = COSP
00044100 T(3,4) = SINT*SINP
00044200 T(4,2) = -SINT
00044300 T(4,4) = COST
00044400 120 CONTINUE
00044500 RETURN
00044600 END
00044700 SUBROUTINE RELVEC(R,E,C1,C2)
00044800 IMPLICIT REAL*4(A-H,O-Z)
00044900 DIMENSION E(3),C1(3),C2(3)
00045000 X = 0.D0
00045100 DO 10 I=1,3
00045200 E(I) = C2(I)-C1(I)
00045300 X = X+E(I)**2
00045400 10 CONTINUE

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00045500 R= SQRT(X)
00045600 JJ 40 I=1,3
00045700 IF (R.GT..000001D0) GO TO 30
00045800 20 JJ TO 40
00045900 30 E(I) =E(I)/R
00046000 40 CONTINUE
00046100 RETURN
00046200 END
00046300 FUNCTION FACT(N)
00046400 IMPLICIT REAL*4(A-H,O-Z)
00046500 PRODT = 1.D0
00046600 20 JJ 30 I=1,N
00046700 30 PRODT=PRODT* FLOAT(I)
00046800 40 FACT=PRODT
00046900 RETURN
00047000 END
00047100 SUBROUTINE BINTGS(X,K)
00047200 IMPLICIT REAL*4(A-H,O-Z)
00047300 C-----FILLS ARRAY OF B-INTEGRALS. NOTE THAT B(I) IS B(I-1) IN THE
00047400 C-----USUAL NOTATION
00047500 C-----FOR X.GT.3 EXPONENTIAL FORMULA IS USED
00047600 C-----FOR 2.LT.X.LE.3 AND K.LE.10 EXPONENTIAL FORMULA IS USED
00047700 C-----FOR 2.LT.X.LE.3 AND K.GT.10 15 TERM SERIES IS USED
00047800 C-----FOR 1.LT.X .E.2 AND K.LE.7 EXPONENTIAL FORMULA IS USED
00047900 C-----FOR 1.LT.X.LE.2 AND K.GT.7 12 TERM SERIES IS USED
00048000 C-----FOR .5.LT.X.LE.1 AND K.LE.5 EXPONENTIAL FORMULA IS USED
00048100 C-----FOR .5.LT.X.LE.1 AND K.GT.5 7 TERM SERIES IS USED
00048200 C-----FOR X.LE..5 6 TERM SERIES IS USED
00048300 C-----*****
00048400 COMMON/AUXINT/A(17),B(17)
00048500 I0=0
00048600 ABSX= ABS(X)
00048700 IF(ABSX.GT.3.D0) GO TO 120
00048800 10 IF(ABSX.GT.2.D0) GO TO 20
00048900 40 IF(ABSX.GT.1.D0) GO TO 50
00049000 70 IF(ABSX.GT..5D0) GO TO 80
00049100 100 IF(ABSX.GT..000001D0) GO TO 110
00049200 GO TO 170
00049300 110 LAST=6
00049400 GO TO 140
00049500 80 IF(K.LE.5) GO TO 120
00049600 90 LAST=7
00049700 GO TO 140
00049800 50 IF(K.LE.7) GO TO 120
00049900 60 LAST=12
00050000 GO TO 140
00050100 20 IF(K.LE.10) GO TO 120
00050200 30 LAST=15
00050300 GO TO 140
00050400
00050500 120 EXPX= EXP(X)
00050600 EXPMX=1.D0/EXPX
00050700 B(1)=(EXPX-EXPMX)/X
00050800 JJ 130 I=1,K
00050900 130 B(I+1)=( FLOAT(I)*B(I)+(-1.D0)**I*EXPX-EXPMX)/X
00051000 GO TO 190
00051100 140 JJ 160 I=I0,K
00051200 Y=0.D0
00051300 JJ 150 M=I0, LAST
00051400 150 Y=Y+(-X)**M*(1.D0-(-1.D0)**(M+I+1))/(FACT(M)* FLOAT(M+I+1))
00051500 160 B(I+1)=Y
00051600 GO TO 190
00051700
00051800 170 JJ 180 I=I0,K
00051900 130 B(I+1)=(1.D0-(-1.D0)**(I+1))/ FLOAT(I+1)
00052000 190 CONTINUE

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0052100 RETURN
0052200 END
0052300 SUBROUTINE AINTGS(X,K)
0052400 IMPLICIT REAL*4(A-H,O-Z)
0052500 COMMON/AUXINT/A(17),B(17)
0052600 A(1) = EXP(-X)/X
0052700 DO 10 I=1,K
0052800 10 A(I+1) =(A(I)* FLOAT(I)+ EXP(-X))/X
0052900 RETURN
0053000 END
0053100 SUBROUTINE DEIGCH(A,N,N1,NE,NV,EPS,W,LW,E,V)
0053200 IMPLICIT REAL*8 (A-H, O-Z)
0053300 COMPLEX*16 A,V,CR
0053400 COMPLEX*32 CS
0053500 REAL*16 S
0053600 LOGICAL SW, LW
0053700 DIMENSION A(N1,1), E(1), V(N1,1), W(N1,7), LW(1)
0053800 IF(N.LE.0 .OR. NE.EQ.0 ) GO TO 910
0053900 NEA=IABS(NE)
0054000 NVA=IABS(NV)
0054100 IF(N1.LT.N .OR. N.LT.NEA .OR. NEA.LT.NVA ) GO TO 920
0054200 IF(EPS.LT.0.D0) EPS=1.D-16
0054300 N1=N-1
0054400 N2=N-2
0054500 IF(N2) 10, 20, 50
0054600 C WHEN N=1
0054700 10 E(1)=A(1,1)
0054800 IF( NV,NE.0 ) V(1,1) = 1.0D0
0054900 GO TO 900
0055000 C WHEN N=2
0055100 C COMPUTE EIGENVALUES OF 2*2 MATRIX
0055200 20 CALL ERRSET(202,256,-1,1)
0055300 V(1,1)=A(1,1)
0055400 V(2,1)=A(2,2)
0055500 V(1,2)=CDABS(A(2,1))
0055600 A(1,1)=A(2,1)/W(1,2)
0055700 T = 0.5D0*(W(1,1)+W(2,1))
0055800 R=W(1,1)*W(2,1)-W(1,2)**2
0055900 J=T*T-R
0056000 Q=DABS(T)+DSQRT(D)
0056100 IF(T.LT.0.) Q=-Q
0056200 T=T*DFLOAT(NE)
0056300 IF(T) 40, 30, 30
0056400 30 E(1)=Q
0056500 IF(NEA.EQ.2) E(2)=R/Q
0056600 GO TO 310
0056700 40 E(1)=R/Q
0056800 IF(NEA.EQ.2) E(2)=Q
0056900 GO TO 310
0057000 C WHEN N=3,4,...
0057100 C REDUCE TO TRIDIAGONAL FORM BY HOUSEHOLDER'S METHOD
0057200 50 DO 60 I=1,N
0057300 60 V(I,1)=A(I,1)
0057400 DO 190 K=1,N2
0057500 S=0.
0057600 DO 70 J=K+1,N
0057700 70 S=S+DREAL(A(I,K))**2+DIMAG(A(I,K))**2
0057800 SR = QSQRT(S)
0057900 T=CDABS(A(K+1,K))
0058000 V(K,2)=-SR
0058100 IF(T) 90, 80, 90
0058200 80 A(K,K) = 1.0D0
0058300 GO TO 100
0058400 90 A(K,K)=A(K+1,K)/T
0058500 100 IF(S.EQ.0.) GO TO 190
0058600 R = 1.0D0/(S+T*SR)

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0058700 A(K+1,K)=A(K+1,K)+SR*A(K,K)
0058800 JJ 140 I=K+1,N
0058900 CS=(0.,0.)
0059000 IF(I.EQ.K+1) GO TO 120
0059100 JJ 110 J=K+1,I-1
0059200 110 CS=CS+A(I,J)*A(J,K)
0059300 120 CS=CS+W(I,1)*A(I,K)
0059400 IF(I.EQ.N) GO TO 140
0059500 DD 130 J=I+1,N
0059600 130 CS=CS+DCONJG(A(J,I))*A(J,K)
0059700 140 A(I,I)=CS*R
0059800 CS=(0.,0.)
0059900 JJ 150 I=K+1,N
0060000 150 CS=CS+DCONJG(A(I,K))*A(I,I)
0060100 CS = 0.500*R*CS
0060200 DD 160 I=K+1,N
0060300 160 A(I,I)=A(I,I)-CS*A(I,K)
0060400 DD 170 I=K+1,N
0060500 170 A(I,1) = w(I,1)-2.000*DREAL(A(I,K)*DCONJG(A(I,I)))
0060600 DD 180 I=K+2,N
0060700 DD 180 J=K+1,I-1
0060800 180 A(I,J)=A(I,J)-A(I,K)*DCONJG(A(J,J))-A(I,I)*DCONJG(A(J,K))
0060900 190 CONTINUE
0061000 W(NM1,2)=CDABS(A(N,NM1))
0061100 IF(W(NM1,2)) 196,195,196
0061200 195 A(NM1,NM1)=1.D0
0061300 GO TO 198
0061400 196 CONTINUE
0061500 A(NM1,NM1)=A(N,NM1)/W(NM1,2)
0061600 198 CONTINUE
0061700 C COMPUTE EIGENVALUES BY BISECTION METHOD
0061800 CALL ERRSET(202,256,-1,1)
0061900 R=DMAX1((DABS(W(1,1))+DABS(W(1,2))), (DABS(W(NM1,2))+DABS(W(N,1)
0062000 DD 200 I=2,NM1
0062100 T=DABS(W(I-1,2))+DABS(W(I,1))+DABS(W(I,2))
0062200 IF(T.GT.R) R=T
0062300 200 CONTINUE
0062400 EPS1=R*0.1D-15
0062500 EPS2=R*EPS
0062600 DD 210 I=1,NM1
0062700 210 W(I,3)=W(I,2)**2
0062800 IF(NE.LT.0) R=-R
0062900 F=R
0063000 DD 220 I=1,NEA
0063100 220 E(I)=-R
0063200 DD 300 K=1,NEA
0063300 J=E(K)
0063400 230 T = 0.500*(D+F)
0063500 IF(DABS(D-T).LE.EPS2 .OR. DABS(F-T).LE.EPS2 ) GO TO 300
0063600 J=0
0063700 I=1
0063800 240 J=W(I,1)-T
0063900 250 IF(Q.GE.0.) J=J+1
0064000 IF(Q.EQ.0.) GO TO 260
0064100 I=I+1
0064200 IF(I.GT.N) GO TO 270
0064300 CALL OVERFL(L)
0064400 J=W(I,1)-T-W(I-1,3)/Q
0064500 CALL OVERFL(L)
0064600 IF(L.NE.1) GO TO 250
0064700 J=J+1
0064800 I=I-1
0064900 260 I=I+2
0065000 IF(I.LE.N) GO TO 240
0065100 270 IF(NE.LT.0) J=N-J
0065200 IF(J.GE.K) GO TO 260

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00065300 F=T
00065400 GO TO 230
00065500 280 J=T
00065600 M=MIN0(J,NEA)
00065700 DO 290 I=K,M
00065800 290 E(I)=T
00065900 GO TO 230
00066000 300 E(K)=T
00066100 C COMPUTE EIGENVECTORS BY INVERSE ITERATION
00066200 310 CALL ERRSET(202, 10, 5,2)
00066300 IF(NV.EQ.0) GO TO 900
00066400 IM=584287
00066500 CALL ERRSET(202,256,-1,1)
00066600 DO 490 I=1,NVA
00066700 DO 320 J=1,N
00066800 V(J,3)=W(J,1)-E(I)
00066900 V(J,4)=W(J,2)
00067000 320 V(J,7) = 1.000
00067100 NV=.FALSE.
00067200 C REDUCE TO TRIANGULAR FORM
00067300 DO 340 J=1,NM1
00067400 IF(DABS(W(J,3)).LT.DABS(W(J,2))) GO TO 330
00067500 IF(W(J,3).EQ.0.) W(J,3)=1.0D-30
00067600 V(J,6)=W(J,2)/W(J,3)
00067700 LW(J)=.FALSE.
00067800 V(J+1,3)=W(J+1,3)-W(J,6)*W(J,4)
00067900 V(J,5)=0.
00068000 GO TO 340
00068100 330 V(J,6)=W(J,3)/W(J,2)
00068200 LW(J)=.TRUE.
00068300 V(J,3)=W(J,2)
00068400 T=W(J,4)
00068500 V(J,4)=W(J+1,3)
00068600 V(J,5)=W(J+1,4)
00068700 V(J+1,3)=T-W(J,6)*W(J,4)
00068800 V(J+1,4)=-W(J,6)*W(J,5)
00068900 340 CONTINUE
00069000 IF(W(N,3).EQ.0.) W(N,3)=1.0D-30
00069100 C BEGIN BACK SUBSTITUTION
00069200 IF(I.EQ.1 .OR. DABS(E(I)-E(I-1)).GE.EPS1) GO TO 360
00069300 C GENERATE RANDOM NUMBERS
00069400 DO 350 J=1,N
00069500 IM=MM*48828125
00069600 350 V(J,7)=FLOAT(MM)*0.4656613E-9
00069700 360 CALL OVERFL(L)
00069800 T=W(N,7)
00069900 R=W(N-1,7)
00070000 370 V(N,7)=T/W(N,3)
00070100 V(N-1,7)=(R-W(N-1,4)*W(N,7))/W(N-1,3)
00070200 CALL OVERFL(L)
00070300 IF(L.NE.1) GO TO 390
00070400 DO 380 J=1,N2
00070500 380 V(J,7)=W(J,7)*1.0D-5
00070600 T=T*1.0D-5
00070700 R=R*1.0D-5
00070800 GO TO 370
00070900 390 IF(N.EQ.2) GO TO 440
00071000 K=N2
00071100 400 T=W(K,7)
00071200 410 V(K,7)=(T-W(K,4)*W(K+1,7)-W(K,5)*W(K+2,7))/W(K,3)
00071300 CALL OVERFL(L)
00071400 IF(L.NE.1) GO TO 430
00071500 DO 420 J=1,N
00071600 420 V(J,7)=W(J,7)*1.0D-5
00071700 T=T*1.0D-5
00071800 GO TO 410

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00071900 430 <=K-1
00072000 IF(K) 440,440,400
00072100 440 IF(SW) GO TO 470
00072200 SW=.TRUE.
00072300 JJ 460 J=1,NM1
00072400 IF(LW(J)) GO TO 450
00072500 V(J+1,7)=W(J+1,7)-W(J,6)*W(J,7)
00072600 GO TO 460
00072700 450 T=W(J,7)
00072800 V(J,7)=W(J+1,7)
00072900 V(J+1,7)=T-W(J,6)*W(J+1,7)
00073000 460 CONTINUE
00073100 GO TO 360
00073200 470 JJ 480 J=1,N
00073300 430 V(J,I)=W(J,7)
00073400 490 CONTINUE
00073500 C BEGIN BACK TRANSFORMATION (1)
00073600 CR = 1.0D0
00073700 JJ 500 J=2,N
00073800 CR=CR*A(J-1,J-1)
00073900 JJ 500 I=1,NVA
00074000 500 V(J,I)=V(J,I)*CR
00074100 C BEGIN BACK TRANSFORMATION (2)
00074200 CALL ERRSET(202, 10, 5,2)
00074300 IF(N.EQ.2) GO TO 600
00074400 JJ 590 I=1,NVA
00074500 <=N2
00074600 550 CR=-A(K+1,K)*DCONJG(A(K,K))*W(K,2)
00074700 IF(DREAL(CR).EQ.0.0 .AND. DIMAG(CR).EQ.0.0) GO TO 580
00074800 CR = 1.0D0/CR
00074900 CS=(0.,0.)
00075000 JJ 560 J=K+1,N
00075100 560 CS=CS+DCONJG(A(J,K))*V(J,I)
00075200 CR=CR*CS
00075300 JJ 570 J=K+1,N
00075400 570 V(J,I)=V(J,I)-CR*A(J,K)
00075500 580 <=K-1
00075600 IF(K.GE.1) GO TO 550
00075700 590 CONTINUE
00075800 600 CONTINUE
00075900 C NORMALIZE EIGENVECTORS
00076000 C NORMALIZE AS MAXIMUM ELEMENT=1
00076100 JJ 620 I=1,NVA
00076200 T=DABS(DREAL(V(1,I)))+DABS(DIMAG(V(1,I)))
00076300 <=1
00076400 JJ 610 J=2,N
00076500 R=DABS(DREAL(V(J,I)))+DABS(DIMAG(V(J,I)))
00076600 IF(T.GE.R) GO TO 610
00076700 T=R
00076800 <=J
00076900 610 CONTINUE
00077000 CR = 1.0D0/V(K,I)
00077100 JJ 620 J=1,N
00077200 620 V(J,I)=V(J,I)*CR
00077300 IF(NV.LT.0) GO TO 900
00077400 C SORT DIAGONALIZE AS NORM=1
00077500 JJ 680 I=1,NVA
00077600 IF(I.EQ.1 .OR. DABS(E(I)-E(I-1)).GT.EPS) GO TO 650
00077700 JJ 640 J=M,I-1
00077800 CS=(0.,0.)
00077900 JJ 630 K=1,N
00078000 630 CS = CS + DCONJG(V(K,J))*V(K,I)
00078100 JJ 640 K=1,N
00078200 640 V(K,I)=V(K,I)-CS*V(K,J)
00078300 GO TO 660
00078400 650 I=I

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00078500 C  NORMALIZE AS NORM=1
00078600 660  S=0.
00078700      JD 670 J=1,N
00078800 670  S=S+DREAL(V(J,I))*2+DIMAG(V(J,I))*2
00078900      T = QSQR(1.0Q0/S)
00079000      JD 680 J=1,N
00079100 680  V(J,I)=V(J,I)*T
00079200 900  RETURN
00079300 C  PRINT ERROR MESSAGE
00079400 910  WRITE(6,1000) N,NE
00079500      JD TO 900
00079600 920  WRITE(6,1100) NV,NE,N,N1
00079700      JD TO 900
00079800 1000 FORMAT(1H0,'(SUBR. DEIGCH) N=',I5,',NE=',I5,', N SHOULD BE GREA
00079900 1  THAN ZERO AND NE SHOULD BE NON-ZERO. RETURN WITH NO CALCULATIO
00080000 2 ')
00080100 1100 FORMAT(1H0,'(SUBR. DEIGCH) NV=',I5,',NE=',I5,',N=',I5,',N1=',I5
00080200 1' NV,NE,N,N1 SHOULD SATISFY THE FOLLOWING INEQUALITIES, INVI <=
00080300 2EI <= N <= N1 .' /1H ,'RETURN WITH NO CALCULATION.')
00080400      END
00080500      SUBROUTINE MATDUT(MATOP)
00080600      COMPLEX*16 ZS,ZH,PM,RM
00080700      REAL*8 V
00080800      COMMON/ARRAYS/S(40,40),Y(9,5,203),Z(17,45)
00080900      COMMON/COM01/ ZS(40,40),ZH(40,40)
00081000      COMMON/COM02/ PM(40,40),RM(40,40)
00081100      COMMON/COM03/ V(40),W(20,40)
00081200      COMMON/NATOMS/ NATOMS,N,NK
00081300      REAL*8 A(2,40,40),B(2,40,40),C(2,40,40)
00081400      EQUIVALENCE (A(1,1,1),ZS(1,1))
00081500      EQUIVALENCE (B(1,1,1),PM(1,1))
00081600      EQUIVALENCE (C(1,1,1),ZH(1,1))
00081700 C  IF(MATOP.NE.3.AND.MATOP.NE.5) GO TO 90
00081800      JD 80 M=1,N,12
00081900      <=M+11
00082000      IF (K.LE.N) GO TO 30
00082100 20 <=N
00082200 30 CONTINUE
00082300      IF(MATOP.NE.3) GO TO 11
00082400      WRITE(6,10) (V(J),J=M,K)
00082500 10 FORMAT(7X,12F9.4)
00082600 11 CONTINUE
00082700      WRITE(6,40) (J,J=M,K)
00082800 40 FORMAT(//,7X,12(4X,I2,3X),//)
00082900      JD 60 I=1,N
00083000      GO TO (41,42,43,44,45),MATOP
00083100 41 WRITE(6,50) I,(S(I,J),J=M,K) ;GO TO 60
00083200 42 WRITE(6,50) I,(A(1,I,J),J=M,K)
00083300      WRITE(6,50) I,(A(2,I,J),J=M,K) ;GO TO 60
00083400 43 WRITE(6,50) I,(A(1,I,J),J=M,K)
00083500      WRITE(6,50) I,(A(2,I,J),J=M,K) ;GO TO 60
00083600 44 WRITE(6,50) I,(C(1,I,J),J=M,K)
00083700      WRITE(6,50) I,(C(2,I,J),J=M,K) ;GO TO 60
00083800 45 WRITE(6,50) I,(B(1,I,J),J=M,K)
00083900      WRITE(6,50) I,(B(2,I,J),J=M,K) ;GO TO 60
00084000 50 FORMAT(1X,I2,4X,50(F9.4))
00084100 60 CONTINUE
00084200      WRITE(6,70)
00084300 70 FORMAT(//)
00084400 80 CONTINUE
00084500 90 RETURN
00084600      END
00084700      SUBROUTINE SOLUT
00084800      COMPLEX*16 S,H,PM,RM,SUM,DEN
00084900      REAL*8 EI,WW,V
00085000      DIMENSION LW(40),EI(40),WW(40,7)

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00085100 C-----*** SOLUTION OF SECULAR DETERMINANT ***
00085200 COMMON/COM01/ S(40,40),H(40,40)
00085300 COMMON/COM02/ PM(40,40),RM(40,40)
00085400 COMMON/COM03/ V(40),N(20,40)
00085500 COMMON/COM19/ IRET,ISTOP,NNAT
00085600 COMMON/NATOMS/ NATOMS,N,NK
00085700 JDEBUG,SUBCHK
00085800 C COMPLEX*8 ZH(24,24)
00085900 C DO 3 I=1,24
00086000 C DO 3 J=1,24
00086100 C 3 ZH(I,J)=H(I,J)
00086200 DO 2 I=1,N
00086300 DO 2 J=1,N
00086400 2 RM(I,J)=S(I,J)
00086500 C-----
00086600 EPS=1.E-15
00086700 CALL DEIGCH(S,N,40,-N,N,EPS,WW,LW,EI,PM)
00086800 C-----
00086900 DO 10 I=1,N
00087000 IF(EI(I) .LE.0.0) GO TO 41
00087100 C-----
00087200 10 V(I)=1.0/SQRT(EI(I) )
00087300 DO 13 I=1,N
00087400 DO 12 J=1,N
00087500 12 S(I,J)=PM(I,J)*V(J)
00087600 13 CONTINUE
00087700 C-----
00087800 DO 16 I=1,N
00087900 DO 15 J=1,N
00088000 PM(I,J)=0.0
00088100 DO 14 K=1,N
00088200 14 PM(I,J)=PM(I,J)+CONJG(S(K,I))*H(K,J)
00088300 15 CONTINUE
00088400 16 CONTINUE
00088500 DO 19 I=1,N
00088600 DO 18 J=1,N
00088700 H(I,J)=0.0
00088800 DO 17 K=1,N
00088900 17 H(I,J)=H(I,J)+PM(I,K)*S(K,J)
00089000 18 CONTINUE
00089100 19 CONTINUE
00089200 C-----
00089300 C DO 3333 I=1,N
00089400 C DO 3333 J=I,N
00089500 C3333 H(J,I)=CONJG(H(I,J))
00089600 CALL DEIGCH(H,N,40,-N,N,EPS,WW,LW,V,PM)
00089700 C-----
00089800 DO 21 I=1,N
00089900 21 V(NK-1,I)=V(I)
00090000 DO 52 I=1,N
00090100 DO 51 J=1,N
00090200 H(I,J)=0.0
00090300 DO 50 K=1,N
00090400 50 H(I,J)=H(I,J)+S(I,K)*PM(K,J)
00090500 51 CONTINUE
00090600 52 CONTINUE
00090700 C-----
00090800 DO 25 I=1,N
00090900 SUM=0.0
00091000 DO 24 J=1,N
00091100 DO 23 K=1,N
00091200 23 SUM=SUM+CONJG(H(J,I))*H(K,I)*RM(J,K)
00091300 24 CONTINUE
00091400 DEN=SQRT(SUM)
00091500 DO 26 L=1,N
00091600 26 S(L,1)=H(L,1)/DEN

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00091700 25 CONTINUE
00091800 C   DO 31 I=1,N
00091900 C   DO 31 J=1,N
00092000 C   31 I(I,J)=0.
00092100 C   DO 32 I=1,N
00092200 C   DO 32 J=1,N
00092300 C   DO 32 K=1,N
00092400 C   32 I(I,J)=H(I,J)+(ZH(I,K)-V(J)*RM(I,K))*S(K,J)
00092500 C   WRITE(6,33)
00092600 C   33 FORMAT(' (H-ES)X=')
00092700 C   CALL MATOUT(4)
00092800 C   GO TO 60
00092900 41 WRITE(6,42)
00093000 42 FORMAT(' OVERLAP MATRIX IS NON-POSITIVE. STOP')
00093100 STOP
00093200 60 RETURN
00093300 END
00093400 PROGRAM PLBAND
00093500 DIMENSION W(20,40),AK(40),V(40)
00093600 READ(20,51) N,MNK1,VECK1
00093700 51 FORMAT(2I10,F10.4)
00093800 READ(20,50) ((W(I,J),J=1,N),I=1,MNK1)
00093900 50 FORMAT(24F10.4)
00094000 DO 1 I=1,MNK1
00094100 1 AK(I)=(I-1)*VECK1/(MNK1-1)
00094200 DO 4 I=1,MNK1
00094300 DO 4 J=1,N
00094400 IF(W(I,J).GE.40.) W(I,J)=40.
00094500 4 CONTINUE
00094600 NK1=MNK1+1 ;NK2=MNK1+2
00094700 AK(NK1)=0. ;AK(NK2)=-0.075 ;V(NK1)=-40. ;V(NK2)=2.
00094800 C   WRITE(6,100) N,MNK1,VECK1,((W(I,J),J=1,N),I=1,MNK1)
00094900 C 100 FORMAT(1H ,2I10,F10.4,/1H ,(12F10.4,/1H ))
00095000 CALL PLOTS(999.,999.,'EHT SP SIO2')
00095100 CALL PLOT(2.,15.,-3)
00095200 AXL=VECK1/0.075
00095300 CALL AXIS(0.,0.,'K',-1,AXL,-90.,AK(NK1),0.075)
00095400 CALL AXIS(0.,0.,'ENERGY',6,40.,0.,V(NK1),V(NK2))
00095500 DO 2 I=1,N
00095600 DO 3 J=1,MNK1
00095700 3 V(J)=W(J,I)
00095800 CALL LINE(V,AK,MNK1,1,0,0)
00095900 WRITE(6,101) I,(V(K),K=1,MNK1)
00096000 101 FORMAT(1H ,I10,/1H ,(12F10.4/1H ))
00096100 2 CONTINUE
00096200 CALL PLOTV
00096300 STOP ;END

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BER BAND JF A1402.S.FORT LIST END

NUMBER BETA

JF A1402.S.FORT

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00000100 SUBROUTINE MATOUT(MATOP)
00000200 COMPLEX*16 ZS,ZH,PM,RM
00000300 REAL*8 V
00000400 COMMON/ARRAYS/S(40,40),Y(9,5,203),Z(17,45)
00000500 COMMON/COM01/ ZS(40,40),ZH(40,40)
00000600 COMMON/COM02/ PM(40,40),RM(40,40)
00000700 COMMON/COM03/ V(40),W(20,40)
00000800 COMMON/NATOMS/ NATOMS,N,NK
00000900 REAL*8 A(2,40,40),B(2,40,40),C(2,40,40)
00001000 EQUIVALENCE (A(1,1,1),ZS(1,1))
00001100 EQUIVALENCE (B(1,1,1),PM(1,1))
00001200 EQUIVALENCE(C(1,1,1),ZH(1,1))
00001300 C IF(MATOP.NE.3.AND.MATOP.NE.5) GO TO 90
00001400 DO 80 M=1,N,12
00001500 <=M+11
00001600 IF (K.LE.N) GO TO 30
00001700 20 <=N
00001800 30 CONTINUE
00001900 IF(MATOP.NE.3) GO TO 11
00002000 WRITE(6,10) (V(J),J=M,K)
00002100 10 FORMAT(7X,12F9.4)
00002200 11 CONTINUE
00002300 WRITE(6,40) (J,J=M,K)
00002400 40 FORMAT(//,7X,12(4X,I2,3X),//)
00002500 DO 60 I=1,N
00002600 GO TO (41,42,43,44,45),MATOP
00002700 41 WRITE(6,50) I,(S(I,J),J=M,K) ;GO TO 60
00002800 42 WRITE(6,50) I,(A(1,I,J),J=M,K)
00002900 WRITE(6,50) I,(A(2,I,J),J=M,K) ;GO TO 60
00003000 43 WRITE(6,50) I,(A(1,I,J),J=M,K)
00003100 WRITE(6,50) I,(A(2,I,J),J=M,K) ;GO TO 60
00003200 44 WRITE(6,50) I,(C(1,I,J),J=M,K)
00003300 WRITE(6,50) I,(C(2,I,J),J=M,K) ;GO TO 60
00003400 45 WRITE(6,50) I,(B(1,I,J),J=M,K)
00003500 WRITE(6,50) I,(B(2,I,J),J=M,K) ;GO TO 60
00003600 50 FORMAT(1X,I2,4X,50(F9.4))
00003700 60 CONTINUE
00003800 WRITE(6,70)
00003900 70 FORMAT(//)
00004000 80 CONTINUE
00004100 90 RETURN
00004200 END
00004300 PROGRAM BETA
00004400 COMMON/COM03/ V(40),W(20,40)
00004500 COMMON/VECK/VECK(3)
00004600 C-----GENERATION OF MATRIX VOIP AND AZETA-----
00004700 COMMON/VOIP/ VOIP(4,6),AZETA(4,6),CONST,OM1,OM2,VP(4,6),AZP(4,
00004800 COMMON/POS/ POS(3,6),F(3,7),BONDL,AU,BAU,NC(18),LC(10),MC(10)
00004900 COMMON/COM17/TOEL(30),EN(40)
00005000 COMMON/COM13/ TDP(10,10)
00005100 COMMON/INFO/ AN(35),NOUT
00005200 COMMON/NATOMS/ NATOMS,N,NK
00005300 COMMON /CON/CSSSS,CSSSX,CSSXX,COOSS,COOSX,COOXX,CSS,CSX,CXS,CX
00005310 REAL*8 VM(40)
00005400 REAL*8 V
00005500 INTEGER AN
00005510 DIMENSION AKM(3,3)
00005520 DATA AKM/5*0.,0.4771,3*0.2236/

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00005600 JATA AN/14,14,8,8,8,8/NATOMS/6/
00005700 JATA EN/16*2./,TUEL/4.,4.,6.,6.,6.,6./,OM1,OM2/.5,.5/
00005800 JATA CONST/1.75/
00005900 C JATA VOIP/14.95,7.78,2.05,5*0.,
00006000 C * 32.38,15.34/
00006100 JATA VOIP/12.88,7.08,2.05,5*0.,
00006200 * 32.38,19.58/
00006300 JATA AZETA/1.38,1.38,1.38,5*0.,
00006400 * 2.28,2.28/
00006500 C JATA AZETA/1.56,1.56,1.38,5*0.,2.1,2.1/
00006600 C JATA AZETA/1.6344,1.4284,1.38,5*0.,2.246,2.227/
00006700 JATA PDS/0.,0.,0.,2.,2.,2.,1.,1.,1.,
00006800 * 3.,3.,1.,1.,3.,3.,3.,1.,3./
00006900 JATA F/0.,0.,0.,0.,1.,1.,1.,0.,1.,1.,1.,0.,
00007000 * 0.,-1.,1.,-1.,0.,1.,1.,-1.,0./
00007100 JATA VECK/3*0./
00007200 JDEBUG,SUBCHK
00007300 JJNDL=1.61 ;AU=.529167 ;BAU=BOND/ AU
00007400 B4=BJNDL*4./SQRT(3.)/AU ;B1=B4/4.
00007500 1000 READ(5,14) VOIP(1,1),VOIP(2,1),VOIP(1,3),VOIP(2,3)
00007600 14 FFORMAT(4F10.0)
00007700 WRITE(6,15) VOIP(1,1),VOIP(2,1),VOIP(1,3),VOIP(2,3)
00007800 15 FFORMAT(' VOIP=',4F10.3)
00007810 READ(5,14) AZETA(1,1),AZETA(2,1),AZETA(1,3),AZETA(2,3)
00007820 WRITE(6,16) AZETA(1,1),AZETA(2,1),AZETA(1,3),AZETA(2,3)
00007830 16 FFORMAT(' AZETA=',4F10.3)
00007900 READ(5,5) CSSSS,CSSSX,CSSXX,COOSS,COOSX,COOXX
00008000 5 FFORMAT(3F10.0)
00008600 WRITE(6,7) CSSSS,CSSSX,CSSXX,COOSS,COOSX,COOXX
00008700 7 FFORMAT(' CSSSS,CSSSX,CSSXX,COOSS,COOSX,COOXX=',6F10.3)
00008800 READ(5,8) CSS,CSX,CXS,CXX
00008810 8 FFORMAT(4F10.0)
00008900 WRITE(6,13) CSS,CSX,CXS,CXX
00009000 13 FFORMAT(' CSS,CSX,CXS,CXX=',4F10.3)
00009010 READ(5,9) MODE,MOD1,MNK,ISOL,ITDP,IGRAPH,IHAM
00009020 9 FFORMAT(7I2)
00009030 IF(MODE.EQ.0) STOP
00009040 REWIND 30
00009100 DO 22 I=1,3
00009200 DO 22 J=1,7
00009300 22 F(I,J)=-F(I,J)*B4
00009400 DO 4 I=1,3
00009500 DO 4 J=1,6
00009600 4 PDS(I,J)=PDS(I,J)*B1
00009700 C-----GENERATION OF MATRIX VOIP AND AZETA-----
00009800 DO 10 I=1,4
00009900 VOIP(I,2)=VOIP(I,1)
00010000 AZETA(I,2)=AZETA(I,1)
00010100 DO 10 J=4,6
00010200 VOIP(I,J)=VOIP(I,3)
00010300 AZETA(I,J)=AZETA(I,3)
00010400 10 CONTINUE
00010500 DO 11 I=1,4
00010600 DO 11 J=1,6
00010700 VP(I,J)=VOIP(I,J)
00010800 11 AZP(I,J)=AZETA(I,J)
00011000 CALL COEFFT
00011100 CALL INTGRL
00011200 IF(IHAM.EQ.0) GO TO 140
00011300 C----- WRITING OUT S-----
00011400 WRITE(6,350)
00011500 350 FFORMAT(1H1,1X,23HOVERLAP INTEGRAL MATRIX)
00011600 CALL MATOUT(1)
00011700 140 CONTINUE
00011800 JK=1
00011900 C-----SCANNING OF K VECTOR-----

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00012000      2 CONTINUE
00012100      IF(NK-1.GT.MNK) GO TO 1
00012200      GO TO (161,162) ,MODE
00012300      161 INIK=3 ;LASK=1 ;GO TO 170
00012400      162 INIK=1 ;LASK=2 ;GO TO 170
00012500      170 CONTINUE
00012510      AK1=0.
00012520      DO 180 I=1,3
00012530      180 AK1=AK1+(AKM(I,INIK)-AKM(I,LASK))*2
00012540      AK1=SQRT(AK1)
00012550      DO 181 I=1,3
00012560      181 VECK(I)=(AKM(I,INIK)*(MNK-NK+1.0001)
00012570      *      +AKM(I,LASK)*(NK-1.))/(MNK+0.0001)
00012580      NK=NK+1
00012590      CALL SETSH
00012600 C      WRITE(6,351) NK
00012610 C 351 FORMAT(' BLOCH OVERLAP MATRIX AT NK=',I5)
00012620 C      CALL MATOUT(2)
00012630 C      WRITE(6,352) NK
00012640 C 352 FORMAT(' BLOCH HAMILTONIAN MATRIX AT NK=',I5)
00012650 C      CALL MATOUT(4)
00012660      CALL SOLUT
00012670      WRITE(6,12) (VECK(I),I=1,3),(V(I),I=1,N)
00012680      12 FORMAT(' EIGENVALUES AT NK=',3F10.3,' ARE ',/(6F9.4))
00012690 C-----DIFFERENCE-----
00012700      GO TO (40,41,42,42) ,MOD1
00012710      41 WRITE(30) (V(I),I=1,N) ;GO TO 40
00012720      42 READ(30) (VM(I),I=1,N)
00012730      DO 43 I=1,N
00012740      43 VM(I)=V(I)-VM(I)
00012750      WRITE(6,102) NK,(VM(I),I=1,N)
00012760      102 FORMAT(' DIFFERENCE AT NK=',I5,/(6F9.4))
00012770      IF(MOD1.LE.3) GO TO 40
00012780      WRITE(40) (VM(I),I=1,N)
00012790      40 CONTINUE
00012800 C-----ISOL-----
00012810      IF(ISOL.EQ.0) GO TO 103
00012820      WRITE(6,353) NK
00012830      353 FORMAT(' SOLUTION AT NK=',I5)
00012840      CALL MATOUT(3)
00012850      103 CONTINUE
00012860 C-----TDP-----
00012870      IF(ITDP.EQ.0) GO TO 44
00012880      CALL DENSIT
00012890      44 CONTINUE
00012900      GO TO 2
00012910      1 CONTINUE
00012920      IF(IGRAPH.EQ.0) GO TO 1000
00012930      MNK1=MNK+1
00012940      WRITE(20,51) N,MNK1,AK1
00012950      51 FORMAT(2I10,F10.4)
00012960      WRITE(20,50) ((W(I,J),J=1,N),I=1,MNK1)
00012970      50 FORMAT(24F10.4)
00013240      STOP ;END
00015800      SUBROUTINE INTGRL
00015900      IMPLICIT REAL*4(A-H,O-Z)
00016000 C-----ATOMIC INTEGRALS FOR CNDO CALCULATIONS
00016100      COMMON/ARRAYS/S(40,40),Y(9,5,203),Z(17,45)
00016200      COMMON/INFOJ/ AN(35),NOUT
00016300      COMMON/NATOMS/ NATOMS,N,NK
00016400      COMMON/INFO1/CZ(35),U(80),ULIM(35),LLIM(35),ULK,ULL,ANL,ANK
00016500      COMMON/GAB/T(9,9),PAIRS(9,9),TEMP(9,9),C1(3),C2(3)
00016600      COMMON/AUXINT/A(17),B(17)
00016700      COMMON /SOUTER/SOUTER(10,10,3,7),NZS(2,3,7)
00016800      COMMON/VDIP/ VDIP(4,6),AZETA(4,6),CONST,OM1,OM2,VP(4,6),AZP(4,
00016900      COMMON/POS/ POS(3,6),F(3,7),BONDL,AU,BAU,NC(18),LC(10),MC(10)

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00017000 DIMENSION P(80,80)
00017100 DIMENSION E(3),Q(40)
00017200 EQUIVALENCE (P(1),Y(1))
00017300 INTEGER AN,ULIM,ULK,JLL,CZ,U,ANL,ANK
00017400 C-----DETERMINATION OF SIZE OF AO BASIS IN AND CORE CHARGE CZ
00017500 DEBUG,SUBCHK
00017600 J=0
00017700 C WRITE(6,1100) ((POS(I,J),J=1,6),I=1,3)
00017800 C1100 FORMAT(1H,'POS='//3(6F10.4//))
00017900 C WRITE(6,1101) ((F(I,J),J=1,7),I=1,3)
00018000 C1101 FORMAT(1H,'F='//3(7F10.4//))
00018100 C WRITE(6,1102) ((VOIP(I,J),J=1,6),I=1,4)
00018200 C1102 FORMAT(1H,'VOIP='//4(6F10.4//))
00018300 C WRITE(6,1103) ((AZETA(I,J),J=1,6),I=1,4)
00018400 C1103 FORMAT(1H,'AZETA='//4(6F10.4//))
00018500 DO 60 I=1,NATOMS
00018600 LLIM(I) = N+1
00018700 L=1
00018800 IF (AN(I).LT.11) GO TO 20
00018900 10 J=N+4
00019000 CZ(I)=AN(I)-10
00019100 GO TO 50
00019200 20 IF (AN(I).LT.3) GO TO 40
00019300 30 J=N+4
00019400 CZ(I) = AN(I)-2
00019500 GO TO 50
00019600 40 J=N+1
00019700 CZ(I)= AN(I)
00019800 50 CONTINUE
00019900 JLIM(I) = N
00020000 60 CONTINUE
00020100 C-----ASSIGNMENT OF ANGULAR MOMENTUM QUANTUM NOS. TO ATOMIC ORBITALS
00020200 LC(1)=0
00020300 LC(2)=1
00020400 LC(3)=1
00020500 LC(4)=1
00020600 LC(5)=2
00020700 LC(6)=2
00020800 LC(7)=2
00020900 LC(8)=2
00021000 LC(9)=2
00021100 IC(1)=0
00021200 IC(2)=1
00021300 IC(3)=-1
00021400 IC(4)=0
00021500 IC(5)=0
00021600 IC(6)=1
00021700 IC(7)=-1
00021800 IC(8)=2
00021900 IC(9)=-2
00022000 C-----FILL U ARRAY---U(J) IDENTIFIES THE ATOM TO WHICH ORBITAL J IS
00022100 C-----ATTACHED E.G. ORBITAL 32 ATTACHED TO ATOM 7, ETC.
00022200 C-----ASSIGNMENT OF ORBITAL EXPONENTS TO ATOMS BY SLATERS RULES
00022300 IC(8)=2 ;NC(14)=3
00022400 DO 92 K=1,NATOMS
00022500 LLK=LLIM(K)
00022600 JLK=ULIM(K)
00022700 ANK=AN(K)
00022800 NORBK=ULK-LLK+1
00022900 DO 92 I=1,NORBK
00023000 LLKP=LLK+I-1
00023100 LCZETA=LC(I)+1
00023200 J(LLKP)=AZETA(LCZETA,K)
00023300 J(LLKP)=K
00023400 92 CONTINUE
00023500 C-----STEP THRU PAIRS OF ATOMS

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00023600      JJ 320 IF=1,7
00023700      NIF=0
00023800      JO 320 K=1,NATOMS
00023900      JO 320 L=K,NATOMS
00024000      JO 100 I=1,3
00024100      C1(I)=POS(I,K)
00024200      100 C2(I)=POS(I,L)+F(I,IF)
00024300 C-----CALCULATE UNIT VECTOR ALONG INTERATOM AXIS,E
00024400      CALL RELVEC(R,E,C1,C2)
00024500      IF(R.GT.2*BAU+0.1) GO TO 320
00024600      IF(IF.EQ.1) GO TO 102
00024700      NIF=NIF+1
00024800      NZS(1,NIF,IF)=K
00024900      NZS(2,NIF,IF)=L
00025000      102 CONTINUE
00025100      LLK = LLIM(K)
00025200      LLL = LLIM(L)
00025300      JLK = ULIM(K)
00025400      JLL = ULIM(L)
00025500      NORBK=ULK-LLK+1
00025600      NORBL=ULL-LLL+1
00025700      ANK=AN(K)
00025800      ANL=AN(L)
00025900 C-----LOOP THRU PAIRS OF BASIS FUNCTIONS, ONE ON EACH ATOM
00026000      JJ 200 I=1,NORBK
00026100      JJ 200 J=1,NORBL
00026200      IF(K.EQ.L.AND.IF.EQ.1) GO TO 160
00026300      110 IF(MC(I).NE.MC(J)) GO TO 150
00026400      120 IF(MC(I).LT.0) GO TO 140
00026500      LLKP=LLK+I-1 ; LLLP=LLL+J-1
00026600      130 PAIRS(I,J)= SQRT((Q(LLKP)*R)**(2*NC(ANK)+1)*(Q(LLLP)*R)**(2*NC
00026700      1)+1)/(FACT(2*NC(ANK))*FACT(2*NC(ANL)))*(-1.00)**(LC(J)+MC(J))
00026800      2*SS(NC(ANK),LC(I),MC(I),NC(ANL),LC(J),Q(LLKP)*R,Q(LLLP)*R)
00026900      GO TO 190
00027000      140 PAIRS(I,J)=PAIRS(I-1,J-1)
00027100      GO TO 190
00027200      150 PAIRS(I,J)=0.000
00027300      GO TO 190
00027400      160 IF (I.EQ.J) GO TO 170
00027500      180 PAIRS(I,J)=0.000
00027600      GO TO 190
00027700      170 PAIRS(I,J)=1.000
00027800      190 CONTINUE
00027900      200 CONTINUE
00028000      LCULK=LC(NORBK)
00028100      LCULL=LC(NORBL)
00028200      MAXL=MAX0(LCULK,LCULL)
00028300      IF(R.GT.0.00000100) GO TO 220
00028400      210 GO TO 250
00028500 C-----ROTATE INTEGRALS FROM DIATOMIC BASIS TO MOLECULAR BASIS
00028600      220 CALL HARMTR(T,MAXL,E)
00028700      JJ 230 I=1,NORBK
00028800      JJ 230 J=1,NORBL
00028900      TEMP(I,J) = 0.00
00029000      JJ 230 KK=1,NORBL
00029100      TEMP(I,J) = TEMP(I,J)+T(J,KK)*PAIRS(I,KK)
00029200      230 CONTINUE
00029300      JO 240 I=1,NORBK
00029400      JO 240 J=1,NORBL
00029500      PAIRS(I,J) = 0.00
00029600      JO 240 KK=1,NORBK
00029700      PAIRS(I,J) = PAIRS(I,J)+T(I,KK)*TEMP(KK,J)
00029800      240 CONTINUE
00029900 C-----FILL S MATRIX
00030000      250 CONTINUE
00030100      IF(IF.NE.1) GO TO 262

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00030200      DO 260 I=1,NORBK
00030300      LLLP=LLK+I-1
00030400      DO 260 J=1,NORBL
00030500      LLLP=LLL+J-1
00030600      250 S(LLKP,LLLP)=PAIRS(I,J)
00030700      GO TO 320
00030800      252 CONTINUE
00030900      DO 264 I=1,NORBK
00031000      DO 264 J=1,NORBL
00031100      254 SOUTER(I,J,NIF,IF)=PAIRS(I,J)
00031200      320 CONTINUE
00031300      330 CONTINUE
00031400      RETURN
00031500      END
00031600      SUBROUTINE SETSH
00031700      IMPLICIT COMPLEX*16 (Z)
00031800      COMMON/COM01/ ZS(40,40),ZH(40,40)
00031900      COMMON/VOIP/ VOIP(4,6),AZETA(4,6),CONST,OM1,OM2,VP(4,6),AZP(4,
00032000      COMMON/ARRAYS/S(40,40),Y(9,5,203),Z(17,45)
00032100      COMMON/INFOJ/ AN(35),NDUT
00032200      COMMON/INFO1/CZ(35),J(80),ULIM(35),LLIM(35),ULK,ULL,ANL,ANK
00032300      COMMON /SOUTER/SOUTER(10,10,3,7),NZS(2,3,7)
00032400      COMMON/NATOMS/ NATOMS,N,NK
00032500      COMMON/VECK/VECK(3)
00032600      COMMON/POS/ PUS(3,6),F(3,7),BONDL,AU,BAU,NC(18),LC(10),MC(10)
00032700      COMMON /CON/CSSSS,CSSSX,CSSXX,COOSS,COOSX,COOXX,CSS,CSX,CXS,CX
00032800      INTEGER AN,ULIM,ULK,ULL,CZ,U,ANL,ANK
00032900      REAL*4 Z
00033000      DEBUG,SUBCHK
00033100      C      WRITE(6,100) (((NZS(I,J,K),J=1,3),I=1,2),K=1,7)
00033200      C 100 FORMAT(1H0,'NZS=',/1H ,2(3I2/1H ))
00033300      C      WRITE(6,101) (((SOUTER(I,J,K,L),J=1,4),I=1,4),K=1,3),L=1,7)
00033400      C 101 FORMAT(1H0,'SOUTER=',/1H ,4(4F10.4/1H ))
00033500      DO 2 I=1,N
00033600      DO 2 J=I,N
00033700      2 ZS(I,J)=S(I,J)
00033800      DO 3 IF=2,7
00033900      ZTHETA=0.
00034000      DO 4 I=1,3
00034100      4 ZTHETA=ZTHETA+VECK(I)*F(I,IF)*(0.,1.)
00034200      ZEXP=EXP(ZTHETA)
00034300      C      WRITE(6,102) ZTHETA,ZEXP,(F(I,IF),I=1,3),IF
00034400      C 102 FORMAT(1H , 'ZTHETA,ZEXP=',4F10.4/1H , 'F,IF=',3F10.4,I3)
00034500      C-----SET UP S MATRIX FOR A CERTAIN K-----
00034600      DO 5 NIF=1,3
00034700      IF(NZS(1,NIF,IF).EQ.0.) GO TO 3
00034800      K=NZS(1,NIF,IF)
00034900      L=NZS(2,NIF,IF)
00035000      LLK=LLIM(K)
00035100      LLL=LLIM(L)
00035200      JLK=ULIM(K)
00035300      JLL=ULIM(L)
00035400      NORBK=ULK-LLK+1
00035500      NORBL=ULL-LLL+1
00035600      DO 6 I=1,NORBK
00035700      DO 6 J=1,NORBL
00035800      LLLP=LLK+I-1
00035900      LLLP=LLL+J-1
00036000      6 ZS(LLKP,LLLP)=ZS(LLKP,LLLP)+SOUTER(I,J,NIF,IF)*ZEXP
00036100      5 CONTINUE
00036200      3 CONTINUE
00036300      C-----CALCULATION OF H MATRIX-----
00036400      DO 8 K=1,NATOMS
00036500      DO 8 L=K,NATOMS
00036600      LLK=LLIM(K)
00036700      LLL=LLIM(L)

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0036800      ULK=ULIM(K)
0036900      ULL=ULIM(L)
0037000      NORBK=ULK-LLK+1
0037100      NORBL=ULL-LLL+1
0037200      DO 9 I=1,NORBK
0037300      DO 9 J=1,NORBL
0037400          LLKP=LLK+I-1
0037500          LLLP=LLL+J-1
0037600          LCI=LC(I)+1
0037700          LCJ=LC(J)+1
0037800          IF(LLKP.EQ.LLLP) GO TO 10
0037900          LLKPU=U(LLKP) ; LLLPU=U(LLLP)
0038000          IF(LLKPU.LE.2.AND.LLLPU.LE.2) GO TO 11
0038100          IF(LLKPU.GE.3.AND.LLLPU.GE.3) GO TO 12
0038200          IF(LCI.EQ.1.AND.LCJ.EQ.1) GO TO 16
0038300          IF(LCI.GE.2.AND.LCJ.GE.2) GO TO 17
0038310          IF((LLKPU.LE.2.AND.LCI.EQ.1).OR.
0038320      *      (LLLPU.LE.2.AND.LCJ.EQ.1)) GO TO 18
0038330          CONST=CXS ; GO TO 13
0038340      18      CONST=CSX ; GO TO 13
0038500      16      CONST=CSS ; GO TO 13
0038600      17      CONST=CXX ; GO TO 13
0038610      11      IF(LCI.EQ.1.AND.LCJ.EQ.1) GO TO 22
0038620          IF(LCI.GE.2.AND.LCJ.GE.2) GO TO 23
0038630          CONST=CSSSX ; GO TO 13
0038640      22      CONST=CSSSS ; GO TO 13
0038650      23      CONST=CSSSX ; GO TO 13
0038710      12      IF(LCI.EQ.1.AND.LCJ.EQ.1) GO TO 20
0038720          IF(LCI.GE.2.AND.LCJ.GE.2) GO TO 21
0038730          CONST=COOSX ; GO TO 13
0038740      20      CONST=COOSS ; GO TO 13
0038750      21      CONST=COOXX ; GO TO 13
0038900      13      CONTINUE
0039000      ZH(LLKP,LLLP)=-ZS(LLKP,LLLP)*(VOIP(LCI,K)+VOIP(LCJ,L))*
0039100      *      CONST/2.
0039200          GO TO 9
0039300      10      ZH(LLKP,LLKP)=-VOIP(LCI,K)
0039400      9      CONTINUE
0039500      8      CONTINUE
0039600      C      CALL MATOUT(4)
0039700      C-----SYMMETRIZATION OF S AND H MATRIX-----
0039800          DO 7 I=1,N
0039900          DO 7 J=I,N
0040000              ZS(J,I)=CONJG(ZS(I,J))
0040100              ZH(J,I)=CONJG(ZH(I,J))
0040200      7      CONTINUE
0040300      C      DO 15 I=1,N
0040400      C      DO 14 J=1,N
0040500      C          ZS(I,J)=0.
0040600      C      14      CONTINUE
0040700      C          ZS(I,I)=1.
0040800      C      15      CONTINUE
0040900          RETURN ; END
0041000          SUBROUTINE SOLUT
0041100          COMPLEX*16 S,H,PM,RM,SUM,DEN
0041200          REAL*8 EI,WW,V
0041300          DIMENSION LW(40),EI(40),WW(40,7)
0041400      C-----***      SOLUTION OF SECULAR DETERMINANT      ***
0041500          COMMON/COM01/ S(40,40),H(40,40)
0041600          COMMON/COM02/ PM(40,40),RM(40,40)
0041700          COMMON/COM03/ V(40),W(20,40)
0041800          COMMON/COM19/ IRET,ISTOP,NNAT
0041900          COMMON/NATOMS/ NATOMS,N,NK
0042000          DEBUG,SUBCHK
0042100      C      COMPLEX*8 ZH(24,24)
0042200      C      DO 3 I=1,24

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00042300 C      DO 3 J=1,24
00042400 C      3 ZH(I,J)=H(I,J)
00042500      DO 2 I=1,N
00042600      DO 2 J=1,N
00042700      2 RM(I,J)=S(I,J)
00042800 C-----
00042900      EPS=1.E-15
00043000      CALL DEIGCH(S,N,40,-N,N,EPS,WW,LW,EI,PM)
00043100 C-----
00043200      DO 10 I=1,N
00043300      IF(EI(I) .LE.0.0) GO TO 41
00043400 C-----
00043500      10 V(I)=1.0/SQRT(EI(I) )
00043600      DO 13 I=1,N
00043700      DO 12 J=1,N
00043800      12 S(I,J)=PM(I,J)*V(J)
00043900      13 CONTINUE
00044000 C-----
00044100      DO 16 I=1,N
00044200      DO 15 J=1,N
00044300      PM(I,J)=0.0
00044400      DO 14 K=1,N
00044500      14 PM(I,J)=PM(I,J)+CONJG(S(K,I))*H(K,J)
00044600      15 CONTINUE
00044700      16 CONTINUE
00044800      DO 19 I=1,N
00044900      DO 18 J=1,N
00045000      H(I,J)=0.0
00045100      DO 17 K=1,N
00045200      17 H(I,J)=H(I,J)+PM(I,K)*S(K,J)
00045300      18 CONTINUE
00045400      19 CONTINUE
00045500 C-----
00045600 C      DO 3333 I=1,N
00045700 C      DO 3333 J=1,N
00045800 C3333 H(J,I)=CONJG(H(I,J))
00045900      CALL DEIGCH(H,N,40,-N,N,EPS,WW,LW,V,PM)
00046000 C-----
00046100      DO 21 I=1,N
00046200      21 V(NK-1,I)=V(I)
00046300      DO 52 I=1,N
00046400      DO 51 J=1,N
00046500      H(I,J)=0.0
00046600      DO 50 K=1,N
00046700      50 H(I,J)=H(I,J)+S(I,K)*PM(K,J)
00046800      51 CONTINUE
00046900      52 CONTINUE
00047000 C-----
00047100      DO 25 I=1,N
00047200      SUM=0.0
00047300      DO 24 J=1,N
00047400      DO 23 K=1,N
00047500      23 SUM=SUM+CONJG(H(J,I))*H(K,I)*RM(J,K)
00047600      24 CONTINUE
00047700      DEN=SQRT(SUM)
00047800      DO 26 L=1,N
00047900      26 S(L,I)=H(L,I)/DEN
00048000      25 CONTINUE
00048100 C      DO 31 I=1,N
00048200 C      DO 31 J=1,N
00048300 C      31 H(I,J)=0.
00048400 C      DO 32 I=1,N
00048500 C      DO 32 J=1,N
00048600 C      DO 32 K=1,N
00048700 C      32 H(I,J)=H(I,J)+(ZH(I,K)-V(J)*RM(I,K))*S(K,J)
00048800 C      WRITE(6,33)

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00048900 C 33 FORMAT(' (H-ES)X=' )
00049000 C CALL MATOUT(4)
00049100 GO TO 60
00049200 41 WRITE(6,42)
00049300 42 FORMAT(' OVERLAP MATRIX IS NON-POSITIVE. STOP')
00049400 STOP
00049500 60 RETURN
00049600 END
00049700 SUBROUTINE DENSIT
00049800 COMPLEX*16 S,H,PM,RM
00049900 REAL*8 V
00050000 C-----*** CALC. OF POPULATIONS ***
00050100 COMMON/COM01/ S(40,40),H(40,40)
00050200 COMMON/COM02/ PM(40,40),RM(40,40)
00050300 COMMON/COM03/ V(40),W(20,40)
00050400 COMMON/COM17/ TOEL(30),EN(40)
00050500 COMMON/COM21/ CON,SUMEN,CONSK
00050600 COMMON/NATOMS/ NATOMS,N,NK
00050700 COMMON/INFO/ AN(35),NOUT
00050800 COMMON/COM13/ TDP(10,10)
00050900 COMMON/COM19/ IRET,ISTOP,NNAT
00051000 COMMON/INFO1/CZ(35),U(80),ULIM(35),LLIM(35),ULK,ULL,ANL,ANK
00051100 INTEGER AN,ULIM,ULK,ULL,CZ,U,ANL,ANK
00051200 SUMEN=0.0
00051300 DO 1 I=1,N
00051400 1 SUMEN=SUMEN+EN(I)*V(I)
00051500 DO 21 I=1,N
00051600 PM(I,I)=0.0
00051700 DO 21 J=1,N
00051800 DO 21 K=1,N
00051900 21 PM(I,I)=PM(I,I)+REAL(CONJG(S(I,J))*S(K,J)*RM(I,K))*EN(J)
00052000 NI=N-1
00052100 DO 22 I=1,NI
00052200 IMA=I+1
00052300 DO 22 J=IMA,N
00052400 PM(I,J)=0.0
00052500 DO 22 K=1,N
00052600 22 PM(I,J)=PM(I,J)+2.0*REAL(RM(I,J)*CONJG(S(I,K))*S(J,K))*EN(K)
00052700 DO 2 I=1,NI
00052800 IJK=I+1
00052900 DO 2 J=IJK,N
00053000 2 PM(J,I)=PM(I,J)
00053100 C-----*** CALC. OF TOTAL ***
00053200 NNAT=NATOMS
00053300 NI=N-1
00053400 NNATA=NNAT-1
00053500 DO 31 L=1,NNATA
00053600 LKM=L+1
00053700 DO 31 K=LKM,NNAT
00053800 TDP(L,K)=0.0
00053900 DO 32 I=1,NI
00054000 IMJ=I+1
00054100 DO 32 J=IMJ,N
00054200 IF(U(I).NE.L) GO TO 32
00054300 IF(U(J).NE.K) GO TO 32
00054400 TDP(L,K)=TDP(L,K)+PM(I,J)
00054500 TDP(K,L)=TDP(L,K)
00054600 32 CONTINUE
00054700 31 CONTINUE
00054800 DO 3 I=1,NNAT
00054900 TDP(I,I)=0.0
00055000 DO 4 J=1,N
00055100 IF(U(J).NE.I) GO TO 4
00055200 TDP(I,I)=TDP(I,I)+PM(J,J)
00055300 4 CONTINUE
00055400 3 CONTINUE

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00055500 WRITE(6,40) ((TDP(I,J),J=1,NATOMS),I=1,NATOMS)
00055600 40 FORMAT(1H0,'TDP=' /1H ,6(6F10.4/1H ))
00055700 RETURN
00055800 END
00055900 SUBROUTINE CHANGE
00056000 C-----CHANGING OF VOIP AND AZETA-----
00056100 REAL*8 V
00056200 COMMON/COM03/ V(40),W(20,40)
00056300 COMMON/NATOMS/ NATOMS,N,NK
00056400 COMMON/VOIP/ VOIP(4,6),AZETA(4,6),CONST,OM1,OM2,VP(4,6),AZP(4,
00056500 COMMON/COM17/TOEL(30),EN(40)
00056600 COMMON/COM13/ TDP(10,10)
00056700 RETURN ;END
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BER BETA JF A1402.S.FORT LIST END
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BER ALPHA JF A1402.S.FORT

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00000100 PROGRAM ALPHA
00000200 COMMON/COM01/ ZS(40,40),ZH(40,40)
00000300 COMMON/ARRAYS/S(40,40),Y(9,5,203),Z(17,45)
00000400 COMMON/COM03/ V(40),J(20,40)
00000500 COMMON/VECK/VECK(3)
00000600 C-----GENERATION OF MATRIX VOIP AND AZETA-----
00000700 COMMON/VOIP/ VOIP(4,9),AZETA(4,9),CONST,OM1,OM2,VP(4,9),AZP(4,9)
00000800 COMMON/POS/ POS(3,9),F(3,13),BONDL,AU,BAU,NC(18),LC(10),MC(10)
00000900 COMMON/COM17/TOEL(30),EN(40)
00001000 COMMON/COM13/ TDP(10,10)
00001100 COMMON/INFO/ AN(40),NOUT
00001110 COMMON/INFO1/CZ(40),U(80),ULIM(40),LLIM(40),ULK,ULL,ANL,ANK
00001200 COMMON/NATOMS/ NATOMS,N,НК
00001300 COMMON /TM/TM(3,3),GM(3,3),POST(3,9),AK(3),NF(3,13),IFMAX,NUNIT
00001400 COMMON /CON/CSSSS,CSSSX,CSSXX,COOSS,COOSX,COOXX,CSS,CSX,CXS,CXX
00001410 INTEGER AN,ULIM,ULK,ULL,CZ,U,ANL,ANK
00001420 COMPLEX*16 ZS,ZH
00001500 REAL*8 VM(40)
00001600 REAL*8 V
00001605 DIMENSION OVM(40)
00001610 DIMENSION AKM(3,6)
00001620 DATA AKM/3*,0.,.3908,.2256,.0,.3908,.2256,.3080,
00001630 * .0,.0,.3080,.2256,.0,.0,.2256,.0,.3080/
00001800 DATA AN/14,14,14,8,8,8,8,8,8/,NATOMS/9/
00001900 DATA EN/24*2./,TOEL/4.,4.,4.,6.,6.,6.,6.,6.,6./,OM1,OM2/.5,.5/
00002000 DATA CONST/1.75/,IFMAX,NUNIT/13,9/
00002100 C DATA VOIP/14.95,7.78,2.05,9*0.,
00002200 C * 32.38,15.84/
00002300 C DATA VOIP/12.88,7.08,2.05,9*0.,
00002400 C * 32.38,19.58/
00002500 C DATA AZETA/1.38,1.38,1.38,9*0.,
00002600 C * 2.28,2.28/
00002700 C DATA AZETA/1.56,1.56,1.38,9*0.,2.1,2.1/
00002800 C DATA AZETA/1.6344,1.4284,1.38,9*0.,2.246,2.227/
00002900 DATA TM/4.254,0.,0.,-2.456,4.912,0.,0.,0.,5.396/,
00003000 * GM/1.477,0.7385,0.,0.,1.279,0.,0.,0.,1.1643/
00003100 DATA POST/0.465,0.,0.,0.535,0.535,0.333,0.,0.465,0.667,
00003200 * 0.415,0.272,0.120,0.585,0.857,0.213,0.857,0.585,0.453,
00003300 * 0.143,0.728,0.880,0.728,0.143,0.787,0.272,0.415,0.547/
00003400 DATA NF/0,0,0,1,0,0,0,1,0,0,0,1,-1,0,0,0,-1,0,0,0,-1,
00003500 * 0,-1,-1,0,-1,1,0,1,1,0,1,-1,-1,0,1,1,0,-1/
00003600 DEBUG,SUBCHK
00003700 C-----MAKING TM AND GM MATRIX-----
00003800 AU=.529167
00003900 DO 31 I=1,3
00004000 DO 31 J=1,3
00004100 TM(I,J)=TM(I,J)/AU
00004200 31 GM(I,J)=GM(I,J)*AU
00004300 C-----MAKING POSITION AND F(TRANSLATION) MATRIX-----
00004400 DO 32 I=1,3
00004500 DO 32 J=1,9
00004600 POS(I,J)=0.
00004700 DO 32 K=1,3
00004800 32 POS(I,J)=POS(I,J)+TM(K,I)*POST(K,J)
00004900 DO 33 I=1,3
00005000 DO 33 J=1,13
00005100 F(I,J)=0.
00005200 DO 33 K=1,3

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0005300 33 F(I,J)=F(I,J)+TM(K,I)*NF(K,J)
0005400 C-----VOIP,AZETA,C,MODE,ETC INPUT-----
0005500 1000 READ(5,14) VOIP(1,1),VOIP(2,1),VOIP(1,4),VOIP(2,4)
0005600 14 FORMAT(4F10.0)
0005700 READ(5,14) AZETA(1,1),AZETA(2,1),AZETA(1,4),AZETA(2,4)
0005800 READ(5,5) CSSSS,CSSSX,CSSXX,COOSS,COOSX,COOXX
0005900 5 FORMAT(3F10.0)
0006000 READ(5,8) CSS,CSX,CXS,CXX
0006100 8 FORMAT(4F10.0)
0006200 READ(5,9) MODE,MOD1,MNK,ISOL,ITDP,IGRAPH,IHAM
0006300 9 FORMAT(7I2)
0006310 IF(MODE.EQ.0) STOP
0006320 REWIND 30
0006400 CALL COEFFT
0006500 C IF(MODE.NE.5) GO TO 120
0006600 C NNN=0
0006700 C 17 NNN=NNN+1
0006800 C REWIND 30
0006900 C GO TO (110,111,112,113,121,122,123,124,
0007000 C * 125,126,127,128,129,130,131),NNN
0007100 C 110 VOIP(1,1)=VOIP(1,1)-.5 ;GO TO 120
0007200 C 111 VOIP(1,1)=VOIP(1,1)+.5 ;VOIP(2,1)=VOIP(2,1)-.5 ;GO TO 120
0007300 C 112 VOIP(2,1)=VOIP(2,1)+.5 ;VOIP(1,4)=VOIP(1,4)-.5 ;GO TO 120
0007400 C 113 VOIP(1,4)=VOIP(1,4)+.5 ;VOIP(2,4)=VOIP(2,4)-.5 ;GO TO 120
0007500 C 121 VOIP(2,4)=VOIP(2,4)+.5 ;CSSSS=CSSSS-.05 ;GO TO 120
0007600 C 122 CSSSS=CSSSS+.05 ;CSSSX=CSSSX-.05 ;GO TO 120
0007700 C 123 CSSSX=CSSSX+.05 ;CSSXX=CSSXX-.05 ;GO TO 120
0007800 C 124 CSSXX=CSSXX+.05 ;COOSS=COOSS-.05 ;GO TO 120
0007900 C 125 COOSS=COOSS+.05 ;COOSX=COOSX-.05 ;GO TO 120
0008000 C 126 COOSX=COOSX+.05 ;COOXX=COOXX-.05 ;GO TO 120
0008100 C 127 COOXX=COOXX+.05 ;CSS=CSS-.05 ;GO TO 120
0008200 C 128 CSS=CSS+.05 ;CSX=CSX-.05 ;GO TO 120
0008300 C 129 CSX=CSX+.05 ;CXS=CXS-.05 ;GO TO 120
0008400 C 130 CXS=CXS+.05 ;CXX=CXX-.05 ;GO TO 120
0008500 C 131 STOP 0001
0008600 C 120 CONTINUE
0008700 C-----GENERATION OF MATRIX VOIP AND AZETA-----
0008800 DO 10 I=1,2
0008900 VOIP(I,2)=VOIP(I,1)
0009000 AZETA(I,2)=AZETA(I,1)
0009100 VOIP(I,3)=VOIP(I,1)
0009200 AZETA(I,3)=AZETA(I,1)
0009300 DO 10 J=5,9
0009400 VOIP(I,J)=VOIP(I,4)
0009500 AZETA(I,J)=AZETA(I,4)
0009600 10 CONTINUE
0009700 WRITE(6,15) VOIP(1,1),VOIP(2,1),VOIP(1,4),VOIP(2,4)
0009800 15 FORMAT(' VOIP=',4F10.3)
0009900 WRITE(6,16) AZETA(1,1),AZETA(2,1),AZETA(1,4),AZETA(2,4)
0010000 16 FORMAT(' AZETA=',4F10.3)
0010100 WRITE(6,7) CSSSS,CSSSX,CSSXX,COOSS,COOSX,COOXX
0010200 7 FORMAT(' CSSSS,CSSSX,CSSXX,COOSS,COOSX,COOXX=',6F10.3)
0010300 WRITE(6,13) CSS,CSX,CXS,CXX
0010400 13 FORMAT(' CSS,CSX,CXS,CXX=',4F10.3)
0010500 CALL INTGRL
0010510 IF(IHAM.EQ.0) GO TO 140
0010600 C----- WRITING OUT S-----
0010700 WRITE(6,350)
0010800 350 FORMAT(1H1,1X,23HOVERLAP INTEGRAL MATRIX)
0010900 CALL MATOUT(1)
0011100 C-----CALCULATION OF H MATRIX-----
0011200 DO 408 K=1,NATOMS
0011300 DO 408 L=K,NATOMS
0011400 LLK=LLIM(K)
0011500 LLL=LLIM(L)
0011600 ULK=ULIM(K)

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00011700      ULL=ULIM(L)
00011800      NORBK=ULK-LLK+1
00011900      NORBL=ULL-LLL+1
00012000      DO 409 I=1,NORBK
00012100      DO 409 J=1,NORBL
00012200          LLKP=LLK+I-1
00012300          LLLP=LLL+J-1
00012400          LCI=LC(I)+1
00012500          LCJ=LC(J)+1
00012600          IF(LLKP, EQ, LLLP) GO TO 410
00012700          LLKPU=U(LLKP) ; LLLPU=U(LLLPU)
00012800          IF(LLKPU, LE, 3, AND, LLLPU, LE, 3) GO TO 411
00012900          IF(LLKPU, GE, 4, AND, LLLPU, GE, 4) GO TO 412
00013000          IF(LCI, EQ, 1, AND, LCJ, EQ, 1) GO TO 416
00013100          IF(LCI, GE, 2, AND, LCJ, GE, 2) GO TO 417
00013200          IF((LLKPU, LE, 3, AND, LCI, EQ, 1), OR,
00013300      *          (LLLPU, LE, 3, AND, LCJ, EQ, 1)) GO TO 418
00013400          CONST=CXS ; GO TO 413
00013500      418      CONST=CSX ; GO TO 413
00013600      416      CONST=CSS ; GO TO 413
00013700      417      CONST=CXX ; GO TO 413
00013800      411      IF(LCI, EQ, 1, AND, LCJ, EQ, 1) GO TO 422
00013900          IF(LCI, GE, 2, AND, LCJ, GE, 2) GO TO 423
00014000          CONST=CSSSX ; GO TO 413
00014100      422      CONST=CSSSS ; GO TO 413
00014200      423      CONST=CSSXX ; GO TO 413
00014300      412      IF(LCI, EQ, 1, AND, LCJ, EQ, 1) GO TO 420
00014400          IF(LCI, GE, 2, AND, LCJ, GE, 2) GO TO 421
00014500          CONST=COOSX ; GO TO 413
00014600      420      CONST=COOSS ; GO TO 413
00014700      421      CONST=COOXX ; GO TO 413
00014800      413      CONTINUE
00014900          ZH(LLKP, LLLP)=-S(LLKP, LLLP)*(VOIP(LCI, K)+VOIP(LCJ, L))*
00015000      *          CONST/2.
00015100          GO TO 409
00015200      410      ZH(LLKP, LLKP)=-VOIP(LCI, K)
00015300      409      CONTINUE
00015400      408      CONTINUE
00015500          WRITE(6, 400) NK
00015600      400      FORMAT(' HAMILTONIAN MATRIX AT NK=', I5)
00015700          CALL MATOUT(4)
00015800      140      CONTINUE
00015900          IK=1
00016000      C-----SCANNING OF K VECTOR-----
00016100          2 CONTINUE
00016200          IF(NK-1, GT, MNK) GO TO 1
00016210          GO TO (161, 162, 163, 164, 165, 166, 167, 168, 168,
00016220      *          190, 191, 192, 193) , MODE
00016400      161      INIK=1 ; LASK=2 ; GO TO 170
00016500      162      INIK=2 ; LASK=3 ; GO TO 170
00016600      163      INIK=3 ; LASK=4 ; GO TO 170
00016700      164      INIK=4 ; LASK=1 ; GO TO 170
00016800      165      INIK=1 ; LASK=5 ; GO TO 170
00016900      166      INIK=5 ; LASK=6 ; GO TO 170
00017000      167      INIK=6 ; LASK=4 ; GO TO 170
00017100      168      STOP
00017200      170      CONTINUE
00017300          AK1=0.
00017400          DO 180 I=1,3
00017500      180      AK1=AK1+(AKM(I, INIK)-AKM(I, LASK))*#2
00017600          AK1=SQRT(AK1)
00017700          DO 181 I=1,3
00017800      181      VECK(I)=(AKM(I, INIK)*(MNK-NK+1.0001)
00017900      *          +AKM(I, LASK)*(NK-1.)) / (MNK+0.0001)
00018200          IK=NK+1
00018300          CALL SETSH

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0018400 C WRITE(6,351) NK
0018500 C 351 FORMAT(' BLOCH OVERLAP MATRIX AT NK=',I5)
0018600 C CALL MATOUT(2)
0018700 C WRITE(6,352) NK
0018800 C 352 FORMAT(' BLOCH HAMILTONIAN MATRIX AT NK=',I5)
0018900 C CALL MATOUT(4)
0019000 CALL SOLUT
0019100 WRITE(6,12) (VECK(I),I=1,3),(V(I),I=1,N)
0019200 12 FORMAT(' EIGENVALUES AT NK=',3F10.3,' ARE',/(6F9.4))
0019210 C-----DIFFERENCE-----
0019220 GO TO (40,41,42,42),MOD1
0019400 41 WRITE(30) (V(I),I=1,N);GO TO 40
0019500 42 READ(30) (VM(I),I=1,N)
0019600 DO 43 I=1,N
0019700 43 VM(I)=V(I)-VM(I)
0019800 WRITE(6,102) NK,(VM(I),I=1,N)
0019900 102 FORMAT(' DIFFERENCE AT NK=',I5,/(6F9.4))
0020000 IF(MOD1.LE.3) GO TO 40
0020100 WRITE(40) (VM(I),I=1,N)
0020200 40 CONTINUE
0020210 C-----ISOL-----
0020300 IF(ISOL.EQ.0) GO TO 103
0020400 WRITE(6,353) NK
0020500 353 FORMAT(' SOLUTION AT NK=',I5)
0020600 CALL MATOUT(3)
0020700 103 CONTINUE
0020710 C-----TDP-----
0020800 IF(ITDP.EQ.0) GO TO 44
0020900 CALL DENSIT
0021000 44 CONTINUE
0021100 GO TO 2
0021200 1 CONTINUE
0021300 IF(IGRAPH.EQ.0) GO TO 1000
0021500 MNK1=MNK+1
0021600 WRITE(20,51) N,MNK1,AK1
0021700 51 FORMAT(2I10,F10.4)
0021800 WRITE(20,50) ((W(I,J),J=1,N),I=1,MNK1)
0021900 50 FORMAT(24F10.4)
0021902 STOP 0002
0021904 C-----DDS CALCULATION-----
0021906 190 IKZ=1 ;LKZ=2 ;GO TO 194
0021908 191 IKZ=3 ;LKZ=4 ;GO TO 194
0021910 192 IKZ=5 ;LKZ=6 ;GO TO 194
0021912 193 IKZ=7 ;LKZ=7 ;GO TO 194
0021914 194 CONTINUE
0021916 NK=0
0021918 DO 195 KZ=IKZ,LKZ
0021920 VECK(3)=0.0238+(KZ-1)*0.0434
0021922 DO 195 KX=1,9
0021924 VECK(1)=0.0217+(KX-1)*0.0434
0021926 PORN=0.5773*VECK(1)-0.026
0021928 IF(PORN.LT.0.) GO TO 195
0021930 LKY=PORN/0.0434 ;LKY=LKY+1
0021932 DO 195 KY=1,LKY
0021934 VECK(2)=0.0260+(KY-1)*0.0434
0021936 NK=NK+1
0021938 CALL SETSH
0021940 CALL SOLUT
0021942 WRITE(6,197) NK,(VECK(I),I=1,3),(V(I),I=1,N)
0021944 197 FORMAT(' NK=',I4,',K=',3F10.3,/(6F9.4))
0021946 DO 196 I=1,N
0021948 196 JVM(I)=V(I)
0021950 WRITE(50) (VJM(I),I=1,N)
0021952 195 CONTINUE
0022000 STOP ;END
0022100 SUBROUTINE INTGRL

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0022200 IMPLICIT REAL*4(A-H,O-Z)
0022300 C-----ATOMIC INTEGRALS FOR CNDO CALCULATIONS
0022400 COMMON/ARRAYS/S(40,40),Y(9,5,203),Z(17,45)
0022500 COMMON/INFO/ AN(40),NOUT
0022600 COMMON/NATOMS/ NATOMS,N,NK
0022700 COMMON/INFO1/CZ(40),J(80),ULIM(40),LLIM(40),ULK,ULL,ANL,ANK
0022800 COMMON/GAB/T(9,9),PAIRS(9,9),TEMP(9,9),C1(3),C2(3)
0022900 COMMON/AUXINT/A(17),d(17)
0023000 COMMON /SOUTER/SOUTER(4,4,4,13),NZS(2,4,13)
0023100 COMMON/VOIP/ VOIP(4,9),AZETA(4,9),CONST,OM1,OM2,VP(4,9),AZP(4,9)
0023200 COMMON/POS/ POS(3,9),F(3,13),BONDL,AU,BAU,NC(18),LC(10),MC(10)
0023300 COMMON /TM/TM(3,3),GM(3,3),POST(3,9),AK(3),NF(3,13),IFMAX,NUNIT
0023400 DIMENSION P(80,80)
0023500 DIMENSION E(3),Q(40)
0023600 EQUIVALENCE (P(1),Y(1))
0023700 INTEGER AN,ULIM,ULK,ULL,CZ,U,ANL,ANK
0023800 C-----DETERMINATION OF SIZE OF AO BASIS IN AND CORE CHARGE CZ
0023900 DEBUG,SUBCHK
0024000 N=0
0024100 C WRITE(6,1100) ((POS(I,J),J=1,9),I=1,3)
0024200 C1100 FORMAT(1H,'POS='//3(9F10.4/))
0024300 C WRITE(6,1101) ((F(I,J),J=1,13),I=1,3)
0024400 C1101 FORMAT(1H,'F='//3(13F10.4/))
0024500 C WRITE(6,1102) ((VOIP(I,J),J=1,9),I=1,4)
0024600 C1102 FORMAT(1H,'VOIP='//4(9F10.4/))
0024700 C WRITE(6,1103) ((AZETA(I,J),J=1,9),I=1,4)
0024800 C1103 FORMAT(1H,'AZETA='//4(9F10.4/))
0024900 DO 60 I=1,NATOMS
0025000 LLIM(I) = N+1
0025100 <=1
0025200 IF (AN(I).LT.11) GO TO 20
0025300 10 N=N+4
0025400 CZ(I)=AN(I)-10
0025500 GO TO 50
0025600 20 IF (AN(I).LT.3) GO TO 40
0025700 30 N=N+4
0025800 CZ(I) = AN(I)-2
0025900 GO TO 50
0026000 40 N=N+1
0026100 CZ(I)= AN(I)
0026200 50 CONTINUE
0026300 LLIM(I) = N
0026400 60 CONTINUE
0026500 C-----ASSIGNMENT OF ANGULAR MOMENTUM QUANTUM NOS. TO ATOMIC ORBITALS
0026600 LC(1)=0
0026700 LC(2)=1
0026800 LC(3)=1
0026900 LC(4)=1
0027000 LC(5)=2
0027100 LC(6)=2
0027200 LC(7)=2
0027300 LC(8)=2
0027400 LC(9)=2
0027500 IC(1)=0
0027600 IC(2)=1
0027700 IC(3)=-1
0027800 IC(4)=0
0027900 IC(5)=0
0028000 IC(6)=1
0028100 IC(7)=-1
0028200 IC(8)=2
0028300 IC(9)=-2
0028400 C-----FILL U ARRAY---U(J) IDENTIFIES THE ATOM TO WHICH ORBITAL J IS
0028500 C-----ATTACHED E.G. ORBITAL 32 ATTACHED TO ATOM 7, ETC.
0028600 C-----ASSIGNMENT OF ORBITAL EXPONENTS TO ATOMS BY SLATERS RULES
0028700 IC(8)=2 ;NC(14)=3

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0028800      JJ 92 K=1,NATOMS
0028900      LLK=LLIM(K)
0029000      JLK=ULIM(K)
0029100      ANK=AN(K)
0029200      NORBK=ULK-LLK+1
0029300      JJ 92 I=1,NORBK
0029400      LLKP=LLK+I-1
0029500      LCZETA=LC(I)+1
0029600      J(LLKP)=AZETA(LCZETA,K)
0029700      J(LLKP)=K
0029800      92 CONTINUE
0029900 C-----STEP THRU PAIRS OF ATOMS
0030000      JJ 320 IF=1,13
0030100      IIF=0
0030200      JJ 320 K=1,NATOMS
0030300      JJ 320 L=K,NATOMS
0030400      JJ 100 I=1,3
0030500      C1(I)=POS(I,K)
0030600      100 C2(I)=POS(I,L)+F(I,IF)
0030700 C-----CALCULATE UNIT VECTOR ALONG INTERATOM AXIS,E
0030800      CALL RELVEC(R,E,C1,C2)
0030900      IF(R.GT.3.1/AU) GO TO 320
0031000      IF(IF.EQ.1) GO TO 102
0031100      IIF=NIF+1
0031200      NZS(1,NIF,IF)=K
0031300      NZS(2,NIF,IF)=L
0031400      102 CONTINUE
0031500      LLK = LLIM(K)
0031600      LLL = LLIM(L)
0031700      JLK = ULIM(K)
0031800      JLL = ULIM(L)
0031900      NORBK=ULK-LLK+1
0032000      NORBL=ULL-LLL+1
0032100      ANK=AN(K)
0032200      ANL=AN(L)
0032300 C-----LOOP THRU PAIRS OF BASIS FUNCTIONS, ONE ON EACH ATOM
0032400      JJ 200 I=1,NORBK
0032500      JJ 200 J=1,NORBL
0032600      IF(K.EQ.L.AND.IF.EQ.1) GO TO 160
0032700      110 IF(MC(I).NE.MC(J)) GO TO 150
0032800      120 IF(MC(I).LT.0) GO TO 140
0032900      LLKP=LLK+I-1 ; LLLP=LLL+J-1
0033000      130 PAIRS(I,J)= SQRT((Q(LLKP)*R)**(2*NC(ANK)+1)*(Q(LLLP)*R)**(2*NC(
0033100      1)+1)/(FACT(2*NC(ANK))*FACT(2*NC(ANL))))*(-1.00)**(LC(J)+MC(J))
0033200      2*SS(NC(ANK),LC(I),MC(I),NC(ANL),LC(J),Q(LLKP)*R,Q(LLLP)*R)
0033300      GO TO 190
0033400      140 PAIRS(I,J)=PAIRS(I-1,J-1)
0033500      GO TO 190
0033600      150 PAIRS(I,J)=0.000
0033700      GO TO 190
0033800      160 IF (I.EQ.J) GO TO 170
0033900      180 PAIRS(I,J)=0.000
0034000      GO TO 190
0034100      170 PAIRS(I,J)=1.000
0034200      190 CONTINUE
0034300      200 CONTINUE
0034400      LCULK=LC(NORBK)
0034500      LCULL=LC(NORBL)
0034600      MAXL=MAX0(LCULK,LCULL)
0034700      IF(R.GT.0.000001D0) GO TO 220
0034800      210 GO TO 250
0034900 C-----ROTATE INTEGRALS FROM DIATOMIC BASIS TO MOLECULAR BASIS
0035000      220 CALL HARMTR(T,MAXL,E)
0035100      JJ 230 I=1,NORBK
0035200      JJ 230 J=1,NORBL
0035300      TEMP(I,J) = 0.00

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5400      DD 230 KK=1,NORBL
5500      TEMP(I,J) = TEMP(I,J)+T(J,KK)*PAIRS(I,KK)
5600  230 CONTINUE
5700      DD 240 I=1,NORBK
5800      DD 240 J=1,NORBL
5900      PAIRS(I,J) = 0.D0
6000      DD 240 KK=1,NORBK
6100      PAIRS(I,J) = PAIRS(I,J)+T(I,KK)*TEMP(KK,J)
6200  240 CONTINUE
6300 C-----FILL S MATRIX
6400  250 CONTINUE
6500      IF(IF.NE.1) GO TO 262
6600      DD 260 I=1,NORBK
6700      LLKP=LLK+I-1
6800      DD 260 J=1,NORBL
6900      LLLP=LLL+J-1
7000  260 S(LLKP,LLLP)=PAIRS(I,J)
7100      GO TO 320
7200  262 CONTINUE
7300      DD 264 I=1,NORBK
7400      DD 264 J=1,NORBL
7500  264 SOUTER(I,J,NIF,IF)=PAIRS(I,J)
7600  320 CONTINUE
7700  330 CONTINUE
7800      RETURN
7900      END
8000  SUBROUTINE SETSH
8100  IMPLICIT COMPLEX*16 (Z)
8200  COMMON/COM01/ ZS(40,40),ZH(40,40)
8300  COMMON/ARRAYS/S(40,40),Y(9,5,203),Z(17,45)
8400  COMMON/NATOMS/ NATOMS,N,NK
8500  COMMON/VECK/VECK(3)
8600  COMMON/VOIP/ VOIP(4,9),AZETA(4,9),CONST,OM1,OM2,VP(4,9),AZP(4,9)
8700  COMMON/POS/ POS(3,9),F(3,13),BONDL,AU,BAU,NC(18),LC(10),MC(10)
8800  COMMON/INFO/ AN(40),NOUT
8900  COMMON/INFO1/CZ(40),U(80),ULIM(40),LLIM(40),ULK,ULL,ANL,ANK
9000  COMMON /SOUTER/SOUTER(4,4,4,13),NZS(2,4,13)
9100  COMMON /TM/TM(3,3),GM(3,3),POST(3,9),AK(3),NF(3,13),IFMAX,NUNIT
9200  COMMON /CON/CSSSS,CSSSX,CSSXX,COOSS,COOSX,COOXX,CSS,CSX,CXS,CXX
9300  INTEGER AN,ULIM,ULK,ULL,CZ,U,ANL,ANK
9400  REAL*4 Z
9500  JEBUG,SUBCHK
9600 C      WRITE(6,100) (((NZS(I,J,K),J=1,4),I=1,2),K=1,13)
9700 C 100 FORMAT(1H0,'NZS=',/1H ,2(4I2/1H ))
9800 C      WRITE(6,101) (((SOUTER(I,J,K,L),J=1,4),I=1,4),K=1,4),L=1,13)
9900 C 101 FORMAT(1H0,'SOUTER=',/1H ,4(4F10.4/1H ))
1000      DD 2 I=1,N
1010      DD 2 J=I,N
1020      2 ZS(I,J)=S(I,J)
1030      DD 3 IF=2,13
1040      ZTHETA=0.
1050      DD 4 I=1,3
1060      4 ZTHETA=ZTHETA+VECK(I)*F(I,IF)*(0.,1.)
1070      ZEXP=EXP(ZTHETA)
1080 C      WRITE(6,102) ZTHETA,ZEXP,(F(I,IF),I=1,3),IF
1090 C 102 FORMAT(1H., 'ZTHETA,ZEXP=',4F10.4/1H , 'F,IF=',3F10.4,13)
1100 C-----SET UP S MATRIX FOR A CERTAIN K-----
1110      DD 5 NIF=1,4
1120      IF(NZS(1,NIF,IF).EQ.0.) GO TO 3
1130      K=NZS(1,NIF,IF)
1140      L=NZS(2,NIF,IF)
1150      LLK=LLIM(K)
1160      LLL=LLIM(L)
1170      JLK=ULIM(K)
1180      JLL=ULIM(L)
1190      JDRBK=ULK-LLK+1

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2000      JDRBL=ULL-LLL+1
2100      DO 6 I=1,NORBK
2200      DO 6 J=1,NORBL
2300          LLKP=LLK+I-1
2400          LLLP=LLL+J-1
2500      6   ZS(LLKP,LLLP)=ZS(LLKP,LLLP)+SOUTER(I,J,NIF,IF)*ZEXP
2600      5   CONTINUE
2700      3   CONTINUE
2800  C-----CALCULATION OF H MATRIX-----
2900      DO 8 K=1,NATOMS
3000      DO 8 L=K,NATOMS
3100          LLK=LLIM(K)
3200          LLL=LLIM(L)
3300          ULK=ULIM(K)
3400          ULL=ULIM(L)
3500          NORBK=ULK-LLK+1
3600          NORBL=ULL-LLL+1
3700          DO 9 I=1,NORBK
3800          DO 9 J=1,NORBL
3900              LLKP=LLK+I-1
4000              LLLP=LLL+J-1
4100              LCI=LC(I)+1
4200              LCJ=LC(J)+1
4300              IF(LLKP,EQ,LLLP) GO TO 10
4400              LLKPU=U(LLKP) ; LLLPU=U(LLLP)
4500              IF(LLKPU,LE,3,AND,LLLPU,LE,3) GO TO 11
4600              IF(LLKPU,GE,4,AND,LLLPU,GE,4) GO TO 12
4700              IF(LCI,EQ,1,AND,LCJ,EQ,1) GO TO 16
4800              IF(LCI,GE,2,AND,LCJ,GE,2) GO TO 17
4900              IF((LLKPU,LE,3,AND,LCI,EQ,1).OR.
5000      *      (LLLPU,LE,3,AND,LCJ,EQ,1)) GO TO 18
5100              CONST=CXS ;GO TO 13
5200      18   CONST=CSX ;GO TO 13
5300      16   CONST=CSS ;GO TO 13
5400      17   CONST=CXX ;GO TO 13
5500      11   IF(LCI,EQ,1,AND,LCJ,EQ,1) GO TO 22
5600              IF(LCI,GE,2,AND,LCJ,GE,2) GO TO 23
5700              CONST=CSSSX ;GO TO 13
5800      22   CONST=CSSSS ;GO TO 13
5900      23   CONST=CSSXX ;GO TO 13
6000      12   IF(LCI,EQ,1,AND,LCJ,EQ,1) GO TO 20
6100              IF(LCI,GE,2,AND,LCJ,GE,2) GO TO 21
6200              CONST=COOSX ;GO TO 13
6300      20   CONST=COOSS ;GO TO 13
6400      21   CONST=COOXX ;GO TO 13
6500      13   CONTINUE
6600          ZH(LLKP,LLLP)=-ZS(LLKP,LLLP)*(VOIP(LCI,K)+VOIP(LCJ,L))*
6700      *      CONST/2.
6800          GO TO 9
6900      10  ZH(LLKP,LLKP)=-VOIP(LCI,K)
7000      9   CONTINUE
7100      8   CONTINUE
7200  C      IF(NK,EQ,1) CALL MATOUT(4)
7300  C-----SYMMETRIZATION OF S AND H MATRIX-----
7400      DO 7 I=1,N
7500      DO 7 J=I,N
7600          ZS(J,I)=CONJG(ZS(I,J))
7700          ZH(J,I)=CONJG(ZH(I,J))
7800      7   CONTINUE
7900  C      DO 15 I=1,N
8000  C      DO 14 J=1,N
8100  C      ZS(I,J)=0.
8200  C      14  CONTINUE
8300  C      ZS(I,I)=1.
8400  C      15  CONTINUE
8500      RETURN ;END

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5600 SUBROUTINE DENSIT
5700 COMPLEX*16 S,H,PM,RM
5800 REAL*8 V
5900 C-----*** CALC. OF POPULATIONS ***
6000 COMMON/COM01/ S(40,40),H(40,40)
6100 COMMON/COM02/ PM(40,40),RM(40,40)
6200 COMMON/COM03/ V(40),W(20,40)
6300 COMMON/COM17/ TOEL(30),EN(40)
6400 COMMON/COM21/ CON,SUMEN,CONSK
6500 COMMON/NATOMS/ NATOMS,N,NK
6600 COMMON/INFO/ AN(40),NOUT
6700 COMMON/COM13/ TDP(10,10)
6800 COMMON/COM19/ IRET,ISTOP,NNAT
6900 COMMON/INFO1/CZ(40),U(80),ULIM(40),LLIM(40),ULK,ULL,ANL,ANK
7000 INTEGER AN,ULIM,ULK,ULL,CZ,U,ANL,ANK
7100 SUMEN=0.0
7200 DO 1 I=1,N
7300 1 SUMEN=SUMEN+EN(I)*V(I)
7400 DO 21 I=1,N
7500 PM(I,I)=0.0
7600 DO 21 J=1,N
7700 DO 21 K=1,N
7800 21 PM(I,I)=PM(I,I)+REAL(CONJG(S(I,J))*S(K,J)*RM(I,K))*EN(J)
7900 II=N-1
8000 DO 22 I=1,NI
8100 IMA=I+1
8200 DO 22 J=IMA,N
8300 PM(I,J)=0.0
8400 DO 22 K=1,N
8500 22 PM(I,J)=PM(I,J)+2.0*REAL(RM(I,J)*CONJG(S(I,K))*S(J,K))*EN(K)
8600 DO 2 I=1,NI
8700 IJK=I+1
8800 DO 2 J=IJK,N
8900 2 PM(J,I)=PM(I,J)
9000 C-----*** CALC. OF TOTAL ***
9100 NNAT=NATOMS
9200 NI=N-1
9300 NNATA=NNAT-1
9400 DO 31 L=1,NNATA
9500 LKM=L+1
9600 DO 31 K=LKM,NNAT
9700 TDP(L,K)=0.0
9800 DO 32 I=1,NI
9900 IMJ=I+1
10000 DO 32 J=IMJ,N
10100 IF(U(I).NE.L) GO TO 32
10200 IF(U(J).NE.K) GO TO 32
10300 TDP(L,K)=TDP(L,K)+PM(I,J)
10400 TDP(K,L)=TDP(L,K)
10500 32 CONTINUE
10600 31 CONTINUE
10700 DO 3 I=1,NNAT
10800 TDP(I,I)=0.0
10900 DO 4 J=1,N
11000 IF(U(J).NE.I) GO TO 4
11100 TDP(I,I)=TDP(I,I)+PM(J,J)
11200 4 CONTINUE
11300 3 CONTINUE
11400 WRITE(6,40) ((TDP(I,J),J=1,NATOMS),I=1,NATOMS)
11500 40 FORMAT(1H0,'TDP=' /1H ,9(9F8.4/1H ))
11600 RETURN
11700 END

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ALPHA JF A1402.S.FORT LIST END

ER DOS

JF A1402.S.FORT

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0000100 PROGRAM DOS
0000200 DIMENSION V(160,36),D(500),E(500)
0000210 DIMENSION A(70)
0000220 DATA B/' ','S/'*'/
0000300 DO 10 I=1,61
0000400 10 E(I)=-33.+(I-1)*0.05
0000500 DO 11 I=62,303
0000600 11 E(I)=-22.+(I-62)*0.05
0000700 DO 12 I=304,425
0000800 12 E(I)=-2.+(I-304)*0.05
0000900 I=425 ;DEL=0.05 ;DEL2=0.05**2
0001000 PAID=DEL/3.141592/154
0001100 DO 50 J=1,44
0001200 50 READ(50) (V(J,I),I=1,36)
0001300 DO 51 J=45,88
0001400 51 READ(51) (V(J,I),I=1,36)
0001500 DO 52 J=89,132
0001600 52 READ(52) (V(J,I),I=1,36)
0001700 DO 53 J=133,154
0001800 53 READ(53) (V(J,I),I=1,36)
0001900 DO 20 I=1,N
0002000 D(I)=0.
0002100 DO 21 J=1,154
0002200 DO 21 K=1,30
0002300 21 D(I)=D(I)+1./((E(I)-V(J,K))**2+DEL2)
0002400 D(I)=D(I)*PAID
0002500 C IF(D(I).GT.25.) D(I)=25.
0002600 20 CONTINUE
0002610 C WRITE(6,100) (E(I),D(I),I=1,N)
0002620 C 100 FORMAT(1H ,2F9.4,3X,2F9.4,3X,2F9.4)
0002625 C DO 31 I=1,70
0002630 C 31 A(I)=B
0002635 C DO 30 I=1,N
0002640 C IP=5.83*D(I)
0002645 C A(IP)=S
0002650 C WRITE(6,101) E(I),(A(J),J=1,70)
0002655 C 101 FORMAT(1H ,F9.4,70A1)
0002660 C 30 A(IP)=B
0002700 CALL PLOTS(999.,999.,'DOS')
0002800 CALL PLOT(3.,3.,-3)
0002810 I=3 ;NOM=N/M
0002820 I=NOM
0002830 DO 33 I=1,NOM
0002840 II=M*(I-1)+1
0002850 J(I)=D(II)
0002860 E(I)=E(II)
0002870 33 CONTINUE
0002880 I1=N+1.;N2=N+2
0003000 E(N1)=-33.
0003100 E(N2)=1.
0003200 J(N1)=0.
0003300 J(N2)=0.5
0003400 CALL AXIS(0.,0.,'ENERGY',-6,40.,0.,E(N1),E(N2))
0003500 CALL AXIS(0.,0.,'DOS',3,25.,90.,D(N1),D(N2))
0003800 CALL LINE(E,D,N;1,0,0)
0003900 CALL PLOTV
0004000 STOP ;END

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ER SURF

JF A1402.I.FORT

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0000100 PROGRAM SURF
0000200 IMPLICIT COMPLEX*8 (G,V,Z)
0000300 COMPLEX*8 H(8,16),V(8,8)
0000400 COMPLEX*8 G(8,8),CDET,CW(8)
0000500 COMPLEX*8 ZP(8,8)
0000600 COMPLEX*8 GST(8,8,30),ZQ(8,8)
0000700 COMPLEX*8 GOUT(4,4,130)
0000800 COMMON /R/R1,R2,R3,R4,R5,R6,R7,R8,R9,R10,R11,R12,R13
0000900 * ,AK1,AK2
0001000 COMMON /COMH/H
0001100 COMMON /H0HDF/ H0,HD,F
0001200 DIMENSION IP(8),RG3M(130),RG4M(130)
0001300 EQUIVALENCE (H(1,9),V(1,1))
0001400 DIMENSION AV1(2),AV2(2),XV(2),YV(2),AKV(2)
0001500 DIMENSION HD(8,16,6),F(3,6),H0(8,16)
0001510 C DIMENSION H1(8,16)
0001600 C DIMENSION CM(2,2,3),PQ(2),SIGN(2,4)
0001700 C DATA CM/1.,0.,0.,1.,.5,.866,.866,-.5,.5,.866,-.866,.5/
0001800 C DATA PQ/1.,.25/,SIGN/1.,1.,-1.,1.,1.,-1.,-1.,-1./
0001900 DATA AV1/-.6124,.3535/,AV2/-.6124,-.3535/,
0002000 * XV/-.8165,1.4142/,YV/-1.4142,-.8165/
0002100 DATA V/64*0./
0002110 C-----PRESENT1-----
0002120 DATA R1,R2,R3,R4,R5,R6,R7,R8,R9,R10,R11,R12,R13/
0002130 * -.536,-1.585,-4.105,-.553,-.324,.264,.21,-.084,.034,
0002140 *.199,-.06,.069,-.484/
0002200 C-----PP PARAMETERS-----
0002300 C DATA R1,R2,R3,R4,R5,R6,R7,R8,R9,R10,R11,R12,R13/
0002400 C * -0.911,-1.098,-4.091,-0.551,-0.274,0.245,0.265,
0002500 C * -0.075,-0.315,0.025,0.025,0.025,-0.315/
0002600 C-----DRESSELHAUS PARAMETERS-----
0002700 C DATA R1,R2,R3,R4,R5,R6,R7,R8,R9,R10,R11,R12,R13/
0002800 C * -2.095,-2.965,-0.4,0.61,-1.74,-1.02,
0002900 C * 0.04125,0.19125,-0.41375,0.18125,0.09125,0.15625,0.04625/
0002910 C-----CHADI PARAMETAERS-----
0002920 C DATA R1,R2,R3,R4,R5,R6,R7,R8,R9,R10,R11,R12,R13/
0002930 C * 0.2250,-1.475,-5.2541,-0.5328,-0.2903,0.6310,
0002940 C * 7*0./
0003000 DATA F/-.6124,0.3536,0.,-0.6124,-0.3536,0.,
0003100 * 0.,0.7071,0.,0.,-0.7071,0.,
0003200 * 0.6124,-0.3536,0.,0.6124,0.3536,0./
0003300 DATA H0/128*0./,HD/768*0./
0003400 DATA BETA/2.58/
0003500 DATA PAI/3.141592/
0003510 R1=R1-5.15
0003520 WRITE(6,299) R1,R2,R3,R4,R5,R6,R7,R8,R9,R10,R11,R12,R13
0003530 299 FORMAT(' R1-R13=',13F8.3)
0003600 XV(1)=XV(1) ;YV(1)=YV(1)
0003700 AG1=1. ;EPSG=0.05
0003710 WRITE(6,8)
0003720 8 FFORMAT(' INPUT EI,EF,DE,DELTA,EPG IN 5F10.0')
0003730 EI=-11. ;EF=0. ;DE=0.1 ;DELTA=0.04 ;EPG=0.05
0003740 READ(5,9) DEI,DEF,DDE,DDELTA,DEPSG
0003750 9 FORMAT(5F10.0)
0003760 IF(DEI.NE.0.) EI=DEI
0003770 IF(DEF.NE.0.) EF=DEF
0003780 IF(DDE.NE.0.) DE=DDE
0003790 IF(DDELTA.NE.0.) DELTA=DDELTA

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00003800 IF(DEPSG,NE,0.) EPSG=DEPSG
00003810 NN=(EF-EI+0.01)/DE ;NN=NN+1
00003900 ICONT=0 ;BNDCT=0
00004000 READ(5,300) ICONT,BNDCT
00004100 300 FORMAT(I1,F10.3)
00004200 B1=2.35-BNDCT
00004300 B2=SQRT(5.5225+B1**2+1.569*B1)
00004400 EXP1=EXP(BETA*(2.35-B1))
00004500 EXP2=EXP(BETA*(3.84-B2))
00004600 ISC=0
00004700 REWIND 20
00004800 READ(5,11) ISKIP,NKEND
00004900 C CALL SETHD
00005000 C CALL RWRITE(H0,'H0 ',8,16,8)
00005100 C CALL RWRITE(F,'F ',3,6,6)
00005200 C DO 14 IF=1,6
00005300 C DO 15 J=1,16
00005400 C DO 15 I=1,8
00005500 C 15 H1(I,J)=HD(I,J,IF)
00005600 C 14 CALL RWRITE(H1,'H1 ',8,16,8)
00005700 11 FORMAT(2I3)
00005800 IF(ISKIP.EQ.0) GO TO 13
00005900 DO 12 IS=1,ISKIP
00006000 12 READ(20) (((GOUT(I,J,NUME),I=1,4),J=1,4),NUME=1,NN),
00006100 * (RG3M(I),RG4M(I),I=1,NN)
00006200 13 CONTINUE
00006300 C-----SCANNING OF K-----
00006400 NUMK=0
00006500 DO 1 K1=1,12
00006600 AKV(1)=-1.62+0.28*(K1-1)
00006700 DO 1 K2=1,14
00006800 AKV(2)=-1.88+0.28*(K2-1)
00006900 IF(AKV(2).LT.(0.5774*AKV(1)-1.8856).OR.
00007000 * AKV(2).LT.(-0.5774*AKV(1)-1.8856).OR.
00007100 * AKV(2).GT.(0.5774*AKV(1)+1.8856).OR.
00007200 * AKV(2).GT.(-0.5774*AKV(1)+1.8856)) GO TO 1
00007300 AK1=PAI*(AV1(1)*AKV(1)+AV1(2)*AKV(2))
00007400 AK2=PAI*(AV2(1)*AKV(1)+AV2(2)*AKV(2))
00007500 NUMK=NUMK+1
00007600 IF(NUMK.LE.ISKIP.OR.NUMK.GT.NKEND) GO TO 1
00007700 10 WRITE(6,105) AK1,AK2,K1,K2,NUMK,AKV
00007800 C WRITE(6,106) AK1,AK2,AKV
00007900 C 106 FORMAT(' AK1,AK2,AKV=',4F10.4)
00008000 C WRITE(6,107) ((CM(J1,J2,I3),J2=1,2),J1=1,2),
00008100 C * (SIGN(J3,I4),J3=1,2)
00008200 C 107 FORMAT(' CM,SIGN=',6F10.4)
00008300 105 FORMAT(' AK1,AK2,K1,K2,NUMK,AKV=',2F8.3,3I3,2F8.3)
00008400 C-----SETTING UP OF HAMILTONIAN-----
00008500 CALL SETH11
00008600 C CALL H111K(H,H0,HD,AKV,F)
00008700 C CALL SETH
00008800 C CALL CWRITE(H,'H ',8,16,8)
00009000 C-----RESETTING OF G-----
00009100 DO 30 I=1,8
00009200 DO 30 J=1,8
00009300 30 G(J,I)=0.
00009400 C-----SCANNING OF ENERGY-----
00009500 E=EI-DE ;NUME=0
00009600 C-----CHANGE ENERGY-----
00009700 40 NUME=NUME+1
00009800 E=E+DE
00009900 IF(E.GT.EF+0.1*DE) GO TO 2
00100000 ZE=E+(0.,1.)*DELTA
00101000 N=0 ;IN=0 ;ISW=0
00102000 50 N=N+1
00103000 C-----CALCULATION OF NEW G-----

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0010305      DO 51 I=1,8
0010310      DO 51 J=1,8
0010315          ZP(I,J)=0.
0010320      DO 51 L=1,8
0010325      51  ZP(I,J)=ZP(I,J)+V(I,L)*G(L,J)
0010330      DO 52 I=1,8
0010335      DO 52 J=1,8
0010340          ZQ(I,J)=-H(I,J)
0010345      DO 52 L=1,8
0010350      52  ZQ(I,J)=ZQ(I,J)-ZP(I,L)*CONJG(V(J,L))
0010400  C      DO 51 I=1,8
0010500  C      DO 51 J=1,8
0010600  C      ZQ(I,J)=-H(I,J)
0010700  C      DO 51 K=1,8
0010800  C      DO 51 L=1,8
0010900  C      51  ZQ(I,J)=ZQ(I,J)-V(I,L)*G(L,K)*CONJG(V(J,K))
0011000      DO 53 I=1,8
0011100      53  ZQ(I,I)=ZQ(I,I)+ZE
0011200      CALL CINV(ZQ,8,0,8,8,1.D-14,CDET,CW,IP,NSTOP)
0011300  C      WRITE(6,205) N,EPSC,G(1,1),G(4,4),G(5,5),G(8,8),IN,ISW
0011400  C      205  FORMAT(1H ,I4,9F8.3,2I2)
0011500  C-----CONVERGENCE CHECK-----
0011600      C1=ABS(G(1,1)-ZQ(1,1))/(ABS(ZQ(1,1))+0.001)
0011700      C2=ABS(G(4,4)-ZQ(4,4))/(ABS(ZQ(4,4))+0.001)
0011800      C3=ABS(G(5,5)-ZQ(5,5))/(ABS(ZQ(5,5))+0.001)
0011900      C4=ABS(G(8,8)-ZQ(8,8))/(ABS(ZQ(8,8))+0.001)
0012000      EPSC=C1+C2+C3+C4
0012100      DO 230 J=1,8
0012200      DO 230 I=1,8
0012300      230  S(I,J)=ZQ(I,J)
0012400      IF(ICONT.EQ.1.AND.ISC.EQ.1) GO TO 303
0012500      IF(EPSC.GT.EPSG) GO TO 203
0012600      GO TO 204
0012700  C-----NOT YET CONVERGED-----
0012800      203  AG2=ABS(G(1,1))+ABS(G(2,2))
0012900      IF(N.LT.3) GO TO 240
0013000      IF((AG2-AG1)*(AG1-AG0).GT.0.) GO TO 241
0013100  C-----MAX OR MIN-----
0013200      IF(IN.GE.29) GO TO 244
0013300      GO TO (243,244) ,ISW
0013400      243  ISW=ISW+1
0013500  C-----BEFORE AVERAGING-----
0013600      241  IF(ISW.EQ.0) GO TO 240
0013700  C-----IN AVERAGING-----
0013800      IN=IN+1
0013900  C-----STORAGE-----
0014000      DO 245 I=1,8
0014100      DO 245 J=1,8
0014200      245  S(J,I,IN)=G(J,I)
0014300      GO TO 240
0014400  C-----AVERAGE AND CHANGE-----
0014500      244  DO 247 I=1,8
0014600      DO 247 J=1,8
0014700          S(J,I)=0.
0014800      DO 248 K=1,IN
0014900      248  S(J,I)=G(J,I)+GST(J,I,K)
0015000      247  S(J,I)=G(J,I)/IN
0015100      ISW=0 ; IN=0
0015200      240  AG0=AG1 ; AG1=AG2
0015300      GO TO 50
0015400  C-----CONVERGED-----
0015500      204  CONTINUE
0015600  C      CALL CWRITE(G,'G      ',8,8,8)
0015700      IF(ICONT.EQ.0) GO TO 302
0015800      DO 301 J=1,4
0015900      DO 301 I=1,4

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00016000      H(I,J+8)=H(I,J+8)*EXP2
00016100      H(I+4,J+12)=H(I+4,J+12)*EXP2
00016200  301  H(I+4,J+8)=H(I+4,J+8)*EXP1
00016300  C   CALL CWRITE(H,'H      ',8,16,8)
00016400  C   WRITE(6,305) B1,B2,EXP1,EXP2
00016500  C 305  FORMAT(' B1,B2,EXP1,EXP2',4F10.3)
00016600      ISC=1 ;GO TO 50
00016700  303  CONTINUE
00016800      ISC=0
00016900      DO 306 J=1,4
00017000      DO 306 I=1,4
00017100      H(I,J+8)=H(I,J+8)/EXP2
00017200      H(I+4,J+12)=H(I+4,J+12)/EXP2
00017300  306  H(I+4,J+8)=H(I+4,J+8)/EXP1
00017400  302  CONTINUE
00017500      WRITE(6,202) N,NUME,E,EPSC,G(1,1),G(4,4),G(5,5),G(8,8)
00017600  C   CALL CWRITE(G,'G      ',8,8,8)
00017700  202  FORMAT(1H ,2I3,F7.2,F8.3,8F7.3)
00017800      RG3=AIMAG(G(5,5)) ;RG4=AIMAG(G(8,8))
00017900      DO 60 J=1,4
00018000      DO 60 I=1,4
00018100      60  GOUT(I,J,NUME)=G(I,J)
00018200      RG3M(NUME)=RG3 ;RG4M(NUME)=RG4
00018300      GO TO 40
00018400  C-----OUTPUT ON FILE-----
00018500      2  CONTINUE
00018600      WRITE(20) (((GOUT(I,J,NUME),I=1,4),J=1,4),NUME=1,NN),
00018700      *              (RG3M(I),RG4M(I),I=1,NN)
00018800      1  CONTINUE
00018900      STOP ;END
00019000      SUBROUTINE SETH11
00019100      IMPLICIT COMPLEX*8 (P)
00019200      COMPLEX*8 H(8,16)
00019300      COMMON /R/R1,R2,R3,R4,R5,R6,R7,R8,R9,R10,R11,R12,R13
00019400      *              ,AK1,AK2
00019500      COMMON /COMH/H
00019600      AK3=AK1-AK2
00019700      P1=EXP((0.,1.)*AK1) ;P11=CONJG(P1)
00019800      P2=EXP((0.,1.)*AK2) ;P12=CONJG(P2)
00019900      P3=EXP((0.,1.)*AK3) ;P13=CONJG(P3)
00200000      C1=COS(AK1) ;C2=COS(AK2) ;C3=COS(AK3)
0020100  C-----SUBMATRIX 1-1-----
0020200      H(1,1)=R1+2*R8*(C3+C1+C2)
0020300      H(2,2)=R1+2*R7*(C3+C2)+2*R8*C1
0020400      H(3,3)=R1+2*R7*(C3+C1)+2*R8*C2
0020500      H(4,4)=R1+2*R7*(C1+C2)+2*R8*C3
0020600      H(1,2)=R2+R10*(P3+P12)+R11*(P13+P2)+2*R12*C1
0020700      H(1,3)=R2+R10*(P13+P11)+R11*(P3+P1)+2*R12*C2
0020800      H(1,4)=R2+R10*(P1+P2)+R11*(P11+P12)+2*R12*C3
0020900      H(2,3)=R2+R10*(P11+P2)+R11*(P1+P12)+R9*P13+R13*P3
0021000      H(2,4)=R2+R10*(P13+P1)+R11*(P3+P11)+R9*P2+R13*P12
0021100      H(3,4)=R2+R10*(P2+P3)+R11*(P12+P13)+R9*P1+R13*P11
0021200  C-----SUBMATRIX 2-2-----
0021300      DO 20 I=5,8
0021400      DO 20 J=I,8
0021500      20  H(I,J)=H(9-J,9-I)
0021600  C-----SUBMATRIX 1-2-----
0021700      H(1,5)=R4+R5*(P1+P2)
0021800      H(4,8)=H(1,5)
0021900      H(1,6)=R4*P1+R5*(1.+P2)
0022000      H(3,8)=H(1,6)
0022100      H(1,7)=R4*P2+R5*(1.+P1)
0022200      H(2,8)=H(1,7)
0022300      H(1,8)=R6*(1.+P1+P2)
0022400      H(2,5)=R4*(1.+P2)+R5*P1
0022500      H(4,7)=H(2,5)

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0022600      4(2,6)=R4*(P1+P2)+R5
0022700      4(3,7)=H(2,6)
0022800      4(2,7)=R3*P2+R6*(1.+P1)
0022900      4(3,5)=R4*(1.+P1)+R5*P2
0023000      4(4,6)=H(3,5)
0023100      4(3,6)=R3*P1+R6*(1.+P2)
0023200      4(4,5)=R3+R6*(P1+P2)
0023300      DO 30 I=1,7
0023400      I1=I+1
0023500      DO 30 J=I1,8
0023600      30 4(J,I)=CONJG(H(I,J))
0023700 C-----SUBMATRIX 2-3-----
0023800      4(5,9)=R4 ; H(6,9)=R4 ; H(7,9)=R4 ; H(8,10)=R4 ; H(8,11)=R4
0023900      4(8,12)=R4
0024000      4(5,10)=R5 ; H(5,11)=R5 ; H(6,10)=R5 ; H(6,12)=R5 ; H(7,11)=R5
0024100      4(7,12)=R5
0024200      4(5,12)=R6 ; H(6,11)=R6 ; H(7,10)=R6 ; H(8,9)=R3
0024300 C-----SUBMATRIX 1-3-----
0024400      4(1,9)=R7*(1.+P1+P2)
0024500      4(1,10)=R11*(1.+P1)+R13*P2
0024600      4(1,11)=R11*(1.+P2)+R13*P1
0024700      4(1,12)=R11*(P1+P2)+R13
0024800      4(2,9)=R9*P2+R10*(1.+P1)
0024900      4(2,10)=R7*P2+R8*(1.+P1)
0025000      4(2,11)=R10*P2+R11*P1+R12
0025100      4(2,12)=R10*P2+R11+R12*P1
0025200      4(3,9)=R9*P1+R10*(1.+P2)
0025300      4(3,10)=R10*P1+R11*P2+R12
0025400      4(3,11)=R7*P1+R8*(1.+P2)
0025500      4(3,12)=R10*P1+R11+R12*P2
0025600      4(4,9)=R9+R10*(P1+P2)
0025700      4(4,10)=R10+R11*P2+R12*P1
0025800      4(4,11)=R10+R11*P1+R12*P2
0025900      4(4,12)=R7+R8*(P1+P2)
0026000 C-----SUBMATRIX 2-4-----
0026100      DO 10 I=5,8
0026200      DO 10 J=13,16
0026300      10 4(I,J)=H(17-J,17-I)
0026400      RETURN ;END
0026500      SUBROUTINE SETH
0026600      IMPLICIT COMPLEX*8 (P)
0026700      COMPLEX*8 H(8,16)
0026800      COMMON /R/R1,R2,R3,R4,R5,R6,R7,R8,R9,R10,R11,R12,R13
0026900      *      ,AK1,AK2
0027000      COMMON /COMH/H
0027100      PH1=EXP((0.,1.)*AK1)
0027200      PH2=CONJG(PH1)
0027300      PH3=EXP((0.,1.)*AK2)
0027400      PH4=CONJG(PH3)
0027500      PH6=PH1*PH3
0027600      4(1,1)=R1+R7*(PH3+PH4)+R8*(PH1+PH2)
0027700      4(2,2)=H(1,1)
0027800      4(3,3)=R1+R7*(PH1+PH2)+R8*(PH3+PH4)
0027900      4(4,4)=H(3,3)
0028000      4(1,2)=R2+R12*(PH1+PH2)+R9*PH4+R13*PH3
0028100      4(1,3)=R2+R10*(PH2+PH4)+R11*(PH1+PH3)
0028200      4(1,4)=R2+R10*(PH1+PH4)+R11*(PH2+PH3)
0028300      4(2,3)=R2+R10*(PH2+PH3)+R11*(PH1+PH4)
0028400      4(2,4)=R2+R10*(PH1+PH3)+R11*(PH2+PH4)
0028500      4(3,4)=R2+R12*(PH3+PH4)+R9*PH1+R13*PH2
0028600 C
0028700      4(5,5)=H(3,3)
0028800      4(6,6)=H(3,3)
0028900      4(7,7)=H(1,1)
0029000      4(8,8)=H(1,1)
0029100      4(5,6)=H(3,4)

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0029200 H(5,7)=H(2,4)
0029300 H(5,8)=H(1,4)
0029400 H(6,7)=H(2,3)
0029500 H(6,8)=H(1,3)
0029600 H(7,8)=H(1,2)
0029700 C
0029800 H(1,5)=R4+R5*PH1
0029900 H(2,5)=H(1,5)
0030000 H(4,7)=H(1,5)
0030100 H(4,8)=H(1,5)
0030200 H(1,6)=R4*PH1+R5
0030300 H(2,6)=H(1,6)
0030400 H(3,7)=H(1,6)
0030500 H(3,8)=H(1,6)
0030600 H(1,7)=R5*(1.+PH1)
0030700 H(2,8)=H(1,7)
0030800 H(1,8)=R6*(1.+PH1)
0030900 H(2,7)=H(1,8)
0031000 H(3,5)=R4*(1.+PH1)
0031100 H(4,6)=H(3,5)
0031200 H(3,6)=R3*PH1+R6
0031300 H(4,5)=R3+R6*PH1
0031400 C
0031500 DO 10 I=1,7
0031600 I1=I+1
0031700 DO 10 J=I1,8
0031800 10 H(J,I)=CONJG(H(I,J))
0031900 C
0032000 H(5,9)=R4*PH3+R5
0032100 H(6,9)=H(5,9)
0032200 H(8,11)=H(5,9)
0032300 H(8,12)=H(5,9)
0032400 H(5,10)=R4+R5*PH3
0032500 H(6,10)=H(5,10)
0032600 H(7,11)=H(5,10)
0032700 H(7,12)=H(5,10)
0032800 H(5,11)=R5*(1.+PH3)
0032900 H(6,12)=H(5,11)
0033000 H(5,12)=R6*(1.+PH3)
0033100 H(6,11)=H(5,12)
0033200 H(7,9)=R4*(1.+PH3)
0033300 H(8,10)=H(7,9)
0033400 H(7,10)=R3+R6*PH3
0033500 H(8,9)=R3*PH3+R6
0033600 C
0033700 H(1,9)=R7*(PH3+PH6)+R8*(1.+PH1)
0033800 H(1,10)=R10*(1.+PH1)+R11*(PH3+PH6)
0033900 H(1,11)=R11*(PH1+PH3)+R12+R13*PH6
0034000 H(1,12)=R11*(1.+PH6)+R12*PH1+R13*PH3
0034100 H(2,9)=R10*(PH3+PH6)+R11*(1.+PH1)
0034200 H(2,10)=R7*(1.+PH1)+R8*(PH3+PH6)
0034300 H(2,11)=R11*(1.+PH6)+R12*PH3+R13*PH1
0034400 H(2,12)=R11*(PH1+PH3)+R12*PH6+R13
0034500 H(3,9)=R9*PH6+R10*(PH1+PH3)+R12
0034600 H(3,10)=R9*PH1+R10*(1.+PH6)+R12*PH3
0034700 H(3,11)=R7*(PH1+PH6)+R8*(1.+PH3)
0034800 H(3,12)=R10*(PH1+PH6)+R11*(1.+PH3)
0034900 H(4,9)=R9*PH3+R10*(1.+PH6)+R12*PH1
0035000 H(4,10)=R9+R10*(PH1+PH3)+R12*PH6
0035100 H(4,11)=R10*(1.+PH3)+R11*(PH1+PH6)
0035200 H(4,12)=R7*(1.+PH3)+R8*(PH1+PH6)
0035300 DO 20 I=1,4
0035400 H(9-I,16)=H(1,8+I)
0035500 H(9-I,15)=H(2,8+I)
0035600 H(9-I,14)=H(3,8+I)
0035700 20 H(9-I,13)=H(4,8+I)

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0035800 RETURN ;END
0035900 SUBROUTINE CINV(A,N,M,N1,M1,EPS,DET,W,IP,NSTOP)
0036000 IMPLICIT REAL*4(A-H,O-Z)
0036100 COMPLEX*8 A,DET,PIVOT,W,AWK,PVT
0036200 DIMENSION A(N1,1),IP(1),W(1)
0036300 REAL MAX
0036400 JM = N+M
0036500 EPSS = 1.0E-2*EPS
0036600 DET = 1.0E0
0036700 DO 160 I=1,N
0036800 IP(I) = 0
0036900 160 CONTINUE
0037000 C
0037100 C PIVOT SERCH.
0037200 C
0037300 DO 270 K=1,N
0037400 MAX = -1.0E0
0037500 DO 190 I=1,N
0037600 IF ( IP(I) ) 170,170,190
0037700 170 CONTINUE
0037800 ABSS = ABS(A(I,K))
0037900 IF ( MAX-ABSS ) 180,190,190
0038000 180 CONTINUE
0038100 MAX = ABSS
0038200 L = I
0038300 190 CONTINUE
0038400 C
0038500 C CHECK SINGULARITY AND CALCULATE DETERMINANT.
0038600 C
0038700 IF ( MAX-EPS ) 1010,1010,200
0038800 200 CONTINUE
0038900 PIVOT = A(L,K)
0039000 DET = DET*PIVOT
0039100 C
0039200 C START SWEEP OUT.
0039300 C
0039400 IP(L) = K
0039500 PVT = -1.0D+0/PIVOT
0039600 DO 250 J=1,NM
0039700 IF ( J-K ) 210,250,210
0039800 210 CONTINUE
0039900 AWK = A(L,J) * PVT
0040000 IF ( ABS(AWK)-EPSS ) 240,240,220
0040100 220 CONTINUE
0040200 DO 230 I=1,N
0040300 A(I,J) = A(I,J) + A(I,K)*AWK
0040400 230 CONTINUE
0040500 240 CONTINUE
0040600 A(L,J) = -AWK
0040700 250 CONTINUE
0040800 DO 260 I=1,N
0040900 A(I,K) = A(I,K) * PVT
0041000 260 CONTINUE
0041100 A(L,K) = -PVT
0041200 270 CONTINUE
0041300 C
0041400 C EXCHANGE COLUMN.
0041500 C
0041600 DO 290 J=1,NM
0041700 DO 280 I=1,N
0041800 V(I) = A(I,J)
0041900 280 CONTINUE
0042000 DO 290 I=1,N
0042100 A( IP(I), J ) = W(I)
0042200 290 CONTINUE
0042300 IF ( N-1 ) 350,350,300

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0042400 300 CONTINUE
0042500 DO 320 I=1,N
0042600 DO 310 J=1,N
0042700 V(J) = A(I,J)
0042800 310 CONTINUE
0042900 DO 320 J=1,N
0043000 A(I,J) = W( IP(J) )
0043100 320 CONTINUE
0043200 DO 340 I=1, N-1
0043300 DO 340 J=I+1,N
0043400 IF ( IP(I)-IP(J) ) 340,340,330
0043500 330 CONTINUE
0043600 DET = -DET
0043700 340 CONTINUE
0043800 350 CONTINUE
0043900 ISTOP = 0
0044000 RETURN
0044100 C
0044200 C ARGUMENT ERROR RETURN.
0044300 C
0044400 1000 CONTINUE
0044500 ISTOP = 3
0044600 WRITE(6,10) N,M,N1,M1
0044700 RETURN
0044800 C
0044900 C MATRIX IS SINGULAR.
0045000 C
0045100 1010 CONTINUE
0045200 DET = 0.0E0
0045300 IF ( MAX ) 1011,1020,1011
0045400 1011 CONTINUE
0045500 WRITE(6,20) K
0045600 ISTOP = 2
0045700 RETURN
0045800 1020 CONTINUE
0045900 WRITE(6,30)
0046000 ISTOP = 1
0046100 RETURN
0046200 10 FORMAT(1H0,'(SUBR. CINV) INVALID ARGUMENT. N,M,N1,M1 =',4I5)
0046300 20 FORMAT(1H0,'(SUBR. CINV) MATRIX IS SINGULAR AT STEP #',I5)
0046400 30 FORMAT(1H0,'(SUBR. CINV) MATRIX IS SINGULAR.')
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0046500 END
SER SURF OF A1402.I.FORT LIST END
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PROGRAM SURF12

JF A1402.I.FORT

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0000100 PROGRAM SURF12
0000200 IMPLICIT COMPLEX*8 (G,V,Z)
0000300 COMPLEX*8 H(8,16),V(8,8)
0000400 COMPLEX*8 G(8,8),ZP(8,8),CDET,CW(8)
0000500 COMPLEX*8 GST(8,8,30),ZQ(8,8)
0000600 COMMON /R/R1,R2,R3,R4,R5,R6,R7,R8,R9,R10,R11,R12,R13
0000700 * ,AK1,AK2
0000800 COMMON /COMH/H
0000900 DIMENSION IP(8)
0001000 EQUIVALENCE (H(1,9),V(1,1))
0001100 DATA V/64*0./
0001200 DATA R1,R2,R3,R4,R5,R6,R7,R8,R9,R10,R11,R12,R13/
0001300 * -2.095,-2.965,-0.4,0.61,-1.74,-1.02,
0001400 * 0.04125,0.19125,-0.41375,0.18125,0.09125,0.15625,0.04625/
0001500 DELTA=0.01
0001600 AK1=0. ;AK2=0.
0001700 CALL SETH11
0001800 DO 1 IE=1,160
0001900 E=-1.+(IE-1)*0.025
0002000 C-----RESETTING OF G-----
0002100 DO 30 I=1,8
0002200 DO 30 J=1,8
0002300 30 G(J,I)=0.
0002400 ZE=E+(0.,1.)*DELTA
0002500 I=0
0002600 DO 2 NM=1,16
0002700 I=N+1
0002800 C-----CALCULATION OF NEW G-----
0002900 DO 51 I=1,8
0003000 DO 51 J=1,8
0003100 ZP(I,J)=0.
0003200 DO 51 L=1,8
0003300 51 ZP(I,J)=ZP(I,J)+V(I,L)*G(L,J)
0003400 DO 52 I=1,8
0003500 DO 52 J=1,8
0003600 ZQ(I,J)=-H(I,J)
0003700 DO 52 L=1,8
0003800 52 ZQ(I,J)=ZQ(I,J)-ZP(I,L)*CONJG(V(J,L))
0003900 DO 53 I=1,8
0004000 53 ZQ(I,I)=ZQ(I,I)+ZE
0004100 CALL CINV(ZQ,8,0,8,8,1.D-14,CDET,CW,IP,NSTOP)
0004200 DO 230 J=1,8
0004300 DO 230 I=1,8
0004400 230 G(I,J)=ZQ(I,J)
0004500 IF(N.EQ.1.OR.N.EQ.2.OR.N.EQ.4.OR.N.EQ.8.OR.N.EQ.16)
0004600 * GO TO 3
0004700 GO TO 2
0004800 3 RG1=AIMAG(G(1,1)) ;RG2=AIMAG(G(4,4))
0004900 RG3=AIMAG(G(5,5)) ;RG4=AIMAG(G(8,8))
0005000 WRITE(20) E,RG1,RG2,RG3,RG4
0005100 WRITE(6,100) N,E,RG1,RG2,RG3,RG4
0005200 100 FORMAT(1H ,I3,5F9.3)
0005300 2 CONTINUE
0005400 1 CONTINUE
0005500 STOP ;END
0005600 PROGRAM PLS
0005700 DIMENSION G(280,5,4),E(282),R(282)
0005800 I=160 ;N1=N+1 ;N2=N+2

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00005900      XM=8. ;YM=20.
00006000      DO 1 J=1,160
00006100      DO 1 I=1,5
00006200      READ(20) E(J),G(J,I,1),G(J,I,2),G(J,I,3),G(J,I,4)
00006300      1 CONTINUE
00006400      DO 6 I=1,N
00006500      DO 6 J=1,5
00006600      DO 6 K=1,4
00006700      G(I,J,K)=-G(I,J,K)
00006800      6 IF(G(I,J,K).GT.12.) G(I,J,K)=12.
00006900 C      DO 7 J=1,N
00007000 C      DO 7 I=1,5
00007100 C      7 WRITE(6,100) E(J),G(J,I,1),G(J,I,2),G(J,I,3),G(J,I,4)
00007200 C 100 FORMAT(1H ,5F8.3)
00007300      CALL PLOTS(0.,0.,'SURF')
00007400      CALL PLOT(2.,2.,-3)
00007500      R(N1)=0. ;R(N2)=0.5 ;E(N1)=-1. ;E(N2)=0.5
00007600      DO 2 K=1,4
00007700      DO 3 I=1,5
00007800      CALL AXIS(0.,0.,'ENERGY',-6,XM,0.,-1.,0.5)
00007900      CALL AXIS(0.,0.,'LDOS',4,YM,90.,0.,0.5)
00008000      DO 4 J=1,N
00008100      4 R(J)=G(J,I,K)
00008200      CALL LINE(E,R,N,1,0,0)
00008300      3 CALL PLOT(10.,0.,-3)
00008400      2 CONTINUE
00008500      CALL PLOTV
00008600      STOP ;END
00008700      PROGRAM PLS1
00008800      DIMENSION G(280,5,4),E(282),R(282)
00008900      N=160 ;N1=N+1 ;N2=N+2
00009000      XM=8. ;YM=20.
00009100      DO 1 J=1,N
00009200      I=1
00009300      READ(20) E(J),G(J,I,1),G(J,I,2),G(J,I,3),G(J,I,4)
00009400      1 CONTINUE
00009500      DO 6 I=1,N
00009600      J=1
00009700      DO 6 K=1,4
00009800      G(I,J,K)=-G(I,J,K)
00009900      6 IF(G(I,J,K).GT.12.) G(I,J,K)=12.
00010000 C      DO 7 J=1,N
00010100 C      DO 7 I=1,5
00010200 C      7 WRITE(6,100) E(J),G(J,I,1),G(J,I,2),G(J,I,3),G(J,I,4)
00010300 C 100 FORMAT(1H ,5F8.3)
00010400      CALL PLOTS(0.,0.,'SURF')
00010500      CALL PLOT(2.,2.,-3)
00010600      DO 2 K=1,4
00010700      R(N1)=0. ;R(N2)=0.5 ;E(N1)=-1. ;E(N2)=0.5
00010800      CALL AXIS(0.,0.,'ENERGY',-6,XM,0.,-1.,0.5)
00010900      CALL AXIS(0.,0.,'LDOS',4,YM,90.,0.,0.5)
00011000      I=1
00011100      DO 4 J=1,N
00011200      4 R(J)=G(J,I,K)
00011300      CALL LINE(E,R,N,1,0,0)
00011400      CALL PLOT(10.,0.,-3)
00011500      2 CONTINUE
00011600      CALL PLOTV
00011700      STOP ;END

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NUMBER SURF12 DF A1402.I.FORT LIST END

ER CBLM3

JF A1402.SS.FORT

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000100 PROGRAM CBLM
000200 IMPLICIT COMPLEX*8 (C)
000300 DIMENSION GSMAT(800),GPMAT(800),EMAT(800)
000400 DIMENSION CTEMP(4,4),SGSMAT(800),SGPMAT(800)
000500 DATA CA,CB,CD,CF,CG,CAO,CBO,CDO,CFG,CGO/
000600 *      10*0./
000700 DATA PAI/3.141592/
000800 JK=0 ; IGRAPH=0
000900 ITS=0
001000 SU=0 ; SV=0 ; ST=0 ; SX=0
001100 C-----SILICDN EHT INCLUDING OVERLAP-----
001200 C      JO=-5. ; V0=0. ; T0=2.5 ; X0=3.1 ; ES=-15.7 ; EP=-7.8
001300 C      SU=.24 ; SV=0. ; ST=-.19 ; SX=-.21
001400 C-----GERMANIUM CHADI-----
001500 C      JO=-1.7 ; V0=0.7 ; T0=1.7 ; X0=1.4 ; ES=-6.3 ; EP=2.1
001600 C-----SILICON CHADI-----
001700 C      JO=-2.0 ; V0=0.8 ; T0=1.9 ; X0=1.5 ; ES=-6. ; EP=1.2
001800 WRITE(6,113) ES,EP,U0,V0,T0,X0,SU,SV,ST,SX
001900 113 FORMAT(1H1,'ES,EP,U0,V0,T0,X0,SU,SV,ST,SX=',10F7.3)
002000 READ(5,63) IGRAPH,EI,EF,DE,EPS,EPSF
002100 63 FORMAT(1I,5F10.0)
002200 IF(EPSF.EQ.0.) EPSF=0.001
002300 IF(EPS.EQ.0.) EPS=1.
002400 IF(DE.EQ.0.) DE=0.1
002500 IF(EF.EQ.0.) EF=5.
002600 E=EI
002700 WRITE(6,64)
002800 64 FORMAT(1H1,'      E      EPS      IT',
002900 *      12X,'GP',12X,'GS',11X,'SGP',11X,'SGS',11X,'TGP',11X,'TGS
003000 *      )
003100 60 CONTINUE
003200 IF(E.GT.EF) GO TO 100
003300 NNN=10
003400 IT=0
003500 U=U0-E*SU ; V=V0-E*SV ; T=T0-E*ST ; X=X0-E*SX
003600 62 CONTINUE
003700 IT=IT+1
003800 CE=CMPLX(0.,EPS)
003900 CQ=-3*X*CG+U*CD
004000 CP=V*CA+2*T*CB+X*CF
004100 CR=T*CA+V*CB+T*CB+X*CF
004200 CY=-X*CA-2*X*CB+U*CF
004300 CZ=V*CG+2*T*CG+X*CD
004400 CPC=E+CE-EP-3*CP
004500 CQC=E+CE-ES-3*CQ
004600 DO 20 I=1,3
004700 DO 20 J=1,3
004800 20 CTEMP(I,J)=CR
004900 DO 30 I=1,3
005000 CTEMP(I,I)=CPC
005100 CTEMP(4,I)=CY
005200 30 CTEMP(I,4)=CZ
005300 CTEMP(4,4)=CQC
005400 CALL INV(CTEMP)
005500 CQD=CTEMP(4,4)
005600 CPD=CTEMP(1,1)
005700 CRD=CTEMP(2,1)
005800 CYD=CTEMP(4,1)

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005900 CZD=CTEMP(1,4)
006000 CAO=CA ;CBO=CB ;CDO=CD ;CFO=CF ;CGO=CG
006100 CA=CPD*V+2*CRD*T-CZD*X
006200 CB=CRD*V+CPD*T+CRD*T-CZD*X
006300 CD=3*CYD*X+CQD*U
006400 CF=-CYD*V-2*CYD*T+CQD*X
006500 CG=-CPD*X-2*CRD*X-CZD*U
006600 ERR=MAX(ABS(CA-CAO),ABS(CB-CBO),ABS(CD-CDO),
006700 * ABS(CF-CFO),ABS(CG-CGO))
006800 C CA =(OMEGA*CA+OMEGA1*CAO)
006900 C CB =OMEGA*CB+OMEGA1*CBO
007000 C CD =OMEGA*CD+OMEGA1*CDO
007100 C CF =OMEGA*CF+OMEGA1*CFO
007200 C CG =OMEGA*CG+OMEGA1*CGO
007300 I=MOD(IT,NNN)+1
007400 CAR=(CA+CAR*(N-1))/N
007500 CBR=(CB+CBR*(N-1))/N
007600 CDR=(CD+CDR*(N-1))/N
007700 CFR=(CF+CFR*(N-1))/N
007800 CGR=(CG+CGR*(N-1))/N
007900 IF(N.NE.NNN) GO TO 503
008000 CA=CAR ;CB=CBR ;CD=CDR ;CF=CFR ;CG=CGR
008100 503 CONTINUE
008200 IF(IT.GE.300) GO TO 601
008300 IF(ERR.LE.0.0001) GO TO 500
008400 GO TO 62
008500 500 CONTINUE
008600 IF(E.EQ.EI.AND.EPS.GT.EPSF) GO TO 600
008700 GO TO 601
008800 600 EPS=EPS/10
008900 GO TO 62
009000 601 CONTINUE
009100 ITS=ITS+IT
009200 IF(IGRAPH.EQ.9) GO TO 60
009300 CGP=-1./(E-EP-4*(CA*V+2*CB*T+CF*X))/PAI
009400 CGS=-1./(E-ES+4*(3*CG*X-CD*U))/PAI
009500 CSGP=4*(CA*SV+2*CB*ST+CF*SX)*CGP
009600 CSGS=4*(-3*CG*SX+CD*SU)*CGS
009700 CTGP=CGP+CSGP
009800 CTGS=CGS+CSGS
009900 IF(IGRAPH.EQ.1) GO TO 401
010000 WRITE(6,400) E,EPS,IT,CGP,CGS,CSGP,CSGS,CTGP,CTGS
010100 400 FORMAT(1H ,F6.2,F6.4,I4,4F7.4,10F7.3)
010200 401 JK=NK+1
010300 GPMAT(NK)=AIMAG(CGP)*3.
010400 GSMAT(NK)=AIMAG(CGS)
010500 SGPMAT(NK)=AIMAG(CSGP)*3.
010600 SGSMAT(NK)=AIMAG(CSGS)
010700 EMAT(NK)=E ;E=E+DE
010800 GO TO 60
010900 100 WRITE(6,106) ITS
011000 106 FORMAT(' TOTAL ITERATION NUMBER=',I10)
011100 IF(IGRAPH.EQ.0.OR.IGRAPH.EQ.9) STOP
011200 WRITE(20,105) NK
011300 105 FORMAT(I5)
011400 WRITE(20,104) (GPMAT(I),GSMAT(I),SGPMAT(I),SGSMAT(I),EMAT(I),
011500 * I=1,NK)
011600 104 FORMAT(5F10.4)
011700 STOP ;END
011800 SUBROUTINE INV(A)
011900 COMMON NSTJP
012000 COMPLEX A,DET,PIVOT,W,AWK,PVT
012100 DIMENSION A(4,4),IP(4),W(4)
012200 REAL MAX
012300 C
012400 C ARGUMENT CHECK.

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0012500 C
0012600 N=4 ;M=0 ;N1=4 ;M1=4 ;EPS=1.0E-5
0012700 NM = N+M
0012800 IF ( N ) 1000,1000,100
0012900 100 CONTINUE
0013000 IF ( N-N1 ) 110,110,1000
0013100 110 CONTINUE
0013200 IF ( M ) 1000,120,120
0013300 120 CONTINUE
0013400 IF ( NM-M1 ) 130,130,1000
0013500 130 CONTINUE
0013600 IF ( EPS ) 140,150,150
0013700 140 CONTINUE
0013800 EPS = 1.0E-5
0013900 150 CONTINUE
0014000 C
0014100 C INITIALIZATION.
0014200 C
0014300 EPSS = 1.0E-2*EPS
0014400 DET = 1.0E0
0014500 DO 160 I=1,N
0014600 IP(I) = 0
0014700 160 CONTINUE
0014800 C
0014900 C PIVOT SERCH.
0015000 C
0015100 DO 270 K=1,N
0015200 MAX = -1.0E0
0015300 DO 190 I=1,N
0015400 IF ( IP(I) ) 170,170,190
0015500 170 CONTINUE
0015600 ABSS = CABS(A(I,K))
0015700 IF ( MAX-ABSS) 180,190,190
0015800 180 CONTINUE
0015900 MAX = ABSS
0016000 L = I
0016100 190 CONTINUE
0016200 C
0016300 C CHECK SINGULARITY AND CALCULATE DETERMINANT.
0016400 C
0016500 IF ( MAX-EPS ) 1010,1010,200
0016600 200 CONTINUE
0016700 PIVOT = A(L,K)
0016800 DET = DET*PIVOT
0016900 C
0017000 C START SWEEP OUT.
0017100 C
0017200 IP(L) = K
0017300 PVT = -1.0D+0/PIVOT
0017400 DO 250 J=1,NM
0017500 IF ( J-K) 210,250,210
0017600 210 CONTINUE
0017700 AWK = A(L,J) * PVT
0017800 IF ( CABS(AWK)-EPSS ) 240,240,220
0017900 220 CONTINUE
0018000 DO 230 I=1,N
0018100 A(I,J) = A(I,J) + A(I,K)*AWK
0018200 230 CONTINUE
0018300 240 CONTINUE
0018400 A(L,J) = -AWK
0018500 250 CONTINUE
0018600 DO 260 I=1,N
0018700 A(I,K) = A(I,K) * PVT
0018800 260 CONTINUE
0018900 A(L,K) = -PVT
0019000 270 CONTINUE

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019100 C
019200 C EXCHANGE COLUMN.
019300 C
019400 JJ 290 J=1,NM
019500 JJ 280 I=1,N
019600 J(I) = A(I,J)
019700 280 CONTINUE
019800 JJ 290 I=1,N
019900 A( IP(I), J) = W(I)
020000 290 CONTINUE
020100 IF ( N-1 ) 350,350,300
020200 300 CONTINUE
020300 JJ 320 I=1,N
020400 JJ 310 J=1,N
020500 J(J) = A(I,J)
020600 310 CONTINUE
020700 JJ 320 J=1,N
020800 A(I,J) = W( IP(J) )
020900 320 CONTINUE
021000 JJ 340 I=1, N-1
021100 JJ 340 J=I+1,N
021200 IF ( IP(I)-IP(J) ) 340,340,330
021300 330 CONTINUE
021400 DET = -DET
021500 340 CONTINUE
021600 350 CONTINUE
021700 JSTOP = 0
021800 RETURN
021900 C
022000 C ARGUMENT ERROR RETURN.
022100 C
022200 1000 CONTINUE
022300 JSTOP = 3
022400 WRITE(6,10) N,M,N1,M1
022500 RETURN
022600 C
022700 C MATRIX IS SINGULAR.
022800 C
022900 1010 CONTINUE
023000 DET = 0.0E0
023100 IF ( MAX ) 1011,1020,1011
023200 1011 CONTINUE
023300 WRITE(6,20) K
023400 JSTOP = 2
023500 RETURN
023600 1020 CONTINUE
023700 WRITE(6,30)
023800 JSTOP = 1
023900 RETURN
024000 10 FORMAT(1H0,'(SUBR. CINV) INVALID ARGUMENT. N,M,N1,M1 =',4I5)
024100 20 FORMAT(1H0,'(SUBR. CINV) MATRIX IS SINGULAR AT STEP #',I5)
024200 30 FORMAT(1H0,'(SUBR. CINV) MATRIX IS SINGULAR.')
```

END

PROGRAM PLDOS

DIMENSION GSMAT(800),GPMAT(800),SGSMAT(800),SGPMAT(800)

DIMENSION Y1(800),Y2(800),X(800),Y3(800)

READ(20,100) NK

100 FORMAT(15)

READ(20,101)(GPMAT(I),GSMAT(I),SGPMAT(I),SGSMAT(I),X(I),I=1,NK)

101 FORMAT(5F10.4)

CALL PLOTS(999.,999.,'SAKURAI TAKAYASU')

CALL PLOT(1.,5.,-3)

DO 10 J=1,3

DO TO (1,2,3),J

1 DO 11 K=1,NK

Y1(K)=GPMAT(K)

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0025700 11 Y2(K)=GSMAT(K)
0025800 GO TO 4
0025900 2 DO 12 K=1,NK
0026000 Y1(K)=SGPMAT(K)
0026100 12 Y2(K)=SGSMAT(K)
0026200 GO TO 4
0026300 3 DO 13 K=1,NK
0026400 Y1(K)=GPMAT(K)+SGPMAT(K)
0026500 13 Y2(K)=GSMAT(K)+SGSMAT(K)
0026600 GO TO 4
0026700 4 DO 14 K=1,NK
0026800 14 Y3(K)=Y1(K)+Y2(K)
0026900 NK1=NK+1 ; NK2=NK+2
0027000 Y1(NK1)=Y1(1) ; Y1(NK2)=.2
0027100 Y2(NK1)=Y1(1) ; Y2(NK2)=.2
0027200 Y3(NK1)=Y1(1) ; Y3(NK2)=.2
0027300 X(NK1)=X(1) ; X(NK2)=2.
0027400 CALL AXIS(0.,0.,'ENERGY',-6,20.,0.,X(NK1),X(NK2))
0027500 CALL AXIS(0.,0.,'DOS',3,10.,90.,Y1(NK1),Y1(NK2))
0027600 CALL LINE(X,Y1,NK,1,0,0)
0027700 CALL DASHLN(X,Y2,NK,1)
0027800 CALL LINE(X,Y3,NK,1,0,0)
0027900 IF(J.EQ.2) GO TO 15
0028000 CALL PLOT(0.,15.,-3)
0028100 GO TO 16
0028200 15 CALL PLOT(28.,-15.,-3)
0028300 16 CONTINUE
0028400 10 CONTINUE
0028500 CALL PLOTV
0028600 STOP ;END

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BER CBLM3 JF A1402.SS.FORT LIST END

ER GEE

JF A1402.S.FORT

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0000100      FUNCTION-HH(ANK,LCI,MCI,ANL,LCJ,R,NANK,NANL)
0000200      INTEGER ANK,ANL
0000300 C-----PRESENT1-----
0000400      JATA SVSS,SVSP,SVPS,SVPPS,SVPPP,
0000500      *      SUSS,SUSP,SUPS,SUPPS,SUPPP,
0000600      *      DSESS,DSESP/
0000700      *-2.144,2.09,2.09,2.346,-0.588,
0000800      *) .123,-0.366,-0.366,0.435,-0.154,
0000900      *-5.29,1.049/
0001000      JATA VSS,VSP,VPS,VPPS,VPPP,
0001100      *      USS,USP,UPS,UPPS,UPPP,
0001200      *      DESS,DESP,DEDS,DEOP/
0001300      *      -2.85,5.4,9.5,5.4,-1.4,
0001400      *      -0.15,0.,0.,0.45,-0.45,
0001500      *      4.42,10.67,-14.63,-1.83/
0001600 C      *-1.5,3.76,3.5,5.71,-0.64,
0001700 C      *-0.6,0.8,0.8,1.29,-0.16,
0001800 C      *3.86,8.36,-16.36,-1.77/
0001900 C-----PP PARAMETERS-----
0002000 C      JATA SVSS,SVSP,SVPS,SVPPS,SVPPP,
0002100 C      *      SUSS,SUSP,SUPS,SUPPS,SUPPP,
0002200 C      *      DSESS,DSESP/
0002300 C      *      -2.08,2.12,2.12,2.32,-0.52,
0002400 C      *      0.,0.,0.,0.58,-0.1,
0002500 C      *      -4.203,0.187/
0002600 C-----CJ PARAMETERS-----
0002700 C      JATA SVSS,SVSP,SVPS,SVPPS,SVPPP,
0002800 C      *      SUSS,SUSP,SUPS,SUPPS,SUPPP,
0002900 C      *      DSESS,DSESP/
0003000 C      *      -2.075,2.7583,2.7583,3.129,-0.9212,
0003100 C      *      5*0.,
0003200 C      *      -4.2,1.7/
0003300      JATA ZOS,ZOP,ZSS,ZSP/2.246,2.227,1.6344,1.4284/,
0003400      *      ROS/3.0434/
0003500      JATA B/2.58/
0003600      JATA DSO,DSS/-10.4,-5.15/
0003700      ESS=DSO+DESS
0003800      ESP=DSO+DESP
0003900      EOS=DSO+DEOS
0004000      EOP=DSO+DEOP
0004100      SESS=DSESS+DSS
0004200      SESP=DSESP+DSS
0004300      IF(NANK.EQ.5) GO TO 200
0004400      IF(NANK.EQ.2.AND.NANL.EQ.4) GO TO 400
0004500 C      IF((NANK.NE.2.AND.NANL.EQ.4).OR.
0004600 C      *      (NANK.EQ.2.AND.NANL.NE.4)) GO TO 30
0004700      IF(ABS(R).GT.0.01) GO TO 20
0004800 C-----DIAGANAL-----
0004900 C      IF(NANK.EQ.4) GO TO 15
0005000      IF(ANK.EQ.14.AND.LCI.EQ.0) GO TO 11
0005100      IF(ANK.EQ.14.AND.LCI.EQ.1) GO TO 12
0005200      IF(ANK.EQ.8.AND.LCI.EQ.0) GO TO 13
0005300      IF(ANK.EQ.8.AND.LCI.EQ.1) GO TO 14
0005400      STOP 0005
0005500      11 HH=ESS ;GO TO 1
0005600      12 HH=ESP ;GO TO 1
0005700      13 HH=EOS ;GO TO 1
0005800      14 HH=EOP ;GO TO 1
    
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005900 C 15 CONTINUE
006000 C IF(LCI.EQ.0) GO TO 16
006100 C IF(LCI.EQ.1) GO TO 17
006200 C 16 4H=SESS ;GO TO 1
006300 C 17 4H=SESP ;GO TO 1
006400 20 CONTINUE
006500 IF(ANK.EQ.14.AND.ANL.EQ.14) GO TO 30
006600 IF(ANK.EQ.14.AND.ANL.EQ.8) GO TO 40
006700 IF(ANK.EQ.8.AND.ANL.EQ.14) GO TO 50
006800 IF(ANK.EQ.8.AND.ANL.EQ.8) GO TO 60
006900 STOP 0006
007000 C-----SI-SI-----
007100 30 CONTINUE
007200 4H=0. ;GO TO 1
007300 C-----SI-D-----
007400 40 CONTINUE
007500 IF(LCI.EQ.0.AND.LCJ.EQ.0) GO TO 41
007600 IF(LCI.EQ.0.AND.LCJ.EQ.1) GO TO 42
007700 IF(LCI.EQ.1.AND.LCJ.EQ.0) GO TO 43
007800 IF(MCI.EQ.0) GO TO 44
007900 IF(MCI.EQ.1) GO TO 45
008000 STOP 0007
008100 41 4H=VSS*OVERS(3,0,0,ZSS,2,0,0,ZOS,R,1)/
008200 * OVERS(3,0,0,ZSS,2,0,0,ZOS,ROS,1);GO TO 1
008300 42 4H=VSP*OVERS(3,0,0,ZSS,2,1,0,ZOP,R,1)/
008400 * OVERS(3,0,0,ZSS,2,1,0,ZOP,ROS,1);GO TO 1
008500 43 4H=-VPS*OVERS(3,1,0,ZSP,2,0,0,ZOS,R,1)/
008600 * OVERS(3,1,0,ZSP,2,0,0,ZOS,ROS,1);GO TO 1
008700 44 4H=VPPS*OVERS(3,1,0,ZSP,2,1,0,ZOP,R,1)/
008800 * OVERS(3,1,0,ZSP,2,1,0,ZOP,ROS,1);GO TO 1
008900 45 4H=VPPP*OVERS(3,1,1,ZSP,2,1,1,ZOP,R,1)/
009000 * OVERS(3,1,1,ZSP,2,1,1,ZOP,ROS,1);GO TO 1
009100 C 41 4H=VSS ;GO TO 1
009200 C 42 4H=VSP ;GO TO 1
009300 C 43 4H=-VPS ;GO TO 1
009400 C 44 4H=VPPS ;GO TO 1
009500 C 45 4H=VPPP ;GO TO 1
009600 C-----D-SI-----
009700 50 CONTINUE
009800 IF(LCI.EQ.0.AND.LCJ.EQ.0) GO TO 51
009900 IF(LCI.EQ.0.AND.LCJ.EQ.1) GO TO 52
010000 IF(LCI.EQ.1.AND.LCJ.EQ.0) GO TO 53
010100 IF(MCI.EQ.0) GO TO 54
010200 IF(MCI.EQ.1) GO TO 55
010300 STOP 0011
010400 51 4H=VSS*OVERS(2,0,0,ZOS,3,0,0,ZSS,R,1)/
010500 * OVERS(2,0,0,ZOS,3,0,0,ZSS,ROS,1);GO TO 1
010600 52 4H=VPS*OVERS(2,0,0,ZOS,3,1,0,ZSP,R,1)/
010700 * OVERS(2,0,0,ZOS,3,1,0,ZSP,ROS,1);GO TO 1
010800 53 4H=-VSP*OVERS(2,1,0,ZOP,3,0,0,ZSS,R,1)/
010900 * OVERS(2,1,0,ZOP,3,0,0,ZSS,ROS,1);GO TO 1
011000 54 4H=VPPS*OVERS(2,1,0,ZOP,3,1,0,ZSP,R,1)/
011100 * OVERS(2,1,0,ZOP,3,1,0,ZSP,ROS,1);GO TO 1
011200 55 4H=VPPP*OVERS(2,1,1,ZOP,3,1,1,ZSP,R,1)/
011300 * OVERS(2,1,1,ZOP,3,1,1,ZSP,ROS,1);GO TO 1
011400 C 51 4H=VSS ;GO TO 1
011500 C 52 4H=VPS ;GO TO 1
011600 C 53 4H=-VSP ;GO TO 1
011700 C 54 4H=VPPS ;GO TO 1
011800 C 55 4H=VPPP ;GO TO 1
011900 C-----D-D-----
012000 60 CONTINUE
012100 IF(LCI.EQ.0.AND.LCJ.EQ.0) GO TO 61
012200 IF(LCI.EQ.0.AND.LCJ.EQ.1) GO TO 62
012300 IF(LCI.EQ.1.AND.LCJ.EQ.0) GO TO 63
012400 IF(MCI.EQ.0) GO TO 64

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0012500 IF(MCI.EQ.1) GO TO 65
0012600 STOP 0012
0012700 61 HH=USS ;GO TO 1
0012800 62 HH=USP ;GO TO 1
0012900 63 HH=-UPS ;GO TO 1
0013000 64 HH=UPPS ;GO TO 1
0013100 65 HH=UPPP ;GO TO 1
0013200 C-----SILICON-----
0013300 200 CONTINUE
0013400 IF(ABS(R).LT.0.01) GO TO 220
0013500 IF(ABS(R).GT.5.) GO TO 210
0013600 C-----1ST NEAREST-----
0013700 400 CONTINUE
0013900 EXPBR=EXP(B*(2.35-.529*R))
0014000 C 3=B
0014100 IF(LCI.EQ.0.AND.LCJ.EQ.0) GO TO 201
0014200 IF(LCI.EQ.0.AND.LCJ.EQ.1) GO TO 202
0014300 IF(LCI.EQ.1.AND.LCJ.EQ.0) GO TO 203
0014400 IF(MCI.EQ.0) GO TO 204
0014500 IF(MCI.EQ.1) GO TO 205
0014600 STOP 0008
0014700 201 HH=EXPBR*SVSS ;GO TO 1
0014800 202 HH=EXPBR*SVSP ;GO TO 1
0014900 203 HH=EXPBR*(-SVPS) ;GO TO 1
0015000 204 HH=EXPBR*SVPPS ;GO TO 1
0015100 205 HH=EXPBR*SVPPP ;GO TO 1
0015200 C 201 HH=SVSS/0.239*OVERS(3,0,0,ZSS,3,0,0,ZSS,R,1);GO TO 1
0015300 C 202 HH=SVSP/(-0.358)*OVERS(3,0,0,ZSS,3,1,0,ZSP,R,1);GO TO 1
0015400 C 203 HH=-SVPS/(0.358)*OVERS(3,1,0,ZSP,3,0,0,ZSS,R,1);GO TO 1
0015500 C 204 HH=SVPPS/(-0.378)*OVERS(3,1,0,ZSP,3,1,0,ZSP,R,1);GO TO 1
0015600 C 205 HH=SVPPP/0.189*OVERS(3,1,1,ZSP,3,1,1,ZSP,R,1);GO TO 1
0015700 C-----2ND NEAREST-----
0015800 210 CONTINUE
0016000 IF(LCI.EQ.0.AND.LCJ.EQ.0) GO TO 211
0016100 IF(LCI.EQ.0.AND.LCJ.EQ.1) GO TO 212
0016200 IF(LCI.EQ.1.AND.LCJ.EQ.0) GO TO 213
0016300 IF(MCI.EQ.0) GO TO 214
0016400 IF(MCI.EQ.1) GO TO 215
0016500 STOP 0009
0016600 211 HH=SUSS ;GO TO 1
0016700 212 HH=SUSP ;GO TO 1
0016800 213 HH=-SUPS ;GO TO 1
0016900 214 HH=SUPPS ;GO TO 1
0017000 215 HH=SUPPP ;GO TO 1
0017100 C 211 HH=SUSS/0.026*OVERS(3,0,0,ZSS,3,0,0,ZSS,R,1);GO TO 1
0017200 C 212 HH=SUSP/(-0.059)*OVERS(3,0,0,ZSS,3,1,0,ZSP,R,1);GO TO 1
0017300 C 213 HH=-SUPS/(0.059)*OVERS(3,1,0,ZSP,3,0,0,ZSS,R,1);GO TO 1
0017400 C 214 HH=SUPPS/(-0.111)*OVERS(3,1,0,ZSP,3,1,0,ZSP,R,1);GO TO 1
0017500 C 215 HH=SUPPP/0.020*OVERS(3,1,1,ZSP,3,1,1,ZSP,R,1);GO TO 1
0017600 220 IF(LCI.EQ.0) GO TO 221
0017700 IF(LCI.EQ.1) GO TO 222
0017800 STOP 0013
0017900 221 HH=SESS ;GO TO 1
0018000 222 HH=SESP ;GO TO 1
0018100 1 CONTINUE
0018200 C WRITE(6,101) HH
0018300 C 101 FORMAT(' HH=',F10.3)
0018400 RETURN ;END
0018500 SUBROUTINE INTGRL
0018600 COMMON/ARRAYS/S(40,40),Y(9,5,203),Z(17,45)
0018700 COMMON/NATOMS/ NATOMS,N,NK
0018800 COMMON/INFO/ AN(40),NOUT
0018900 COMMON/INFO1/CZ(40),J(80),ULIM(40),LLIM(40),ULK,ULL,ANL,ANK
0019000 COMMON/GAB/T(9,9),PAIRS(9,9),TEMP(9,9),C1(3),C2(3)
0019100 COMMON/AUXINT/A(17),B(17)
0019200 COMMON/VOIP/ VOIP(4,10),AZETA(4,10),CONST,OM1,OM2,VP(4,10),

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0019300 * AZP(4,10)
0019400 COMMON /POS/POS(3,10),BL,AU,TH,PAI,R2,R3
0019500 COMMON /NC/NC(18),LC(10),MC(10)
0019600 COMMON /NAN/NAN(40)
0019700 DIMENSION P(80,80)
0019800 DIMENSION E(3),Q(40)
0019900 EQUIVALENCE (P(1),Y(1))
0020000 INTEGER AN,ULIM,ULK,JLL,CZ,U,ANL,ANK
0020100 C JEBUG,SUBCHK
0020200 C-----DETERMINATION OF SIZE OF AO BASIS IN AND CORE CHARGE CZ
0020300 CALL MAKEDN(1,3)
0020400 J=0
0020500 DO 60 I=1,NATOMS
0020600 LLIM(I) = N+1
0020700 <=1
0020800 IF (AN(I).EQ.0) GO TO 10
0020900 IF (AN(I).LT.11) GO TO 20
0021000 10 J=N+4
0021100 CZ(I)=AN(I)-10
0021200 GO TO 50
0021300 20 IF (AN(I).LT.3) GO TO 40
0021400 30 J=N+4
0021500 CZ(I) = AN(I)-2
0021600 GO TO 50
0021700 40 J=N+1
0021800 CZ(I)= AN(I)
0021900 50 CONTINUE
0022000 JLIM(I) = N
0022100 60 CONTINUE
0022200 C-----ASSIGNMENT OF ANGULAR MOMENTUM QUANTUM NOS. TO ATOMIC ORBITALS
0022300 LC(1)=0
0022400 LC(2)=1
0022500 LC(3)=1
0022600 LC(4)=1
0022700 LC(5)=2
0022800 LC(6)=2
0022900 LC(7)=2
0023000 LC(8)=2
0023100 LC(9)=2
0023200 1C(1)=0
0023300 1C(2)=1
0023400 1C(3)=-1
0023500 1C(4)=0
0023600 1C(5)=0
0023700 1C(6)=1
0023800 1C(7)=-1
0023900 1C(8)=2
0024000 1C(9)=-2
0024100 C-----FILL U ARRAY---U(J) IDENTIFIES THE ATOM TO WHICH ORBITAL J IS
0024200 C-----ATTACHED E.G. ORBITAL 32 ATTACHED TO ATOM 7, ETC.
0024300 C-----ASSIGNMENT OF ORBITAL EXPONENTS TO ATOMS BY SLATERS RULES
0024400 NC(8)=2 ;NC(14)=3
0024500 DO 92 K=1,NATOMS
0024600 LLK=LLIM(K)
0024700 JLK=ULIM(K)
0024800 ANK=AN(K)
0024900 JRBK=ULK-LLK+1
0025000 DO 92 I=1,NDRBK
0025100 LLKP=LLK+I-1
0025200 LCZETA=LC(I)+1
0025300 Q(LLKP)=AZETA(LCZETA,K)
0025400 Q(LLKP)=Q(LLKP)
0025500 J(LLKP)=K
0025600 92 CONTINUE
0025700 C-----STEP THRU PAIRS OF ATOMS
0025800 DO 320 K=1,NATOMS

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0025900      DO 320 L=K,NATOMS
0026000      DO 100 I=1,3
0026100      C1(I)=POS(I,K)
0026200      100 C2(I)=POS(I,L)
0026300 C-----CALCULATE UNIT VECTOR ALONG INTERATOM AXIS,E
0026400      CALL RELVEC(R,E,C1,C2)
0026500      THD=(180.-TH)/2.
0026600      CRD=(2.*COS(THD*PAI/180.)+0.1)*BL/AU
0026610      IF(K.EQ.5.AND.L.EQ.6) GO TO 101
0026620      IF(K.EQ.1.AND.L.EQ.6) GO TO 101
0026700      IF(K.EQ.8.AND.L.EQ.10) GO TO 101
0026800      IF(R.GT.CRD) GO TO 320
0026900      101 CONTINUE
0027000      LLK = LLIM(K)
0027100      LLL = LLIM(L)
0027200      JLK = ULIM(K)
0027300      JLL = ULIM(L)
0027400      JDRBK=JLK-LLK+1
0027500      JDRBL=ULL-LLL+1
0027600      ANK=AN(K)
0027700      ANL=AN(L)
0027800      IF(ANK.EQ.0.OR.ANL.EQ.0) GO TO 150
0027900 C-----LOOP THRU PAIRS OF BASIS FUNCTIONS, ONE ON EACH ATOM
0028000      DO 200 I=1,NORBK
0028100      DO 200 J=1,NORBL
0028200      IF(K.EQ.L) GO TO 160
0028300      110 IF(MC(I).NE.MC(J)) GO TO 150
0028400      120 IF(MC(I).LT.0) GO TO 140
0028500      LLKP=LLK+I-1 ; LLLP=LLL+J-1
0028600 C 130 PAIRS(I,J)= SQRT((Q(LLKP)*R)**(2*NC(ANK)+1)*(Q(LLLP)*R)**(2*NC(
0028700 C    1)+1)/(FACT(2*NC(ANK))*FACT(2*NC(ANL))))*(-1.D0)**(LC(J)+MC(J))
0028800 C    2*SS(NC(ANK),LC(I),MC(I),NC(ANL),LC(J),Q(LLKP)*R,Q(LLLP)*R)
0028900      130 PAIRS(I,J)=HH(ANK,LC(I),MC(I),ANL,LC(J),R,NAN(K),NAN(L))
0029000      GO TO 190
0029100      140 PAIRS(I,J)=PAIRS(I-1,J-1)
0029200      GO TO 190
0029300      150 PAIRS(I,J)=0.0D0
0029400      GO TO 190
0029500      160 IF (I.EQ.J) GO TO 170
0029600      180 PAIRS(I,J)=0.0D0
0029700      GO TO 190
0029800 C 170 PAIRS(I,J)=1.0D0
0029900      170 IF(MC(I).LT.0) GO TO 171
0030000      PAIRS(I,J)=HH(ANK,LC(I),MC(I),ANL,LC(J),R,NAN(K),NAN(L))
0030100      GO TO 190
0030200      171 PAIRS(I,J)=PAIRS(I-1,J-1)
0030300      190 CONTINUE
0030400      200 CONTINUE
0030500      LCULK=LC(NORBK)
0030600      LCULL=LC(NORBL)
0030700      MAXL=MAX0(LCULK,LCULL)
0030800      IF(R.GT.0.000001D0) GO TO 220
0030900      210 GO TO 250
0031000 C-----ROTATE INTEGRALS FROM DIATOMIC BASIS TO MOLECULAR BASIS
0031100      220 CALL HARMTR(T,MAXL,E)
0031200      DO 230 I=1,NORBK
0031300      DO 230 J=1,NORBL
0031400      TEMP(I,J) = 0.D0
0031500      DO 230 KK=1,NORBL
0031600      TEMP(I,J) = TEMP(I,J)+T(J,KK)*PAIRS(I,KK)
0031700      230 CONTINUE
0031800      DO 240 I=1,NORBK
0031900      DO 240 J=1,NORBL
0032000      PAIRS(I,J) = 0.D0
0032100      DO 240 KK=1,NORBK
0032200      PAIRS(I,J) = PAIRS(I,J)+T(I,KK)*TEMP(KK,J)

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032300 240 CONTINUE
032400 C-----FILL S MATRIX
032500 250 CONTINUE
032600 DO 260 I=1,NORBK
032700 LLKP=LLK+I-1
032800 DO 260 J=1,NORBL
032900 LLLP=LLL+J-1
033000 260 S(LLKP,LLLP)=PAIRS(I,J)
033100 320 CONTINUE
033200 380 CONTINUE
033300 RETURN
033400 END
033500 PROGRAM GEE
033600 IMPLICIT COMPLEX (G,V,Z)
033700 COMMON/ARRAYS/S(40,40),Y(9,5,203),AZ(17,45)
033800 COMMON /POS/POS(3,10),BL,AU,TH,PAI,R2,R3
033900 COMMON /H/H(40,40)
034000 DIMENSION GLCC(16,16),GSCCM1(16,16),VCED01(16,16),
034100 * ZP(16,16),ZQ(16,16),IT1(16),IT2(16)
034200 DIMENSION GST(16,16,15)
034300 DIMENSION GSSSM1(4,4),GBBBM1(16,16),GOOD(4,4),
034400 * GOODM1(4,4),VOSD(4,4),VBXD(16,8),GXSS(4,4),
034500 * GX00(4,4),GXSD(4,4),GXOS(4,4),GXXX(8,8),
034600 * GXXXM1(8,8),GPBB(16,16),GPXX(8,8),
034700 * GPBX(16,8),GPXB(8,16),ZW4(4),ZW8(8),ZW16(16),
034800 * IP4(4),IP8(8),IP16(16),GSSSK(4,4)
034900 DIMENSION GOUT(4,4,20)
035000 DATA IT1/1,4,2,3,13,14,15,16,5,6,7,8,9,10,11,12/,
035100 * IT2/1,3,4,2,9,10,11,12,13,14,15,16,5,6,7,8/
035200 DATA AU/.529167/,PAI/3.141592/,BL/1.61/
035300 C JEBUG,SUBCHK
035400 NN=20
035500 READ(21) (((GOUT(I,J,K),I=1,4),J=1,4),K=1,NN)
035600 C READ(5,100) EI,DE,EF,DELTA,EPSP
035700 C 100 FORMAT(5F10.0)
035800 EI=-5.5 ;EF=-3.6 ;EPSP=0.05
035900 CALL SETSH
036000 C CALL RWRITE(H,'H ',40,40,8)
036100 C CALL RWRITE(S,'S ',40,40,8)
036200 C-----RESET GLCC-----
036300 DO 10 J=1,16
036400 DO 10 I=1,16
036500 10 GLCC(I,J)=0.
036600 E=EI-0.1 ;NUME=0
036700 C-----CHANGE ENERGY-----
036800 1 DE=0.1 ;DELTA=0.04 ;NUME=NUME+1
036900 C IF(E.GE.-6.01.AND.E.LT.-4.01) DE=0.05
037000 E=E+DE
037100 C IF(E.GT.-5.99.AND.E.LT.-3.99) DELTA=0.02
037200 IF(E.GT.EF+0.1*DE) STUP 0001
037300 ZE=CMPLX(E,DELTA)
037400 J=0
037500 IN=0 ;ISW=0
037600 C-----CALCULATE GSCCM1 & VCED01-----
037700 DO 11 J=1,16
037800 DO 11 I=1,16
037900 GSCCM1(I,J)=ZE*S(I,J)-H(I,J)
038000 11 VCED01(I,J)=H(I,J+16)-ZE*S(I,J+16)
038100 C-----ITERATION FOR GLCC(E)-----
038200 2 J=N+1
038300 DO 20 I=1,16
038400 DO 20 J=I,16
038500 ZP(J,I)=0.
038600 DO 21 K=1,16
038700 DO 21 L=1,16
038800 21 ZP(J,I)=ZP(J,I)+VCED01(J,K)*GLCC(K,L)*VCED01(I,L)

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0038900 20 ZP(I,J)=ZP(J,I)
0039000    DO 22 I=1,16
0039100    DO 22 J=I,16
0039200    ZQ(J,I)=GSCCM1(J,I)-ZP(J,I)-ZP(IT1(J),IT1(I))-ZP(IT2(J),IT2(I))
0039300 22 ZQ(I,J)=ZQ(J,I)
0039400    CALL INVS(ZQ)
0039500 C-----CONVERGENCE CHECK-----
0039600    C1=ABS(GLCC(1,1)-ZQ(1,1))/(ABS(ZQ(1,1))+0.001)
0039700    C2=ABS(GLCC(2,2)-ZQ(2,2))/(ABS(ZQ(2,2))+0.001)
0039800    C3=ABS(GLCC(5,5)-ZQ(5,5))/(ABS(ZQ(5,5))+0.001)
0039900    C4=ABS(GLCC(6,6)-ZQ(6,6))/(ABS(ZQ(6,6))+0.001)
0040000    EPSC=C1+C2+C3+C4
0040100    DO 30 I=1,16
0040200    DO 30 J=I,16
0040300        GLCC(J,I)=ZQ(J,I)
0040400 30 GLCC(I,J)=ZQ(J,I)
0040500    IF(EPSC.GT.EPSG) GO TO 3
0040600 C-----WRITE ON FILE-----
0040700 C    CALL CWRITE(GLCC,'GLCC ',16,16,8)
0040800    WRITE(20) GLCC(1,1),GLCC(2,2),GLCC(1,2),GLCC(2,3)
0040900    *           , ((GLCC(I,J),I=5,8),J=5,8)
0041000    *           , ((GLCC(I,J),I=1,4),J=5,8)
0041100    *           , ((GLCC(I,J),I=5,8),J=9,12)
0041200    WRITE(6,102) N,NUME,E,EPSC,GLCC(1,1),GLCC(2,2),GLCC(5,5),GLCC(6
0041300    DO 303 J=1,4
0041400    DO 303 I=1,4
0041500 303 GSSSK(I,J)=GOUT(I,J,NUME)
0041600 C    CALL CWRITE(GSSSK,'GSSSK',4,4,4)
0041700 C-----MAKE GSSSM1,GBBBM1,GOOD,GDOOM1-----
0041800    DO 300 J=1,4
0041900    DO 300 I=1,4
0042000 300 GSSSM1(I,J)=GSSSK(I,J)
0042100    CALL CINV(GSSSM1,4,0,4,4,1.D-14,ZDET,ZW4,IP4,NSTOP)
0042200 C    CALL CWRITE(GSSSM1,'GSSSM1',4,4,4)
0042300    DO 301 J=1,16
0042400    DO 301 I=1,16
0042500 301 GBBBM1(I,J)=GLCC(I,J)
0042600    CALL CINV(GBBBM1,16,0,16,16,1.D-14,ZDET,ZW16,IP16,NSTOP)
0042700 C    CALL CWRITE(GBBBM1,'GBBBM1',16,16,8)
0042800    DO 302 J=1,4
0042900    DO 302 I=1,4
0043000    GDOOM1(I,J)=ZE*S(I+32,J+32)-H(I+32,J+32)
0043100 302 GOOD(I,J)=GDOOM1(I,J)
0043200    CALL CINV(GOOD,4,0,4,4,1.D-14,ZDET,ZW4,IP4,NSTOP)
0043300 C    CALL CWRITE(GOOD,'GOOD ',4,4,4)
0043400 C    CALL CWRITE(GDOOM1,'GDOOM1',4,4,4)
0043500 C-----MAKE VOSD AND VSXD-----
0043600    DO 310 J=1,4
0043700    DO 310 I=1,4
0043800 310 VOSD(I,J)=H(I+32,J+36)-ZE*S(I+32,J+36)
0043900    DO 311 J=1,8
0044000    DO 311 I=1,16
0044100 311 VBXD(I,J)=H(I,J+32)-ZE*S(I,J+32)
0044200 C    CALL CWRITE(VOSD,'VOSD ',4,4,4)
0044300 C    CALL CWRITE(VBXD,'VBXD ',16,8,8)
0044400 C-----CALCULATE GXSS, GXDD, GXSD, GXDS-----
0044500    DO 320 J=1,4
0044600    DO 320 I=1,4
0044700    GXSS(I,J)=GSSSM1(I,J) ;GXDD(I,J)=GDOOM1(I,J)
0044800    DO 320 K=1,4
0044900    DO 320 L=1,4
0045000    GXDD(I,J)=GXDD(I,J)-VOSD(I,L)*GSSSK(L,K)*VOSD(J,K)
0045100 320 GXSS(I,J)=GXSS(I,J)-VOSD(L,I)*GOOD(L,K)*VOSD(K,J)
0045200    CALL CINV(GXSS,4,0,4,4,1.D-14,ZDET,ZW4,IP4,NSTOP)
0045300    CALL CINV(GXDD,4,0,4,4,1.D-14,ZDET,ZW4,IP4,NSTOP)
0045400 C    CALL CWRITE(GXSS,'GXSS ',4,4,4)

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0045500 C CALL CWRITE(GX00,'GX00 ',4,4,4)
0045600 JJ 322 J=1,4
0045700 JJ 322 I=1,4
0045800 3XS0(I,J)=0. ;GX0S(I,J)=0.
0045900 JJ 322 K=1,4
0046000 JJ 322 L=1,4
0046100 3XSD(I,J)=GXSO(I,J)+GSSSK(I,L)*VUSD(K,L)*GX00(K,J)
0046200 322 3XOS(I,J)=GXOS(I,J)+G000(I,L)*VUSD(L,K)*GXSS(K,J)
0046300 C-----MAKE GXXX AND GXXXM1-----
0046400 JJ 330 J=1,4
0046500 JJ 330 I=1,4
0046600 3XXX(I,J)=GX00(I,J)
0046700 3XXX(I+4,J+4)=GXSS(I,J)
0046800 3XXX(I,J+4)=GXOS(I,J)
0046900 330 3XXX(I+4,J)=GXSD(I,J)
0047000 JJ 331 J=1,8
0047100 JJ 331 I=1,8
0047200 331 3XXXM1(I,J)=GXXX(I,J)
0047300 CALL CINV(GXXXM1,8,0,8,8,1.D-14,ZDET,ZW8,IP8,NSTOP)
0047400 C CALL CWRITE(GXXX,'GXXX ',8,8,8)
0047500 C CALL CWRITE(GXXXM1,'GXXXM1',8,8,8)
0047600 C-----CALCULATE GPBB, GPXX, GPBX, GPXB-----
0047700 JJ 340 J=1,16
0047800 JJ 340 I=1,16
0047900 3PBB(I,J)=GBBBM1(I,J)
0048000 JJ 340 K=1,8
0048100 JJ 340 L=1,8
0048200 340 3PBB(I,J)=GPBB(I,J)-VBXD(I,L)*GXXX(L,K)*VBXD(J,K)
0048300 CALL CINV(GPBB,16,0,16,16,1.D-14,ZDET,ZW16,IP16,NSTOP)
0048400 JJ 341 J=1,8
0048500 JJ 341 I=1,8
0048600 3PXX(I,J)=GXXXM1(I,J)
0048700 JJ 341 K=1,16
0048800 JJ 341 L=1,16
0048900 341 3PXX(I,J)=GPXX(I,J)-VBXD(L,I)*GLCC(L,K)*VBXD(K,J)
0049000 CALL CINV(GPXX,8,0,8,8,1.D-14,ZDET,ZW8,IP8,NSTOP)
0049100 C CALL CWRITE(GPBB,'GPBB ',16,16,8)
0049200 C CALL CWRITE(GPXX,'GPXX ',8,8,8)
0049300 JJ 342 J=1,8
0049400 JJ 342 I=1,16
0049500 3PBX(I,J)=0. ;GPXB(J,I)=0.
0049600 JJ 342 K=1,8
0049700 JJ 342 L=1,16
0049800 3PBX(I,J)=GPBX(I,J)+GLCC(I,L)*VBXD(L,K)*GPXX(K,J)
0049900 342 3PXB(J,I)=GPXB(J,I)+GXXX(J,K)*VBXD(L,K)*GPBB(L,I)
0050000 C CALL CWRITE(GPBX,'GPBX ',16,8,8)
0050100 C CALL CWRITE(GPXB,'GPXB ',8,16,8)
0050200 WRITE(6,343) (GX00(I,I),I=1,4),(GXSS(I,I),I=1,4),
0050300 * (GPBB(I,I),I=1,16),(GPXX(I,I),I=1,8)
0050400 343 FORMAT(' GX004,GXSS4,GPBB16,GPXX8=',8(/1H ,8F10.3))
0050500 GO TO 1
0050600 3 CONTINUE
0050700 102 FORMAT(1H ,2I3,F7.2,F8.3,8F7.3,12)
0050800 C-----AVERAGING-----
0050900 AG2=AIMAG(GLCC(1,1))
0051000 IF(E.LT.-10.) AG2=AIMAG(GLCC(6,6))
0051100 IF(N.LT.3) GO TO 40
0051200 GO TO 46
0051300 46 IF((AG2-AG1)*(AG1-AG0).GT.0.) GO TO 41
0051400 IF(IN.GE.14) GO TO 44
0051500 GO TO(43,44) ,ISW
0051600 43 ISW=ISW+1
0051700 41 IF(ISW.EQ.0) GO TO 40
0051800 IN=IN+1
0051900 JJ 45 I=1,16
0052000 JJ 45 J=1,16

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0052100 45 GST(J,I,IN)=GLCC(J,I)
0052200 30 TO 40
0052300 44 DO 47 I=1,16
0052400 DO 47 J=1,16
0052500 GLCC(J,I)=0.
0052600 DO 48 K=1,IN
0052700 48 GLCC(J,I)=GLCC(J,I)+GST(J,I,K)
0052800 GLCC(J,I)=GLCC(J,I)/IN
0052900 47 GLCC(I,J)=GLCC(J,I)
0053000 ISW=0 ;IN=0
0053100 40 AGO=AG1 ;AG1=AG2
0053200 30 TO 2
0053300 END
0053400 SUBROUTINE SETSH
0053500 COMMON/ARRAYS/S(40,40),Y(9,5,203),Z(17,45)
0053600 COMMON/NATOMS/ NATOMS,N,NK
0053700 COMMON/INFO/ AN(40),NOUT
0053800 COMMON/INFO1/CZ(40),U(80),ULIM(40),LLIM(40),ULK,ULL,ANL,ANK
0053900 COMMON /CON/CSSSS,CSSSX,CSSXX,COOSS,COOSX,COOXX,CSS,CSX,CXS,CXX
0054000 INTEGER AN,ULIM,ULK,ULL,CZ,U,ANL,ANK
0054100 COMMON/VOIP/ VOIP(4,10),AZETA(4,10),CONST,OM1,OM2,VP(4,10),
0054200 * AZP(4,10)
0054300 COMMON /POS/POS(3,10),BL,AU,TH,PAI,R2,R3
0054400 COMMON /H/H(40,40)
0054500 COMMON /NC/NC(18),LC(10),MC(10)
0054600 COMMON /NAN/NAN(40)
0054700 DIMENSION TVEC(3),POS0(3,4),POS1(3,4),ROT0(4,4,4),ROT1(4,4,4),
0054800 * ROT(40,40),SD(40,40),HD(40,40)
0054900 DATA AN/14,8,8,8,14,8,8,8,8,14/,NATOMS/10/
0055000 DATA NAN/2,1,1,1,1,1,1,1,3,4/
0055100 C DEBUG,SUBCHK
0055200 1000 READ(5,14) VOIP(1,1),VOIP(2,1),VOIP(1,4),VOIP(2,4)
0055300 14 FORMAT(4F10.0)
0055400 READ(5,14) AZETA(1,1),AZETA(2,1),AZETA(1,4),AZETA(2,4)
0055500 READ(5,5) CSSSS,CSSSX,CSSXX,COOSS,COOSX,COOXX
0055600 5 FORMAT(3F10.0)
0055700 READ(5,8) CSS,CSX,CXS,CXX
0055800 8 FORMAT(4F10.0)
0055900 CALL COEFFT
0056000 WRITE(6,15) VOIP(1,1),VOIP(2,1),VOIP(1,4),VOIP(2,4)
0056100 15 FORMAT(' VOIP=',4F10.3)
0056200 WRITE(6,16) AZETA(1,1),AZETA(2,1),AZETA(1,4),AZETA(2,4)
0056300 16 FORMAT(' AZETA=',4F10.3)
0056400 WRITE(6,7) CSSSS,CSSSX,CSSXX,COOSS,COOSX,COOXX
0056500 7 FORMAT(' CSSSS,CSSSX,CSSXX,COOSS,COOSX,COOXX=',6F10.3)
0056600 WRITE(6,13) CSS,CSX,CXS,CXX
0056700 13 FORMAT(' CSS,CSX,CXS,CXX=',4F10.3)
0056800 DO 20 I=1,2
0056900 VOIP(I,5)=VOIP(I,1) ;AZETA(I,5)=AZETA(I,1)
0057000 VOIP(I,10)=VOIP(I,1) ;AZETA(I,10)=AZETA(I,1)
0057100 DO 21 J=2,3
0057200 VOIP(I,J)=VOIP(I,4) ;AZETA(I,J)=AZETA(I,4)
0057300 21 CONTINUE
0057400 DO 22 J=6,9
0057500 VOIP(I,J)=VOIP(I,4) ;AZETA(I,J)=AZETA(I,4)
0057600 22 CONTINUE
0057700 20 CONTINUE
0057800 C-----CALCULATE POSITIONS FOR GROUP 0-----
0057900 TVEC(1)=0. ;TVEC(2)=0. ;TVEC(3)=0.
0058000 CALL POSROT(0.,0.,0.,BL,AU,TVEC,POS0,ROT0)
0058100 DO 30 I=1,3
0058200 DO 30 J=1,4
0058300 30 POS(I,J)=POS0(I,J)
0058400 C-----CALCULATE POSITIONS FOR GROUP 1-----
0058500 READ(5,32) TH
0058600 32 FORMAT(F10.0)

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0058700 ALPHA=199.47-TH ;ALPHAR=ALPHA*PAI/180.
0058800 TVEC(1)=(.9428+COS(ALPHAR))*BL/AU
0058900 TVEC(2)=0.
0059000 TVEC(3)=(.3333+SIN(ALPHAR))*BL/AU
0059100 RY=19.47-(128.94-TH)
0059200 CALL POSROT(0.,RY,0.,BL,AU,TVEC,POS1,ROT1)
0059300 DO 33 I=1,3
0059400 DO 33 J=1,4
0059500 33 POS(I,J+4)=POS1(I,J)
0059600 C-----CALCULATE POSITIONS FOR OX-----
0059700 POS(1,9)=0. ;POS(2,9)=0. ;POS(3,9)=-BL/AU
0059800 POS(1,10)=0. ;POS(2,10)=0. ;POS(3,10)=-2*BL/AU
0059900 WRITE(6,1001) ((POS(I,J),J=1,10),I=1,3)
0060000 1001 FORMAT(10F9.3)
0060100 CALL INTGRL
0060200 DO 35 J=1,40
0060300 DO 35 I=1,40
0060400 F(I,J)=S(I,J)
0060500 35 S(I,J)=0.
0060600 DO 36 I=1,40
0060700 36 S(I,I)=1.
0060800 C-----CALCULATION OF H MATRIX-----
0060900 C DO 408 K=1,NATOMS
0061000 C DO 408 L=K,NATOMS
0061100 C LLK=LLIM(K)
0061200 C LLL=LLIM(L)
0061300 C ULK=ULIM(K)
0061400 C ULL=ULIM(L)
0061500 C NORBK=ULK-LLK+1
0061600 C NORBL=ULL-LLL+1
0061700 C DO 409 I=1,NORBK
0061800 C DO 409 J=1,NORBL
0061900 C LLKP=LLK+I-1
0062000 C LLLP=LLL+J-1
0062100 C LCI=LC(I)+1
0062200 C LCJ=LC(J)+1
0062300 C IF(LLKP.EQ.LLLP) GO TO 410
0062400 C LLKPU=U(LLKP) ;LLLPU=U(LLL)
0062500 C IF(AN(LLKPU).EQ.14.AND.AN(LLLPU).EQ.14) GO TO 411
0062600 C IF(AN(LLKPU).EQ.8 .AND.AN(LLLPU).EQ.8 ) GO TO 412
0062700 C IF(LCI.EQ.1.AND.LCJ.EQ.1) GO TO 416
0062800 C IF(LCI.GE.2.AND.LCJ.GE.2) GO TO 417
0062900 C IF((AN(LLKPU).EQ.14.AND.LCI.EQ.1).OR.
0063000 C * (AN(LLLPU).EQ.14.AND.LCJ.EQ.1)) GO TO 418
0063100 C CONST=CXS ;GO TO 413
0063200 C 418 CONST=CSX ;GO TO 413
0063300 C 416 CONST=CSS ;GO TO 413
0063400 C 417 CONST=CXX ;GO TO 413
0063500 C 411 IF(LCI.EQ.1.AND.LCJ.EQ.1) GO TO 422
0063600 C IF(LCI.GE.2.AND.LCJ.GE.2) GO TO 423
0063700 C CONST=CSSSX ;GO TO 413
0063800 C 422 CONST=CSSSS ;GO TO 413
0063900 C 423 CONST=CSSXX ;GO TO 413
0064000 C 412 IF(LCI.EQ.1.AND.LCJ.EQ.1) GO TO 420
0064100 C IF(LCI.GE.2.AND.LCJ.GE.2) GO TO 421
0064200 C CONST=COOSX ;GO TO 413
0064300 C 420 CONST=COOSS ;GO TO 413
0064400 C 421 CONST=COOXX ;GO TO 413
0064500 C 413 CONTINUE
0064600 C H(LLKP,LLL)=-S(LLKP,LLL)*(VOIP(LCI,K)+VOIP(LCJ,L))*
0064700 C * CONST/2.
0064800 C GO TO 409
0064900 C 410 F(LLKP,LLKP)=-VOIP(LCI,K)
0065000 C 409 CONTINUE
0065100 C 408 CONTINUE
0065200 C-----ROTATION TO DESIRED ATOMIC BASIS-----

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0065300 JJ 161 J=1,40
0065400 JJ 161 I=1,40
0065500 161 ROT(I,J)=0.
0065600 JJ 162 J=1,4
0065700 ROT(J+32,J+32)=1.
0065800 JJ 162 I=1,4
0065900 ROT(I,J)=ROT0(I,J,1)
0066000 ROT(I+4,J+4)=ROT0(I,J,2)
0066100 ROT(I+8,J+8)=ROT0(I,J,3)
0066200 ROT(I+12,J+12)=ROT0(I,J,4)
0066300 ROT(I+16,J+16)=ROT1(I,J,1)
0066400 ROT(I+20,J+20)=ROT1(I,J,2)
0066500 ROT(I+24,J+24)=ROT1(I,J,3)
0066600 162 ROT(I+28,J+28)=ROT1(I,J,4)
0066700 TVEC(1)=0. ;TVEC(2)=0. ;TVEC(3)=-2*BL/AU
0066800 CALL POSROT(0.,180.,0.,BL,AU,TVEC,POS0,ROT0)
0066900 JJ 166 J=1,4
0067000 JJ 166 I=1,4
0067100 166 ROT(I+36,J+36)=ROT0(I,J,1)
0067200 JJ 163 I=1,40
0067300 JJ 163 J=1,40
0067400 S(J,I)=S(I,J)
0067500 163 H(J,I)=H(I,J)
0067600 C CALL RWRITE(H,'H',40,40,8)
0067700 C CALL RWRITE(S,'S',40,40,8)
0067800 C CALL RWRITE(ROT,'ROT',40,40,8)
0067900 JJ 164 J=1,40
0068000 JJ 164 I=1,40
0068100 SD(I,J)=0. ;HD(I,J)=0.
0068200 JJ 164 K=1,40
0068300 SD(I,J)=SD(I,J)+S(I,K)*ROT(K,J)
0068400 164 HD(I,J)=HD(I,J)+H(I,K)*ROT(K,J)
0068500 JJ 165 J=1,40
0068600 JJ 165 I=1,40
0068700 S(I,J)=0. ;H(I,J)=0.
0068800 JJ 165 K=1,40
0068900 S(I,J)=S(I,J)+ROT(K,I)*SD(K,J)
0069000 165 H(I,J)=H(I,J)+ROT(K,I)*HD(K,J)
0069100 RETURN ;END
0069200 SUBROUTINE POSROT(RX,RY,RZ,BL,AU,TVEC,POS,ROT)
0069300 DIMENSION TVEC(3),POS(3,4),ROT(4,4,4),HM(3,4),PM(3,3,3),
0069400 * T(4,4),TD(4,4)
0069500 DATA HM/0.,0.,-1.,.9428,.0.,.3333,
0069600 * -.4714,.8165,.3333,-.4714,-.8165,.3333/,
0069700 * PM/.9428,.0.,.3333,.0,1.,.0,-.3333,.0,.9428,
0069800 * -.4714,.8165,.3333,-.8660,-.5,.0,.1667,-.2887,.9428,
0069900 * -.4714,-.8165,.3333,.8660,-.5,.0,.1667,.2887,.9428/
0070000 C JDEBUG,SUBCHK
0070100 PAI=3.141592
0070200 X=RX*PAI/180. ;Y=RY*PAI/180. ;Z=RZ*PAI/180.
0070300 JJ 50 I=1,3
0070400 JJ 50 J=1,4
0070500 50 POS(I,J)=BL*HM(I,J)/AU
0070600 POS(3,1)=0.
0070700 JJ 51 I=1,4
0070800 51 ROT(1,I,1)=.5
0070900 JJ 52 I=2,4
0071000 ROT(1,1,I)=1.
0071100 JJ 52 J=2,4
0071200 ROT(1,J,I)=0.
0071300 52 ROT(J,1,I)=0.
0071400 JJ 53 I=1,3
0071500 JJ 53 J=1,4
0071600 53 ROT(I+1,J,1)=HM(I,J)*.8660
0071700 JJ 54 K=1,3
0071800 JJ 54 J=1,3

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0071900      JO 54 I=1,3
0072000      54 ROT(I+1,J+1,K+1)=PM(I,J,K)
0072100      IF(X.EQ.0.) GO TO 20
0072200 C-----X AXIS ROTATION-----
0072300      JO 11 J=1,4
0072400      JO 11 I=1,4
0072500      11 T(I,J)=0.
0072600          T(1,1)=1. ;T(2,2)=1.
0072700          ;X=SIN(X) ;CX=COS(X)
0072800          T(3,3)=CX ;T(3,4)=-SX
0072900          T(4,3)=SX ;T(4,4)=CX
0073000      JO 12 J=1,4
0073100      JO 12 I=1,4
0073200          TD(I,J)=0.
0073300      JO 12 K=1,4
0073400      12 TD(I,J)=TD(I,J)+T(I,K)*ROT(K,J,1)
0073500      JO 13 J=1,4
0073600      JO 13 I=1,4
0073700      13 ROT(I,J,1)=TD(I,J)
0073800      JO 15 L=2,4
0073900      JO 14 J=1,4
0074000      JO 14 I=1,4
0074100          TD(I,J)=0.
0074200      JO 14 K=1,4
0074300      14 TD(I,J)=TD(I,J)+T(I,K)*ROT(K,J,L)
0074400      JO 15 J=1,4
0074500      JO 15 I=1,4
0074600      15 ROT(I,J,L)=TD(I,J)
0074700      JO 16 J=1,4
0074800      JO 16 I=1,3
0074900          TD(I,J)=0.
0075000      JO 16 K=1,3
0075100      16 TD(I,J)=TD(I,J)+T(I+1,K+1)*POS(K,J)
0075200      JO 17 J=1,4
0075300      JO 17 I=1,3
0075400      17 POS(I,J)=TD(I,J)
0075500 C-----Y AXIS ROTATION-----
0075600      20 IF(Y.EQ.0.) GO TO 30
0075700      JO 21 J=1,4
0075800      JO 21 I=1,4
0075900      21 T(I,J)=0.
0076000          T(1,1)=1. ;T(3,3)=1.
0076100          ;Y=SIN(Y) ;CY=COS(Y)
0076200          T(2,2)=CY ;T(2,4)=SY
0076300          T(4,2)=-SY ;T(4,4)=CY
0076400      JO 22 J=1,4
0076500      JO 22 I=1,4
0076600          TD(I,J)=0.
0076700      JO 22 K=1,4
0076800      22 TD(I,J)=TD(I,J)+T(I,K)*ROT(K,J,1)
0076900      JO 23 J=1,4
0077000      JO 23 I=1,4
0077100      23 ROT(I,J,1)=TD(I,J)
0077200      JO 25 L=2,4
0077300      JO 24 J=1,4
0077400      JO 24 I=1,4
0077500          TD(I,J)=0.
0077600      JO 24 K=1,4
0077700      24 TD(I,J)=TD(I,J)+T(I,K)*ROT(K,J,L)
0077800      JO 25 J=1,4
0077900      JO 25 I=1,4
0078000      25 ROT(I,J,L)=TD(I,J)
0078100      JO 26 J=1,4
0078200      JO 26 I=1,3
0078300          TD(I,J)=0.
0078400      JO 26 K=1,3

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0078500 26 TD(I,J)=TD(I,J)+T(I+1,K+1)*POS(K,J)
0078600    JO 27 J=1,4
0078700    JO 27 I=1,3
0078800 27 POS(I,J)=TD(I,J)
0078900 C-----Z AXIS ROTATION-----
0079000 30 IF(Z.EQ.0.) GO TO 40
0079100    JO 31 J=1,4
0079200    JO 31 I=1,4
0079300 31 T(I,J)=0.
0079400    T(1,1)=1. ;T(4,4)=1.
0079500    SZ=SIN(Z) ;CZ=COS(Z)
0079600    T(2,2)=CZ ;T(2,3)=-SZ
0079700    T(3,2)=SZ ;T(3,3)=CZ
0079800    JO 32 J=1,4
0079900    JO 32 I=1,4
0080000    TD(I,J)=0.
0080100    JO 32 K=1,4
0080200 32 TD(I,J)=TD(I,J)+T(I,K)*ROT(K,J,1)
0080300    JO 33 J=1,4
0080400    JO 33 I=1,4
0080500 33 ROT(I,J,1)=TD(I,J)
0080600    JO 35 L=2,4
0080700    JO 34 J=1,4
0080800    JO 34 I=1,4
0080900    TD(I,J)=0.
0081000    JO 34 K=1,4
0081100 34 TD(I,J)=TD(I,J)+T(I,K)*ROT(K,J,L)
0081200    JO 35 J=1,4
0081300    JO 35 I=1,4
0081400 35 ROT(I,J,L)=TD(I,J)
0081500    JO 36 J=1,4
0081600    JO 36 I=1,3
0081700    TD(I,J)=0.
0081800    JO 36 K=1,3
0081900 36 TD(I,J)=TD(I,J)+T(I+1,K+1)*POS(K,J)
0082000    JO 37 J=1,4
0082100    JO 37 I=1,3
0082200 37 POS(I,J)=TD(I,J)
0082300 40 JO 41 J=1,4
0082400    JO 41 I=1,3
0082500 41 POS(I,J)=POS(I,J)+TVEC(I)
0082600    RETURN ;END
0082700    SUBROUTINE INVS(A)
0082800    COMPLEX A,N
0082900    DIMENSION A(16,16),NOSEQ(16)
0083000 C    JEBUG,SUBCHK
0083100    EPSL=1.E-10 ;N=16
0083200    JO 10 NN=1,N
0083300 10 NOSEQ(NN)=NN
0083400    JO 100 NN=1,N
0083500    P=0.
0083600    JO 20 I=NN,N
0083700    IF(P-ABS(A(I,1))) 21,20,20
0083800 21 P=ABS(A(I,1))
0083900    IP=I
0084000 20 CONTINUE
0084100    IF(P-EPSL) 4,4,5
0084200 4 WRITE(6,22)
0084300 22 FORMAT(' PIVOT IS TOO SMALL. I DON'T THINK YOU ARE SMART. ')
0084400 5 IW=NOSEQ(IP)
0084500    NOSEQ(IP)=NOSEQ(NN)
0084600    NOSEQ(NN)=IW
0084700    JO 30 J=1,N
0084800    W=A(IP,J)
0084900    A(IP,J)=A(NN,J)
0085000 30 A(NN,J)=W

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085100      V=A(NN,1)
085200      DD 40 J=2,N
085300      40 A(NN,J-1)=A(NN,J)/W
085400      A(NN,N)=1./W
085500      DD 50 I=1,N
085600      IF(I-NN) 51,50,51
085700      51 V=A(I,1)
085800      DD 60 J=2,N
085900      60 A(I,J-1)=A(I,J)-W*A(NN,J-1)
086000      A(I,N)=-W*A(NN,N)
086100      50 CONTINUE
086200      100 CONTINUE
086300      DD 200 NN=1,N
086400      DD 70 J=NN,N
086500      IF(NOSEQ(J)-NN) 70,71,70
086600      70 CONTINUE
086700      71 NOSEQ(J)=NOSEQ(NN)
086800      DD 80 I=1,N
086900      V=A(I,J)
087000      A(I,J)=A(I,NN)
087100      80 A(I,NN)=W
087200      200 CONTINUE
087300      RETURN ;END

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ER GEE DF A1402.S.FORT LIST END

DATA0 JF A1402.S.FORT

000010	-5.5	-3.6	0.1	0.04	0.05
000020	179.				
000100	14.95	7.78	29.6	12.7	
000200	1.6344	1.4284	2.2460	2.227	
000300	.87	1.69	2.5		
000400	2.5	4.3	6.0		
000500	1.34	2.1	2.1	2.9	
000600	180.				
000700					
000800					
000900					
001000					
001100					
001200					
001300					
001400					
001500					
001600					

DATA0 JF A1402.S.FORT LIST END

ER GEE0

JF A1402.I.FORT

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0000100      PROGRAM GEE0
0000200      IMPLICIT COMPLEX*8 (G,V,Z)
0000300      COMMON/ARRAYS/S(40,40),Y(9,5,203),AZ(17,45)
0000400      COMMON /POS/POS(3,10),BL,AU,TH,PAI,R2,R3
0000500      COMMON /H/H(40,40)
0000600      DIMENSION GB11(16,16),GB11M1(16,16),V1AD(16,4),GAAA(4,4),
0000700      *          GAAAM1(4,4),GABAA(4,4),GAB11(16,16),GABA1(4,16),
0000800      *          GAB1A(16,4),ZW4(4),ZW16(16),IP4(4),IP16(16)
0000900      DIMENSION GOUT(8,8)
0001000      DIMENSION GCCCM1(20,20),GICC(20,20),V2CD(16,20),ZW20(20),
0001100      *          IP20(20)
0001200      DIMENSION GD(16,16),RM(130,20)
0001300      DATA AU/.529167/,PAI/3.141592/,BL/1.61/
0001400      WRITE(6,8)
0001500      8 FORMAT(' INPUT EI,EF,DE,DELTA IN 4F10.0')
0001600      EI=-11. ;EF=0. ;DE=0.1 ;DELTA=0.04
0001700      READ(5,9) DEI,DEF,DDE,DDELTA
0001800      9 FORMAT(4F10.0)
0001900      IF(DEI.NE.0.) EI=DEI
0002000      IF(DEF.NE.0.) EF=DEF
0002100      IF(DDE.NE.0.) DE=DDE
0002200      IF(DDELTA.NE.0.) DELTA=DDELTA
0002300      NN=(EF-EI+0.01)/DE ;NN=NN+1
0002400      REWIND 22
0002500      ISKIP=(EI-(-11.)+0.01)/DE
0002600      IF(ISKIP.EQ.0) GO TO 103
0002700      JO 104 I=1,ISKIP
0002800      CALL TREAD(GB11)
0002900      104 CONTINUE
0003000      103 CONTINUE
0003100      READ(5,105) IOUT
0003200      105 FORMAT(I3)
0003300      C-----SET UP S AND H-----
0003400      CALL SHBAB(IANS)
0003500      C      CALL RWRITE(H,'H      ',40,40,10)
0003600      C      CALL RWRITE(S,'S      ',40,40,10)
0003700      E=EI-DE ;NUME=0
0003800      C-----CHANGE ENERGE-----
0003900      1  NUME=NUME+1
0004000      E=E+DE
0004100      IF(E.GT.EF+0.1*DE) GO TO 3
0004200      ZE=CMPLX(E,DELTA)
0004300      C-----CALL TREAD-----
0004400      CALL TREAD(GB11)
0004500      C      CALL CWRITE(GB11,'GB11 ',16,16,8)
0004600      IF(IANS.EQ.0) GO TO 101
0004700      C-----MAKE V1AD AND GAAAM1-----
0004800      JO 10 J=1,4
0004900      JO 10 I=1,16
0005000      10 V1AD(I,J)=H(I,J+16)-ZE*S(I,J+16)
0005100      IF(NUME.EQ.1.AND.IOUT.EQ.1)
0005200      * CALL CWRITE(V1AD,'V1AD ',16,4,4)
0005300      JO 11 J=1,4
0005400      JO 11 I=1,4
0005500      11 GAAAM1(I,J)=ZE*S(I+16,J+16)-H(I+16,J+16)
0005510      IF(NUME.EQ.1.AND.IOUT.EQ.1)
0005520      * CALL CWRITE(GAAAM1,'GAAAM1',4,4,4)
0005600      C      CALL CWRITE(GAAAM1,'GAAAM1',4,4,4)

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0005700 C-----MAKE GAAA AND GB11M1-----
0005800     JO 20 J=1,4
0005900     JO 20 I=1,4
0006000     20 GAAA(I,J)=GAAAM1(I,J)
0006100     CALL CINV(GAAA,4,0,4,4,1.D-14,ZDET,ZW4,IP4,NSTOP)
0006200 C     CALL CWRITE(GAAA,'GAAA',4,4,4)
0006300     JO 21 J=1,16
0006400     JO 21 I=1,16
0006500     21 GB11M1(I,J)=GB11(I,J)
0006600     CALL CINV(GB11M1,16,0,16,16,1.D-14,ZDET,ZW16,IP16,NSTOP)
0006700 C     CALL CWRITE(GB11M1,'GB11M1',16,16,8)
0006800     GO TO 150
0006900 C-----CALCULATE GABAA AND GAB11-----
0007000 C-----SI-SI BOND IN SIU2-----
0007100     101 CONTINUE
0007200 C-----MAKE VIAD AND GAAAM1 AND GAAA----
0007300     JO 110 J=1,4
0007400     JO 110 I=1,16
0007500     110 VIAD(I,J)=H(I,J+20)-ZE*S(I,J+20)
0007600     JO 112 J=1,4
0007700     JO 112 I=5,16
0007800     112 VIAD(I,J)=0.
0007900 C     CALL CWRITE(VIAD,'VIAD',16,4,4)
0008000     JO 111 J=1,4
0008100     JO 111 I=1,4
0008200     GAAA(I,J)=GB11(I,J)
0008300     111 GAAAM1(I,J)=GB11(I,J)
0008400     CALL CINV(GAAAM1,4,0,4,4,1.D-14,ZDET,ZW4,IP4,NSTOP)
0008500 C     CALL CWRITE(GAAA,'GAAA',4,4,4)
0008600 C     CALL CWRITE(GAAAM1,'GAAAM1',4,4,4)
0008700 C-----MAKE GB11M1-----
0008800     JO 120 J=1,16
0008900     JO 120 I=1,16
0009000     120 GB11M1(I,J)=GB11(I,J)
0009100     CALL CINV(GB11M1,16,0,16,16,1.D-14,ZDET,ZW16,IP16,NSTOP)
0009200 C     CALL CWRITE(GB11M1,'GB11M1',16,16,8)
0009300     150 CONTINUE
0009400     JO 31 J=1,4
0009500     JO 31 I=1,4
0009600     GABAA(I,J)=GAAAM1(I,J)
0009700     JO 31 K=1,16
0009800     JO 31 L=1,16
0009900     31 GABAA(I,J)=GABAA(I,J)-VIAD(L,I)*GB11(L,K)*VIAD(K,J)
0010000     CALL CINV(GABAA,4,0,4,4,1.D-14,ZDET,ZW4,IP4,NSTOP)
0010100 C     CALL CWRITE(GABAA,'GABAA',4,4,4)
0010200     JO 32 J=1,16
0010300     JO 32 I=1,16
0010400     GAB11(I,J)=GB11M1(I,J)
0010500     JO 32 K=1,4
0010600     JO 32 L=1,4
0010700     32 GAB11(I,J)=GAB11(I,J)-VIAD(I,L)*GAAA(L,K)*VIAD(J,K)
0010800     CALL INVS(GAB11)
0010900 C     CALL CWRITE(GAB11,'GAB11',16,16,8)
0011000 C-----CALCULATE GABA1 AND GAB1A-----
0011100     JO 40 J=1,16
0011200     JO 40 I=1,4
0011300     GABA1(I,J)=0.
0011400     JO 40 K=1,16
0011500     JO 40 L=1,4
0011600     40 GABA1(I,J)=GABA1(I,J)+GAAA(I,L)*VIAD(K,L)*GAB11(K,J)
0011700 C     CALL CWRITE(GABA1,'GABA1',4,16,8)
0011800     JO 41 J=1,4
0011900     JO 41 I=1,16
0012000     GAB1A(I,J)=0.
0012100     JO 41 K=1,4
0012200     JO 41 L=1,16

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0012300      41  GAB1A(I,J)=GAB1A(I,J)+GB11(I,L)*VIAD(L,K)*GABAA(K,J)
0012400 C      CALL CWRITE(GAB1A,'GAB1A',16,4,4)
0012500 C-----MAKE GOUT-----
0012600      DO 42 J=1,4
0012700      DO 42 I=1,4
0012800          GOUT(I,J)=GAB11(I,J)
0012900          GOUT(I+4,J+4)=GABAA(I,J)
0013000          GOUT(I,J+4)=GAB1A(I,J)
0013100      42  GOUT(I+4,J)=GABA1(I,J)
0013200 C      CALL CWRITE(GOUT, 'GOUT ',8,8,8)
0013300 C-----OUTPUT-----
0013400      WRITE(6,100) E,(GOUT(I,I),I=1,8)
0013500      100 FORMAT(1H ,17F7.3)
0013600      IF(IANS.EQ.0) GO TO 72
0013700      WRITE(20) ((GOUT(I,J),J=I,8),I=1,8)
0013800 C-----MAKE GCCM1 AND V2CD-----
0013900      DO 50 J=1,20
0014000      DO 50 I=1,16
0014100      50  V2CD(I,J)=H(I+20,J)-ZE* $S(I+20,J)$ 
0014200          JMIN=5
0014300          IF(IANS.NE.0) JMIN=1
0014400          DO 54 J=JMIN,16
0014500          DO 54 I=1,4
0014600      54  V2CD(I,J)=0.
0014700          IF(NUME.EQ.1.AND.IOUT.EQ.1)
0014800          * CALL CWRITE(V2CD,'V2CD ',16,20,8)
0014900          DO 51 J=1,4
0015000          DO 51 I=1,4
0015100      51  GCCCM1(I+16,J+16)=GABAA(I,J)
0015200          DO 52 J=1,16
0015300          DO 52 I=1,16
0015400      52  GCCCM1(I,J)=GAB11(I,J)
0015500          DO 53 J=1,4
0015600          DO 53 I=1,16
0015700          GCCCM1(I,J+16)=GAB1A(I,J)
0015800      53  GCCCM1(J+16,I)=GABA1(J,I)
0015810 C      CALL CWRITE(GCCCM1,'GCCCM1',20,20,8)
0015900 C      CALL CINV(GCCCM1,20,0,20,20,1.D-14,ZDET,ZW20,IP20,NSTOP)
0015910 C      CALL CWRITE(GCCCM1,'GCCCM1',20,20,8)
0016000 C-----CALCULATE GICC-----
0016100      DO 60 J=1,16
0016200      DO 60 I=1,20
0016300          GD(I,J)=0.
0016400      DO 60 L=1,16
0016500      60  GD(I,J)=GD(I,J)+V2CD(L,I)*GB11(L,J)
0016600      DO 61 J=1,20
0016700      DO 61 I=1,20
0016800          GICC(I,J)=GCCCM1(I,J)
0016900      DO 61 L=1,16
0017000      61  GICC(I,J)=GICC(I,J)-GD(I,L)*V2CD(L,J)
0017010 C      CALL CWRITE(GICC,'GICC ',20,20,8)
0017100 C      CALL CINV(GICC,20,0,20,20,1.D-14,ZDET,ZW20,IP20,NSTOP)
0017110 C      CALL CWRITE(GICC,'GICC ',20,20,8)
0017120 C-----OUTPUT GOOD FOR WEAK-----
0017130 C      WRITE(28) ((GICC(I,J),J=17,20),I=17,20)
0017140      WRITE(29) ((GICC(I,J),J=1,4),I=1,4)
0017200      72 CONTINUE
0017300      DO 70 I=1,8
0017400      70  RM(NUME,I)=AIMAG(GOUT(I,I))
0017500      DO 71 I=1,12
0017600      71  RM(NUME,I+8)=AIMAG(GICC(I+8,I+8))
0017700      WRITE(6,73) E,(RM(NUME,I),I=1,20)
0017800      73 FORMAT(1H ,13F7.3)
0017900      GO TO 1
0018000      3 CONTINUE
0018100      WRITE(30) ((RM(NUME,I),I=1,20),NUME=1,NN)

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00018200 CALL RMAT(RM,'RM ',130,20,NN,10)
00018300 STOP 0002
00018400 END
00018500 SUBROUTINE SHBAB(IAN5)
00018600 COMMON/ARRAYS/S(40,40),Y(9,5,203),Z(17,45)
00018700 COMMON/NATOMS/ NATOMS,N,NK
00018800 COMMON/INFO/ AN(40),NOUT
00018900 COMMON/INFO1/CZ(40),U(80),ULIM(40),LLIM(40),ULK,ULL,ANL,ANK
00019000 COMMON /CON/CSSSS,CSSSX,CSSXX,COOSS,COOSX,COOXX,CSS,CSX,CXS,CX
00019100 INTEGER AN,ULIM,ULK,ULL,CZ,U,ANL,ANK
00019200 COMMON/VOIP/ VOIP(4,10),AZETA(4,10),CONST,OM1,OM2,VP(4,10),
00019300 * AZP(4,10)
00019400 COMMON /POS/POS(3,10),BL,AU,TH,PAI,R2,R3
00019500 COMMON /H/H(40,40)
00019600 COMMON /NC/NC(18),LC(10),MC(10)
00019700 COMMON /NAN/NAN(40)
00019800 DIMENSION TVEC(3),POS0(3,4),POS1(3,4),ROT0(4,4,4),ROT1(4,4,4),
00019900 * ROT(40,40),SD(40,40),HD(40,40)
0020000 DATA AN/14,8,8,8,8,14,8,8,8/,NATOMS/9/
0020100 DATA NAN/2,1,1,1,3,4,1,1,1/
0020200 1000 READ(5,14) VOIP(1,1),VOIP(2,1),VOIP(1,4),VOIP(2,4)
0020300 14 FORMAT(4F10.0)
0020400 READ(5,14) AZETA(1,1),AZETA(2,1),AZETA(1,4),AZETA(2,4)
0020500 READ(5,5) CSSSS,CSSSX,CSSXX,COOSS,COOSX,COOXX
0020600 5 FORMAT(3F10.0)
0020700 READ(5,8) CSS,CSX,CXS,CXX
0020800 8 FORMAT(4F10.0)
0020900 CALL COEFFT
0021000 WRITE(6,15) VOIP(1,1),VOIP(2,1),VOIP(1,4),VOIP(2,4)
0021100 15 FORMAT(' VOIP=',4F10.3)
0021200 WRITE(6,16) AZETA(1,1),AZETA(2,1),AZETA(1,4),AZETA(2,4)
0021300 16 FORMAT(' AZETA=',4F10.3)
0021400 WRITE(6,7) CSSSS,CSSSX,CSSXX,COOSS,COOSX,COOXX
0021500 7 FORMAT(' CSSSS,CSSSX,CSSXX,COOSS,COOSX,COOXX=',6F10.3)
0021600 WRITE(6,13) CSS,CSX,CXS,CXX
0021700 13 FORMAT(' CSS,CSX,CXS,CXX=',4F10.3)
0021800 DO 20 I=1,2
0021900 VOIP(I,6)=VOIP(I,1) ;AZETA(I,6)=AZETA(I,1)
0022000 DO 21 J=2,3
0022100 VOIP(I,J)=VOIP(I,4) ;AZETA(I,J)=AZETA(I,4)
0022200 21 CONTINUE
0022300 DO 22 J=7,9
0022400 VOIP(I,J)=VOIP(I,4) ;AZETA(I,J)=AZETA(I,4)
0022500 22 CONTINUE
0022600 20 CONTINUE
0022700 C-----INPUT INFORMATION ON IMPURITY-----
0022800 READ(5,200) AN(5),ETA1,ETA2
0022900 200 FORMAT(I2,2F10.0)
0023000 WRITE(6,202) AN(5),ETA1,ETA2
0023100 IAN5=AN(5)
0023200 202 FORMAT(' AN(5),ETA1,ETA2=',I2,2F10.3)
0023300 READ(5,201) VOIP(1,5),VOIP(2,5)
0023400 READ(5,201) AZETA(1,5),AZETA(2,5)
0023500 201 FORMAT(2F10.0)
0023600 WRITE(6,203) VOIP(1,5),VOIP(2,5),AZETA(1,5),AZETA(2,5)
0023700 203 FORMAT(' VOIP=',2F10.3,' AZETA=',2F10.3)
0023800 READ(5,204) CASSS,CASSX,CASXS,CASXX,
0023900 * CAOSS,CAOSX,CAOXS,CAOXX
0024000 204 FORMAT(8F10.0)
0024100 WRITE(6,205) CASSS,CASSX,CASXS,CASXX,
0024200 * CAOSS,CAOSX,CAOXS,CAOXX
0024300 205 FORMAT(' CASSS,CASSX,CASXS,CASXX,CAOSS,CAOSX,CAOXS,CAOXX=',
0024400 * 8F10.3)
0024500 IF(AN(5).NE.8) GO TO 23
0024600 DO 24 I=1,2
0024700 VOIP(I,5)=VOIP(I,4) ;AZETA(I,5)=AZETA(I,4)

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024800 24 CONTINUE
024900 23 CONTINUE
025000 C-----CALCULATE POSITIONS FOR GROUP 0-----
025100 3BLAUE1=BL/AU*(1.+ETA1)
025200 3BLAUE2=BL/AU*(1.+ETA2)
025300 TVEC(1)=0. ;TVEC(2)=0. ;TVEC(3)=BLAUE1
025400 CALL POSROT(0.,0.,0.,BL,AU,TVEC,POS0,ROT0)
025500 DD 30 I=1,3
025600 DD 30 J=1,4
025700 30 PJS(I,J)=POS0(I,J)
025800 C-----CALCULATE POSITIONS FOR GROUP A-----
025900 PJS(1,5)=0.; POS(2,5)=0. ;POS(3,5)=0.
026000 C-----CALCULATE POSITIONS FOR GROUP 1-----
026100 READ(5,32) TH,RZ
026200 32 FORMAT(2F10.0)
026300 THR=TH*PAI/180.
026400 WRITE(6,34) TH,RZ
026500 34 FORMAT(' TH,RZ=',2F10.3)
026600 TVEC(1)=SIN(THR)*BLAUE2 ;TVEC(2)=0. ;TVEC(3)=COS(THR)*BLAUE2
026700 CALL POSROT(0.,TH,RZ,BL,AU,TVEC,POS1,ROT1)
026800 DD 33 I=1,3
026900 DD 33 J=1,4
027000 33 PJS(I,J+5)=POS1(I,J)
027100 CALL RWRITE(POS,'POS ',3,10,10)
027200 CALL INTGRL
027300 DD 35 J=1,40
027400 DD 35 I=1,40
027500 H(I,J)=S(I,J)
027600 35 S(I,J)=0.
027700 DD 36 I=1,40
027800 36 S(I,I)=1.
027900 C-----CALCULATION OF H MATRIX-----
028000 C DD 408 K=1,NATOMS
028100 C DD 408 L=K,NATOMS
028200 C LLK=LLIM(K)
028300 C LLL=LLIM(L)
028400 C ULK=ULIM(K)
028500 C ULL=ULIM(L)
028600 C NORBK=ULK-LLK+1
028700 C NORBL=ULL-LLL+1
028800 C DO 409 I=1,NORBK
028900 C DO 409 J=1,NORBL
029000 C LLKP=LLK+I-1
029100 C LLLP=LLL+J-1
029200 C LCI=LC(I)+1
029300 C LCJ=LC(J)+1
029400 C IF(LLKP.EQ.LLLP) GO TO 410
029500 C LLKPU=U(LLKP) ;LLLPU=U(LLLPU)
029600 C NA=AN(5)
029700 C IF(NA.EQ.8) GO TO 414
029800 C IF(AN(LLKPU).EQ.NA.OR.AN(LLLPU).EQ.NA) GO TO 430
029900 C 414 CONTINUE
030000 C IF(AN(LLKPU).EQ.14.AND.AN(LLLPU).EQ.14) GO TO 411
030100 C IF(AN(LLKPU).EQ.8 .AND.AN(LLLPU).EQ.8 ) GO TO 412
030200 C IF(LCI.EQ.1.AND.LCJ.EQ.1) GO TO 416
030300 C IF(LCI.GE.2.AND.LCJ.GE.2) GO TO 417
030400 C IF((AN(LLKPU).EQ.14.AND.LCI.EQ.1).OR.
030500 C * (AN(LLLPU).EQ.14.AND.LCJ.EQ.1)) GO TO 418
030600 C CONST=CXS ;GO TO 413
030700 C 418 CONST=CSX ;GO TO 413
030800 C 416 CONST=CSS ;GO TO 413
030900 C 417 CONST=CXX ;GO TO 413
031000 C 411 IF(LCI.EQ.1.AND.LCJ.EQ.1) GO TO 422
031100 C IF(LCI.GE.2.AND.LCJ.GE.2) GO TO 423
031200 C CONST=CSSSX ;GO TO 413
031300 C 422 CONST=CSSSS ;GO TO 413

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031400 C 423   CONST=CSSXX ;GO TO 413
031500 C 412   IF(LCI.EQ.1.AND.LCJ.EQ.1) GO TO 420
031600 C       IF(LCI.GE.2.AND.LCJ.GE.2) GO TO 421
031700 C       CONST=CDOOSX ;GO TO 413
031800 C 420   CONST=CDOSS  ;GO TO 413
031900 C 421   CONST=CDOXX  ;GO TO 413
032000 C 430   IF(AN(LLKPU).EQ.14.OR.AN(LLLPU).EQ.14) GO TO 431
032100 C       IF(LCI.EQ.1.AND.LCJ.EQ.1) GO TO 432
032200 C       IF(LCI.GE.2.AND.LCJ.GE.2) GO TO 433
032300 C       IF((AN(LLKPU).EQ.NA.AND.LCI.EQ.1).OR.
032400 C *      (AN(LLLPU).EQ.NA.AND.LCJ.EQ.1)) GO TO 434
032500 C       CONST=CAOXS  ;GO TO 413
032600 C 432   CONST=CAOSS  ;GO TO 413
032700 C 433   CONST=CAOXX  ;GO TO 413
032800 C 434   CONST=CAOSX  ;GO TO 413
032900 C 431   IF(LCI.EQ.1.AND.LCJ.EQ.1) GO TO 435
033000 C       IF(LCI.GE.2.AND.LCJ.GE.2) GO TO 436
033100 C       IF((AN(LLKPU).EQ.NA.AND.LCI.EQ.1).OR.
033200 C *      (AN(LLLPU).EQ.NA.AND.LCJ.EQ.1)) GO TO 437
033300 C       CONST=CASXS  ;GO TO 413
033400 C 435   CONST=CASSS  ;GO TO 413
033500 C 436   CONST=CASXX  ;GO TO 413
033600 C 437   CONST=CASSX  ;GO TO 413
033700 C 413   CONTINUE
033800 C       H(LLKP,LLLPP)=-S(LLKP,LLLPP)*(VOIP(LCI,K)+VOIP(LCJ,L))*
033900 C *      CONST/2.
034000 C       GO TO 409
034100 C 410   H(LLKP,LLKP)=-VOIP(LCI,K)
034200 C 409   CONTINUE
034300 C 408   CONTINUE
034400 C       DO 1005 KK=1,3
034500 C       JMIN=16*(KK-1)+1 ;JMAX=MIN(40,16*KK)
034600 C-----ROTATION TO DESIRED ATOMIC BASIS-----
034700 C       DO 161 J=1,40
034800 C       DO 161 I=1,40
034900 C 161   ROT(I,J)=0.
035000 C       DO 162 J=1,4
035100 C       ROT(J+16,J+16)=1.
035200 C       DO 162 I=1,4
035300 C       ROT(I,J)=ROT0(I,J,1)
035400 C       ROT(I+4,J+4)=ROT0(I,J,2)
035500 C       ROT(I+8,J+8)=ROT0(I,J,3)
035600 C       ROT(I+12,J+12)=ROT0(I,J,4)
035700 C       ROT(I+20,J+20)=ROT1(I,J,1)
035800 C       ROT(I+24,J+24)=ROT1(I,J,2)
035900 C       ROT(I+28,J+28)=ROT1(I,J,3)
036000 C 162   ROT(I+32,J+32)=ROT1(I,J,4)
036100 C       WRITE(6,1002) ((ROT(II,JJ),JJ=1,40),II=1,40)
036200 C1002  FORMAT('! ROT=',10F8.3)
036300 C       DO 163 I=1,40
036400 C       DO 163 J=I,40
036500 C       S(J,I)=S(I,J)
036600 C 163   H(J,I)=H(I,J)
036700 C       DO 164 J=1,40
036800 C       DO 164 I=1,40
036900 C       SD(I,J)=0. ;HD(I,J)=0.
037000 C       DO 164 K=1,40
037100 C       SD(I,J)=SD(I,J)+S(I,K)*ROT(K,J)
037200 C 164   HD(I,J)=HD(I,J)+H(I,K)*ROT(K,J)
037300 C       DO 165 J=1,40
037400 C       DO 165 I=1,40
037500 C       S(I,J)=0. ;H(I,J)=0.
037600 C       DO 165 K=1,40
037700 C       S(I,J)=S(I,J)+ROT(K,I)*SD(K,J)
037800 C 165   H(I,J)=H(I,J)+ROT(K,I)*HD(K,J)
037900 C       RETURN ;END

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038000 SUBROUTINE TREAD(G)
038100 COMPLEX G(16,16)
038200 READ(22) G(1,1),G(2,2),G(1,2),G(2,3)
038300 *      , ((G(I,J),I=5,8),J=5,8)
038400 *      , ((G(I,J),I=1,4),J=5,8)
038500 *      , ((G(I,J),I=5,8),J=9,12)
038600 DO 201 I=3,4
038700     G(I,I)=G(2,2)
038800 201   G(I,I)=G(1,2)
038900     G(2,4)=G(2,3) ; G(3,4)=G(2,3)
039000 DO 202 I=1,4
039100     I1=I+1
039200 DO 202 J=I1,4
039300 202   G(J,I)=G(I,J)
039400 DO 203 I=5,8
039500 DO 203 J=5,8
039600     G(J+4,I+4)=G(J,I)
039700 203   G(J+8,I+8)=G(J,I)
039800 DO 204 I=5,8
039900 DO 204 J=9,12
040000     G(I+4,J+4)=G(I,J)
040100 204   G(I,J+4)=G(I,J)
040200 DO 205 I=1,4
040300     G(7,I+12)=-G(7,I+12)
040400 205   G(I+4,15)=-G(I+4,15)
040500 DO 206 I=5,8
040600     G(1,I+4)=G(1,I) ; G(1,I+8)=G(1,I)
040700     G(2,I+4)=G(4,I) ; G(2,I+8)=G(3,I)
040800     G(3,I+4)=G(2,I) ; G(3,I+8)=G(4,I)
040900     G(4,I+4)=G(3,I) ; G(4,I+8)=G(2,I)
041000 206   CONTINUE
041100 DO 207 I=1,16
041200 DO 207 J=I,16
041300 207   G(J,I)=G(I,J)
041400 RETURN ; END
041500 SUBROUTINE RWRITE(A,IC,N,M,MO)
041600 REAL A
041700 DIMENSION A(N,M),IC(2)
041800 WRITE(6,100) IC,N,M,N,MO
041900 100 FORMAT(1H0,2A4,'(',I3,',',I3,') IN (',I3,',',I3,')',
042000 *      30('*'))
042100     KMAX=M/MO
042200     IF(MO*KMAX.NE.M) KMAX=KMAX+1
042300     DO 10 K=1,KMAX
042400     JMIN=1+(K-1)*MO ; JMAX=MIN(M,MO*K)
042500     WRITE(6,103) (J,J=JMIN,JMAX)
042600 103 FORMAT(1H ,12I10)
042700     DO 11 I=1,N
042800     11 WRITE(6,101) I,(A(I,J),J=JMIN,JMAX)
042900 101 FORMAT(1H ,I2,12F10.3)
043000     WRITE(6,102)
043100 102 FORMAT(' -----')
043200     10 CONTINUE
043300     RETURN ; END
043400 SUBROUTINE CWRITE(A,IC,N,M,MO)
043500 COMPLEX*8 A
043600 DIMENSION A(N,M),IC(2)
043700 WRITE(6,100) IC,N,M,N,MO
043800 100 FORMAT(1H0,2A4,'(',I3,',',I3,') IN (',I3,',',I3,')',
043900 *      30('*'))
044000     KMAX=M/MO
044100     IF(MO*KMAX.NE.M) KMAX=KMAX+1
044200     DO 10 K=1,KMAX
044300     JMIN=1+(K-1)*MO ; JMAX=MIN(M,MO*K)
044400     WRITE(6,103) (J,J=JMIN,JMAX)
044500 103 FORMAT(1H ,8I16)

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0044600      DD 11 I=1,N
0044700      11 WRITE(6,101) I,(A(I,J),J=JMIN,JMAX)
0044800      101 FORMAT(1H ,I2,16F8.3)
0044900      WRITE(6,102)
0045000      102 FORMAT(' -----')
0045100      10 CONTINUE
0045200      RETURN ;END
0045300      SUBROUTINE TWRITE(A,IC,N,M,L,MO)
0045400      COMPLEX*8 A
0045500      DIMENSION A(N,M,L),IC(2)
0045600      WRITE(6,100) IC,N,M,L,N,MO
0045700      100 FORMAT(1H0,2A4,'(',I3,',',I3,') BY (',
0045800      *      I3,',',I3,')',30('*'))
0045900      KMAX=M/MO
0046000      IF(MO*KMAX.NE.M) KMAX=KMAX+1
0046100      DD 12 KK=1,L
0046200      DD 10 K=1,KMAX
0046300      JMIN=1+(K-1)*MO ;JMAX=MIN(M,MO*K)
0046400      WRITE(6,103) (J,J=JMIN,JMAX)
0046500      103 FORMAT(1H ,8I16)
0046600      DD 11 I=1,N
0046700      11 WRITE(6,101) I,(A(I,J,KK),J=JMIN,JMAX)
0046800      101 FORMAT(1H ,I2,16F8.3)
0046900      WRITE(6,102)
0047000      102 FORMAT(' -----')
0047100      10 CONTINUE
0047200      12 CONTINUE
0047300      RETURN ;END
0047400      SUBROUTINE RMAT(A,IC,N,M,NO,MO)
0047500      REAL A
0047600      DIMENSION A(N,M),IC(2)
0047700      WRITE(6,100) IC,N,M,NO,MO
0047800      100 FORMAT(1H0,2A4,'(',I3,',',I3,') IN (',I3,',',I3,')',
0047900      *      30('*'))
0048000      KMAX=M/MO
0048100      IF(MO*KMAX.NE.M) KMAX=KMAX+1
0048200      DD 10 K=1,KMAX
0048300      JMIN=1+(K-1)*MO ;JMAX=MIN(M,MO*K)
0048400      WRITE(6,103) (J,J=JMIN,JMAX)
0048500      103 FORMAT(1H ,16I8)
0048600      DD 11 I=1,NO
0048700      11 WRITE(6,101) I,(A(I,J),J=JMIN,JMAX)
0048800      101 FORMAT(1H ,I2,16F8.3)
0048900      WRITE(6,102)
0049000      102 FORMAT(' -----')
0049100      10 CONTINUE
0049200      RETURN ;END
0049300      SUBROUTINE CMAT(A,IC,N,M,NO,MO)
0049400      COMPLEX*8 A
0049500      DIMENSION A(N,M),IC(2)
0049600      WRITE(6,100) IC,N,M,NO,MO
0049700      100 FORMAT(1H0,2A4,'(',I3,',',I3,') IN (',I3,',',I3,')',
0049800      *      30('*'))
0049900      KMAX=M/MO
0050000      IF(MO*KMAX.NE.M) KMAX=KMAX+1
0050100      DD 10 K=1,KMAX
0050200      JMIN=1+(K-1)*MO ;JMAX=MIN(M,MO*K)
0050300      WRITE(6,103) (J,J=JMIN,JMAX)
0050400      103 FORMAT(1H ,8I16)
0050500      DD 11 I=1,NO
0050600      11 WRITE(6,101) I,(A(I,J),J=JMIN,JMAX)
0050700      101 FORMAT(1H ,I2,16F8.3)
0050800      WRITE(6,102)
0050900      102 FORMAT(' -----')
0051000      10 CONTINUE
0051100      RETURN ;END

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051200 SUBROUTINE RWRT(A,IC,M,MO)
051300 DIMENSION A(1),IC(2)
051400 WRITE(6,100) IC,MO
051500 100 FORMAT(1H0,2A4,' IN (' ,I3,')')
051600 <MAX=M/MO
051700 IF(MO*KMAX.NE.M) KMAX=KMAX+1
051800 DO 10 K=1,KMAX
051900 JMIN=1+(K-1)*MO ;JMAX=MIN(M,MO*K)
052000 WRITE(6,103) (J,J=JMIN,JMAX)
052100 103 FORMAT(1H ,16I8)
052200 WRITE(6,101) (A(J),J=JMIN,JMAX)
052300 101 FORMAT(1H ,2X,16F8.3)
052400 WRITE(6,102)
052500 102 FORMAT(' -----')
052600 10 CONTINUE
052700 RETURN ;END
052800 SUBROUTINE DWRT(A,IC,M,MO)
052900 REAL*8 A
053000 DIMENSION A(1),IC(2)
053100 WRITE(6,100) IC,MO
053200 100 FORMAT(1H0,2A4,' IN (' ,I3,')')
053300 <MAX=M/MO
053400 IF(MO*KMAX.NE.M) KMAX=KMAX+1
053500 DO 10 K=1,KMAX
053600 JMIN=1+(K-1)*MO ;JMAX=MIN(M,MO*K)
053700 WRITE(6,103) (J,J=JMIN,JMAX)
053800 103 FORMAT(1H ,16I8)
053900 WRITE(6,101) (A(J),J=JMIN,JMAX)
054000 101 FORMAT(1H ,2X,16F8.3)
054100 WRITE(6,102)
054200 102 FORMAT(' -----')
054300 10 CONTINUE
054400 RETURN ;END

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ER GEE0 OF A1402.I.FORT LIST END

ER DGEE0 JF A1402.I.FORT

0000010	-3.	0.	0.1	0.04	0.05
0000020	1				
0000100	14.95	7.78	29.6	12.7	
0000200	1.6344	1.4284	2.2460	2.227	
0000300	.87	1.69	2.5		
0000400	2.5	4.3	6.0		
0000500	1.34	2.1	2.1	2.9	
0000600	0 0.	0.			
0000700					
0000800					
0000900					
001000	120.	0.			

ER DGEE0 JF A1402.I.FORT LIST END

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PER PERFIN JF A1402.I.FORT
0000100 PROGRAM PERFIN
0000200 IMPLICIT COMPLEX*8 (G,V,Z)
0000300 COMMON/ARRAYS/S(40,40),Y(9,5,203),AZ(17,45)
0000400 COMMON /POS/POS(3,10),BL,AU,TH,PAI,R2,R3
0000500 COMMON /H/H(40,40)
0000510 REAL*4 VYS
0000520 DIMENSION GD(8,8)
0000600 DIMENSION GOUT(12,12,20),GAV(12,12,20)
0000700 *, GYYY(8,8),GSSSK(4,4),GSSSM1(4,4),GYYYM1(8,8),
0000800 * GSURF(4,4,40),
0000900 * GPYYK(8,8),GPSSK(4,4),GPSYK(4,8),GPYSK(8,4)
0001000 DIMENSION SYS(8,4),VYS(8,4),VYSD(8,4),RG3M(130),RG4M(130),
0001100 * ZW4(4),ZW8(8),IP4(4),IP8(8)
0001200 DIMENSION AV1(2),AV2(2),XV(2),YV(2),AKV(2)
0001210 DIMENSION VGV(8,8)
0001300 DATA AV1/-.6124,.3535/,AV2/-.6124,-.3535/,
0001400 * XV/-.8165,1.4142/,YV/-1.4142,-.8165/
0001500 DATA AU/.529167/,PAI/3.141592/,BL/1.61/
0001505 XV(1)=XV(1) ;YV(1)=YV(1)
0001510 REWIND 21
0001515 READ(5,11) ISKIP,NKEND
0001520 11 FORMAT(2I3)
0001525 IF(ISKIP.EQ.0) GO TO 13
0001530 DO 12 IS=1,ISKIP
0001535 READ(21) (((GSURF(I,J,NUME),I=1,4),J=1,4),NUME=1,NN),
0001540 * (RG3M(I),RG4M(I),I=1,NN)
0001545 12 CONTINUE
0001550 13 CONTINUE
0001560 WRITE(6,8)
0001570 8 FORMAT(' INPUT EI,EF,DE,DELTA,EPDG IN 5F10.0')
0001580 EI=-11. ;EF=0. ;DE=0.1 ;DELTA=0.04 ;EPDG=0.05
0001590 READ(5,9) DEI,DEF,DDE,DDELTA,DEPSG
0001600 9 FORMAT(5F10.0)
0001610 IF(DEI.NE.0.) EI=DEI
0001620 IF(DEF.NE.0.) EF=DEF
0001630 IF(DDE.NE.0.) DE=DDE
0001640 IF(DDELTA.NE.0.) DELTA=DDELTA
0001650 IF(DEPSG.NE.0.) EPDG=DEPSG
0001660 NN=(EF-EI+0.01)/DE ;NN=NN+1
0001800 C-----SET UP S AND H-----
0001900 CALL SHBAB(IAN5)
0001910 DO 6 J=1,4
0001920 DO 6 I=1,4
0001930 H(I,J+20)=0.
0001940 6 H(I+20,J)=0.
0002000 C CALL RWRITE(H,'H ',40,40,10)
0002100 C CALL RWRITE(S,'S ',40,40,10)
0002200 C-----MAKE VYS AND SYS-----
0002300 DO 400 J=1,4
0002400 DO 400 I=1,4
0002500 VYS(I,J)=H(I,J+20) ;SYS(I,J)=S(I,J+20)
0002600 VYS(I+4,J)=H(I+16,J+20) ;SYS(I+4,J)=S(I+16,J+20)
0002700 400 CONTINUE
0002800 C CALL RWRITE(VYS,'VYS ',8,4,4)
0002900 C CALL RWRITE(SYS,'SYS ',8,4,4)
0003000 C-----SCANNING OF K-----
0003100 NUMK=0
0003110 DO 1 K1=1,12

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003120 AKV(1)=-1.62+0.28*(K1-1)
003130 DO 1 K2=1,14
003140 AKV(2)=-1.88+0.28*(K2-1)
003150 IF(AKV(2).LT.(0.5774*AKV(1)-1.8856)).OR.
003160 * AKV(2).LT.(-0.5774*AKV(1)-1.8856)).OR.
003170 * AKV(2).GT.(0.5774*AKV(1)+1.8856)).OR.
003180 * AKV(2).GT.(-0.5774*AKV(1)+1.8856)) GO TO 1
003900 AK1=PAI*(AV1(1)*AKV(1)+AV1(2)*AKV(2))
004000 AK2=PAI*(AV2(1)*AKV(1)+AV2(2)*AKV(2))
004100 NUMK=NUMK+1
004110 IF(NUMK.LE.ISKIP.OR.NUMK.GT.NKEND) GO TO 1
004120 10 WRITE(6,105) AK1,AK2,K1,K2,NUMK,AKV
004180 105 FORMAT(' AK1,AK2,K1,K2,NUMK,AKV=',2F8.3,3I3,2F8.3)
004400 C-----REWIND GEE0 FILE-----
004500 REWIND 23
004600 C-----READ-IN SURF-----
004700 READ(21) ((GSURF(I,J,NUME),I=1,4),J=1,4),NUME=1,NN),
004800 * (RG3M(I),RG4M(I),I=1,NN)
004900 RG3M(1)=RG3M(1) ;RG4M(1)=RG4M(1)
005000 C-----SCANNING OF ENERGY-----
005100 E=EI-DE ;NUME=0
005200 C-----CHANGE ENERGY-----
005300 40 NUME=NUME+1
005400 C IF(E.GE.-6.01.AND.E.LT.-4.01) DE=0.05
005500 E=E+DE
005600 C IF(E.GT.-5.99.AND.E.LT.-3.99) DELTA=0.02
005700 IF(E.GT.EF+0.1*DE) GO TO 2
005800 ZE=E+(0.,1.)*DELTA
005900 C-----READ-IN GEE0(GYYY)-----
006000 READ(23) ((GYYY(I,J),J=1,8),I=1,8)
006100 DO 410 I=1,7
006200 I1=I+1
006300 DO 410 J=I1,8
006400 410 GYYY(J,I)=GYYY(I,J)
006500 C CALL CWRITE(GYYY,'GYYY ',8,8,8)
006600 C-----MAKE VYSD AND GSSS-----
006700 DO 420 J=1,4
006800 DO 420 I=1,8
006900 420 VYSD(I,J)=VYS(I,J)-ZE*SYS(I,J)
007000 C CALL CWRITE(VYSD,'VYSD ',8,4,4)
007100 DO 421 J=1,4
007200 DO 421 I=1,4
007300 GSSSK(I,J)=GSURF(I,J,NUME)
007400 421 GSSSM1(I,J)=GSSSK(I,J)
007500 C CALL CWRITE(GSSSK,'GSSSK',4,4,4)
007600 C-----MAKE GYYM1 AND GSSM1-----
007700 DO 430 J=1,8
007800 DO 430 I=1,8
007900 430 GYYM1(I,J)=GYYY(I,J)
008000 CALL CINV(GYYM1,8,0,8,8,1.D-14,ZDET,ZW8,IP8,NSTOP)
008100 CALL CINV(GSSM1,4,0,4,4,1.D-14,ZDET,ZW4,IP4,NSTOP)
008200 C CALL CWRITE(GSSM1,'GSSM1',4,4,4)
008300 C CALL CWRITE(GYYM1,'GYYM1',8,8,8)
008400 C-----CALCULATE GPYYK AND GPSSK-----
008405 DO 439 J=1,4
008410 DO 439 I=1,8
008415 GD(I,J)=0.
008420 DO 439 L=1,4
008425 439 GD(I,J)=GD(I,J)+VYSD(I,L)*GSSSK(L,J)
008430 DO 440 J=1,8
008435 DO 440 I=1,8
008440 GPYYK(I,J)=GYYM1(I,J)
008445 DO 440 L=1,4
008450 440 GPYYK(I,J)=GPYYK(I,J)-GD(I,L)*VYSD(J,L)
008500 C DO 440 J=1,8
008600 C DO 440 I=1,8

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0008700 C      GPYYK(I,J)=GYYM1(I,J)
0008800 C      JD 440 K=1,4
0008900 C      JD 440 L=1,4
0009000 C 440    GPYYK(I,J)=GPYYK(I,J)-VYSD(I,L)*GSSSK(L,K)*VYSD(J,K)
0009100      CALL CINV(GPYYK,8,0,3,8,1.D-14,ZDET,ZW8,IP8,NSTOP)
0009200 C      CALL CWRITE(GPYYK,'GPYYK',8,8,8)
0009205      JD 441 J=1,8
0009210      JD 441 I=1,4
0009215      GD(I,J)=0.
0009220      JD 441 L=1,8
0009225      441 JD(I,J)=GD(I,J)+VYSD(L,I)*GYYY(L,J)
0009230      JD 442 J=1,4
0009235      JD 442 I=1,4
0009240      GPSSK(I,J)=GSSSM1(I,J)
0009245      JD 442 L=1,8
0009250      442 GPSSK(I,J)=GPSSK(I,J)-GD(I,L)*VYSD(L,J)
0009300 C      JD 441 J=1,4
0009400 C      JD 441 I=1,4
0009500 C      GPSSK(I,J)=GSSSM1(I,J)
0009600 C      JD 441 K=1,8
0009700 C      JD 441 L=1,8
0009800 C 441    GPSSK(I,J)=GPSSK(I,J)-VYSD(L,I)*GYYY(L,K)*VYSD(K,J)
0009900      CALL CINV(GPSSK,4,0,4,4,1.D-14,ZDET,ZW4,IP4,NSTOP)
0010000 C      CALL CWRITE(GPSSK,'GPSSK',4,4,4)
0010100 C-----CALCULATE GPYSK AND GPSYK-----
0010105      JD 450 J=1,4
0010110      JD 450 I=1,8
0010115      GD(I,J)=0.
0010120      JD 450 L=1,8
0010125      450 GD(I,J)=GD(I,J)+GYYY(I,L)*VYSD(L,J)
0010130      JD 451 J=1,4
0010135      JD 451 I=1,8
0010140      GPYSK(I,J)=0.
0010145      JD 451 L=1,4
0010150      451 GPYSK(I,J)=GPYSK(I,J)+GD(I,L)*GPSSK(L,J)
0010200 C      JD 451 J=1,4
0010300 C      JD 451 I=1,8
0010400 C      GPYSK(I,J)=0.
0010500 C      JD 451 K=1,4
0010600 C      JD 451 L=1,8
0010700 C 451    GPYSK(I,J)=GPYSK(I,J)+GYYY(I,L)*VYSD(L,K)*GPSSK(K,J)
0010800 C      CALL CWRITE(GPYSK,'GPYSK',8,4,4)
0010805      JD 452 J=1,8
0010810      JD 452 I=1,4
0010815      GD(I,J)=0.
0010820      JD 452 L=1,4
0010825      452 GD(I,J)=GD(I,J)+GSSSK(I,L)*VYSD(J,L)
0010830      JD 458 J=1,8
0010835      JD 458 I=1,4
0010840      GPSYK(I,J)=0.
0010845      JD 458 L=1,8
0010850      458 GPSYK(I,J)=GPSYK(I,J)+GD(I,L)*GPYYK(L,J)
0010900 C      JD 452 J=1,8
0011000 C      JD 452 I=1,4
0011100 C      GPSYK(I,J)=0.
0011200 C      JD 452 K=1,8
0011300 C      JD 452 L=1,4
0011400 C 452    GPSYK(I,J)=GPSYK(I,J)+GSSSK(I,L)*VYSD(K,L)*GPYYK(K,J)
0011500 C      CALL CWRITE(GPSYK,'GPSYK',4,8,8)
0011600 C-----STORE IN GAV-----
0011700      JD 453 J=1,8
0011800      JD 453 I=1,8
0011900      453 GAV(I,J,NUME)=GPYYK(I,J)
0012000      JD 454 J=1,4
0012100      JD 454 I=1,4
0012200      454 GAV(I+8,J+8,NUME)=GPSSK(I,J)

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0012300      DO 455 J=1,4
0012400      DO 455 I=1,8
0012500          GAV(I,J+8,NUME)=GPYSK(I,J)
0012600      455      GAV(J+8,I,NUME)=GPSYK(J,I)
0012610      DO 456 I=1,12
0012620      456      RG3M(I)=AIMAG(GAV(I,I,NUME))
0012630      WRITE(6,457) E,(RG3M(I),I=1,12)
0012640      457      FORMAT(1H ,13F8.3)
0012650      GO TO 40
0012700 C-----WRITE OUT-----
0012710      2 CONTINUE
0012800 C      CALL TWRITE(GAV,'GAV ',12,12,20,8)
0012900 C-----AVERAGING-----
0013100      IF(NUMK.NE.1) GO TO 461
0013110      REWIND 20
0013200      WRITE(20) (((GAV(I,J,NUME),I=1,12),J=1,12),NUME=1,NN)
0013300      461 CONTINUE
0013400      REWIND 20
0013500      READ(20) (((GOUT(I,J,NUME),I=1,12),J=1,12),NUME=1,NN)
0013600      NUMK1=NUMK-1
0013700      DO 460 NUME=1,NN
0013800      DO 460 J=1,12
0013900      DO 460 I=1,12
0014000      460      GAV(I,J,NUME)=(GAV(I,J,NUME)+GOUT(I,J,NUME)*NUMK1)/NUMK
0014100 C-----WRITE ON FILE PERFIN-----
0014110      REWIND 20
0014200      WRITE(20) (((GAV(I,J,NUME),I=1,12),J=1,12),NUME=1,NN)
0014300      1 CONTINUE
0014400      STOP 0002 ;END

```

PER PERFIN OF A1402.I,FORT LIST END

PER DPERF JF A1402.1.FORT

000010	71150				
000020	-5.5	-3.6	0.1	0.04	0.05
000100	14.95	7.78	29.6	12.7	
000200	1.6344	1.4284	2.2460	2.227	
000300	.87	1.69	2.5		
000400	2.5	4.3	6.0		
000500	1.34	2.1	2.1	2.9	
000600	8				
000700					
000800					
000900					
001000	180.	0.			

PER DPERF JF A1402.1.FORT LIST END

ER DANGLE JF A1402.I.FORT

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0000100 PROGRAM DANGLE
0000200 IMPLICIT COMPLEX*8 (G,V,Z)
0000300 COMMON/ARRAYS/S(40,40),Y(9,5,203),AZ(17,45)
0000400 COMMON /POS/POS(3,10),BL,AU,TH,PAI,R2,R3
0000500 COMMON /H/H(40,40)
0000600 REAL*4 VYS
0000700 DIMENSION SYS(8,4),VYS(8,4),VYSD(8,4),
0000800 *          GPPP(12,12,20),GPSSM1(4,4),GDSS(4,4)
0000900 *,
0001000 *          ZW4(4),IP4(4)
0001000 DIMENSION GYYY(8,8)
0001100 DATA AU/.529167/,PAI/3.141592/,BL/1.61/
0001110 REWIND 20
0001120 WRITE(6,8)
0001130 8 FORMAT(' INPUT EI,EF,DE,DELTA,EPG IN 5F10.0')
0001140 EI=-5.5 ;EF=-3.6 ;DE=0.1 ;DELTA=0.04 ;EPG=0.05
0001150 READ(5,9) DEI,DEF,DDE,DDELTA,DEPSG
0001160 9 FORMAT(5F10.0)
0001170 IF(DEI.NE.0.) EI=DEI
0001180 IF(DEF.NE.0.) EF=DEF
0001190 IF(DDE.NE.0.) DE=DDE
0001200 IF(DDELTA.NE.0.) DELTA=DDELTA
0001210 IF(DEPSG.NE.0.) EPG=DEPSG
0001220 NN=(EF-EI+0.01)/DE ;NN=NN+1
0001400 C-----SET UP S AND H-----
0001500 CALL SHBAB(IAN5)
0001510 DO 6 J=1,4
0001520 DO 6 I=1,4
0001530 4(I,J+20)=0.
0001540 6 4(I+20,J)=0.
0001600 C CALL RWRITE(H,'H      ',40,40,10)
0001700 C CALL RWRITE(S,'S      ',40,40,10)
0001800 C-----MAKE VYS AND SYS-----
0001900 DO 400 J=1,4
0002000 DO 400 I=1,4
0002100 VYS(I,J)=H(I,J+20) ;SYS(I,J)=S(I,J+20)
0002200 VYS(I+4,J)=H(I+16,J+20) ;SYS(I+4,J)=S(I+16,J+20)
0002300 400 CONTINUE
0002400 C CALL RWRITE(VYS,'VYS  ',8,4,4)
0002500 C CALL RWRITE(SYS,'SYS  ',8,4,4)
0002600 C-----READ-IN PERFIN-----
0002700 READ(24) ((GPPP(I,J,NUME),I=1,12),J=1,12),NUME=1,NN)
0002800 C-----SCANNING OF ENERGY-----
0002900 E=EI-DE ;NUME=0
0003000 C-----CHANGE ENERGY-----
0003100 40 NUME=NUME+1
0003200 C IF(E.GE.-6.01.AND.E.LT.-4.01) DE=0.05
0003300 E=E+DE
0003400 C IF(E.GT.-5.99.AND.E.LT.-3.99) DELTA=0.02
0003500 IF(E.GT.EF+0.1*DE) GO TO 2
0003600 ZE=E+(0.,1.)*DELTA
0003700 C-----READ-IN GEE0(GYYY)-----
0003800 READ(23) ((GYYY(I,J),J=1,8),I=1,8)
0003900 DO 410 I=1,7
0004000 I1=I+1
0004100 DO 410 J=I1,8
0004200 410 GYYY(J,I)=GYYY(I,J)
0004300 C CALL CWRITE(GYYY,'GYYY  ',8,8,8)
0004400 C-----MAKE VYSD AND GPSSM1-----

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0004500      JD 420 J=1,4
0004600      JD 420 I=1,8
0004700      420 VYSD(I,J)=VYS(I,J)-ZE*SYS(I,J)
0004710 C      CALL CWRITE(VYSD,'VYSD ',8,4,4)
0004800      JD 422 J=1,4
0004900      JD 422 I=1,4
0005000      422 GPSSM1(I,J)=GPPP(I+8,J+8,NUME)
0005100      CALL CINV(GPSSM1,4,0,4,4,1,D-14,ZDET,ZW4,IP4,NSTOP)
0005110 C      CALL CWRITE(GPSSM1,'GPSSM1',4,4,4)
0005200 C-----CALCULATE GDSS-----
0005300      JD 423 J=1,4
0005400      JD 423 I=1,4
0005500      GDSS(I,J)=GPSSM1(I,J)
0005600      JD 423 K=1,8
0005700      JD 423 L=1,8
0005800      423 GDSS(I,J)=GDSS(I,J)+VYSD(L,I)*GYYY(L,K)*VYSD(K,J)
0005900      CALL CINV(GDSS,4,0,4,4,1,D-14,ZDET,ZW4,IP4,NSTOP)
0005910 C      CALL CWRITE(GDSS,'GDSS ',4,4,4)
0006000 C-----OUTPUT ON FILE GDSS-----
0006010      WRITE(6,424) E,(GDSS(I,I),I=1,4)
0006020      424 FORMAT(1H ,9F8.3)
0006100      WRITE(20) ((GDSS(I,J),I=1,4),J=1,4)
0006200      GO TO 40
0006300      2 STOP ;END
0006400      PROGRAM PLDANG
0006500      COMPLEX*8 GDSS(4,4)
0006600      DIMENSION EM(132),R(132),RM(130,2)
0006700      NN=20 ;NN1=NN+1 ;NN2=NN+2 ;EI=-5.5
0006800 C-----MAKE EM-----
0006900 C      JD 14 I=1,51
0007000 C      14 EM(I)=-11.+(I-1)*0.1
0007100 C      JD 15 I=1,40
0007200 C      15 EM(I+51)=-5.95+(I-1)*0.05
0007300 C      JD 16 I=1,39
0007400 C      16 EM(I+91)=-3.9+(I-1)*0.1
0007500      JD 14 I=1,NN
0007600      14 EM(I)=-5.5+(I-1)*0.1
0007700      JD 10 NUME=1,NN
0007800 C-----READ-IN GDSS-----
0007900      READ(26) ((GDSS(I,J),I=1,4),J=1,4)
0008000 C-----MAKE RM-----
0008100      RM(NUME,1)=-AIMAG(GDSS(1,1))
0008200      RM(NUME,2)=-AIMAG(GDSS(2,2))
0008300      10 CONTINUE
0008400      XM=NN*0.2 ;YM=20. ;XM2=XM+2.
0008500      CALL PLOTS(0.,0.,'SURF')
0008600      CALL PLOT(2.,2.,-3)
0008700      R(NN1)=0. ;R(NN2)=0.5 ;EM(NN1)=EI ;EM(NN2)=0.5
0008800      JD 2 K=1,2
0008900      CALL AXIS(0.,0.,'ENERGY',-6,XM,0.,EI,0.5)
0009000      CALL AXIS(0.,0.,'DANGLE',6,YM,90.,0.,0.5)
0009100      JD 4 I=1,NN
0009200      R(I)=-RM(I,K)
0009300      4 CONTINUE
0009400      CALL LINE(EM,R,NN,1,0,0)
0009500      CALL PLOT(XM2,0.,-3)
0009600      2 CONTINUE
0009700      CALL PLOTV
0009800      STOP ;END

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R DANGLE JF A1402.I.FORT LIST END

ER DDANG JF A1402.I.FORT

000010	-5.5	-3.6	0.1	0.04	0.05
000100	14.95	7.78	29.6	12.7	
000200	1.6344	1.4284	2.2460	2.227	
000300	.87	1.69	2.5		
000400	2.5	4.3	6.0		
000500	1.34	2.1	2.1	2.9	
000600	8				
000700					
000800					
000900					
001000	180.	0.			

ER DDANG JF A1402.I.FORT LIST END

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R DVAC          JF  A1402.I.FORT

000100      PROGRAM DVAC
000200      IMPLICIT COMPLEX*8 (G,V,Z)
000300      COMMON/ARRAYS/S(40,40),Y(9,5,203),AZ(17,45)
000400      COMMON /POS/POS(3,10),BL,AU,TH,PAI,R2,R3
000500      COMMON /H/H(40,40)
000600      DIMENSION GBBB(16,16),GBBBM1(16,16),GDSS(4,4),
000700      *          GDSSM1(4,4),VBSD(16,4),GVBB(16,16)
000800      *,          GVSS(4,4),ZW4(4),ZW16(16),IP4(4),IP16(16)
000900      *,          OUT(20,130)
001000      DATA AU/.529167/,PAI/3.141592/,BL/1.61/
001010      WRITE(6,8)
001020      8 FORMAT(' INPUT EI,EF,DE,DELTA,EPDG IN 5F10.0')
001030      EI=-5.5 ;EF=-3.6 ;DE=0.1 ;DELTA=0.04 ;EPDG=0.05
001040      READ(5,9) DEI,DEF,DDE,DDELTA,DEPSG
001050      9 FORMAT(5F10.0)
001060      IF(DEI.NE.0.) EI=DEI
001070      IF(DEF.NE.0.) EF=DEF
001080      IF(DDE.NE.0.) DE=DDE
001090      IF(DDELTA.NE.0.) DELTA=DDELTA
001100      IF(DEPSG.NE.0.) EPDG=DEPSG
001110      NN=(EF-EI+0.01)/DE ;NN=NN+1
001300 C-----SET UP S AND H-----
001400      CALL SHBAB(IANS)
001410 C      DO 6 J=1,4
001420 C      DO 6 I=1,4
001430 C      H(I,J+20)=0.
001440 C      6 H(I+20,J)=0.
001450 C      CALL RWRITE(H,'H      ',40,40,10)
001460 C      CALL RWRITE(S,'S      ',40,40,10)
001500 C-----SCANNING OF ENERGY-----
001600      E=EI-DE ;NUME=0
001700 C-----CHANGE ENERGY-----
001800      40 NUME=NUME+1
002000      E=E+DE
002200      IF(E.GT.EF+0.1*DE) GO TO 2
002210      ZE=E+(0.,1.)*DELTA
002300 C-----READ-IN GBBB AND GDSS-----
002400      CALL TREAD(GBBB)
002500      READ(26) ((GDSS(I,J),I=1,4),J=1,4)
002510 C      CALL CWRITE(GDSS,'GDSS ',4,4,4)
002600 C-----MAKE VBSD-----
002700      DO 420 J=1,4
002800      DO 420 I=1,16
002900      420 VBSD(I,J)=H(I,J+20)-ZE*S(I,J+20)
002902      DO 421 J=1,4
002904      DO 421 I=5,16
002906      421 VBSD(I,J)=0.
002910 C      CALL CWRITE(VBSD,'VBSD ',16,4,4)
003000 C-----MAKE GBBBM1 AND GDSSM1-----
003100      DO 430 J=1,16
003200      DO 430 I=1,16
003300      430 GBBBM1(I,J)=GBBB(I,J)
003400      CALL CINV(GBBBM1,16,0,16,16,1.D-14,ZDET,ZW16,IP16,NSTOP)
003410 C      CALL CWRITE(GBBBM1,'GBBBM1',16,16,8)
003500      DO 431 J=1,4
003600      DO 431 I=1,4
003700      431 GDSSM1(I,J)=GDSS(I,J)
003800      CALL CINV(GDSSM1,4,0,4,4,1.D-14,ZDET,ZW4,IP4,NSTOP)

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0003810 C CALL CWRITE(GDSSM1,'GDSSM1',4,4,4)
0003900 C-----CALCULATE GVBB AND GVSS-----
0004000 JO 440 J=1,16
0004100 JO 440 I=1,16
0004200 GVBB(I,J)=GBBB1(I,J)
0004300 JO 440 K=1,4
0004400 JO 440 L=1,4
0004500 440 GVBB(I,J)=GVBB(I,J)-VBSD(I,L)*GDSS(L,K)*VBSD(J,K)
0004600 CALL CINV(GVBB,16,0,16,16,1,D-14,ZDET,ZW16,IP16,NSTOP)
0004610 C CALL CWRITE(GVBB,'GVBB ',16,16,8)
0004700 JO 441 J=1,4
0004800 JO 441 I=1,4
0004900 GVSS(I,J)=GDSSM1(I,J)
0005000 JO 441 K=1,16
0005100 JO 441 L=1,16
0005200 441 GVSS(I,J)=GVSS(I,J)-VBSD(L,I)*GBBB(L,K)*VBSD(K,J)
0005300 CALL CINV(GVSS,4,0,4,4,1,D-14,ZDET,ZW4,IP4,NSTOP)
0005310 C CALL CWRITE(GVSS,'GVSS ',4,4,4)
0005400 C-----STORE-IN OUT-----
0005500 JO 450 I=1,16
0005600 450 JUT(I,NUME)=AIMAG(GVBB(I,I))
0005700 JO 451 I=1,4
0005800 451 JUT(I+16,NUME)=AIMAG(GVSS(I,I))
0005810 WRITE(6,452) E,(OUT(I,NUME),I=1,20)
0005820 452 FORMAT(' E=',F10.3/1H ,16F7.3/1H ,4F8.3)
0005900 JO TO 40
0006000 C-----OUTPUT ON FILE OVAC-----
0006100 2 CONTINUE
0006200 WRITE(20)((OUT(I,NUME),I=1,20),NUME=1,NN)
0006300 STOP ;END
0006400 PROGRAM PLOVAC
0006500 DIMENSION EM(132),R(132),RM(130,20)
0006600 NN=20 ;NN1=NN+1 ;NN2=NN+2 ;EI=-5.5
0006700 C-----MAKE EM-----
0006800 C JO 14 I=1,51
0006900 C 14 EM(I)=-11.+(I-1)*0.1
0007000 C JO 15 I=1,40
0007100 C 15 EM(I+51)=-5.95+(I-1)*0.05
0007200 C JO 16 I=1,39
0007300 C 16 EM(I+91)=-3.9+(I-1)*0.1
0007400 JO 14 I=1,NN
0007500 14 EM(I)=-5.5+(I-1)*0.1
0007600 C-----READ-IN OVAC-----
0007700 READ(27)((RM(NUME,I),I=1,20),NUME=1,NN)
0007800 XM=NN*0.2 ;YM=20. ;XM2=XM+2.
0007900 CALL PLOTS(0.,0.,'SURF')
0008000 CALL PLOT(2.,2.,-3)
0008100 R(NN1)=0. ;R(NN2)=0.5 ;EM(NN1)=EI ;EM(NN2)=0.5
0008200 JO 2 K=1,20
0008300 CALL AXIS(0.,0.,'ENERGY',-6,XM,0.,EI,0.5)
0008400 CALL AXIS(0.,0.,'OVAC',4,YM,90.,0.,0.5)
0008500 JO 4 I=1,NN
0008600 R(I)=-RM(I,K)
0008700 4 CONTINUE
0008800 CALL LINE(EM,R,NN,1,0,0)
0008900 CALL PLOT(XM2,0.,-3)
0009000 2 CONTINUE
0009100 CALL PLOTV
0009200 STOP ;END
0009300 PROGRAM PLUNI
0009400 DIMENSION E(132),R(132),RM(130,20),NOUT(20)
0009500 INTEGER*8 IP(10)
0009600 I=999.
0009700 WRITE(6,100)
0009800 100 FORMAT(' INPUT NN,KIND,EI,DE IN 2I3,2F10.0')
0009900 READ(5,101) NNN,NKIND,DEI,DDE

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010000 101 FORMAT(2I3,2F10.0)
010100     NN=110 ;KIND=20
010200     IF(NNN.NE.0) NN=NNN
010300     IF(NKIND.NE.0) KIND=NKIND
010400 C-----READ-IN-----
010410     REWIND 30
010500     READ(30) ((RM(NUME,I),I=1,KIND),NUME=1,NN)
010600     NN1=NN+1 ;NN2=NN+2
010700 C-----MAKE E-----
010800     EI=-11. ;DE=0.1
010900     IF(DEI.NE.0.) EI=DEI
011000     IF(DDE.NE.0.) DE=DDE
011100     DO 20 I=1,NN
011200     20 E(I)=EI+(I-1)*DE
011300     CALL PLOTS(0.,0.,'S')
011400     CALL PLOT(2.,2.,-3)
011500 C-----DX,DY-----
011600     WRITE(6,104)
011700 104 FORMAT(' INPUT DX,DY PER ONE CM')
011800     READ(5,105) DDX,DDY
011900 105 FORMAT(2F10.0)
012000     DX=0.5 ;DY=0.5
012100     IF(DDX.NE.0.) DX=DDX
012200     IF(DDY.NE.0.) DY=DDY
012300     YMAX=20./DY ;XMAX=NN*DE/DX ;XMAX2=XMAX+2.
012400     IC=0
012500     R(NN1)=0. ;R(NN2)=DY ;E(NN1)=EI ;E(NN2)=DX
012600     2 CONTINUE
012700     IC=IC+1
012800     WRITE(6,102) IC
012900 102 FORMAT(' INPUT NOUT IN 20I2 ;GRAPH #=',I3)
013000     READ(5,103) (NOUT(I),I=1,20)
013100 103 FORMAT(20I2)
013200     IF(NOUT(1).EQ.0) GO TO 6
013300     DO 10 I=1,20
013400     IF(NOUT(I).NE.0) GO TO 10
013500     LNOUT=I-1 ;GO TO 11
013600     10 CONTINUE
013700     11 CONTINUE
013800     WRITE(6,106) (NOUT(K),K=1,LNOUT)
013900 106 FORMAT(' INPUT TYTLE OF #',20I3)
014000     READ(5,107) (IP(I),I=1,10)
014100 107 FORMAT(10A8)
014200     CALL SYMBOL(0.,0.,0.3,IP(1),0.,8)
014210     DO 3 I=2,7
014300     CALL SYMBOL(S,S,0.3,IP(I),0.,8)
014310     3 CONTINUE
014400     CALL PLOT(0.,2.,-3)
014500     CALL AXIS(0.,0.,'ENERGY',-6,XMAX,0.,EI,DX)
014600     CALL AXIS(0.,0.,'LDDS',4,YMAX,90.,0.,DY)
014700     DO 4 I=1,NN
014800     R(I)=0.
014900     DO 5 K=1,LNOUT
015000     5 R(I)=R(I)-RM(I,NOUT(K))
015100     IF(R(I).GT.20.) R(I)=20.
015200     4 CONTINUE
015300     CALL LINE(E,R,NN,1,0,0)
015400     CALL PLOT(XMAX2,-2.,-3)
015500     GO TO 2
015550     6 CONTINUE
015600     CALL PLOTV
015700     STOP ;END

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R OVAC IF A1402.I.FORT LIST END

DOVAC JF A1402.I.FORT

000100	-5.5	-3.6	0.1	0.04	0.05
000200	14.95	7.78	29.6	12.7	
000300	1.6344	1.4284	2.2460	2.227	
000400	.87	1.69	2.5		
000500	2.5	4.3	6.0		
000600	1.34	2.1	2.1	2.9	
000700	8 -.2	0.			
000800					
000900					
001000					
001100	180.	0.0			

DOVAC JF A1402.I.FORT LIST END

ER OHCL

JF A1402.I.FORT

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000100 PROGRAM OHCL
000200 IMPLICIT COMPLEX*8 (S,V,Z)
000300 COMMON/ARRAYS/S(40,40),Y(9,5,203),Z(17,45)
000400 COMMON/NATOMS/ NATOMS,N,NK
000500 COMMON/INFOJ/ AN(40),NOUT
000600 COMMON/INFO1/CZ(40),U(80),ULIM(40),LLIM(40),ULK,ULL,ANL,ANK
000700 INTEGER AN,ULIM,ULK,ULL,CZ,U,ANL,ANK
000800 REAL*4 VOIP,VP,Z
000900 COMMON/VOIP/ VOIP(4,10),AZETA(4,10),CONST,DM1,DM2,VP(4,10),
001000 * AZP(4,10)
001100 COMMON /POS/POS(3,10),BL,AU,TH,PAI,R2,R3
001200 COMMON /H/H(40,40)
001300 COMMON /NC/NC(18),LC(10),MC(10)
001400 COMMON /NAN/NAN(40)
001500 DIMENSION S1(9,9)
001600 DIMENSION RM(130,9)
001700 DIMENSION ZW4(4),ZW5(5),IP4(4),IP5(5),GWSS(4,4),GWZZ4(4,4),
001800 * GWZZ5(5,5),GDSSM1(4,4),GDSS(4,4),
001900 * VZSD5(5,4),VZSD4(4,4),VZSD1(1,4),
002000 * G888(16,16),GZZZ5(5,5),GZZZ4(4,4),GZZZM5(5,5),
002100 * GZZZM4(4,4),ROT(9,9),ROT1(4,4),SD(9,9),HD(9,9)
002200 DATA NAN/3*1/
002300 DATA AZHS,AZCLS,AZCLP,AZOS,AZOP,AZSIS,AZSIP
002400 * /1.,2.3561,2.0387,2.2458,2.2266,1.6344,1.4284/
002500 DATA EHS,ECLS,ECLP,EJS,EOP,ESIS,ESIP
002600 * /13.6,25.27,13.70,32.33,15.80,14.83,7.75/
002700 DATA AU/0.52916/,POS/9*0./,ROT/81*0./
002800 DATA ROT1/0.5,0.,0.,0.8660,0.5,-0.4082,-0.7071,-0.2887,
002900 * 0.5,-0.4082,0.7071,-0.2887,0.5,0.8165,0.,-0.2887/
002910 5 CONTINUE
003000 READ(5,100) MODE,IBS,DHS,DAS,CONST,RMAX
003100 100 FORMAT(2I1,4F10.0)
003200 WRITE(6,107) MODE,IBS,DHS,DAS,CONST,RMAX
003300 107 FORMAT(' MODE,IBS,DHS,DAS,CONST,RMAX=',2I3,4F10.3)
003310 IF(IBS.EQ.1) GO TO 120
003320 REWIND 26 ;GO TO 121
003330 120 REWIND 22
003340 121 CONTINUE
003400 NATOMS=3
003500 C-----SET-UP SD AND HD-----
003600 CALL COEFFT
003700 C-----INITIALIZE VOIP AND AZETA-----
003800 POS(3,1)=DHS/AU ;POS(3,2)=DAS/AU
003900 AN(1)=1 ;AN(2)=8 ;AN(3)=14
004000 VOIP(1,1)=EHS ;AZETA(1,1)=AZHS
004100 VOIP(1,2)=EOS ;AZETA(1,2)=AZOS
004200 VOIP(2,2)=EOP ;AZETA(2,2)=AZOP
004300 VOIP(1,3)=ESIS ;AZETA(1,3)=AZSIS
004400 VOIP(2,3)=ESIP ;AZETA(2,3)=AZSIP
004500 GO TO (11,11,11,12,12,13),MODE
004600 12 CONTINUE
004700 AN(2)=17
004800 VOIP(1,2)=ECLS ;AZETA(1,2)=AZCLS
004900 VOIP(2,2)=ECLP ;AZETA(2,2)=AZCLP
005000 GO TO 11
005100 13 CONTINUE
005200 AN(2)=9
005300 VOIP(1,2)=40.12 ;AZETA(1,2)=2.5628

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005400      VOIP(2,2)=32.33 ;AZETA(2,2)=2.5500
005500      11 CONTINUE
005600 C-----SET-UP S-----
005700      CALL INTGS(RMAX,1)
005800 C-----CALCULATION OF H MATRIX-----
005900      JO 408 K=1,NATOMS
006000      JO 408 L=K,NATOMS
006100      LLK=LLIM(K)
006200      LLL=LLIM(L)
006300      ULK=ULIM(K)
006400      ULL=ULIM(L)
006500      NORBK=ULK-LLK+1
006600      NORBL=ULL-LLL+1
006700      DO 409 I=1,NORBK
006800      DO 409 J=1,NORBL
006900          LLKP=LLK+I-1
007000          LLLP=LLL+J-1
007100          LCI=LC(I)+1
007200          LCJ=LC(J)+1
007300          IF(LLKP.EQ.LLLP) GO TO 410
007400          H(LLKP,LLLP)=-S(LLKP,LLLP)*(VOIP(LCI,K)+VOIP(LCJ,L))*
007500      * CONST/2.
007600      GO TO 409
007700 410 H(LLKP,LLKP)=-VOIP(LCI,K)
007800 409 CONTINUE
007900 408 CONTINUE
008000      JO 20 I=1,9
008100      JO 20 J=I,9
008200      S(J,I)=S(I,J)
008300 20 CONTINUE
008400      JO 21 I=1,9
008500      JO 21 J=I,9
008600 21 S1(I,J)=S(I,J)
008700      GO TO (22,22,22,26,26,26),MODE
008710 22 CONTINUE
008800      CALL INTGS(RMAX,2)
009000      JO 24 J=2,9
009100      JO 24 I=2,9
009200 24 H(I,J)=S(I,J)
009300      GO TO 26
009400 26 JO 27 I=1,9
009500      JO 27 J=I,9
009600 27 H(J,I)=H(I,J)
009700 C      CALL RMAT(S,'S',,40,9,9,9)
009800 C      CALL RMAT(H,'H',,40,9,9,9)
009900 C-----TRANSFORMATION-----
010000      JO 30 I=1,5
010100 30 ROT(I,I)=1.
010200      JO 31 J=1,4
010300      JO 31 I=1,4
010400 31 ROT(I+5,J+5)=ROT1(I,J)
010500 C      CALL RWRITE(ROT,'ROT',,9,9,9)
010600      JO 32 J=1,9
010700      JO 32 I=1,9
010800      SD(I,J)=0. ;HD(I,J)=0.
010900      JO 32 K=1,9
011000      JO 32 L=1,9
011100      SD(I,J)=SD(I,J)+ROT(L,I)*S1(L,K)*ROT(K,J)
011200 32 HD(I,J)=HD(I,J)+ROT(L,I)*H(L,K)*ROT(K,J)
011300      CALL RWRITE(SD,'SD',,9,9,9)
011400      CALL RWRITE(HD,'HD',,9,9,9)
011500 C-----S=1-----
011600      JO 40 J=1,9
011700      JO 40 I=1,9
011800 40 SD(I,J)=0.
011900      JO 41 I=1,9

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012000 41 SD(I,I)=1.
012100 WRITE(6,8)
012200 8 FORMAT(' INPUT EI,EF,DE,DELTA,EPDG IN 5F10.0')
012300 EI=-11. ;EF=-0.1;DE=0.1 ;DELTA=0.04 ;EPDG=0.05
012400 READ(5,9) DEI,DEF,DDE,DDELTA,DEPSG
012500 9 FFORMAT(5F10.0)
012600 IF(DEI.NE.0.) EI=DEI
012700 IF(DEF.NE.0.) EF=DEF
012800 IF(DDE.NE.0.) DE=DDE
012900 IF(DDELTA.NE.0.) DELTA=DDELTA
013000 IF(DEPSG.NE.0.) EPDG=DEPSG
013100 NN=(EF-EI+0.01)/DE ;NN=NN+1
013200 IF(ABS.EQ.2) GO TO 103
013300 REWIND 22
013400 ISKIP=(EI-(-11.)+0.01)/DE
013500 IF(ISKIP.EQ.0) GO TO 103
013600 DO 104 I=1,ISKIP
013700 CALL TREAD(GBBB)
013800 104 CONTINUE
013900 103 CONTINUE
014000 READ(5,105) IOUT
014100 105 FORMAT(I3)
014200 E=EI-DE ;NUME=0
014300 C-----CHANGE ENERGE-----
014400 1 NUME=NUME+1
014500 E=E+DE
014600 IF(E.GT.EF+0.1*DE) GO TO 3
014700 ZE=CMPLX(E,DELTA)
014800 C-----READ-IN GDSS-----
014900 GO TO (51,52),IBS
015000 51 CALL TREAD(GBBB)
015100 DO 56 J=1,4
015200 DO 56 I=1,4
015300 56 GDSS(I,J)=GBBB(I,J)
015400 GO TO 57
015500 52 READ(26) ((GDSS(I,J),I=1,4),J=1,4)
015600 57 CONTINUE
015700 DO 58 J=1,4
015800 DO 58 I=1,4
015900 58 GDSSM1(I,J)=GDSS(I,J)
016000 CALL CINV(GDSSM1,4,0,4,4,1.D-14,ZDET,ZW4,IP4,NSTOP)
016100 GO TO (60,70,80,70,80,70),MODE
016200 C-----HYDROGEN-----
016300 60 CONTINUE
016400 DO 61 I=1,4
016500 61 VZSD1(1,I)=HD(1,I+5)-ZE*SD(1,I+5)
016600 GZZZ1=1./(ZE-HD(1,1))
016700 IF(IOUT.EQ.1.AND.NUME.EQ.1)
016800 * WRITE(6,106) (VZSD1(1,I),I=1,4),GZZZ1
016900 106 FORMAT(' VZSD1,GZZZ1=',10F8.3)
017000 DO 62 J=1,4
017100 DO 62 I=1,4
017200 62 GWSS(I,J)=GDSSM1(I,J)-VZSD1(1,I)*GZZZ1*VZSD1(1,J)
017300 CALL CINV(GWSS,4,0,4,4,1.D-14,ZDET,ZW4,IP4,NSTOP)
017400 GZZZM1=1./GZZZ1
017500 GWZZ1=GZZZM1
017600 DO 63 J=1,4
017700 DO 63 I=1,4
017800 63 GWZZ1=GWZZ1-VZSD1(1,I)*GDSS(I,J)*VZSD1(1,J)
017900 GZZZ1=1./GWZZ1
018000 WRITE(6,64) E,GWZZ1,(GWSS(I,I),I=1,4)
018100 64 FORMAT(1H ,11F8.3/1H ,10F8.3)
018200 RM(NUME,1)=AIMAG(GWZZ1)
018300 DO 67 I=1,4
018400 67 RM(NUME,I+1)=AIMAG(GWSS(I,I))
018500 GO TO 1

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018600 C-----MATRIX 4-----
018700 70 CONTINUE
018710 C CALL RWRITE(HD,'HD ',9,9,9)
018720 C CALL RWRITE(SD,'SD ',9,9,9)
018800 JJ 71 J=1,4
018900 JJ 71 I=1,4
019000 71 VZSD4(I,J)=HD(I+1,J+5)-ZE*SD(I+1,J+5)
019100 JJ 72 J=1,4
019200 JJ 72 I=1,4
019300 72 GZZZ4(I,J)=ZE*SD(I+1,J+1)-HD(I+1,J+1)
019400 IF(IOUT.EQ.1.AND.NUME.EQ.1)
019500 * CALL CWRITE(VZSD4,'VZSD4',4,4,4)
019600 IF(IOUT.EQ.1.AND.NUME.EQ.1)
019700 * CALL CWRITE(GZZZ4,'GZZZ4M1',4,4,4)
019800 CALL CINV(GZZZ4,4,0,4,4,1.D-14,ZDET,ZW4,IP4,NSTOP)
019900 JJ 73 J=1,4
020000 JJ 73 I=1,4
020100 GWSS(I,J)=GDSSM1(I,J)
020200 JJ 73 K=1,4
020300 JJ 73 L=1,4
020400 73 GWSS(I,J)=GWSS(I,J)-VZSD4(L,I)*GZZZ4(L,K)*VZSD4(K,J)
020500 CALL CINV(GWSS,4,0,4,4,1.D-14,ZDET,ZW4,IP4,NSTOP)
020600 JJ 74 J=1,4
020700 JJ 74 I=1,4
020800 74 GZZZM4(I,J)=GZZZ4(I,J)
020900 CALL CINV(GZZZM4,4,0,4,4,1.D-14,ZDET,ZW4,IP4,NSTOP)
021000 JJ 75 J=1,4
021100 JJ 75 I=1,4
021200 GWZZ4(I,J)=GZZZM4(I,J)
021300 JJ 75 K=1,4
021400 JJ 75 L=1,4
021500 75 GWZZ4(I,J)=GWZZ4(I,J)-VZSD4(I,L)*GDSS(L,K)*VZSD4(J,K)
021600 CALL CINV(GWZZ4,4,0,4,4,1.D-14,ZDET,ZW4,IP4,NSTOP)
021700 WRITE(6,76) E,(GWZZ4(I,I),I=1,4),(GWSS(I,I),I=1,4)
021800 76 FORMAT(1H ,11F8.3/1H ,10F8.3)
021900 JJ 77 I=1,4
022000 RM(NUME,I)=AIMAG(GWZZ4(I,I))
022100 77 RM(NUME,I+4)=AIMAG(GWSS(I,I))
022200 GO TO 1
022300 C-----MATRIX 5-----
022400 80 CONTINUE
022500 JJ 81 J=1,4
022600 JJ 81 I=1,5
022700 81 VZSD5(I,J)=HD(I,J+5)-ZE*SD(I,J+5)
022800 JJ 82 J=1,5
022900 JJ 82 I=1,5
023000 82 GZZZ5(I,J)=ZE*SD(I,J)-HD(I,J)
023100 IF(IOUT.EQ.1.AND.NUME.EQ.1)
023200 * CALL CWRITE(VZSD5,'VZSD5',5,4,4)
023300 IF(IOUT.EQ.1.AND.NUME.EQ.1)
023400 * CALL CWRITE(GZZZ5,'GZZZ5M1',5,5,5)
023500 CALL CINV(GZZZ5,5,0,5,5,1.D-14,ZDET,ZW5,IP5,NSTOP)
023600 JJ 83 J=1,4
023700 JJ 83 I=1,4
023800 GWSS(I,J)=GDSSM1(I,J)
023900 JJ 83 K=1,5
024000 JJ 83 L=1,5
024100 83 GWSS(I,J)=GWSS(I,J)-VZSD5(L,I)*GZZZ5(L,K)*VZSD5(K,J)
024200 CALL CINV(GWSS,4,0,4,4,1.D-14,ZDET,ZW4,IP4,NSTOP)
024300 JJ 84 J=1,5
024400 JJ 84 I=1,5
024500 84 GZZZM5(I,J)=GZZZ5(I,J)
024600 CALL CINV(GZZZM5,5,0,5,5,1.D-14,ZDET,ZW5,IP5,NSTOP)
024700 JJ 85 J=1,5
024800 JJ 85 I=1,5
024900 GWZZ5(I,J)=GZZZM5(I,J)

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025000      JJ 85 K=1,4
025100      JJ 85 L=1,4
025200      35  GWZZ5(I,J)=GWZZ5(I,J)-VZSD5(I,L)*GDSS(L,K)*VZSD5(J,K)
025300      CALL CINV(GWZZ5,5,0,5,5,1.D-14,ZDET,ZW5,IP5,NSTOP)
025400      WRITE(6,86) E,(GWZZ5(I,I),I=1,5),(GWSS(I,I),I=1,4)
025500      36  FJRMAT(1H ,11F8.3/1H ,10F8.3)
025600      JJ 87 I=1,5
025700      37  RM(NUME,I)=AIMAG(GWZZ5(I,I))
025800      JJ 88 I=1,4
025900      38  R1(NUME,I+5)=AIMAG(GWSS(I,I))
026000      GO TO 1
026100      3  CONTINUE
026200  C-----OUTPUT-----
026300      WRITE(30) ((RM(NUME,I),I=1,9),NUME=1,NN)
026400      GO TO 5
026500      END
026600      SUBROUTINE INTGS(RMAX,IP)
026700      COMMON/ARRAYS/S(40,40),Y(9,5,203),Z(17,45)
026800      COMMON/NATOMS/ NATOMS,N,NK
026900      COMMON/INFO/ AN(40),NOUT
027000      COMMON/INFO1/CZ(40),J(80),ULIM(40),LLIM(40),ULK,ULL,ANL,ANK
027100      COMMON/GAB/T(9,9),PAIRS(9,9),TEMP(9,9),C1(3),C2(3)
027200      COMMON/AUXINT/A(17),B(17)
027300      COMMON/VOIP/ VOIP(4,10),AZETA(4,10),CONST,OM1,OM2,VP(4,10),
027400      *  AZP(4,10)
027500      COMMON /POS/PDS(3,10),BL,AU,TH,PAI,R2,R3
027600      COMMON /NC/NC(18),LC(10),MC(10)
027700      COMMON /NAN/NAN(40)
027800      DIMENSION P(80,80)
027900      DIMENSION E(3),Q(40)
028000      EQUIVALENCE (P(1),Y(1))
028100      INTEGER AN,ULIM,ULK,ULL,CZ,U,ANL,ANK
028200  C  DEBUG,SUBCHK
028300  C-----DETERMINATION OF SIZE OF AO BASIS IN AND CORE CHARGE CZ
028400  C  CALL RWRITE(PDS,'POS ',3,10,10)
028500  C  CALL RWRITE(VOIP,'VOIP ',4,10,10)
028600  C  CALL RWRITE(AZETA,'AZETA',4,10,10)
028700      RMAX=99.
028710      CALL MAKEDN(1,3)
028800      J=0
028900      DO 60 I=1,NATOMS
029000      LLIM(I) = N+1
029100      L<=1
029200      IF (AN(I).LT.11) GO TO 20
029300      10  J=N+4
029400      CZ(I)=AN(I)-10
029500      GO TO 50
029600      20  IF (AN(I).LT.3) GO TO 40
029700      30  J=N+4
029800      CZ(I) = AN(I)-2
029900      GO TO 50
030000      40  J=N+1
030100      CZ(I)= AN(I)
030200      50  CONTINUE
030300      JLIM(I) = N
030400      60  CONTINUE
030500  C-----ASSIGNMENT OF ANGULAR MOMENTUM QUANTUM NOS. TO ATOMIC ORBITALS
030600      LC(1)=0
030700      LC(2)=1
030800      LC(3)=1
030900      LC(4)=1
031000      LC(5)=2
031100      LC(6)=2
031200      LC(7)=2
031300      LC(8)=2
031400      LC(9)=2

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00031500      1C(1)=0
00031600      1C(2)=1
00031700      1C(3)=-1
00031800      1C(4)=0
00031900      1C(5)=0
00032000      1C(6)=1
00032100      1C(7)=-1
00032200      1C(8)=2
00032300      1C(9)=-2
00032400 C-----FILL U ARRAY---U(J) IDENTIFIES THE ATOM TO WHICH ORBITAL J IS
00032500 C-----ATTACHED E.G. ORBITAL 32 ATTACHED TO ATOM 7, ETC.
00032600 C-----ASSIGNMENT OF ORBITAL EXPONENTS TO ATOMS BY SLATERS RULES
00032700      NC(8)=2 ;NC(14)=3 ;NC(1)=1 ;NC(17)=3 ;NC(9)=2
00032800      DO 92 K=1,NATOMS
00032900      LLK=LLIM(K)
00033000      JLK=ULIM(K)
00033100      ANK=AN(K)
00033200      JORBK=ULK-LLK+1
00033300      DO 92 I=1,NORBK
00033400      LLKP=LLK+I-1
00033500      LCZETA=LC(I)+1
00033600      J(LLKP)=AZETA(LCZETA,K)
00033700      J(LLKP)=K
00033800      92 CONTINUE
00033900 C-----STEP THRU PAIRS OF ATOMS
00034000      KK1=1
00034100      IF(IP.EQ.1) GO TO 93
00034200      KK1=2
00034300      93 CONTINUE
00034400      DO 320 K=KK1,NATOMS
00034500      DO 320 L=K,NATOMS
00034600      DO 100 I=1,3
00034700      C1(I)=POS(I,K)
00034800      100 C2(I)=POS(I,L)
00034900 C-----CALCULATE UNIT VECTOR ALONG INTERATOM AXIS,E
00035000      CALL RELVEC(R,E,C1,C2)
00035100      IF(R.GT.RMAX) GO TO 320
00035200      LLK = LLIM(K)
00035300      LLL = LLIM(L)
00035400      JLK = ULIM(K)
00035500      JLL = ULIM(L)
00035600      JORBK=ULK-LLK+1
00035700      JORBL=ULL-LLL+1
00035800      ANK=AN(K)
00035900      ANL=AN(L)
00036000 C-----LOOP THRU PAIRS OF BASIS FUNCTIONS, ONE ON EACH ATOM
00036100      DO 200 I=1,NORBK
00036200      DO 200 J=1,NORBK
00036300      IF(K.EQ.L) GO TO 160
00036400      110 IF(MC(I).NE.MC(J)) GO TO 150
00036500      120 IF(MC(I).LT.0) GO TO 140
00036600      LLKP=LLK+I-1 ;LLLJ=LLL+J-1
00036700      130 PAIRS(I,J)= SQRT((Q(LLKP)*R)**(2*NC(ANK)+1)*(Q(LLLJ)*R)**(2*NC
00036800      1)+1)/(FACT(2*NC(ANK))*FACT(2*NC(ANL)))*(-1,DO)**(LC(J)+MC(J))
00036900      2*SS(NC(ANK),LC(I),MC(I),NC(ANL),LC(J),Q(LLKP)*R,Q(LLLJ)*R)
00037000      IF(IP.EQ.1) GO TO 190
00037100      PAIRS(I,J)=HH(ANK,LC(I),MC(I),ANL,LC(J),R,NAN(K),NAN(L))
00037200      GO TO 190
00037300      140 PAIRS(I,J)=PAIRS(I-1,J-1)
00037400      GO TO 190
00037500      150 PAIRS(I,J)=0.000
00037600      GO TO 190
00037700      160 IF (I.EQ.J) GO TO 170
00037800      180 PAIRS(I,J)=0.000
00037900      GO TO 190
00038000      170 PAIRS(I,J)=1.000

```

```

038100      IF(IP.EQ.1) GO TO 190
038200      IF(MC(I).LT.0) GO TO 171
038300      PAIRS(I,J)=HH(ANK,LC(I),MC(I),ANL,LC(J),R,NAN(K),NAN(L))
038400      GO TO 190
038500      171 PAIRS(I,J)=PAIRS(I-1,J-1)
038600      190 CONTINUE
038700      200 CONTINUE
038800      LCULK=LC(NORBK)
038900      LCULL=LC(NORBL)
039000      MAXL=MAX0(LCULK,LCULL)
039100      IF(R.GT.0.000001D0) GO TO 220
039200      210 GO TO 250
039300 C----- ROTATE INTEGRALS FROM DIATOMIC BASIS TO MOLECULAR BASIS
039400      220 CALL HARMTR(T,MAXL,E)
039500      DO 230 I=1,NORBK
039600      DO 230 J=1,NORBL
039700      TEMP(I,J) = 0.D0
039800      DO 230 KK=1,NORBL
039900      TEMP(I,J) = TEMP(I,J)+T(J,KK)*PAIRS(I,KK)
040000      230 CONTINUE
040100      DO 240 I=1,NORBK
040200      DO 240 J=1,NORBL
040300      PAIRS(I,J) = 0.D0
040400      DO 240 KK=1,NORBK
040500      PAIRS(I,J) = PAIRS(I,J)+T(I,KK)*TEMP(KK,J)
040600      240 CONTINUE
040700 C----- FILL S MATRIX
040800      250 CONTINUE
040900      DO 260 I=1,NORBK
041000      LLKP=LLK+I-1
041100      DO 260 J=1,NORBL
041200      LLLP=LLL+J-1
041300      260 S(LLKP,LLLP)=PAIRS(I,J)
041400      320 CONTINUE
041500      330 CONTINUE
041600      RETURN
041700      END

```

R OHCL JF A1402.I,FORT LIST END

ER DOHCL3 JF A1402.I.FORT

0000100	12 3.4	3.0	1.75	20.
0000200	-5.5	-3.6		
0000300	0			
0000400	12 3.3	3.0	1.75	20.
0000500	-5.5	-3.6		
0000600	1			
0000700	12 3.2	2.	1.75	20.
0000800	-5.5	-3.6		
0000900	1			
0001000	12 3.1	4.	1.75	20.
0001100	-5.5	-3.6		
0001200	1			
0001300	12 4.	3.2	1.75	20.
0001400	-5.5	-3.6		
0001500	0			

ER DOHCL3 JF A1402.I.FORT LIST END

ER SIGEE0

JF A1402.I.FORT

```

000100      PROGRAM SIGEE0
000200      IMPLICIT COMPLEX*8 (G,Y,Z)
000300      COMMON/ARRAYS/S(40,40),Y(9,5,203),AZ(17,45)
000400      COMMON /POS/POS(3,10),BL,AU,TH,PAI,R2,R3
000500      COMMON /H/H(40,40)
000600      DIMENSION GYYY(8,8),GSTRSS(4,4),VSY(4,8),GDSS(4,4),ZW4(4),
000700      *          IP4(4),GDSSM1(4,4)
000800      DATA AU/.529167/,PAI/3.141592/,BL/1.61/
000900      WRITE(6,8)
001000      8 FORMAT(' INPUT EI,EF,DE,DELTA,EP SG IN 5F10.0')
001100      EI=-5.5 ;EF=-3.6 ;DE=0.1 ;DELTA=0.04 ;EP SG=0.05
001200      READ(5,9) DEI,DEF,DDE,DDELTA,DEPSG
001300      9 FORMAT(5F10.0)
001400      IF(DEI.NE.0.) EI=DEI
001500      IF(DEF.NE.0.) EF=DEF
001600      IF(DDE.NE.0.) DE=DDE
001700      IF(DDELTA.NE.0.) DELTA=DDELTA
001800      IF(DEPSG.NE.0.) EP SG=DEPSG
001900      EP SG=EP SG
002000      NN=(EF-EI+0.01)/DE ;NN=NN+1
002100 C-----SET UP S AND H-----
002200      CALL SHBAB(IANS)
002300 C      DO 6 J=1,4
002400 C      DO 6 I=1,4
002500 C      I(I,J+20)=0.
002600 C      6 I(I+20,J)=0.
002700 C      CALL RWRITE(H,'H      ',40,40,10)
002800 C-----MAKE VSY-----
002900      DO 420 J=1,4
003000      DO 420 I=1,4
003100      VSY(I,J)=0.
003200      420 VSY(I,J+4)=H(I+20,J+16)
003300 C      CALL CWRITE(VSY,'VSY      ',4,8,8)
003400 C-----SCANNING OF ENERGY-----
003500      E=EI-DE ;NUME=0
003600 C-----CHANGE ENERGY-----
003700      40 NUME=NUME+1
003800      E=E+DE
003900      IF(E.GT.EF+0.1*DE) GO TO 2
004000      DELTA=DELTA
004100 C      ZE=E+(0.,1.)*DELTA
004200 C-----READ-IN GEE0(GYYY)-----
004300      READ(23) ((GYYY(I,J),J=I,8),I=1,8)
004400      DO 410 I=1,7
004500      I1=I+1
004600      DO 410 J=I1,8
004700      410 GYYY(J,I)=GYYY(I,J)
004800 C      CALL CWRITE(GYYY,'GYYY      ',8,8,8)
004900 C-----READ-IN GDSS-----
005000      READ(26) ((GDSS(I,J),I=1,4),J=1,4)
005100 C      CALL CWRITE(GDSS,'GDSS      ',4,4,4)
005200 C-----CALCULATE GSTRSS,GDSSM1-----
005300      DO 431 J=1,4
005400      DO 431 I=1,4
005500      431 GDSSM1(I,J)=GDSS(I,J)
005600      CALL CINV(GDSSM1,4,0,4,4,1,D-14,ZDET,ZW4,IP4,NSTOP)
005700 C      CALL CWRITE(GDSSM1,'GDSSM1',4,4,4)
005800      DO 440 J=1,4

```

```
005900      DO 440 I=1,4
006000          GSTRSS(I,J)=GDSSM1(I,J)
006100      DO 440 K=1,8
006200      DO 440 L=1,8
006300  440      GSTRSS(I,J)=GSTRSS(I,J)-VSY(I,L)*GYYY(L,K)*VSY(J,K)
006400  C      CALL CWRITE(GSTRSS,'GSTRSS',4,4,4)
006500      CALL CINV(GSTRSS,4,0,4,4,1.D-14,ZDET,ZW4,IP4,NSTOP)
006600      WRITE(6,441) E,(GSTRSS(I,I),I=1,4)
006700  441  FORMAT(1H ,9F10.3)
006800      DO TO 40
006900      2  STOP ;END
```

```
ER SIGEEU      JF  A1402.I.FORT  LIST END
```

CR DSIG JF A1402.I.FORT

000100	-5.5	-3.6	0.1	0.04	0.05
000200	14.95	7.78	29.6	12.7	
000300	1.6344	1.4284	2.2460	2.227	
000400	.87	1.69	2.5		
000500	2.5	4.3	6.0		
000600	1.34	2.1	2.1	2.9	
000700	8 0.	.6			
000800					
000900					
001000					
001100	180.	180.			

CR DSIG JF A1402.I.FORT LIST END

ER WEAK

JF A1402.I.FORT

```

0000100 PROGRAM WEAK
0000200 IMPLICIT COMPLEX*8 (G,V,Z)
0000300 COMMON/ARRAYS/S(40,40),Y(9,5,203),AZ(17,45)
0000400 COMMON /POS/POS(3,10),BL,AU,TH,PAI,R2,R3
0000500 COMMON /H/H(40,40)
0000600 DIMENSION GDSS(4,4),GDSSM1(4,4),VSO(4,4),ZW4(4),IP4(4),
0000700 *          GWSS(4,4),G000(4,4)
0000800 DIMENSION ROT(4,4)
0000900 DIMENSION HD(4,4)
0001000 DATA AU/.529167/,PAI/3.141592/,BL/1.61/
0001100 WRITE(6,8)
0001200 8 FORMAT(' INPUT EI,EF,DE,DELTA,EPDG IN 5F10.0')
0001300 EI=-5.5 ;EF=-3.6 ;DE=0.1 ;DELTA=0.04 ;EPDG=0.05
0001400 READ(5,9) DEI,DEF,DDE,DDELTA,DEPSG
0001500 9 FORMAT(5F10.0)
0001600 IF(DEI.NE.0.) EI=DEI
0001700 IF(DEF.NE.0.) EF=DEF
0001800 IF(DDE.NE.0.) DE=DDE
0001900 IF(DDELTA.NE.0.) DELTA=DDELTA
0002000 IF(DEPSG.NE.0.) EPSG=DEPSG
0002100 EPSG=EPSG
0002200 NN=(EF-EI+0.01)/DE ;NN=NN+1
0002300 C-----SET UP S AND H-----
0002400 CALL SHBAB(IAN5)
0002500 C-----MAKE VSO-----
0002600 READ(5,451) RX,RY,RZ
0002700 451 FORMAT(3F10.0)
0002800 CALL ROTAT(RX,RY,RZ,ROT)
0002900 DO 452 I=1,4
0003000 DO 452 J=1,4
0003100 452 HD(I,J)=H(I+20,J+16)
0003200 CALL RWRITE(HD,'HD ',4,4,4)
0003300 C CALL RWRITE(ROT,'ROT ',4,4,4)
0003400 DO 454 I=1,4
0003500 DO 454 J=1,4
0003600 VSO(I,J)=0.
0003700 DO 454 K=1,4
0003800 454 VSO(I,J)=VSO(I,J)+H(I+20,K+16)*ROT(K,J)
0003900 CALL CWRITE(VSO,'VSO ',4,4,4)
0004000 C-----SCANNING OF ENERGY-----
0004100 E=EI-DE ;NUME=0
0004200 C-----CHANGE ENERGY-----
0004300 40 NUME=NUME+1
0004400 E=E+DE
0004500 IF(E.GT.EF+0.1*DE) GO TO 2
0004600 DELTA=DELTA
0004700 C-----READ-IN GDSS-----
0004800 READ(26) ((GDSS(I,J),I=1,4),J=1,4)
0004900 C-----SET G000 AND GDSSM1-----
0005000 DO 431 J=1,4
0005100 DO 431 I=1,4
0005200 431 GDSSM1(I,J)=GDSS(I,J)
0005300 CALL CINV(GDSSM1,4,0,4,4,1.D-14,ZDET,ZW4,IP4,NSTOP)
0005400 READ(23) ((G000(I,J),J=1,4),I=1,4)
0005500 C-----CALCULATE GWSS-----
0005600 DO 440 J=1,4
0005700 DO 440 I=1,4
0005800 GWSS(I,J)=GDSSM1(I,J)

```

```

0005900      JJ 440 K=1,4
0006000      JJ 440 L=1,4
0006100      440  ;WSS(I,J)=GWSS(I,J)-VSO(I,L)*GODO(L,K)*VSO(J,K)
0006200      CALL CINV(GWSS,4,0,4,4,1,D-14,ZDET,ZW4,IP4,NSTOP)
0006300      WRITE(6,441) E,(GWSS(I,I),I=1,4)
0006400      441  FJRMAT(1H,9F10.3)
0006500      GO TO 40
0006600      2  ;STOP ;END
0006700      ;JBRoutine ROTAT(RX,RY,RZ,ROT)
0006800      DIMENSION T(4,4),ROTD(4,4),ROT(4,4)
0006900  C-----MAKE TX*TY*TZ WHICH IS TO BE MULTIPLIED FROM RIGHT OF SOMETHIN
0007000      PAI=3.141592
0007100      ;RX=RX*PAI/180. ;Y=RY*PAI/180. ;Z=RZ*PAI/180.
0007200  C-----RESET ROT-----
0007300      JJ 50 I=1,4
0007400      JJ 50 J=1,4
0007500      50  ROT(I,J)=0.
0007600      JJ 51 I=1,4
0007700      51  ROT(I,I)=1.
0007800  C-----X AXIS ROTATION-----
0007900      IF(X.EQ.0.) GO TO 20
0008000      JJ 11 J=1,4
0008100      JJ 11 I=1,4
0008200      11  T(I,J)=0.
0008300      T(1,1)=1. ;T(2,2)=1.
0008400      ;X=SIN(X) ;CX=COS(X)
0008500      T(3,3)=CX ;T(3,4)=-SX
0008600      T(4,3)=SX ;T(4,4)=CX
0008700      JJ 12 J=1,4
0008800      JJ 12 I=1,4
0008900      ROTD(I,J)=0.
0009000      JJ 12 K=1,4
0009100      12  ROTD(I,J)=ROTD(I,J)+ROT(I,K)*T(K,J)
0009200      JJ 13 I=1,4
0009300      JJ 13 J=1,4
0009400      13  ROT(I,J)=ROTD(I,J)
0009500  C-----Y AXIS ROTATION-----
0009600      20  IF(Y.EQ.0.) GO TO 30
0009700      JJ 21 J=1,4
0009800      JJ 21 I=1,4
0009900      21  T(I,J)=0.
0010000      T(1,1)=1. ;T(3,3)=1.
0010100      ;Y=SIN(Y) ;CY=COS(Y)
0010200      T(2,2)=CY ;T(2,4)=SY
0010300      T(4,2)=-SY ;T(4,4)=CY
0010400      JJ 22 J=1,4
0010500      JJ 22 I=1,4
0010600      ROTD(I,J)=0.
0010700      JJ 22 K=1,4
0010800      22  ROTD(I,J)=ROTD(I,J)+ROT(I,K)*T(K,J)
0010900      JJ 23 I=1,4
0011000      JJ 23 J=1,4
0011100      23  ROT(I,J)=ROTD(I,J)
0011200  C-----Z AXIS ROTATION-----
0011300      30  IF(Z.EQ.0.) GO TO 40
0011400      JJ 31 J=1,4
0011500      JJ 31 I=1,4
0011600      31  T(I,J)=0.
0011700      T(1,1)=1. ;T(4,4)=1.
0011800      ;Z=SIN(Z) ;CZ=COS(Z)
0011900      T(2,2)=CZ ;T(2,3)=-SZ
0012000      T(3,2)=SZ ;T(3,3)=CZ
0012100      JJ 32 J=1,4
0012200      JJ 32 I=1,4
0012300      ROTD(I,J)=0.
0012400      JJ 32 K=1,4

```



```
012500 32 RDTD(I,J)=ROTD(I,J)+ROT(I,K)*T(K,J)
012600    JJ 33 I=1,4
012700    JJ 33 J=1,4
012800 33 RDT(I,J)=RDTD(I,J)
012900 40 RETURN ;END
```

```
ER WEAK    JF A1402.I.FORT LIST END
```

ER DWEAK JF A1402.I.FORT

0000100	-5.5	-3.6	0.1	0.04	0.05
0000200	14.95	7.78	29.6	12.7	
0000300	1.6344	1.4284	2.2460	2.227	
0000400	.87	1.69	2.5		
0000500	2.5	4.3	6.0		
0000600	1.34	2.1	2.1	2.9	
0000700	8 0.	.6			
0000800					
0000900					
0001000					
0001100	180.	0.0			
0001200	0.	30.	0.		

ER DWEAK JF A1402.I.FORT LIST END

SER WEAKS

OF A1402.I.FORT

```

00000100 PROGRAM WEAKS
00000200 IMPLICIT COMPLEX*8 (G,V,Z)
00000300 COMMON/ARRAYS/5(40,40),Y(9,5,203),AZ(17,45)
00000400 COMMON /POS/POS(3,10),BL,AU,TH,PAI,R2,R3
00000500 COMMON /H/H(40,40)
00000600 DIMENSION GDSS(4,4),GDSSM1(4,4),VSS(4,4),ZW4(4),IP4(4),
00000700 *          GWSS(4,4),GBSS(4,4)
00000800 DIMENSION TVEC1(3),POS1(3,4),ROT(4,4,4),ROT1(4,4),ROT2(4,4),
00000900 *          T(4,4),HD(4,4)
00001000 DATA AU/.529167/,PAI/3.141592/,BL/1.61/
00001100 WRITE(6,8)
00001200 8 FORMAT(' INPUT EI,EF,DE,DELTA,EPG IN 5F10.0')
00001300 EI=-5.5 ;EF=-3.6 ;DE=0.1 ;DELTA=0.04 ;EPG=0.05
00001400 READ(5,9) DEI,DEF,DDE,DDELTA,DEPG
00001500 9 FORMAT(5F10.0)
00001600 IF(DEI.NE.0.) EI=DEI
00001700 IF(DEF.NE.0.) EF=DEF
00001800 IF(DDE.NE.0.) DE=DDE
00001900 IF(DDELTA.NE.0.) DELTA=DDELTA
00002000 IF(DEPG.NE.0.) EPG=DEPG
00002100 EPG=EPG
00002200 IN=(EF-EI+0.01)/DE ;NN=NN+1
00002300 C-----SET UP S AND H-----
00002400 CALL SHBAB(IANS)
00002500 C-----MAKE VSS-----
00002600 CALL POSROT(0.,0.,0.,BL,AU,TVEC1,POS1,ROT)
00002700 DO 450 I=1,4
00002800 DO 450 J=1,4
00002900 450 ROT1(I,J)=ROT(I,J,1)
00003000 READ(5,451) RX,RY,RZ
00003100 451 FORMAT(3F10.0)
00003200 CALL POSROT(RX,RY,RZ,BL,AU,TVEC1,POS1,ROT)
00003300 DO 452 I=1,4
00003400 DO 452 J=1,4
00003500 452 ROT2(I,J)=ROT(I,J,1)
00003600 DO 453 I=1,4
00003700 DO 453 J=1,4
00003800 T(I,J)=0.
00003900 DO 453 K=1,4
00004000 453 T(I,J)=T(I,J)+ROT1(K,I)*ROT2(K,J)
00004100 DO 455 I=1,4
00004200 DO 455 J=1,4
00004300 455 HD(I,J)=H(I+20,J)
00004400 DO 454 I=1,4
00004500 DO 454 J=1,4
00004600 VSS(I,J)=0.
00004700 DO 454 K=1,4
00004800 454 VSS(I,J)=VSS(I,J)+HD(I,K)*T(K,J)
00004900 CALL CWRITE(VSS,'VSS ',4,4,4)
00005000 C-----SCANNING OF ENERGY-----
00005100 E=EI-DE ;NUME=0
00005200 C-----CHANGE ENERGY-----
00005300 40 NUME=NUME+1
00005400 E=E+DE
00005500 IF(E.GT.EF+0.1*DE) GO TO 2
00005600 DELTA=DELTA
00005700 C-----READ-IN GDSS-----
00005800 READ(26)((GDSS(I,J),I=1,4),J=1,4)

```

```

005900 C-----SET GBSS AND GDSSM1-----
006000     DD 431 J=1,4
006100     DD 431 I=1,4
006200     431 GDSSM1(I,J)=GDSS(I,J)
006300     CALL CINV(GDSSM1,4,0,4,4,1.D-14,ZDET,ZW4,IP4,NSTOP)
006400     READ(29) ((GBSS(I,J),J=1,4),I=1,4)
006500 C-----CALCULATE GWSS-----
006600     DD 440 J=1,4
006700     DD 440 I=1,4
006800     GWSS(I,J)=GDSSM1(I,J)
006900     DD 440 K=1,4
007000     DD 440 L=1,4
007100     440 GWSS(I,J)=GWSS(I,J)-VSS(I,L)*GBSS(L,K)*VSS(J,K)
007200     CALL CINV(GWSS,4,0,4,4,1.D-14,ZDET,ZW4,IP4,NSTOP)
007300     WRITE(6,441) E,(GWSS(I,I),I=1,4)
007400     441 FORMAT(1H ,9F10.3)
007500     DD TO 40
007600     2 STOP ;END

```

ER WEAKS JF A1402.I.FORT LIST END

ER DWEAKS JF A1402.I.FORT

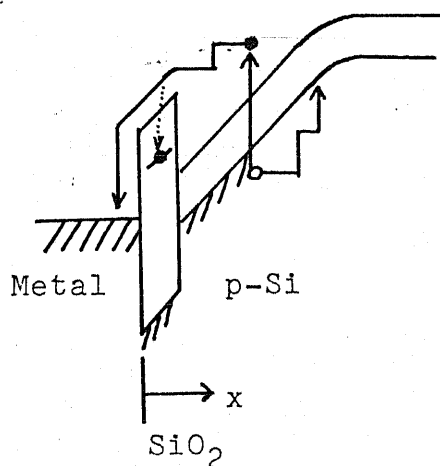
000100	-5.5	-3.6	0.1	0.04	0.05
000200	14.95	7.78	29.6	12.7	
000300	1.6344	1.4284	2.2460	2.227	
000400	.87	1.69	2.5		
000500	2.5	4.3	6.0		
000600	1.34	2.1	2.1	2.9	
000700	0 - .43				
000800					
000900					
001000					
001100	180.	0.0			
001200	0.	30.	0.		

ER DWEAKS JF A1402.I.FORT LIST END

APPENDIX B

MEASUREMENTS OF THE SiO_2 BULK TRAPS

The preliminary results are discussed on the measurements of the SiO_2 bulk traps. The avalanche injection technique is reported in detail and the results of the photo-depopulation measurement are mentioned briefly.



B-1 PRINCIPLE

Injection is carried out by applying AC voltage of the frequency about MHz to MOS diode made with p-Si substrate. AC voltage induces avalanche breakdown and the generated electrons are injected into SiO₂, a part of which are trapped in the SiO₂ film.

The rate equation which governs the trapping mechanics is expressed as

$$\frac{dn_{T_i}(x,t)}{dt} = \frac{j_{inj}}{q} \sigma_i \{ N_{T_i}(x) - n_{T_i}(x,t) \} \quad B-1$$

, where $n(x,t)$ is the number of electrons per unit area which are trapped in the i -th kind of the trap at the location x and time t , j_{inj}/q is the number of the electrons which pass through the SiO₂ film, σ_i is the capture cross section of the i -th kind of the trap, and $N_{T_i}(x)$ is the total number of the i -th kind of the trap. Solving this rate equation under the initial condition of $n_{T_i}(x,0)=0$, we have

$$n_{T_i}(x,t) = N_{T_i}(x) \cdot \left(1 - e^{-\sigma_i \frac{j_{inj}}{q} t} \right) \quad B-2$$

On the other hand, letting C_{ox} , t_{ox} the capacitance and the thickness of the SiO film respectively, the flat band voltage is written as

$$\Delta V_{FB}(t) = \frac{q}{C_{ox} t_{ox}} \int_0^{t_{ox}} x \sum_i n_{T_i}(x,t) dx \quad B-3$$

Substitution of eq. B-2 into eq. B-3 yields

$$\eta_{eff} = \frac{d(C_{ox} \Delta V_{FB}(t))}{dt} \frac{1}{j_{inj}} = \sum_i (N_{T_i})_{eff} \sigma_i e^{-\sigma_i N_{T_i} t} \quad B-4$$

The following notation are used in obtaining eq. B-4.

$$\left\{ \begin{array}{l} \frac{j_{inj}}{q} t \longrightarrow N_{inj} \\ \frac{\bar{x}_i}{t_{ox}} \int_0^{t_{ox}} N_{Ti}(x) dx \longrightarrow (N_{tti})_{eff} \end{array} \right.$$

This eq. B-4 is the fundamental equation. The physical parameters $(N_{tti})_{eff}$ and σ_i are obtained by semilog-plotting η_{eff} versus N_{inj} .

Here, the results of trial calculation in which two kinds of traps are assumed to exist in the SiO_2 film are shown. Figure B-1 is the calculated curve of eq. B-3, fig. B-2 is the semilog plot of fig. B-1, and fig. B-3 is the calculated curve of eq. B-4.

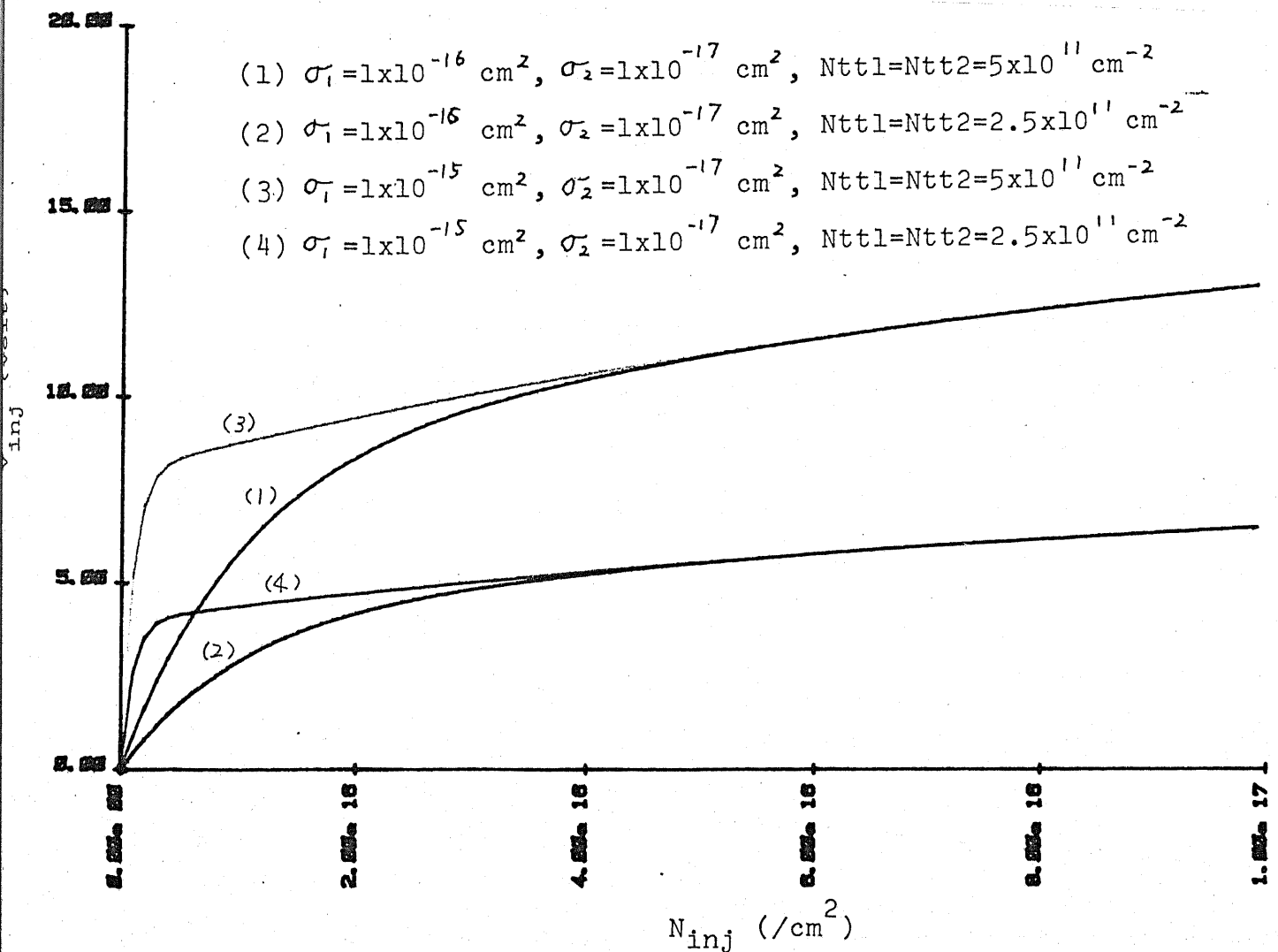


Fig. B-1 Calculated curve of \bar{V}_{inj} versus N_{inj}

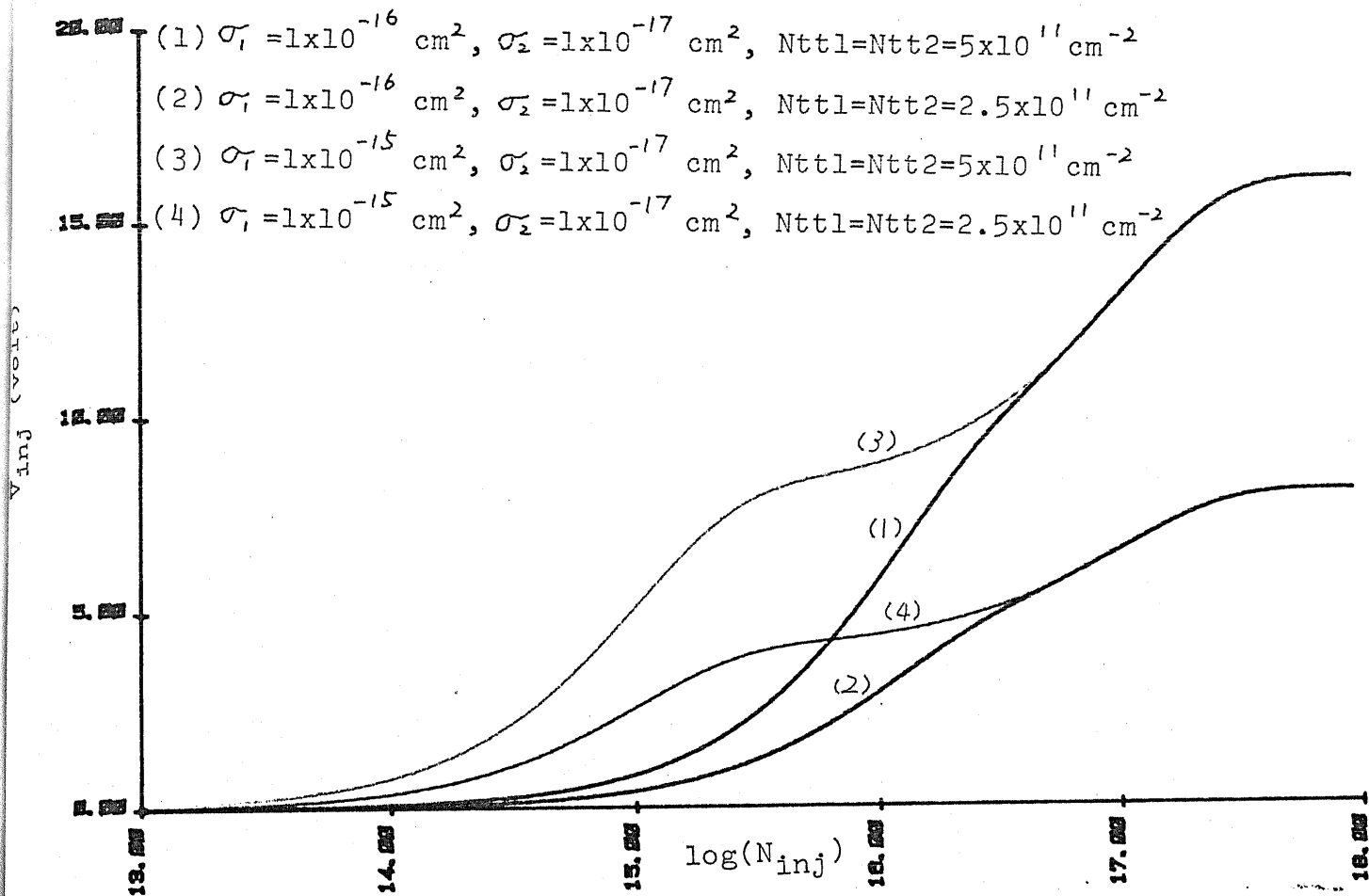


Fig. B-2 Calculated curve of \bar{v}_{inj} versus $\log(N_{inj})$

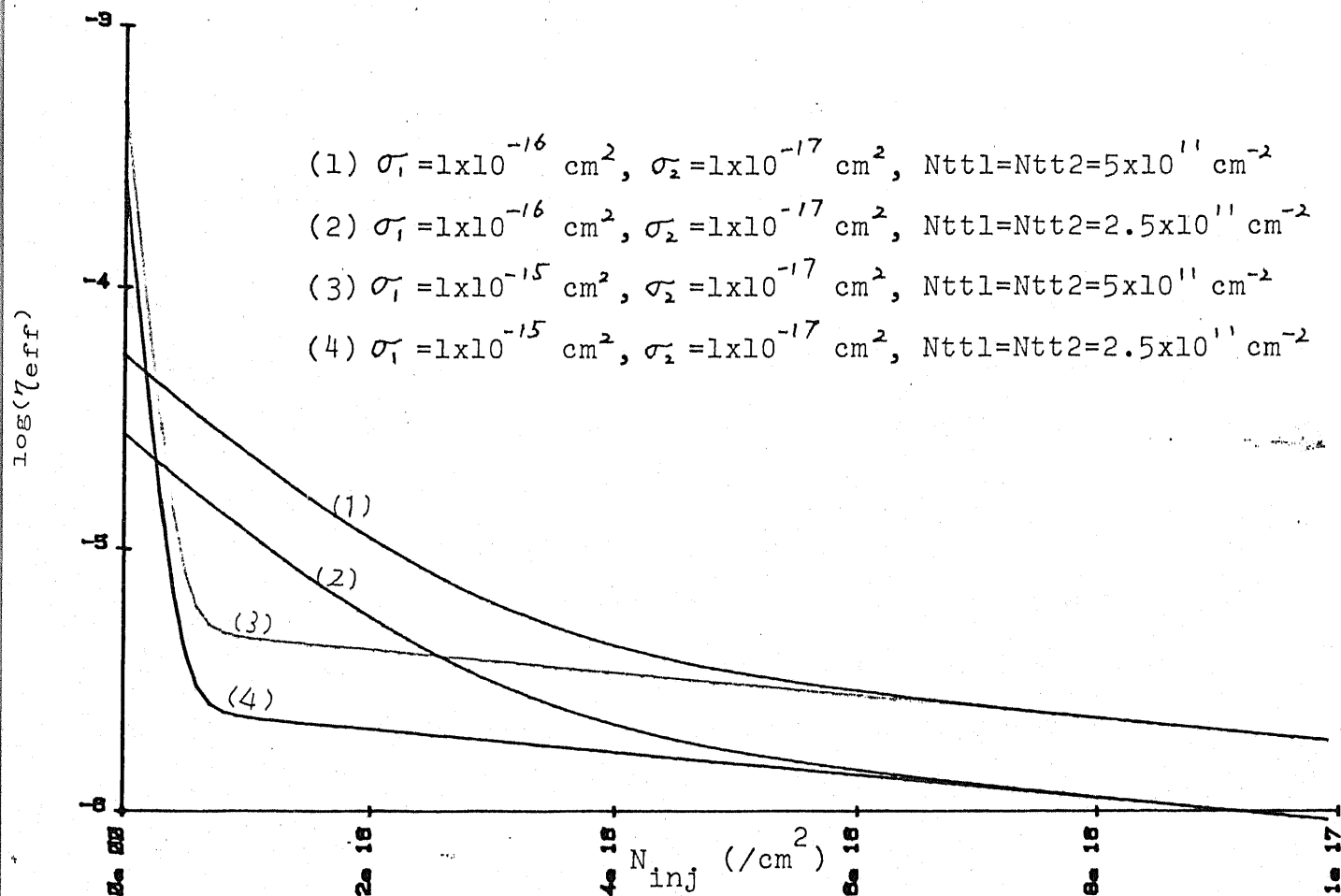


Fig. B-3 Calculated curve of $\log(\eta_{eff})$ versus N_{inj}

B-2 SETUP FOR MEASUREMENT

The main electronic circuit for the measurement is shown in fig. B-4. It gives the feedback voltage $\overline{V_{inj}}$ to the MOS sample so as to keep the DC component of the avalanche current constant. Since the feedback voltage $\overline{V_{inj}}$ equals to the flat band voltage V_{FB} as shown in Fig. B-5, V_{FB} can be monitored if $\overline{V_{inj}}$ is monitored. In order to monitor and process the data of $\overline{V_{inj}}$, a micro-computer system (see fig. B-6) is constructed because the measurements are carried out for a long time, say from 10 min. to 2 hours, and the amount of the data is enormous. Figure B-7 is the interface circuit employed for connecting the micro-computer with the digital voltmeter and fig. B-8 is the program for the data acquisition.

B-3. EXPERIMENTAL RESULTS

The sample used here is 0.5 [ohm.cm] p-Si, which is oxidized in dry O_2 at 1000 [$^{\circ}C$] and annealed in N_2 for 30 min.

The thickness of the oxide is 1000 [\AA] and the area of the sample is 0.36 [mm^2]. The frequency used for the avalanche injection is about 500 [kHz].

The change in the C-V curve as the injection proceeds is given in fig. B-9. It is seen from this C-V curve and from the DLTS experiment (see fig. B-10) that the density of the interface states increases as the amount of injected electrons

increases. So that the correction of the effect of the increased interface states must be considered if the exact analysis is required. But as a preliminary experiment this effect is not taken into account in the following. The reproductivity of this measurement is good if the sample is made with the same process as is seen in fig. B-11. Figures 12 and 13 show the measured $\bar{V}_{inj}(t)$ and the measured $\log(\eta_{eff})$ with the theoretical fit where two kinds of traps are assumed to exist in the SiO_2 film. The fit is not satisfactory and one of the reason of this poor fit is that there exist more kinds of traps in the SiO_2 . The correction of the increased interface states and the consideration of the more kinds of traps are to be done as the next step.

The avalanche current versus the avalanche voltage is plotted in fig. B-14.

B-4. PHOTO-DEPOPULATION MEASUREMENT

Photo-depopulation measurements are carried out by using 1kW Xe lamp and mercury lamp. The sample is first charged up by the avalanche injection technique mentioned above to the flat band voltage shift of about 5 volts and then exposed to the light which includes the photon of the energy up to 6 eV. The depopulation is done under the zero bias condition. The flat band voltage is measured to know how many electrons are

excited to the SiO_2 conduction band and go away. No substantial difference is observed between the sample with and without H anneal. That is, when the flat band voltage of the sample is shifted to 5 eV, then the flat band voltage shift after the bleaching process by the Hg lamp is about 0.1 eV. Since this shift is very small it is difficult to pick up the difference between the sample with and without H anneal. The fact that about 98% of the trapped electrons can not be depopulated by photon although there exist substantial amount of shallow levels (ref. 41) suggests that the photo-depopulation technique, in the present, is not so powerful in determining the characteristics of the traps in the SiO_2 film from a technological viewpoint.

The charging is carried out in the dark and all photo-depopulation experiment is done in the liquid nitrogen at the temperature of 77 [K]. The whole setup is shown in photo B-1.

B-5. CONCLUSION

The avalanche injection measurement is carried out and is thought to be a powerful tool in characterizing the electrically active traps in the SiO_2 film, whereas the photo-depopulation experiment is not so useful because about 98% of the electrically active traps in the oxide are inaccessible by photon.

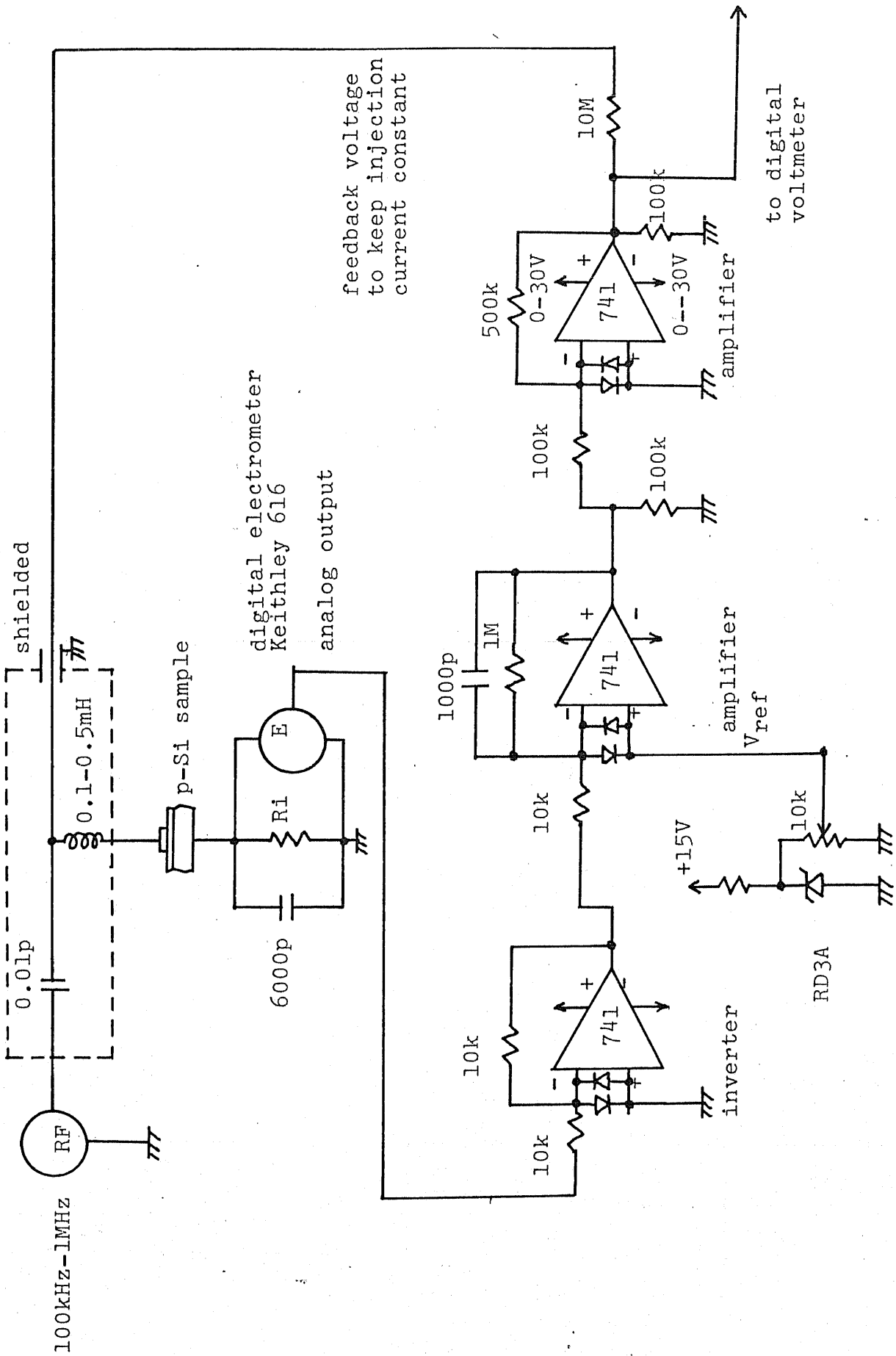


Fig. B-4 Main electronic circuit for the measurement.

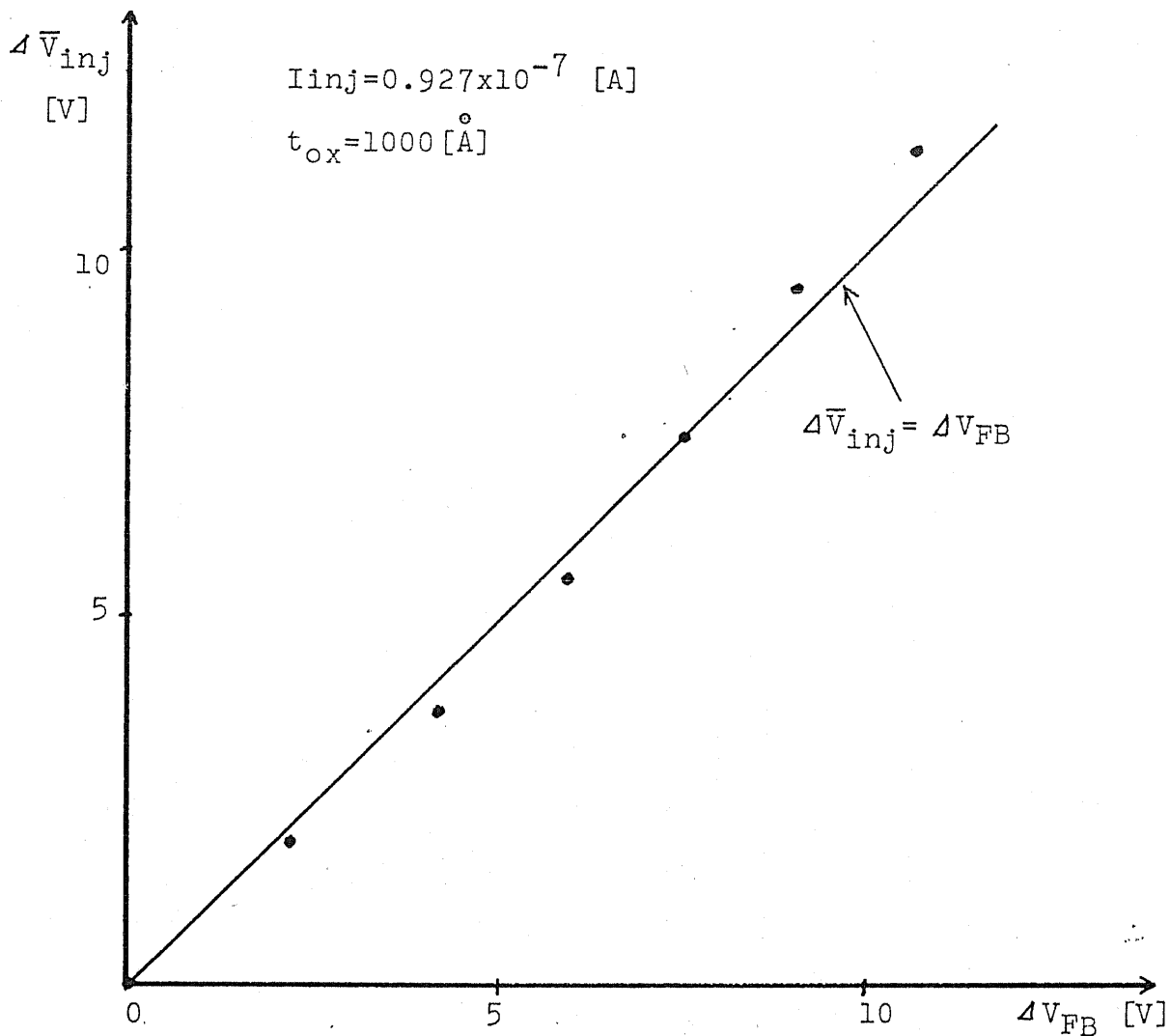


Fig. B-5 Relation between V_{FB} and \bar{V}_{inj} .

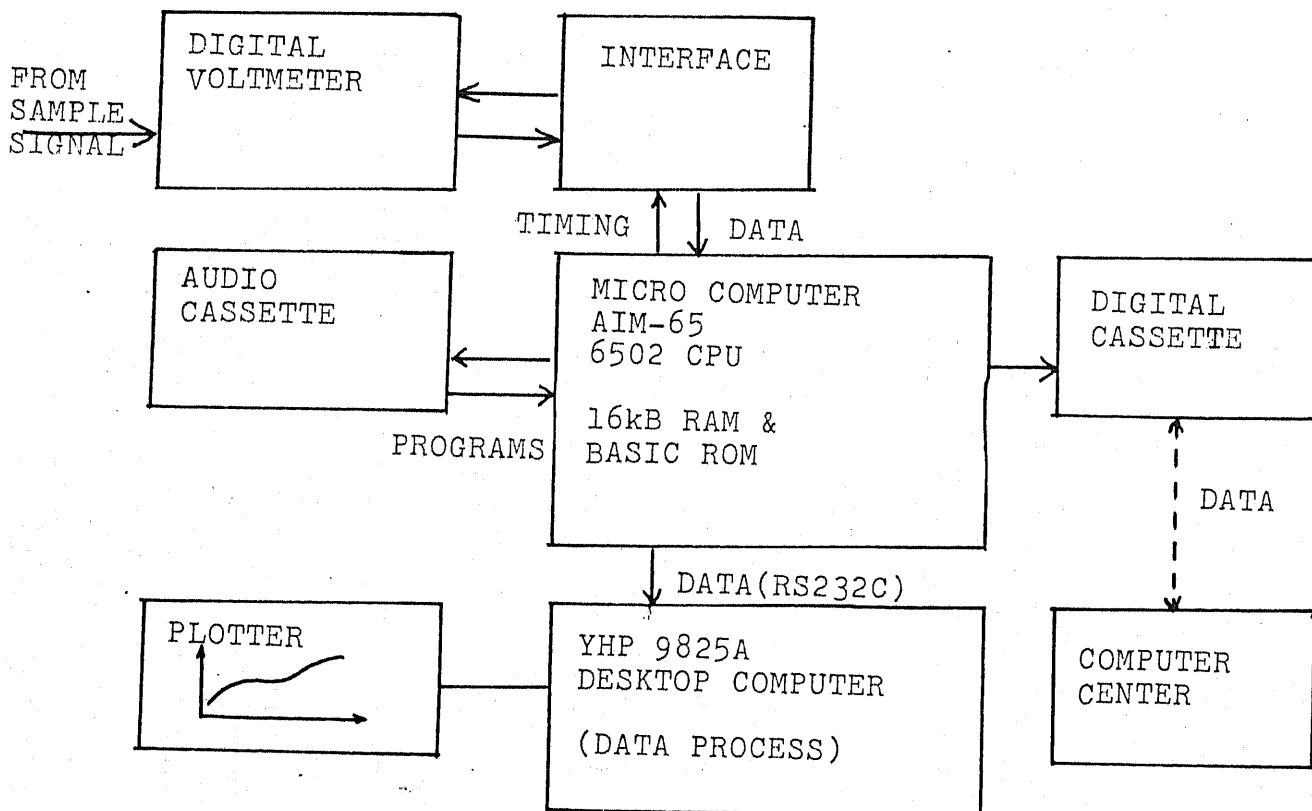


Fig. B-6 Micro-computer system for the measurement.

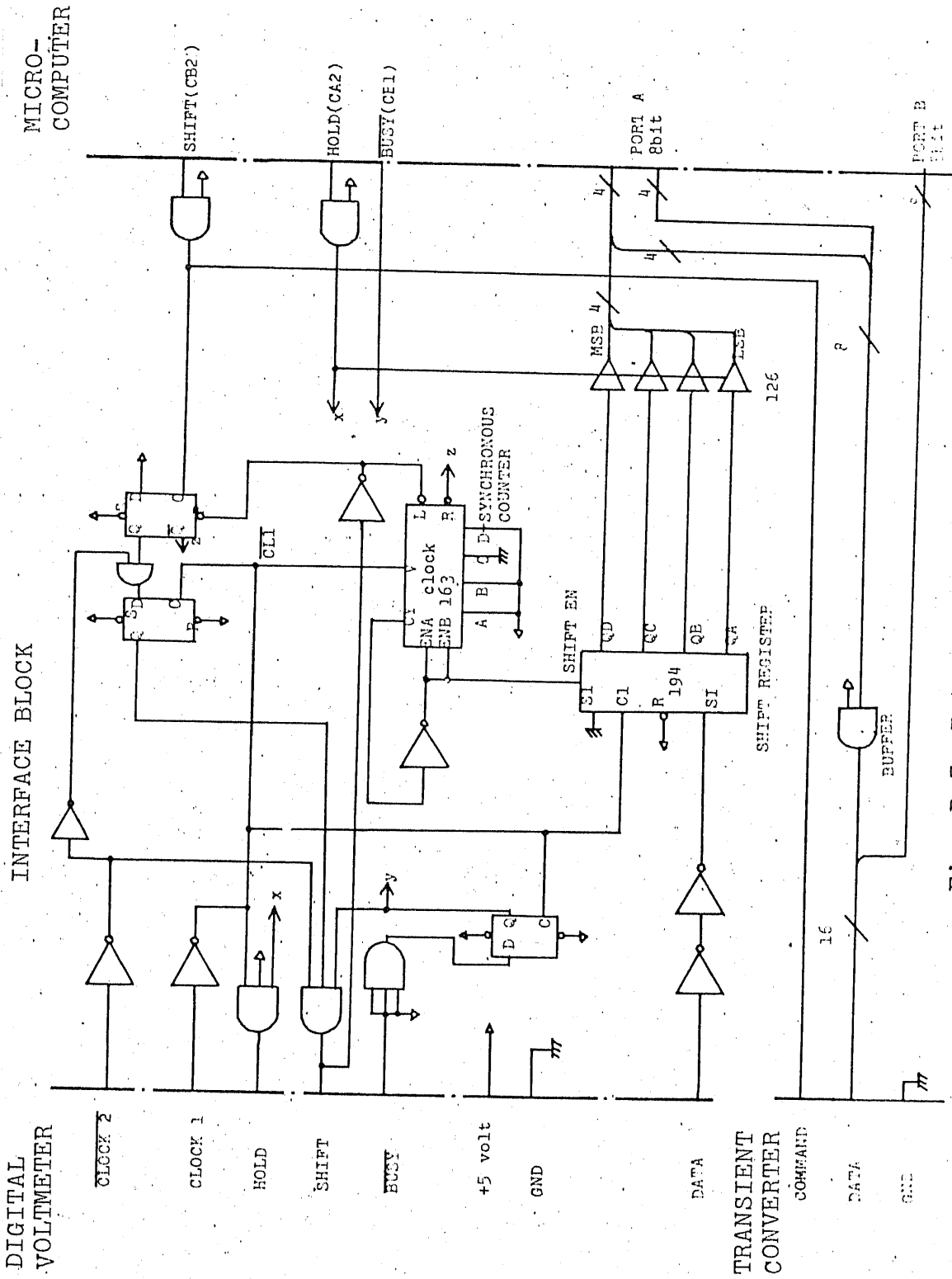


Fig. B-7 Interfacing circuit

Fig. B-8

PROGRAM FOR ELECTRON INJECTION MEASUREMENT
(DATA AQUISITION) written in BASIC

```

10 REM===DATA FROM
DVM===
20 INPUT!"INTVL (SE
C)";IT
25 INPUT!"ADRS IN H
EX(EVEN)";PC$:GOSUB4
000:FRZ=PA00
30 FRZ=PAZ:PRINT! P
AZ:GOSUB3000
40 INPUT!"#DATA (<4
000)";DTX
50 REM===PORT A INP
UT===
60 POKE 40963,0
70 REM===HOLD SET(C
A2) & SFT RESET(CB2)
===
80 AD=40972:A$="CE"
:GOSUB2000
90 FOR D=1TODTX*2ST
EP2
95 DX=INT(D+.1)
100 REM===WAIT===
105 JT=IT*995-404
110 FORI=1TOJT:NEXT
120 REM===HOLD RESE
T(CA2)===
130 AD=40972:A$="CC
":GOSUB2000
140 REM===WAIT UNTI
L BUSY IS OFF (CB1)=
==
145 FOR H=1T080:NEX
TH
150 PK=PEEK(40960):
AD=40972:A$="DC":GOS
UB2000
160 WAIT 40973,16
170 REM===HOLD SET(
CA2)===
180 AD=40972:A$="CE
":GOSUB2000
190 XX=USR(0)
200 P1%=PEEK(16371)
:P2%=PEEK(16372)
205 P3%=PEEK(16373)
:P4%=PEEK(16374)
210 POKE FRZ+DX+1,I
NT(P1% AND 240)+INT(
P2%/16)
220 POKE FRZ+DX,INT
(P3% AND 240)+INT(P4
%/16)
230 NEXTD
240 REM===HOLD RESE
T(CA2)===
250 POKE 40972,204
255 PRINT!"STOP STO
P"
260 STOP:END

1000 REM===DATA TO
TC===
1010 INPUT!"#DATA (<
4000)";DTX
1020 FRZ=8192
1030 REM===PORT AB
OUTPUT===
1040 AD=40962:A$="F
F":GOSUB2000
1050 AD=40963:GOSUB
2000
1060 REM===AB LATCH
CLEAR===
1070 AD=40971:A$="0
3":GOSUB2000
1080 REM===HOLD RES
ET(CA2) & CB2 LOW===
1090 AD=40972:A$="C
C":GOSUB2000
1100 FOR D=1TODTX*2
STEP2
1105 DX=INT(D+.1)
1110 REM===WAIT===
1130 REM===OUTPUT D
ATA===
1140 POKE 40961,PEE
K(FRZ+DX-1)
1150 POKE 40960,PEE
K(FRZ+DX)
1160 REM===8 PULSES
ON CB2===
1170 FOR I=1 TO 8
1180 POKE 40972,236
1200 POKE 40972,204
1220 NEXT I
1230 NEXT D
1240 STOP:END
1999 REM===POKE SUB
ROUTINE===
2000 A1%=ASC(LEFT$(
A$,1)):A2%=ASC(RIGHT
$(A$,1))
2010 IF A1%<58 THEN
A1%=A1%-48:GOTO2030
2020 IF A1%>64 THEN
A1%=A1%-55
2030 IF A2%<58 THEN
A2%=A2%-48:GOTO2050
2040 IF A2%>64 THEN
A2%=A2%-55
2050 AA=INT(A1%*16+
A2%.1)
2060 POKE INT(AD+.1
),AA:RETURN

3000 REM===MAKE MAC
HINE SUBROUTINE===
3010 TX$="8EF03F8DF
13FA200A9EE"
3012 TX$=TX$+"8D0CA
0EAA9CE8D0CAB0EAEA"
3014 TX$=TX$+"AD01A
09DF23FE8E009F0034C0
81F"
3016 TX$=TX$+"AEF03
FADF13F4CD1C0"
3020 FOR I=1TOLEN(T
X$)STEP2
3030 AD=7936+INT(I/
2):A$=MID$(TX$,INT(I
+.1),2)
3040 GOSUB2000
3050 NEXTI
3060 POKE4,0:POKE5,
31
3070 RETURN
4000 REM===HEX TO D
EC===
4010 PC$=RIGHT$("00
0"+PC$,4):PAZ=0
4020 FOR I4=1T04
4030 A1%=ASC(MID$(P
C$,I4,1))
4040 IF A1%<58 THEN
A1%=A1%-48:GOTO4060
4050 IF A1%>64 THEN
A1%=A1%-55
4060 I6%=16^(4-I4)
4065 PAZ=PAZ+A1%*I6
%
4070 NEXT I4
4080 RETURN

```

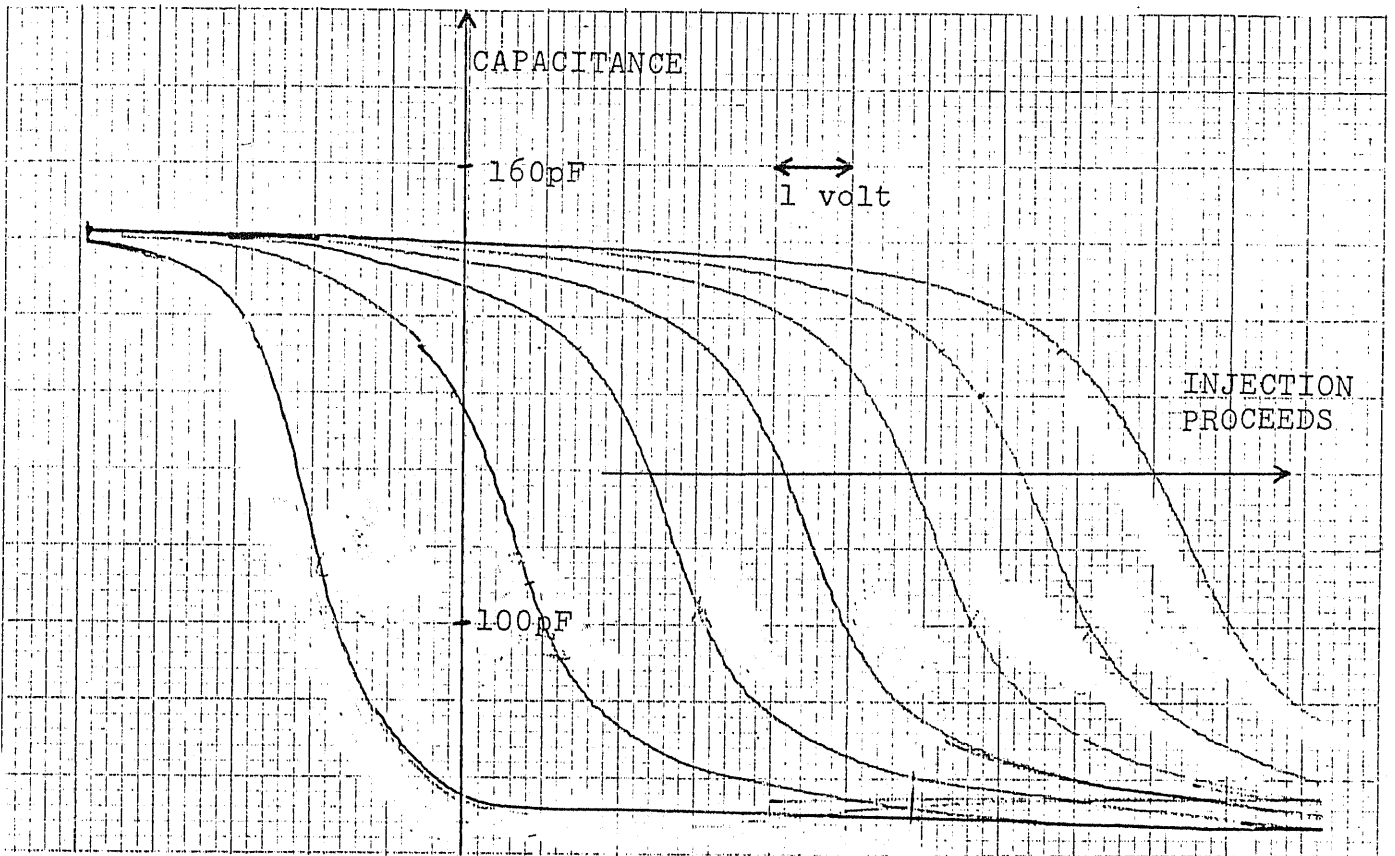



Fig. B-9 Change in C-V curve as injection proceeds.

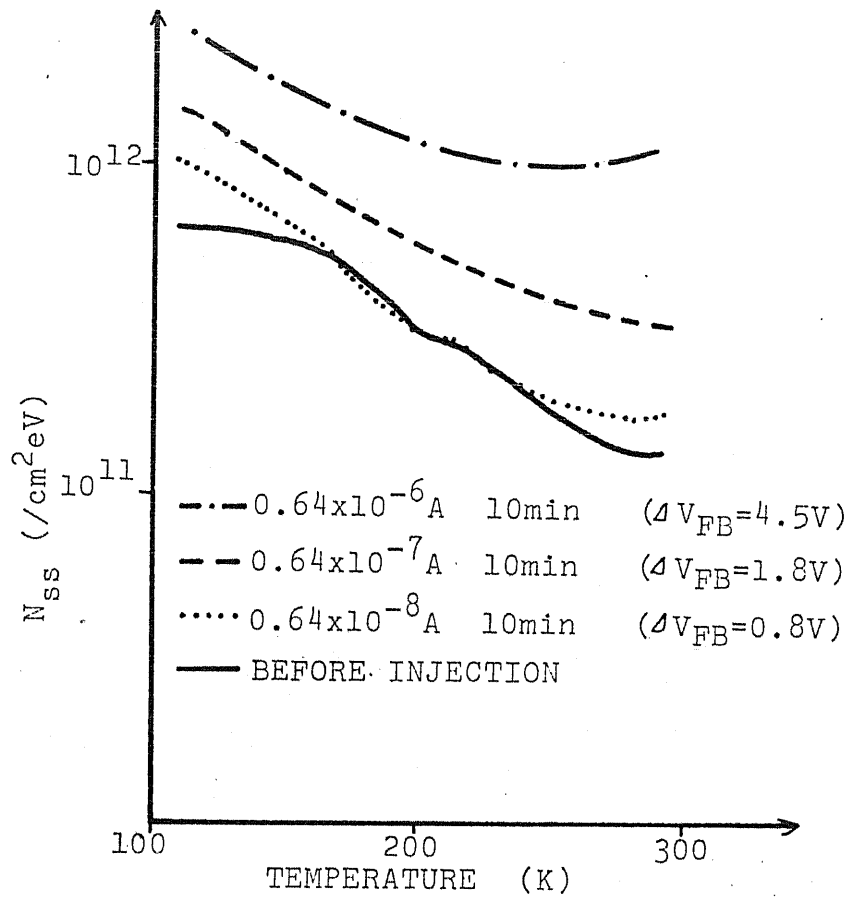


Fig. B-10 DLTS measurement on interface states for various number of injected electrons

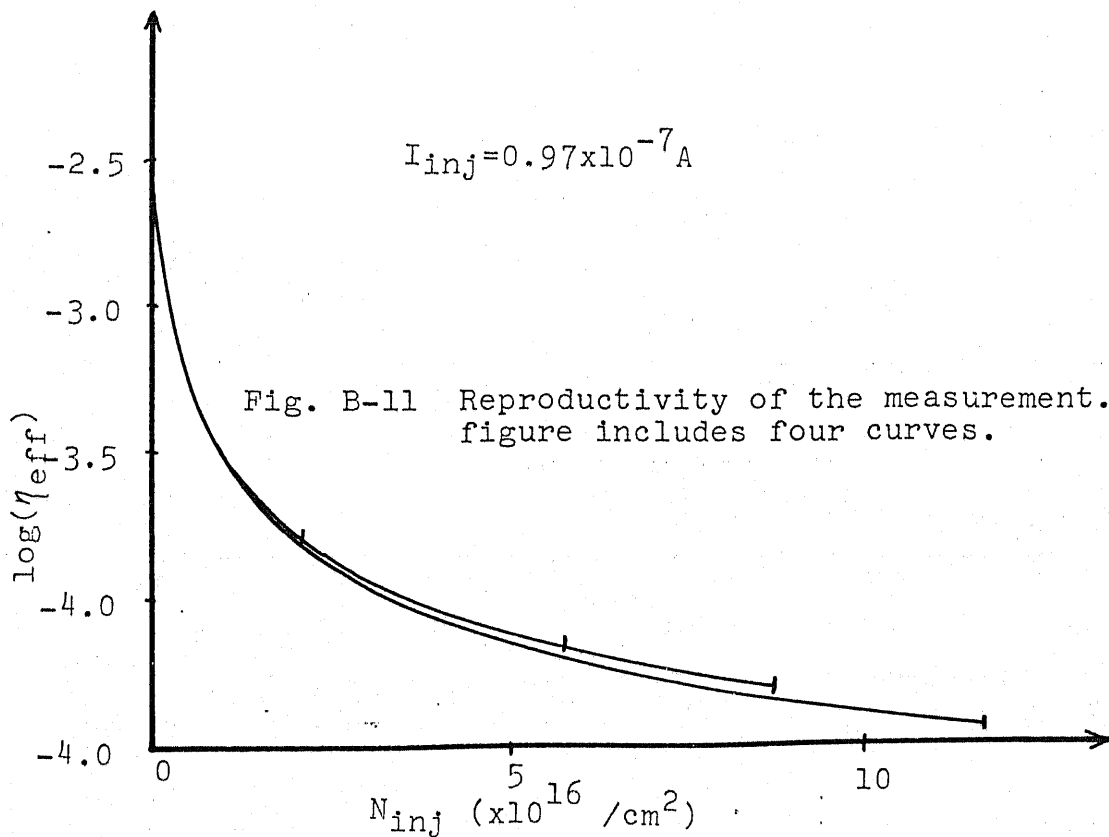


Fig. B-11 Reproducibility of the measurement. This figure includes four curves.

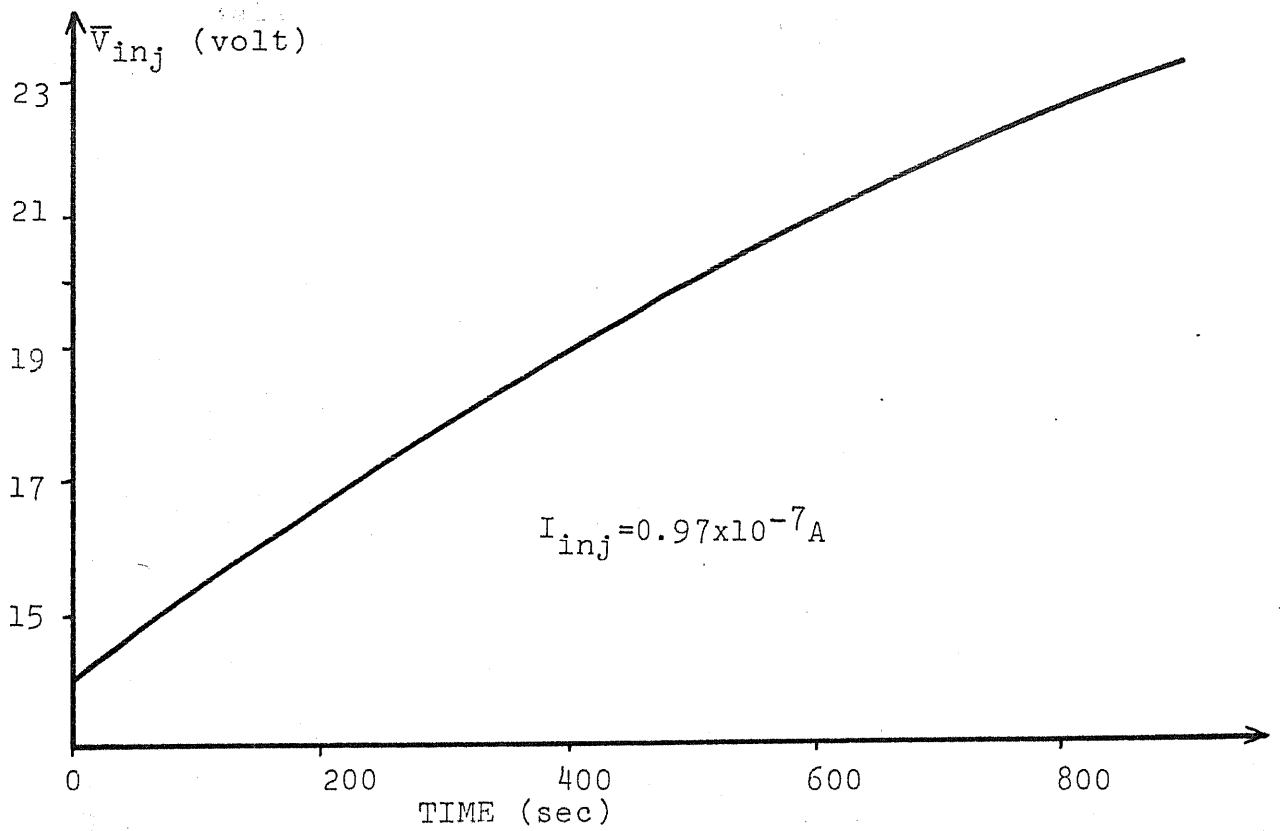


Fig. B-12 Measured \bar{V}_{inj} .

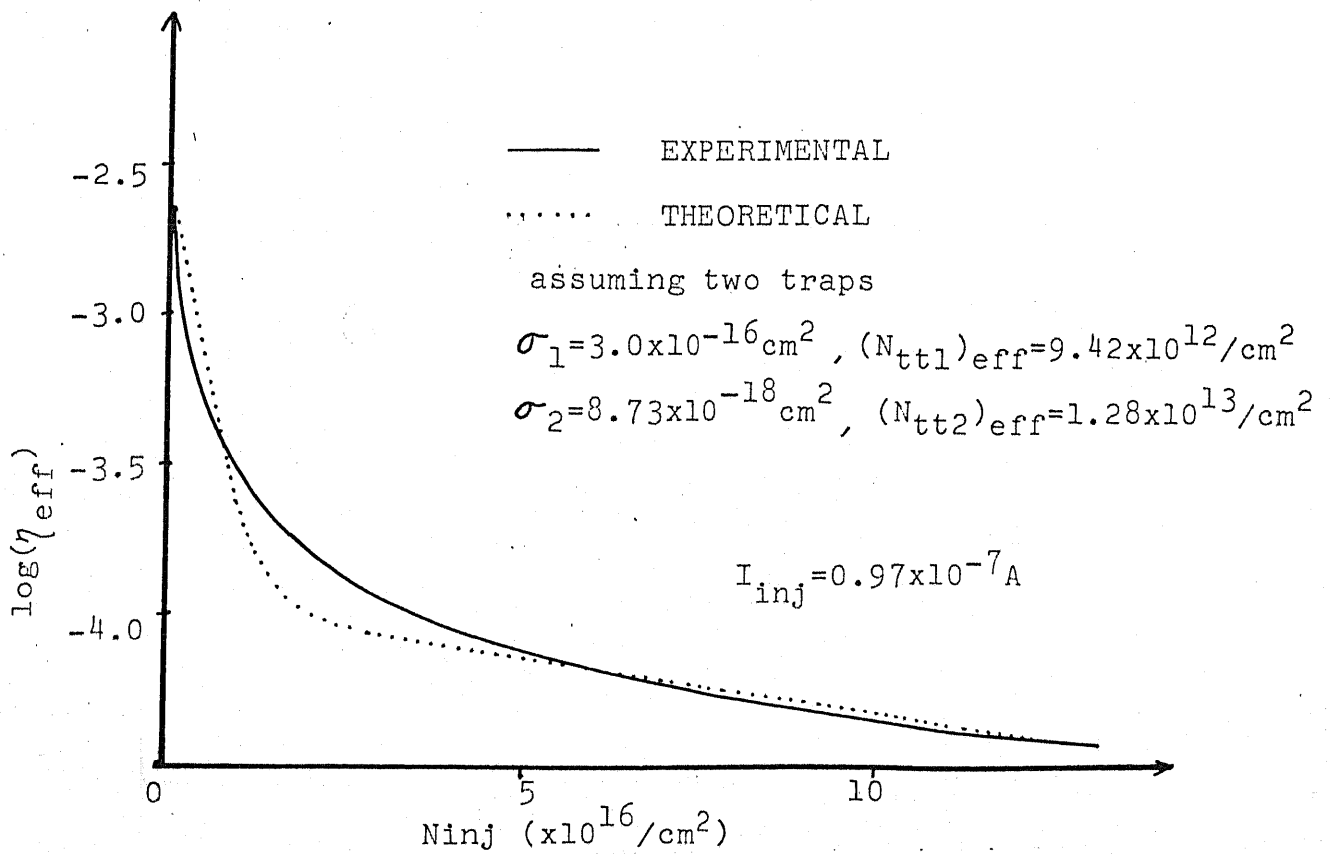


Fig. B-13 Measured $\log(\eta_{eff})$ with the theoretical fit where two kinds of traps are assumed to exist in SiO_2 film.

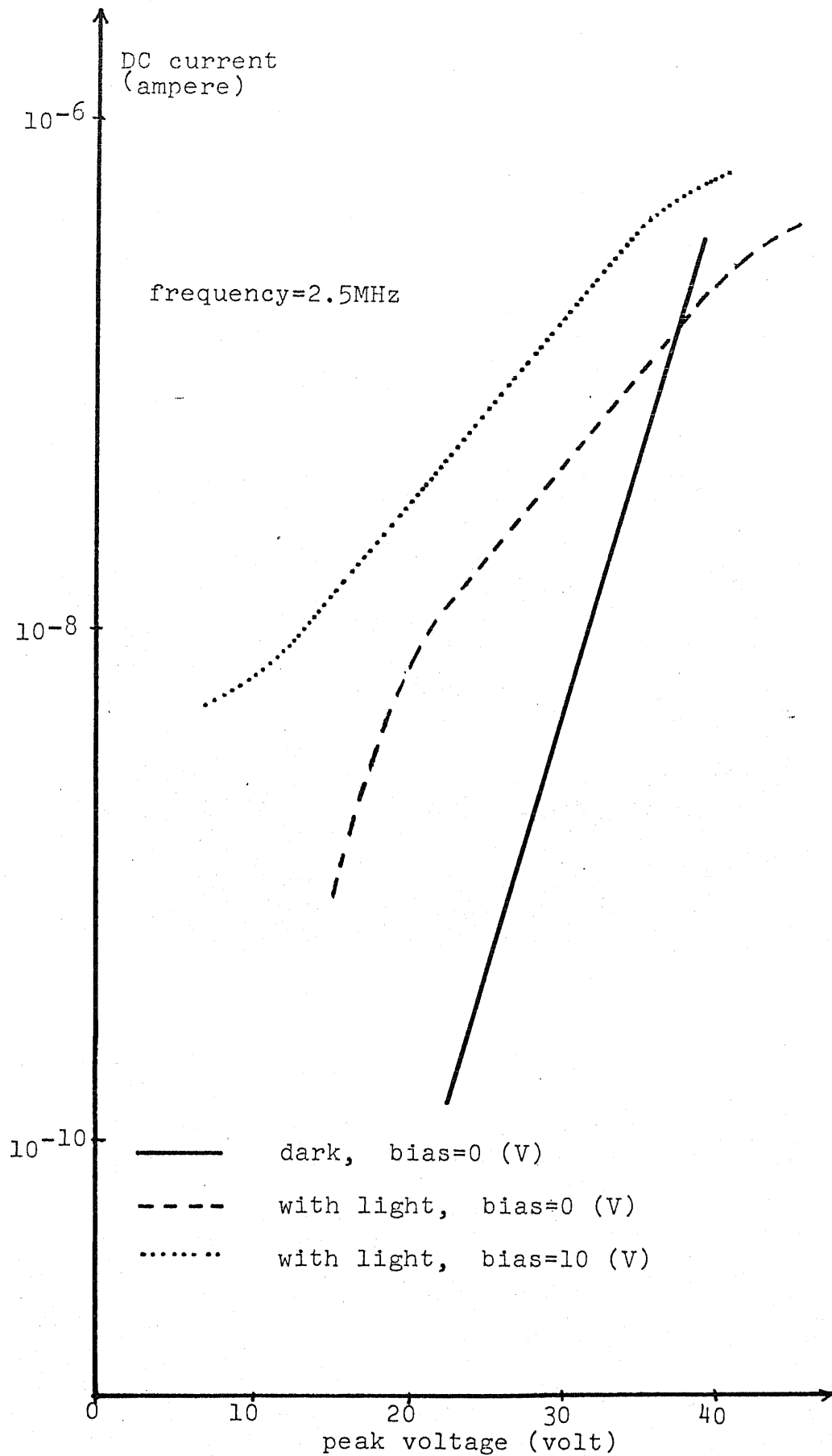


Fig. B-14 Avalanche current versus peak avalanche voltage

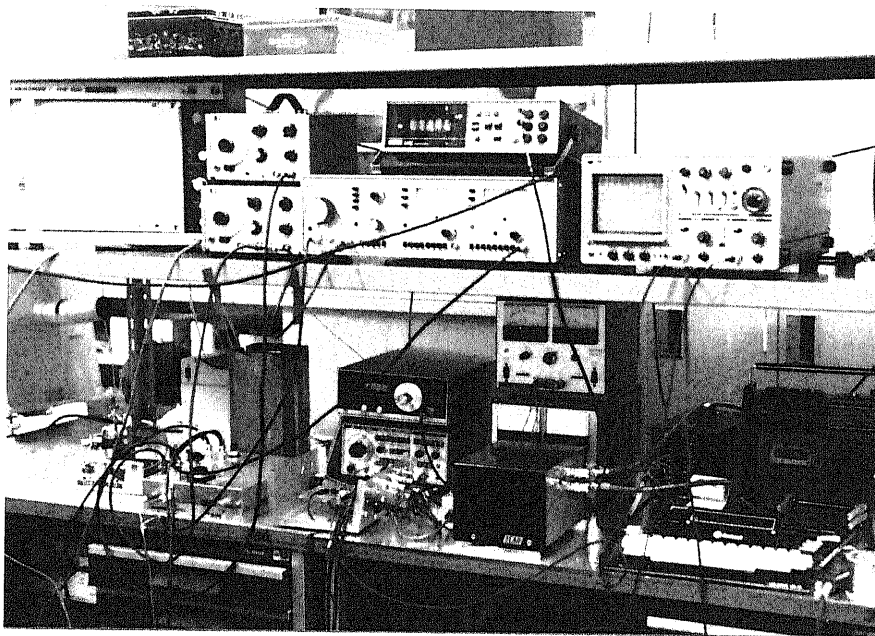


Photo. B-1. Setup for avalanche injection and photodepopulation measurements.

APPENDIX C USEFUL TABLES AND FIGURES

Some of the useful tables and figures used in this thesis are listed only for completion.

Table C-1. Best values of ξ for Slater type orbitals.

Table C-2. Valence Orbital Ionization Potential parameters.

Table C-3. Electro-negativity.

Fig. C-4. Ionicity versus electro-negativity.

Table C-1 Best values of ξ for the ground state of neutral atoms.*

Z	1s	2s	2p	3s	3p	4s	3d	4p
2.	1.6875							
3.	2.6906	0.6396						
4.	3.6848	0.9560						
5.	4.6795	1.2881	1.2107					
6.	5.6727	1.6083	1.5679					
7.	6.6651	1.9237	1.9170					
8.	7.6579	2.2458	2.2266					
9.	8.6501	2.5638	2.5500					
10.	9.6421	2.8792	2.8792					
11.	10.6259	3.2857	3.4009	0.8358				
12.	11.6089	3.6960	3.9129	1.1025				
13.	12.5910	4.1068	4.4817	1.3724	1.3552			
14.	13.5745	4.5100	4.9725	1.6344	1.4284			
15.	14.5578	4.9125	5.4806	1.8806	1.6288			
16.	15.5409	5.3144	5.9885	2.1223	1.8273			
17.	16.5239	5.7152	6.4966	2.3561	2.0387			
18.	17.5075	6.1152	7.0041	2.5856	2.2547			
19.	18.4895	6.5031	7.5136	2.8933	2.5752	0.8738		
20.	19.4730	6.8882	8.0207	3.2005	2.8861	1.0995		
21.	20.4566	7.2868	8.5273	3.4466	3.1354	1.1581	2.3733	
22.	21.4409	7.6883	9.0324	3.6777	3.3679	1.2042	2.7138	
23.	22.4256	8.0907	9.5364	3.9031	3.5950	1.2453	2.9943	
24.	23.4138	8.4919	10.0376	4.1226	3.8220	1.2833	3.2522	
25.	24.3957	8.8969	10.5420	4.3393	4.0364	1.3208	3.5094	
26.	25.3810	9.2995	11.0444	4.5587	4.2593	1.3585	3.7266	
27.	26.3668	9.7025	11.5462	4.7741	4.4782	1.3941	3.9518	
28.	27.3526	10.1063	12.0476	4.9870	4.6950	1.4277	4.1765	
29.	28.3386	10.5099	12.5485	5.1981	4.9102	1.4606	4.4002	
30.	29.3245	10.9140	13.0490	5.4064	5.1231	1.4913	4.6261	
31.	30.3094	11.2995	13.5454	5.6654	5.4012	1.7667	5.0311	1.5554
32.	31.2937	11.6824	14.0411	5.9299	5.6712	2.0109	5.4171	1.6951
33.	32.2783	12.0635	14.5368	6.1985	5.9499	2.2360	5.7928	1.8623
34.	33.2622	12.4442	15.0326	6.4678	6.2350	2.4394	6.1590	2.0718
35.	34.2471	12.8217	15.5282	6.7395	6.5236	2.6382	6.5197	2.2570
36.	35.2316	13.1990	16.0235	7.0109	6.8114	2.8289	6.8753	2.4423

Table C-2. VOIP Isoelectronic Fit Parameters*

Number of Electrons	Configuration	Electron	Standard Deviation	A ^b	B	C
1	1s	1s	0.0	109.84	219.2	109.7
2	1s ²	1s	0.1	109.82	301.7	198.4
2	1s 2p	1s	0.1	109.96	386.8	357.85
3	1s ² 2p	1s	0.1	110.15	467.2	524.8
1	2s	2s	0.0	27.48	54.8	27.4
3	1s ² 2s	2s	0.1	27.62	76.0	43.4
4	(He) 2s ²	2s	0.1	27.64	100.3	75.1
4	(He) 2s 2p	2s	0.3	27.76	81.3	47.9
5	(He) 2s ² 2p	2s	0.1	27.82	120.6	113.4
5	(He) 2s 2p ²	2s	0.3	27.91	119.1	122.25
6	(He) 2s ² 2p ²	2s	0.2	27.95	141.6	150.0
6	(He) 2s 2p ³	2s	0.4	28.00	141.2	171.0
7	(He) 2s ² 2p ³	2s	0.2	28.16	162.2	206.2
7	(He) 2s 2p ⁴	2s	0.1	28.05	163.3	220.0
8	(He) 2s ² 2p ⁴	2s	0.3	27.95	184.6	260.8
9	(He) 2s ² 2p ⁵	2s	0.5	28.07	205.7	323.0
10	(He) 2s ² 2p ⁶	2s	0.1	28.20	227.0	390.9
1	2p	2p	0.0	27.48	54.8	27.4
2	1s 2p	2p	0.1	27.52	57.8	28.0
3	1s ² 2p	2p	0.2	27.74	59.1	28.4
4	(He) 2s 2p	2p	0.2	27.72	97.0	79.8
4	(He) 2p ²	2p	0.4	27.57	76.1	45.35
5	(He) 2s ² 2p	2p	0.2	27.78	102.4	66.75
5	(He) 2s 2p ²	2p	0.3	28.02	90.1	67.0
5	(He) 2p ³	2p	0.1	27.25	94.0	61.4
6	(He) 2s ² 2p ²	2p	0.3	27.95	118.2	85.8
6	(He) 2s 2p ³	2p	0.4	28.03	111.95	80.9
6	(He) 2p ⁴	2p	0.1	28.06	105.4	88.1
7	(He) 2s ² 2p ³	2p	0.2	28.16	133.2	100.4
7	(He) 2s 2p ⁴	2p	2.1	30.01	114.0	129.4
8	(He) 2s ² 2p ⁴	2p	0.4	27.94	149.75	127.4
8	(He) 2s 2p ⁵	2p	0.1	27.76	145.2	126.4
9	(He) 2s ² 2p ⁵	2p	0.4	27.93	165.5	150.4
9	(He) 2s 2p ⁶	2p	0.8	28.22	157.7	155.1
10	(He) 2s ² 2p ⁶	2p	0.3	28.25	180.2	173.9
11	(Ne) 3s	3s	0.0	13.18	68.0	41.0
12	(Ne) 3s ²	3s	0.5	13.13	78.2	61.25
12	(Ne) 3s 3p	3s	0.5	13.14	78.0	71.7
13	(Ne) 3s ² 3p	3s	0.8	13.15	80.0	90.8
13	(Ne) 3s 3p ²	3s	0.0 ^c	9.50	103.0	89.4
14	(Ne) 3s ² 3p ²	3s	1.3	13.08	99.9	119.6
14	(Ne) 3s 3p ³	3s	2.0	11.12	118.2	111.2
15	(Ne) 3s ² 3p ³	3s	0.3	14.27	100.7	151.4
16	(Ne) 3s ² 3p ⁴	3s	0.3	12.23	124.0	168.7
17	(Ne) 3s ² 3p ⁵	3s	0.2	13.70	126.7	203.8
18	(Ne) 3s ² 3p ⁶	3s	0.3	13.24	138.6	235.0
11	(Ne) 3p	3p	0.7	13.33	40.4	23.9
12	(Ne) 3s 3p	3p	0.6	13.21	60.5	36.0
12	(Ne) 3p ²	3p	0.6	12.05	61.9	41.3
13	(Ne) 3s ² 3p	3p	0.0	13.20	71.1	47.85
13	(Ne) 3s 3p ²	3p	0.6	12.44	75.65	42.8
14	(Ne) 3s ² 3p ²	3p	0.3	13.02	81.7	62.5
14	(Ne) 3s 3p ³	3p	2.8	8.82	110.7	19.4
14	(Ne) 3s ² 3p 4s	3p	0.0	13.36	86.3	90.5
15	(Ne) 3s ² 3p ³	3p	0.0 ^c	15.25	83.9	81.0
15	(Ne) 3s 3p ⁴	3p	1.3	14.25	83.85	100.1
15	(Ne) 3s ² 3p ² 4s	3p	0.7	14.63	91.3	114.8
16	(Ne) 3s ² 3p ⁴	3p	0.7	13.17	98.5	93.4
16	(Ne) 3s 3p ⁵	3p	0.7	13.88	94.9	99.7
16	(Ne) 3s ² 3p ³ 4s	3p	0.4	13.57	102.4	131.6
17	(Ne) 3s ² 3p ⁵	3p	0.4	13.49	106.3	110.4
17	(Ne) 3s 3p ⁶	3p	0.0 ^c	13.40	106.4	116.0
17	(Ne) 3s ² 3p ¹ 4s	3p	0.2	13.36	112.0	153.3
18	(Ne) 3s ² 3p ⁶	3p	0.1	13.36	116.6	127.5
18	(Ne) 3s ² 3p ⁵ 4s	3p	0.6	13.39	121.5	175.3
19	(Ar) 3d	3d	0.1	13.10	24.5	12.2
11	(Ne) 4s	4s	0.3	7.47	29.0	15.5
12	(Ne) 3s 4s	4s	0.1	7.67	32.2	19.8
13	(Ne) 3s ² 4s	4s	0.2	7.65	36.1	22.85
14	(Ne) 3s ² 3p 4s	4s	0.8	7.79	39.7	25.15
15	(Ne) 3s ² 3p ² 4s	4s	1.0	9.30	38.5	31.8
16	(Ne) 3s ² 3p ³ 4s	4s	0.2	7.82	45.35	30.1
17	(Ne) 3s ² 3p ⁴ 4s	4s	0.3	8.00	48.0	32.1
18	(Ne) 3s ² 3p ⁵ 4s	4s	0.4	7.99	51.9	33.6
19	(Ar) 4s	4s	0.1	8.09	53.5	34.7

All numbers in 1000cm⁻¹

Multiplication by 0.12398 gives the number in eV.

$$VOIP(q) = Aq^2 + Bq + C$$

, where q is excess charge.

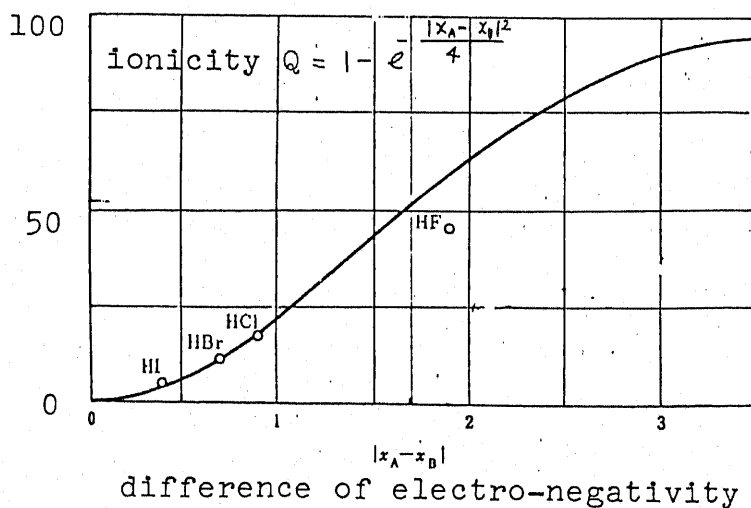
H. Basch et al, Theoret.

Chim. Acta 3, 458 (1965)

Table C-3. Electro-negativity

H																	B	C	N	O	F
2.1																	2.0	2.5	3.0	3.5	4.0
Li	Be															Al	Si	P	S	Cl	
1.0	1.5															1.5	1.8	2.1	2.5	3.0	
Na	Mg															Ga	Ge	As	Se	Br	
0.9	1.2															1.6	1.8	2.0	2.4	2.8	
K	Ca	Sc	Ti	V	Cr	Mn	Fe	Co	Ni	Cu	Zn	Ga	Ge	As	Se	Br					
0.8	1.0	1.3	1.5	1.6	1.6	1.5	1.8	1.8	1.8	1.9	1.6	1.6	1.8	2.0	2.4	2.8					
Rb	Sr	Y	Zr	Nb	Mo	Tc	Ru	Rh	Pd	Ag	Cd	In	Sn	Sb	Te	I					
0.8	1.0	1.2	1.4	1.6	1.8	1.9	2.2	2.2	2.2	1.9	1.7	1.7	1.8	1.9	2.1	2.5					
Cs	Ba	La-Lu	Hf	Ta	W	Re	Os	Ir	Pt	Au	Hg	Tl	Pb	Bi	Po	At					
0.7	0.9	1.1-1.2	1.3	1.5	1.7	1.9	2.2	2.2	2.2	2.4	1.9	1.8	1.8	1.9	2.0	2.2					
Fr	Ra	Ac	Th	Pa	U	Np-No															
0.7	0.9	1.1	1.3	1.5	1.7	1.3															

Fig. C-4. Ionicity



APPENDIX D

DERIVATION OF Eq. 4-4-4

In the problem of crystalline solids, the eigen value is specified by a k -vector and a band number n . Therefore, the spectrum decomposition of Green's function is written as

$$(EI-H)^{-1} = \sum_{n, k} \frac{|En^k\rangle\langle En^k|}{E-En^k} \quad \text{Eq. D-1}$$

Here, $|En^k\rangle$ is expressed as

$$|En^k\rangle = \frac{1}{\sqrt{N}} \begin{pmatrix} \vdots \\ |En_0^k\rangle \\ |En_0^k\rangle e^{ikR_1} \\ |En_0^k\rangle e^{ikR_2} \\ \vdots \\ |En_\nu^k\rangle e^{ikR_\nu} \end{pmatrix} \quad \text{Eq. D-2}$$

This is derived from the Bloch's theorem. In Eq. D-2, $|En_0^k\rangle$ represents the eigen vector belonging to the central unit cell, R_ν denotes the directional vector from the central unit cell to the ν -th unit cell, and N is the number of unit cells included in the system. Substitution of Eq. D-2 into Eq. D-1 yields

$$(EI-H)^{-1} = \frac{1}{N} \sum_k \begin{pmatrix} \ddots & & & & \\ & G^k & G^k e^{-ikR_1} & G^k e^{-ikR_2} & \\ & G^k e^{ikR_1} & G^k & G^k e^{-ik(R_2-R_1)} & \\ & G^k e^{ikR_2} & G^k e^{ik(R_2-R_1)} & G^k & \\ & & & & \ddots \end{pmatrix} \quad \text{Eq. D-3}$$

,where

$$G^k = \sum_n \frac{|En_0^k\rangle \langle En_0^k|}{E - En^k} \quad \text{Eq. D-4}$$

Up to this point it is shown that the Green's function based on usual atomic orbitals as a basis set is written as

$$\begin{aligned} &\text{The part of } (EI-H)^{-1} \text{ for the central unit cell} \\ &= \frac{1}{N} \sum_k G^k \quad \text{Eq. D-5} \end{aligned}$$

The next step is to know the meaning of G^k .

Substitution of Eq. D-2 into the original eigen value problem becomes

$$E_n^k \begin{pmatrix} \vdots \\ |En_0^k\rangle \\ |En_0^k\rangle e^{ikR_1} \\ |En_0^k\rangle e^{ikR_2} \\ \vdots \\ |En_0^k\rangle e^{ikR_D} \end{pmatrix} - \begin{pmatrix} \dots & & & & \\ & H_{00} & H_{01} & H_{02} & \\ & H_{10} & H_{11} & H_{12} & \\ & H_{20} & H_{21} & H_{22} & \\ & & & \dots & \end{pmatrix} \begin{pmatrix} \vdots \\ |En_0^k\rangle \\ |En_0^k\rangle e^{ikR_1} \\ |En_0^k\rangle e^{ikR_2} \\ \vdots \\ |En_0^k\rangle e^{ikR_D} \end{pmatrix} = 0$$

Eq. D-6

All the equations derived from Eq. D-6 turn out to be the same as

$$E_n^k |En_0^k\rangle - \left(\sum_{\nu} H_{0\nu} e^{ikR_{\nu}} \right) |En_0^k\rangle = 0 \quad \text{Eq. D-7}$$

For example,

$$E_n^k e^{ikR_1} |En_0^k\rangle - \left(\sum_{\nu} H_{1\nu} e^{ikR_{\nu}} \right) |En_0^k\rangle = 0 \quad \text{Eq. D-8}$$

can be rewritten as

$$e^{ikR_1} [E_n^k |En_0^k\rangle - \left(\sum_{\nu} H_{0\nu} e^{ikR_{\nu}} \right) |En_0^k\rangle] = 0 \quad \text{Eq. D-9}$$

If we put

$$\sum_{\nu} H_{0\nu} e^{ikR\nu} = H^k \quad , \quad \text{Eq. D-10}$$

we have

$$(E\hat{n}^k I - H^k) |E\hat{n}_0^k\rangle = 0 \quad . \quad \text{Eq. D-11}$$

This eigen value problem happens to equal to that based on the Bloch orbitals as a basis set. This fact and the following equation

$$G^k = (EI - H^k)^{-1} \quad \text{Eq. D-12}$$

shows that G^k is a Green's function based on the Bloch orbitals as a basis set. So that with Eq. D-5, Eq. 4-4-4 is derived.